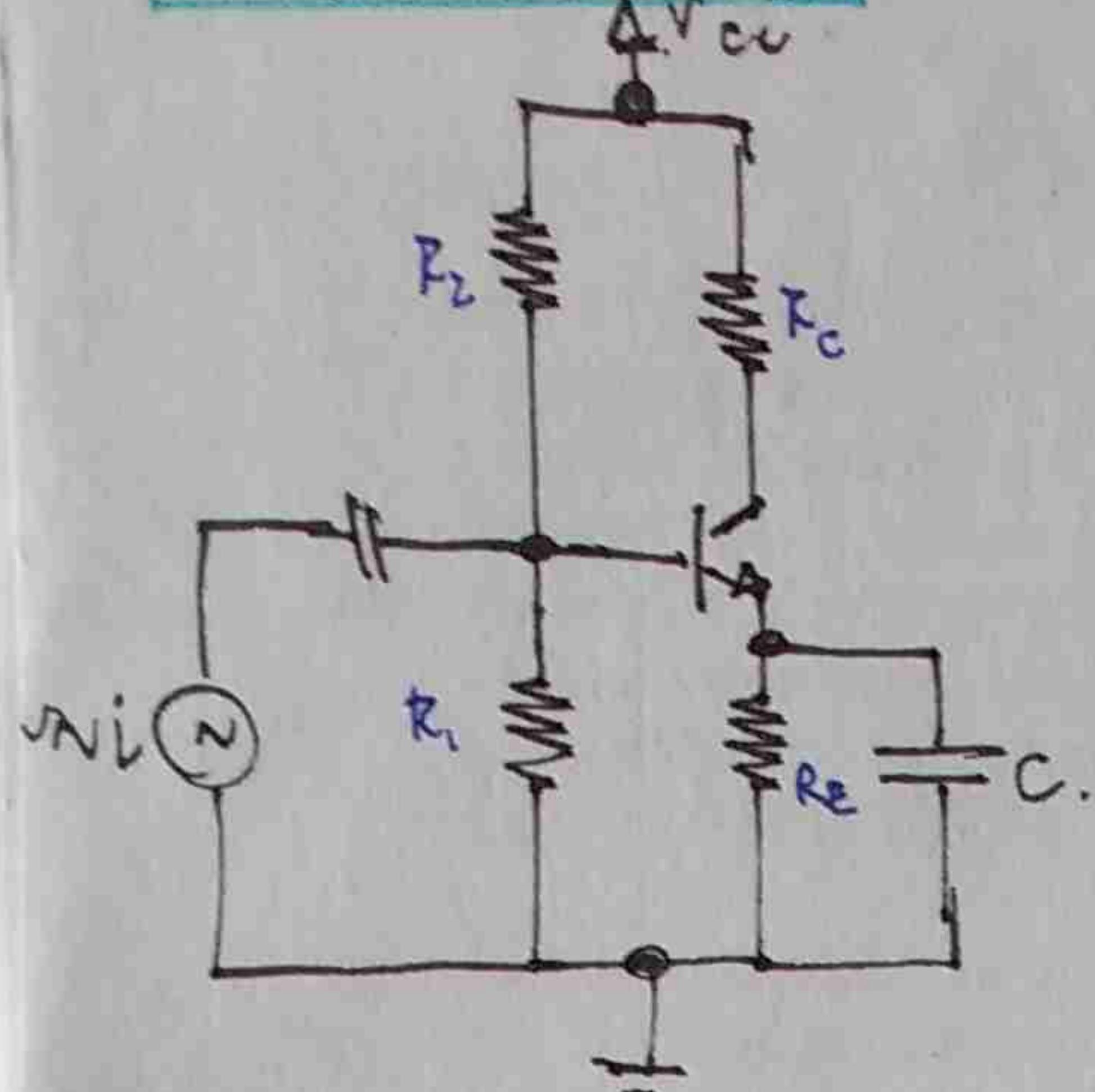
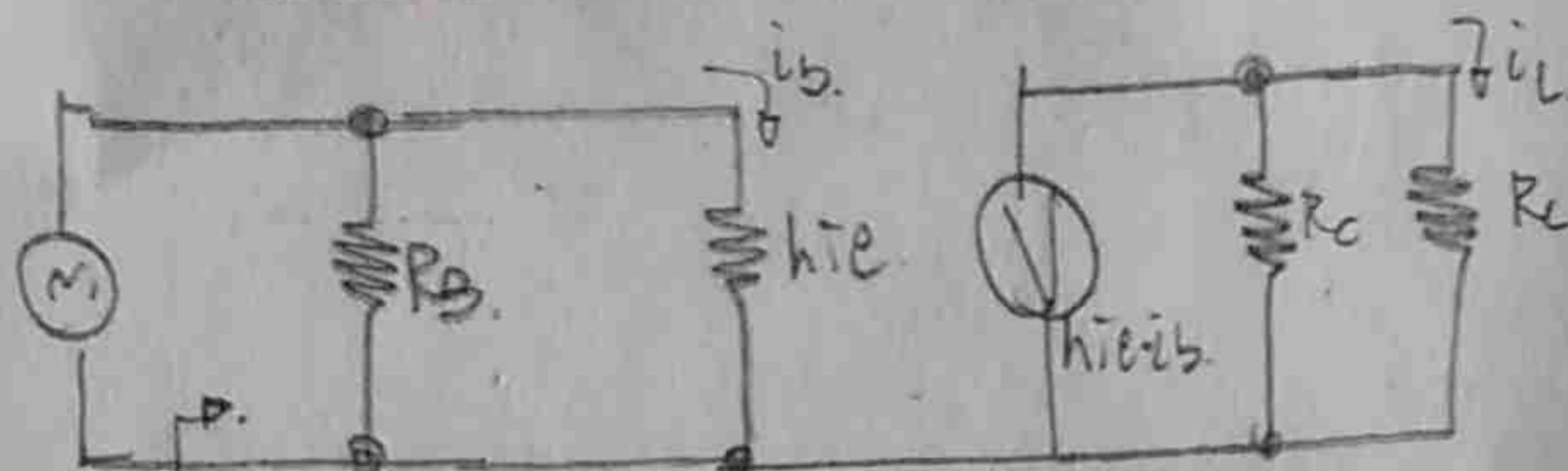


Emissor Comum

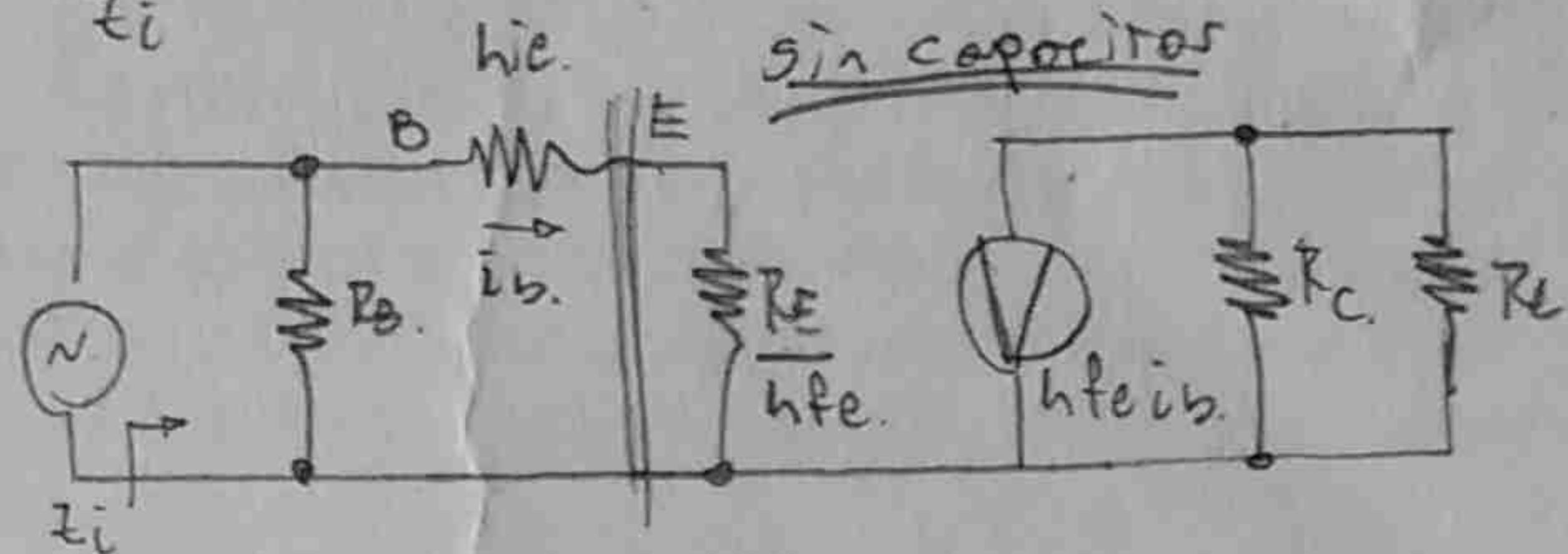


Con Capacitor

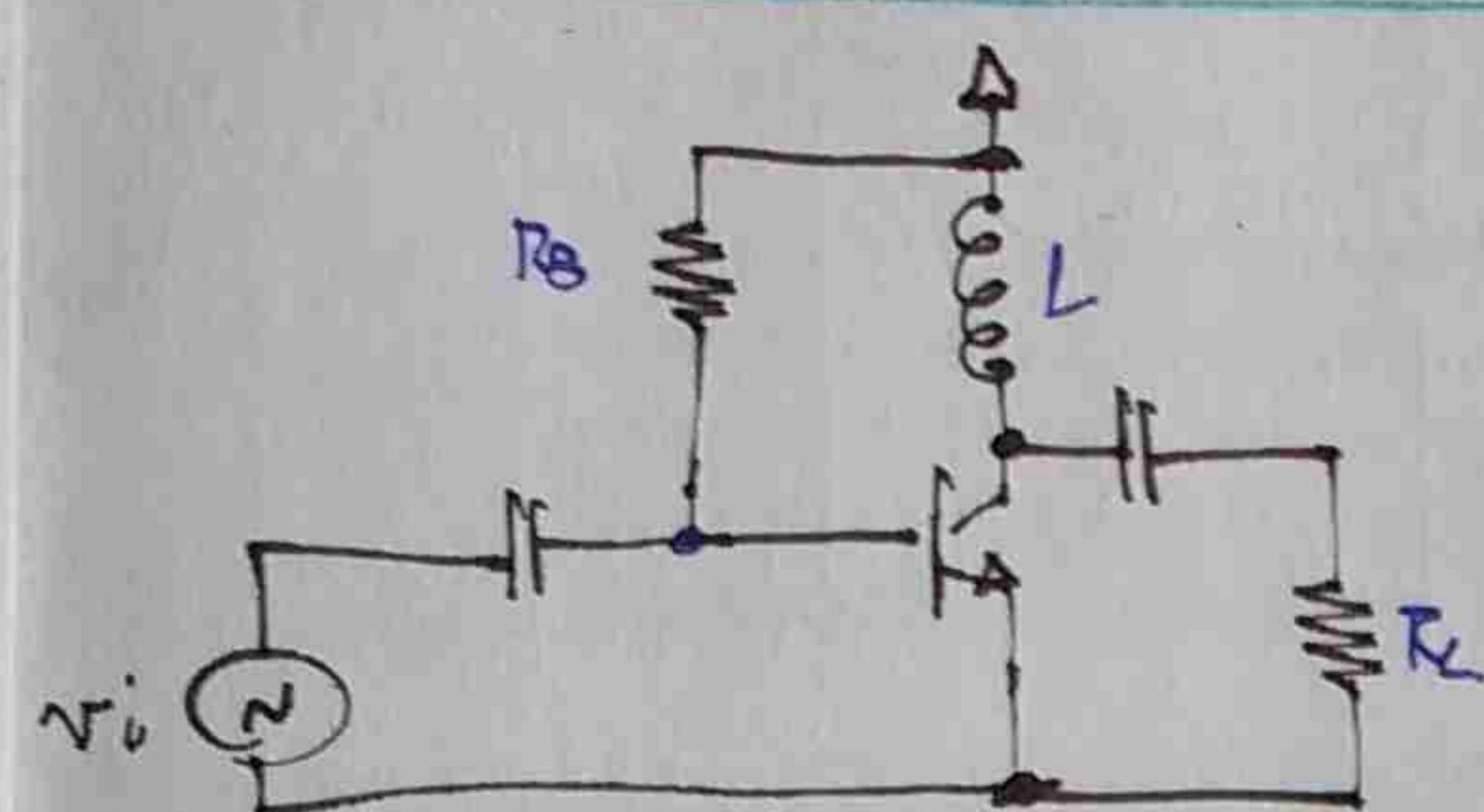


(15)

sin capacitor



Clase A con Transistor

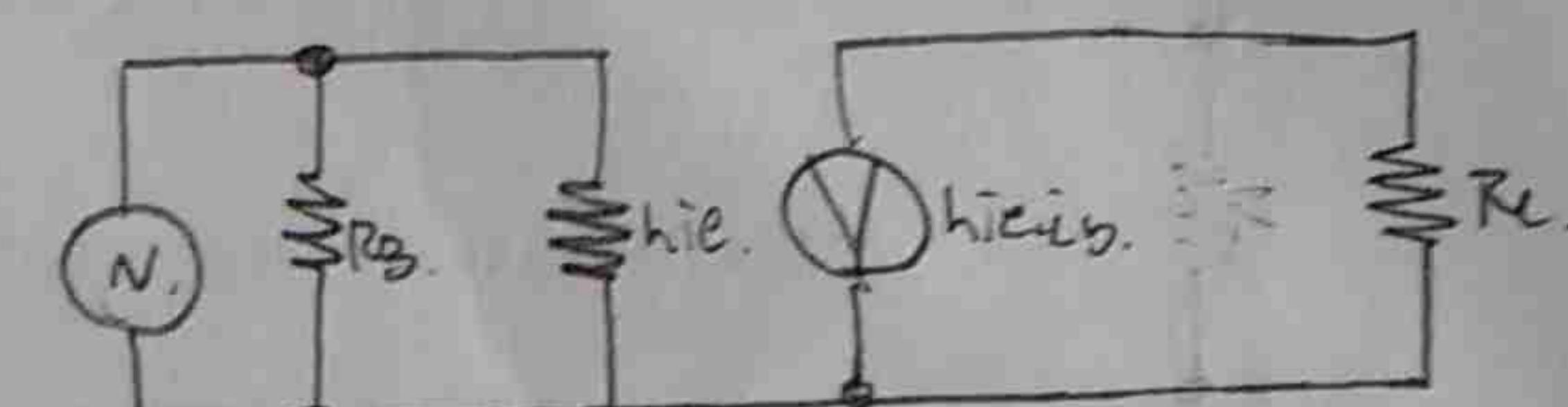


$$FM = z = \frac{P_C}{P_{L \text{ max.}}}$$

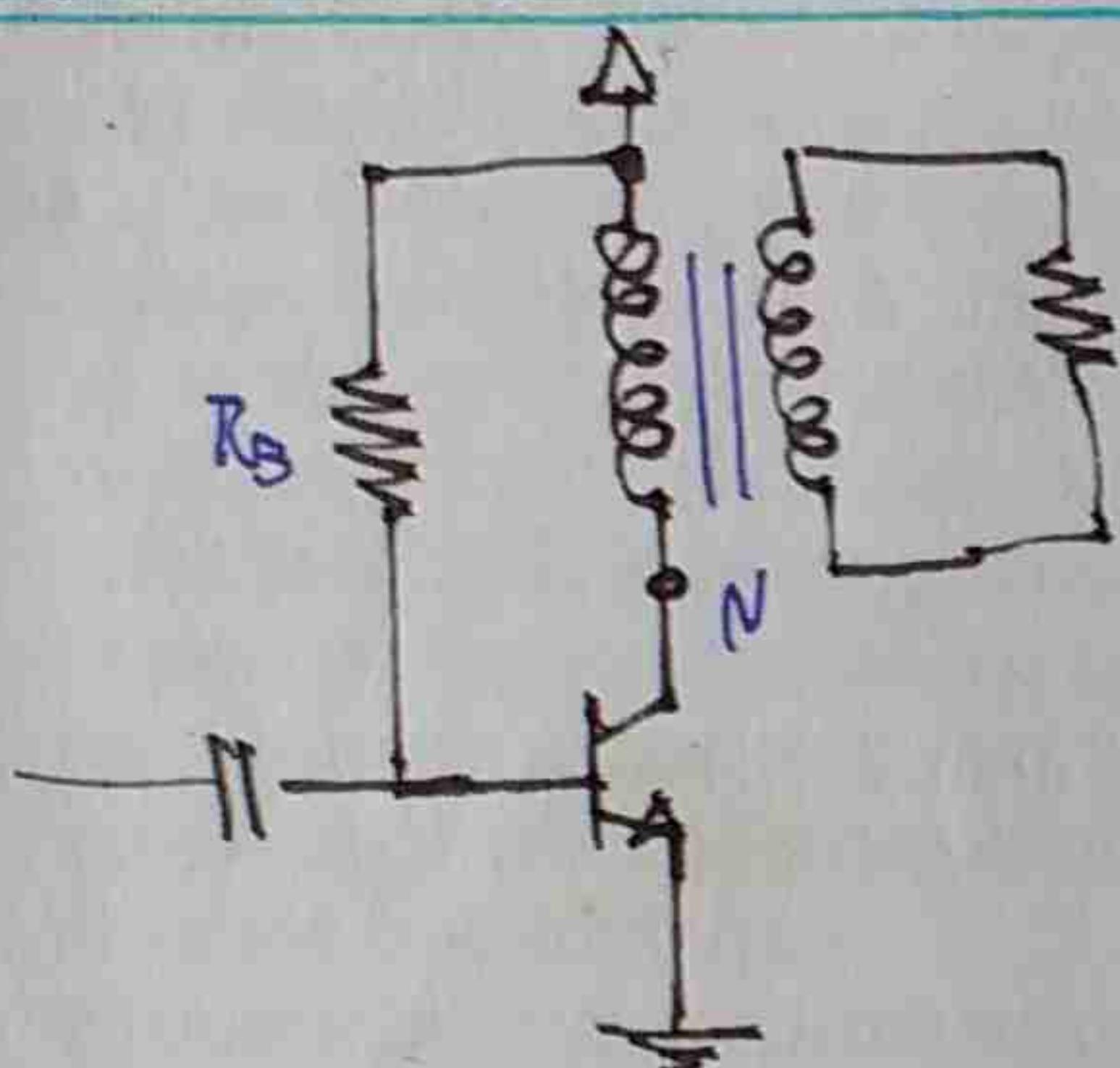
$$I_{CQ} = \frac{V_{CC}}{R_L}$$

$$P_{C \text{ max.}} = \frac{V_{CC}^2}{R_L}$$

$$P_{C \text{ max.}} = \frac{P_{L \text{ max.}}}{z} = \frac{V_{CC}^2}{R_L} = V_{CC} I_{CQ}$$



Clase A con transformador

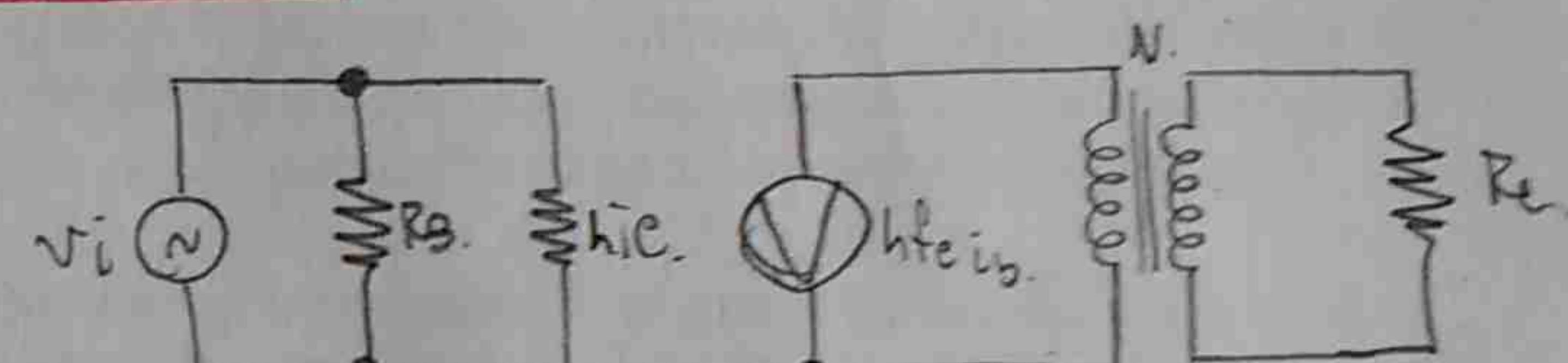


$$R'_L = N^2 R_L$$

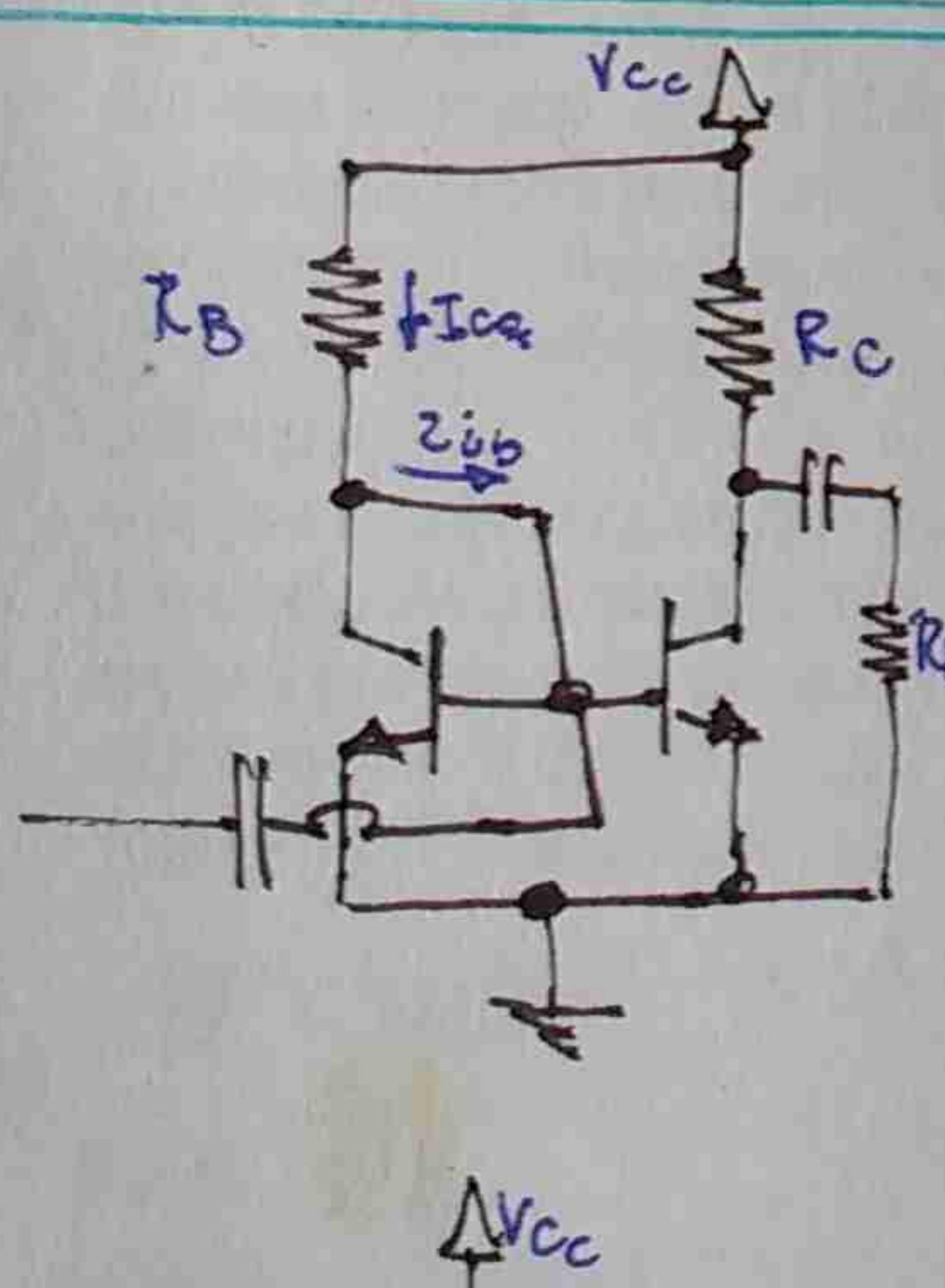
$$I_{CQ} = \frac{V_{CC}}{N^2 R_L}$$

$$P_{L \text{ max.}} = \frac{V_{CC}^2}{2 R'_L}$$

$$P_{C \text{ max.}} = V_{CC} I_{CQ}$$



Espejo Corriente. - Polarización Balanceada.



$$I_{CQ1} = I_{CQ2} (\text{Espejo})$$

$$V_{CC} = R_B \cdot \left(I_{CQ} + \frac{I_{CQ}}{hfe} \right) + V_{BE}$$

$$V_{CC} = R_B I_{CQ} \left(\frac{\beta + 2}{\beta} \right) + V_{BE}$$

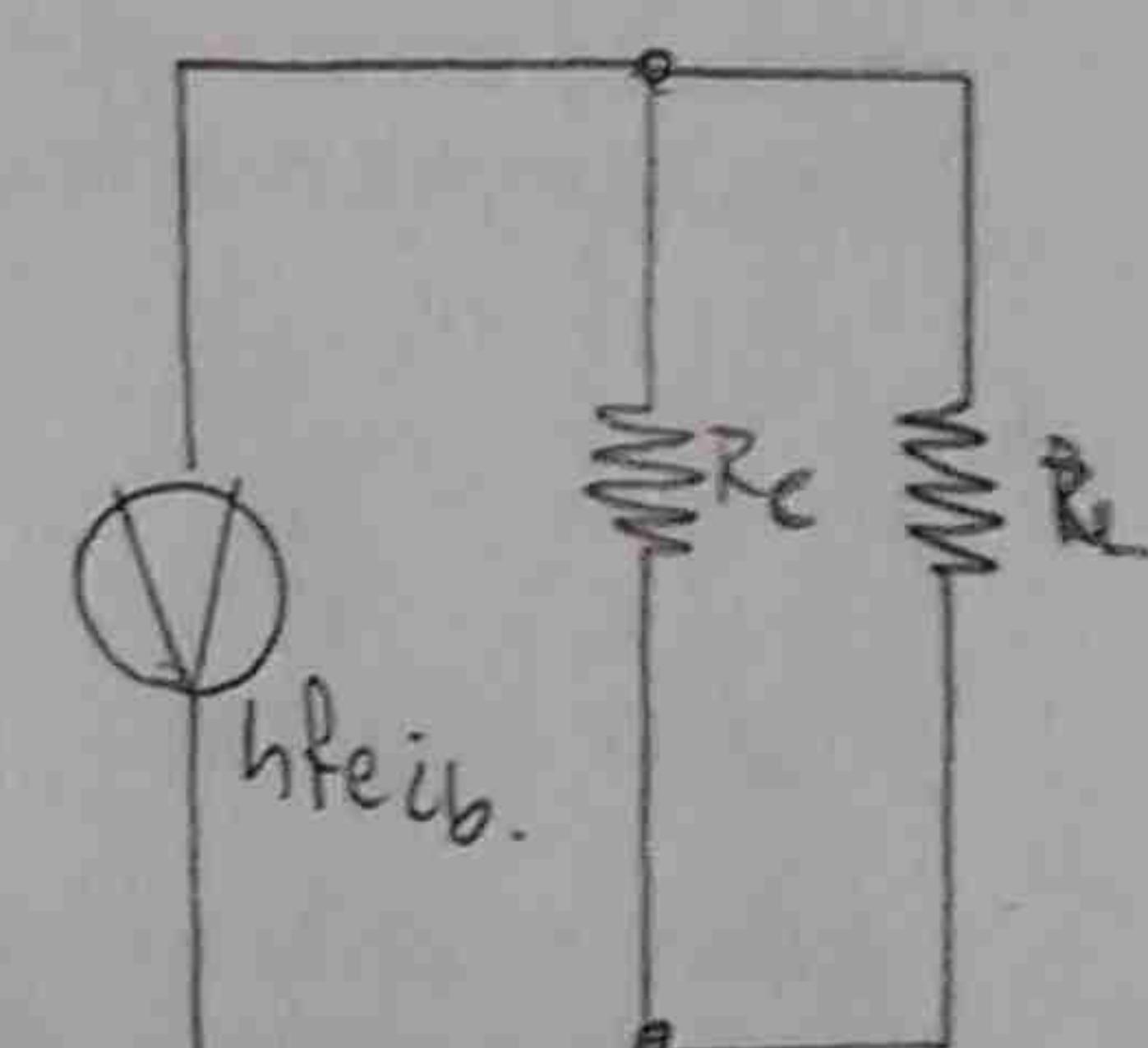
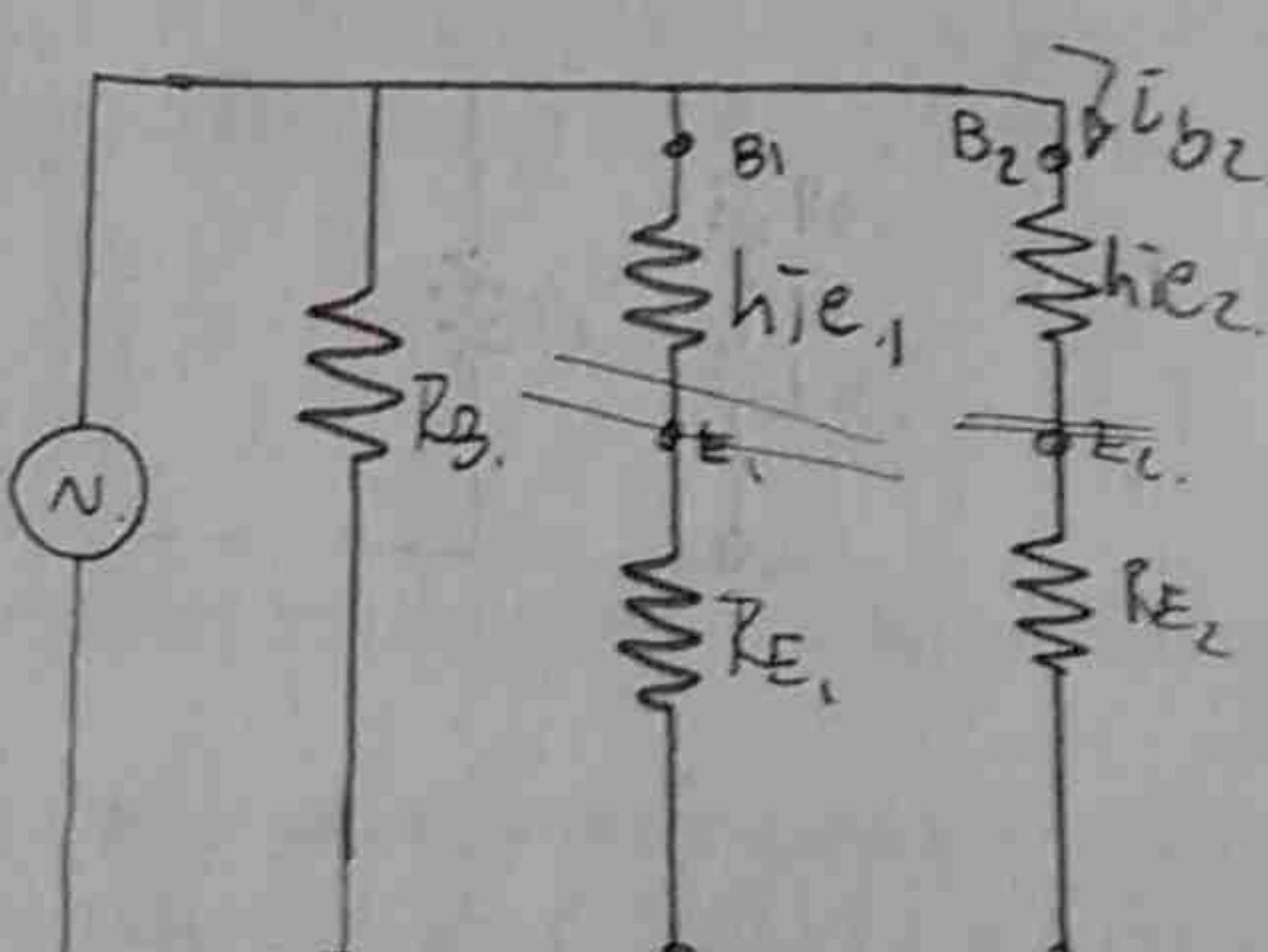
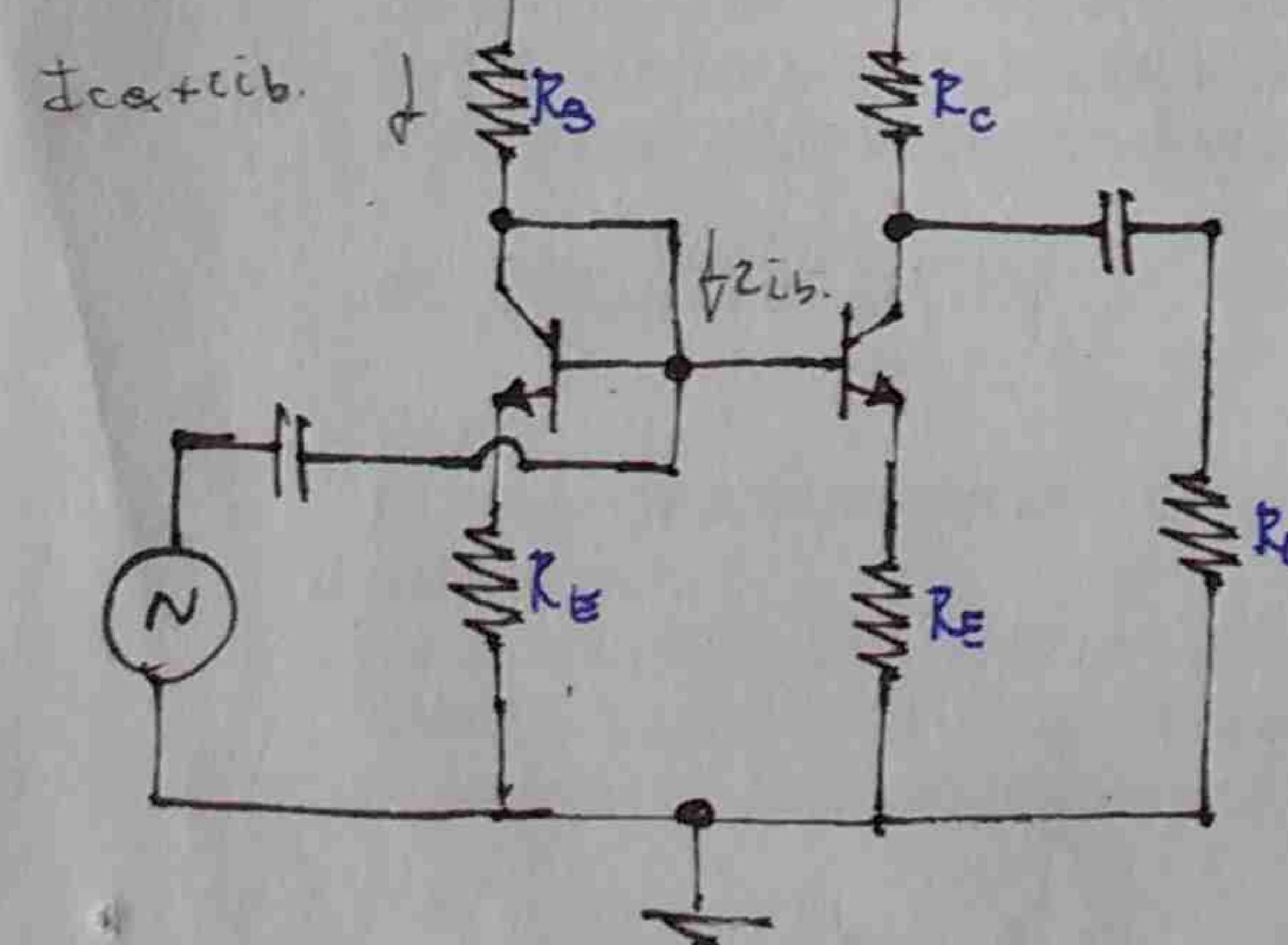
$$I_{CQ} = \frac{V_{CC} - V_{BE}}{R_B}$$

MES en el punto:

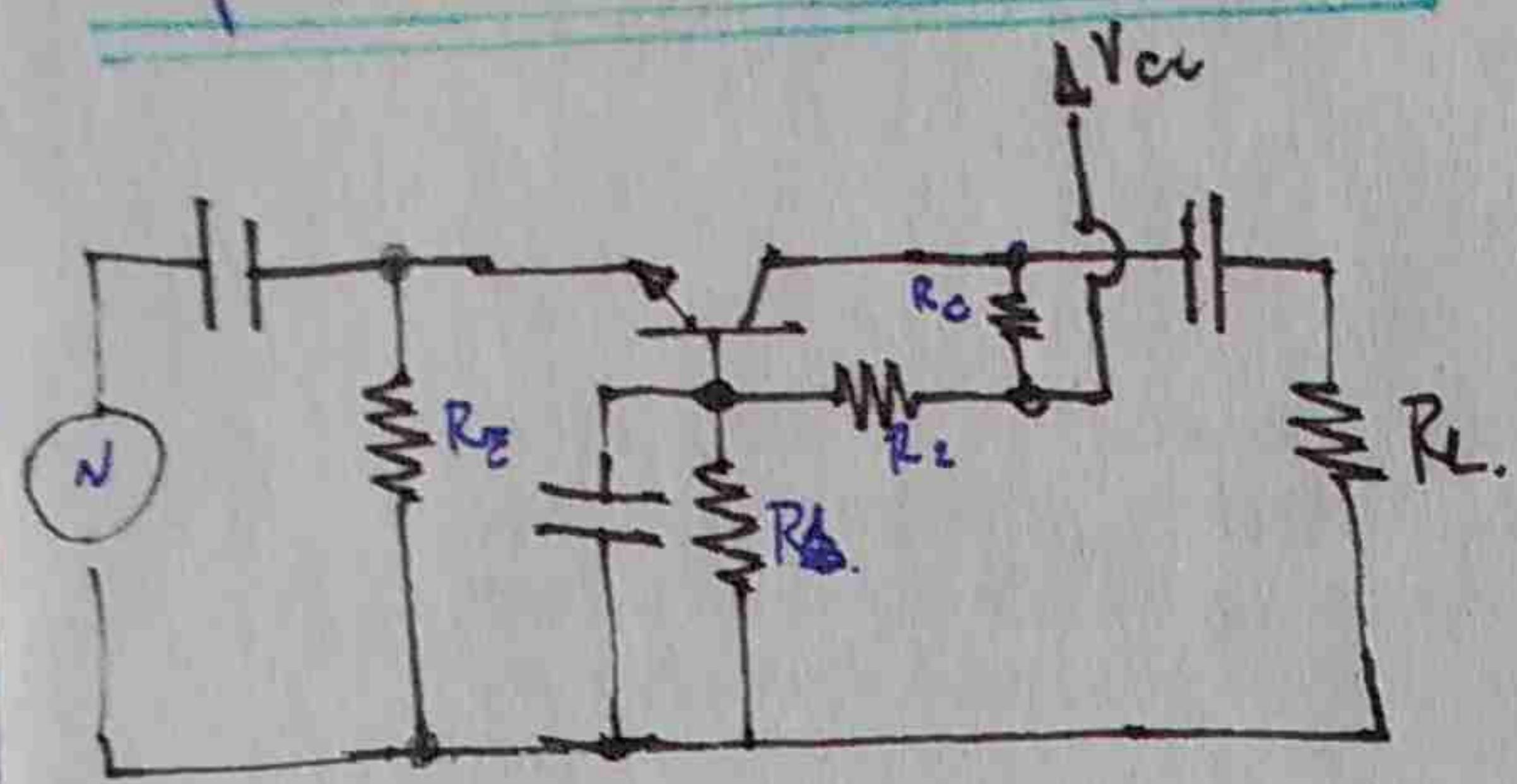
$$I_{CQ \text{ MES}} = \frac{V_{CC}}{R_{CQ} + R_{CE}}$$

$$V_{CEQ \text{ MES}} = V_{CC} - I_{CQ \text{ MES}} R_C$$

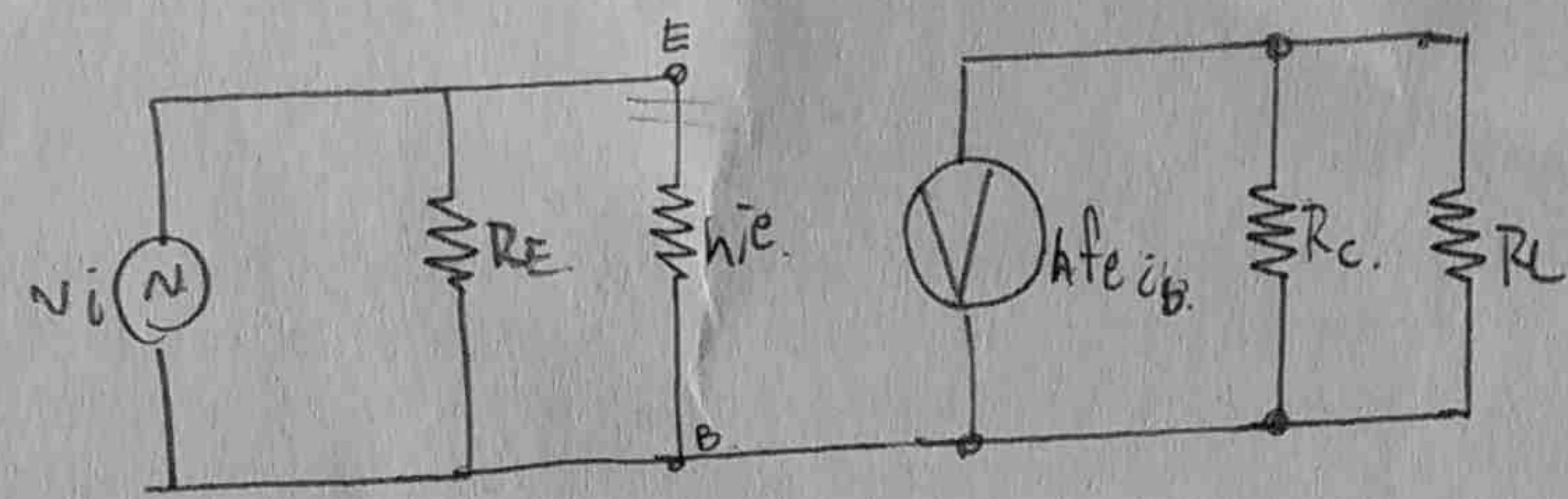
$$R_{CQ \text{ MES}} = \frac{V_{CC} - V_{BE}}{I_{CQ \text{ MES}}}$$



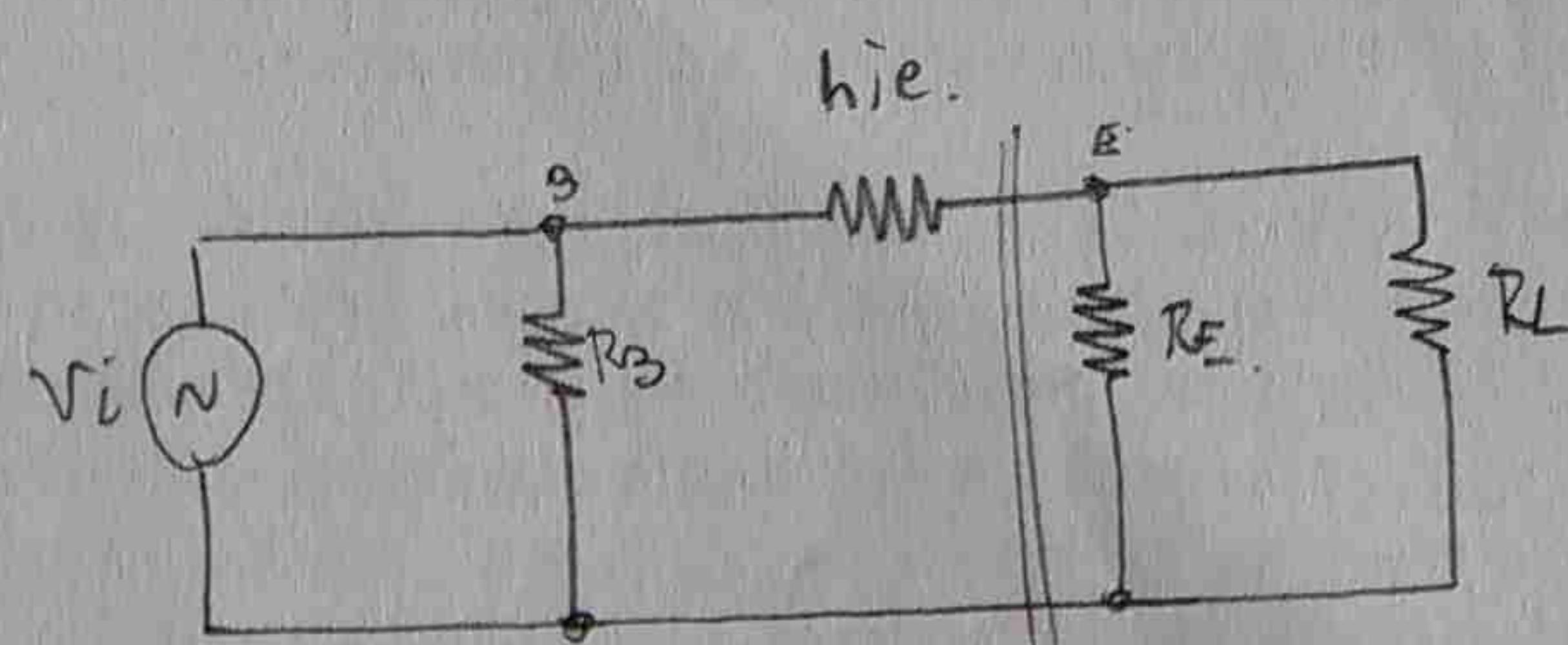
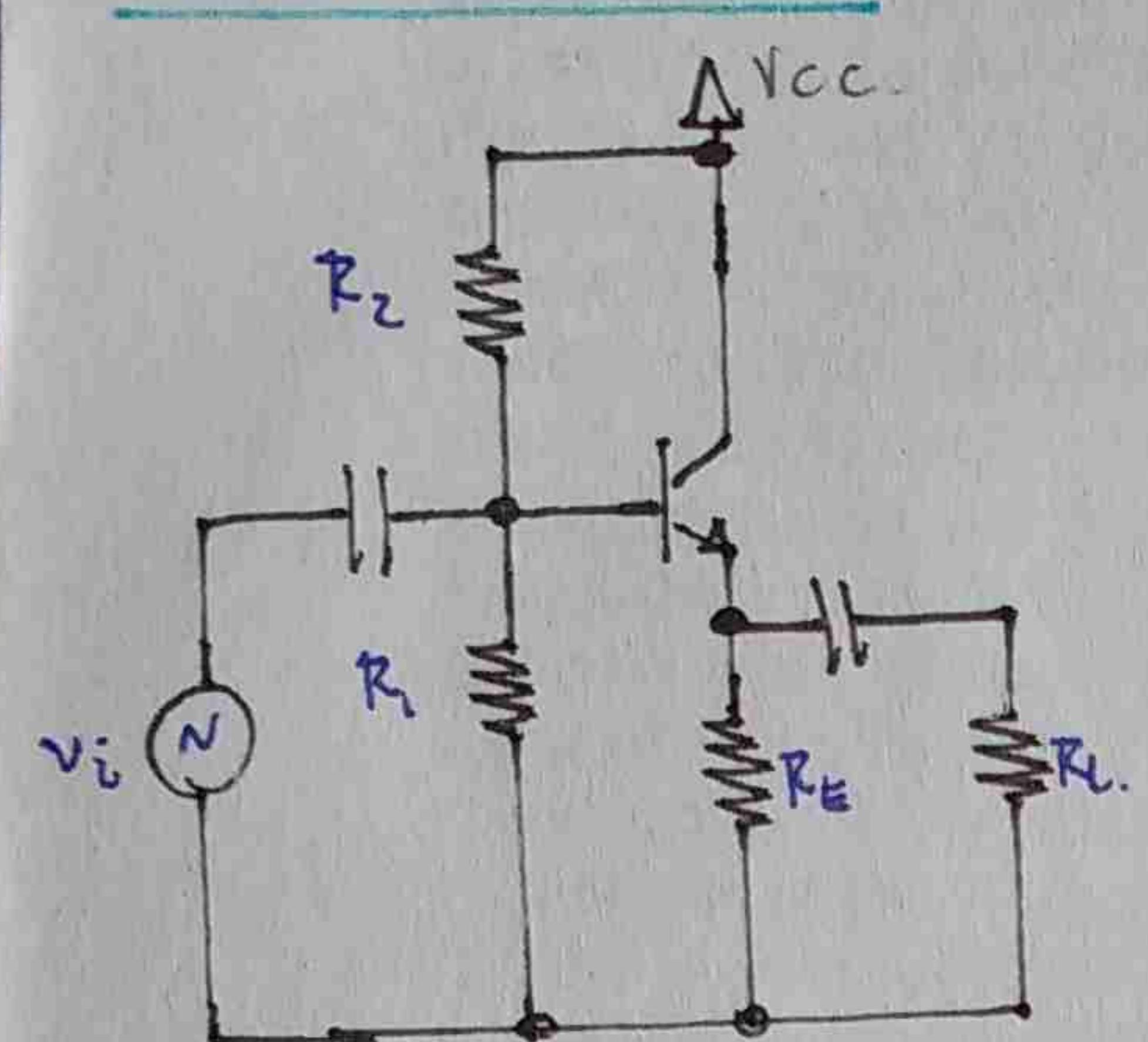
Amplificador Base común



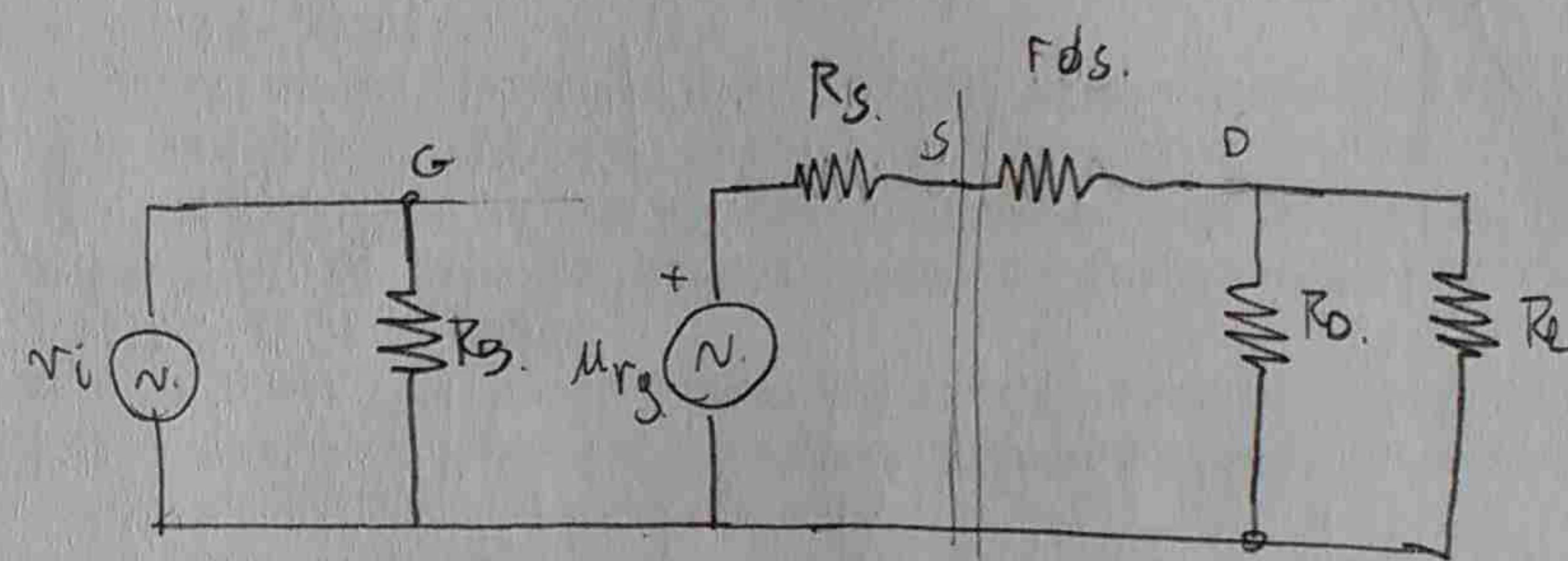
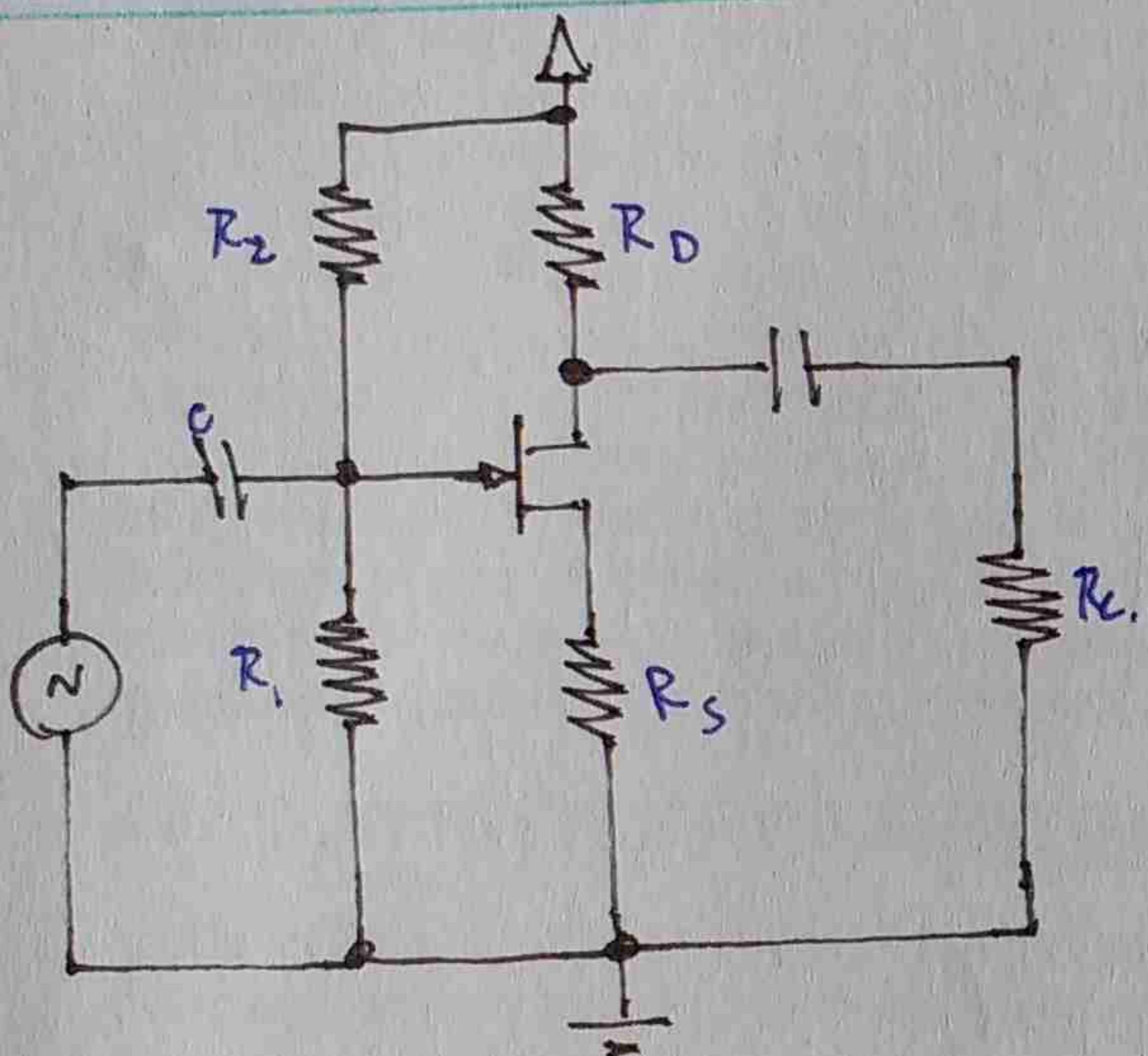
No se refleja.



Colector Común



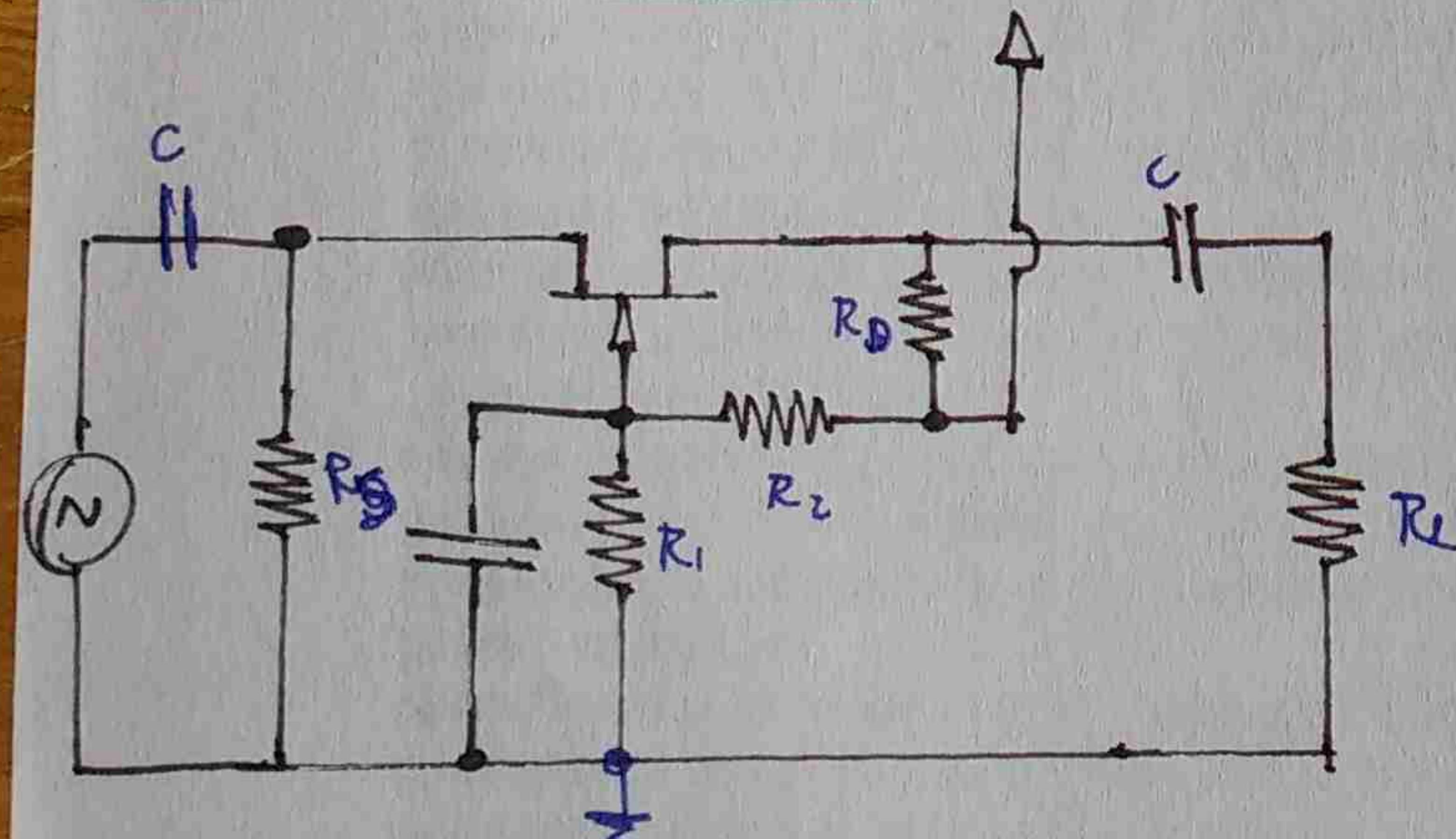
Surtidor Común sin cap. de desacopl.



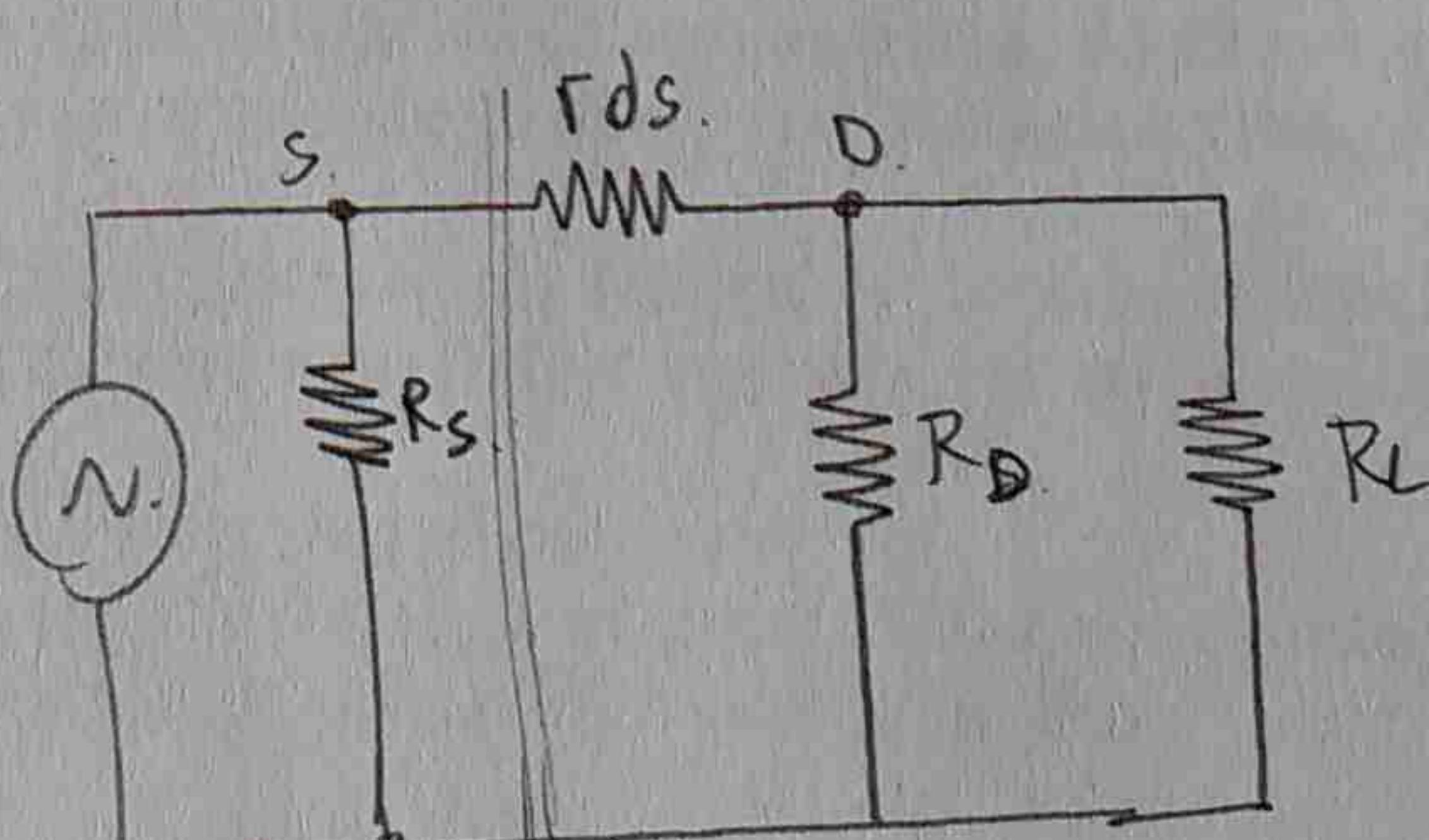
MVg \downarrow $g_m Vg$ \uparrow

$S \parallel D$

Compuerto Común

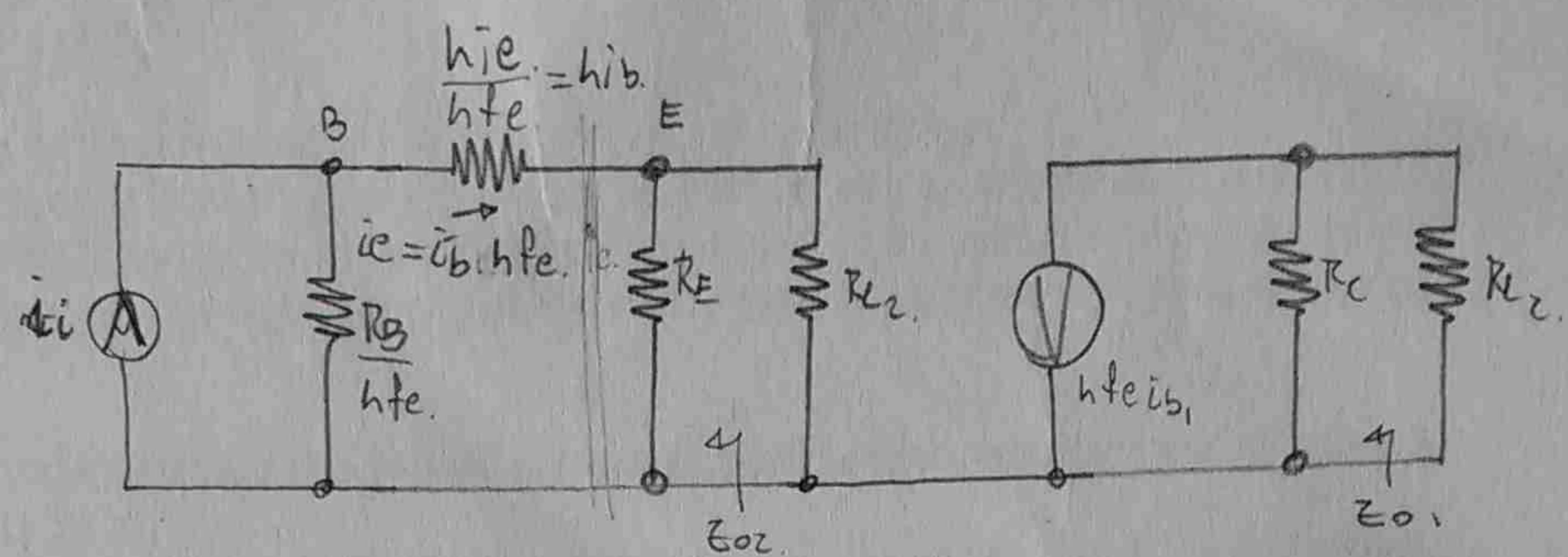
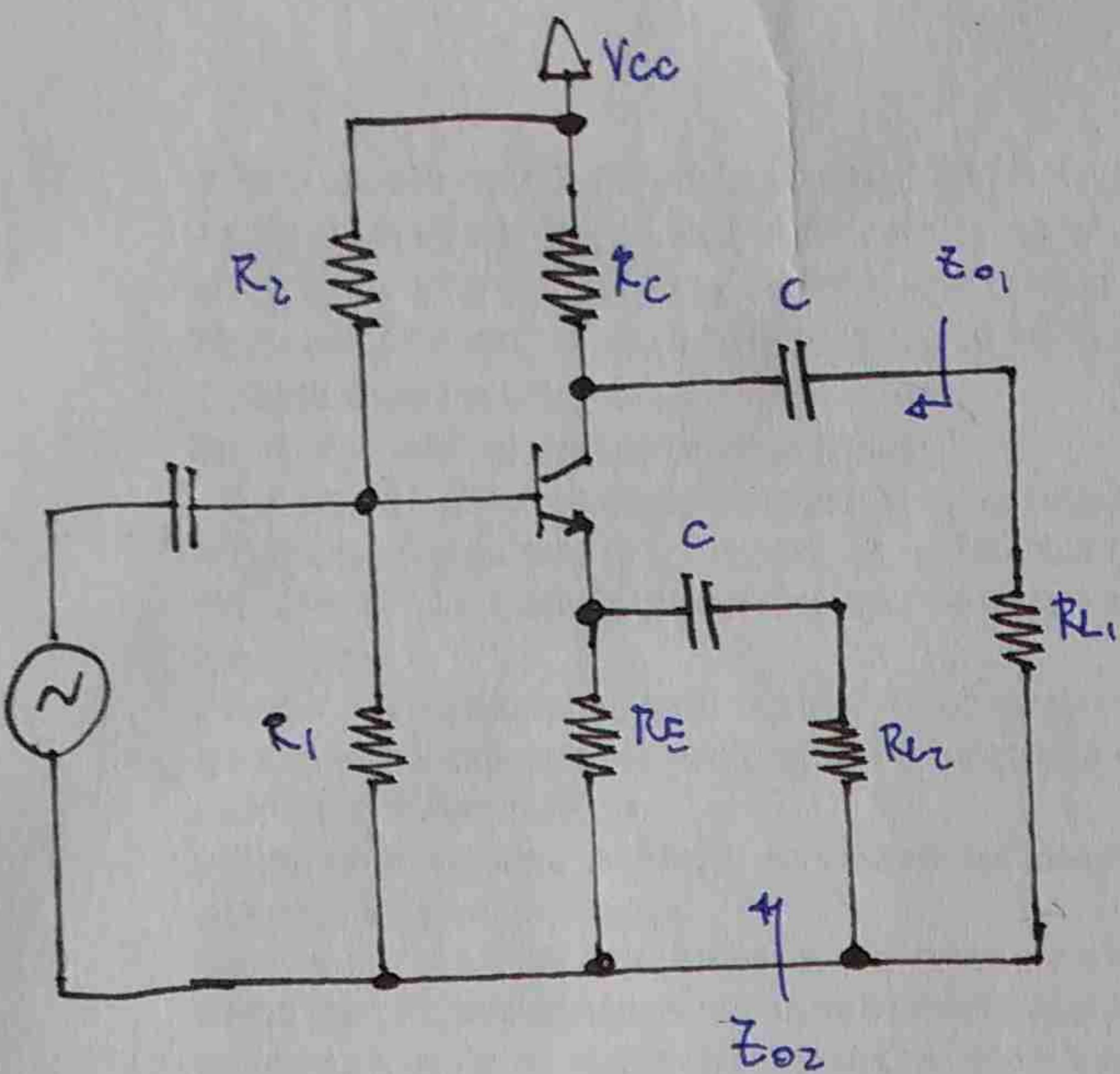


Surtidor — Drenador. M.



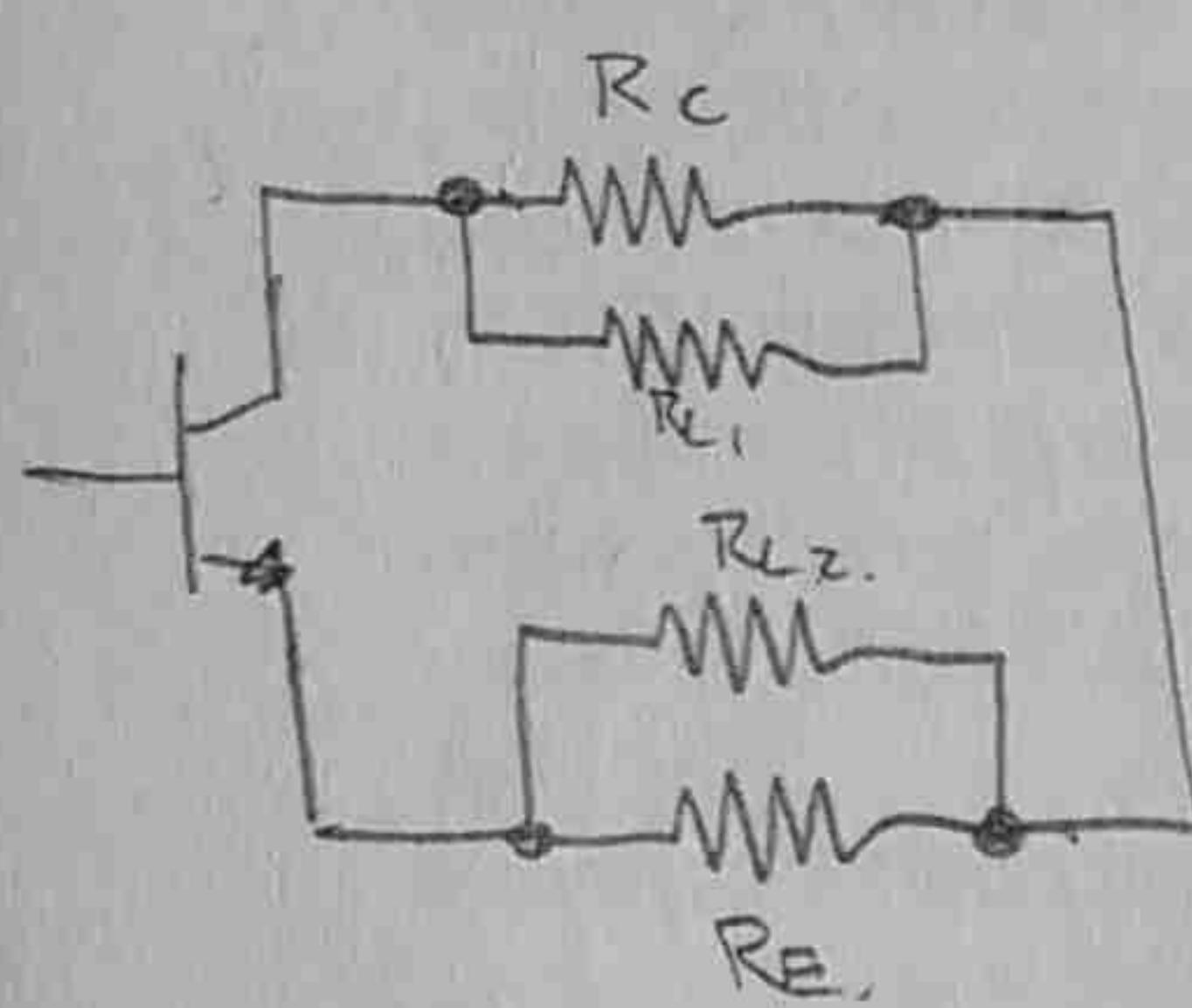
No tiene
igual
base oca

Inversor fase Bipolar



$$Z_{O2} = R_E \parallel \left[h_{ie} + \frac{R_B}{h_{fe}} \right]$$

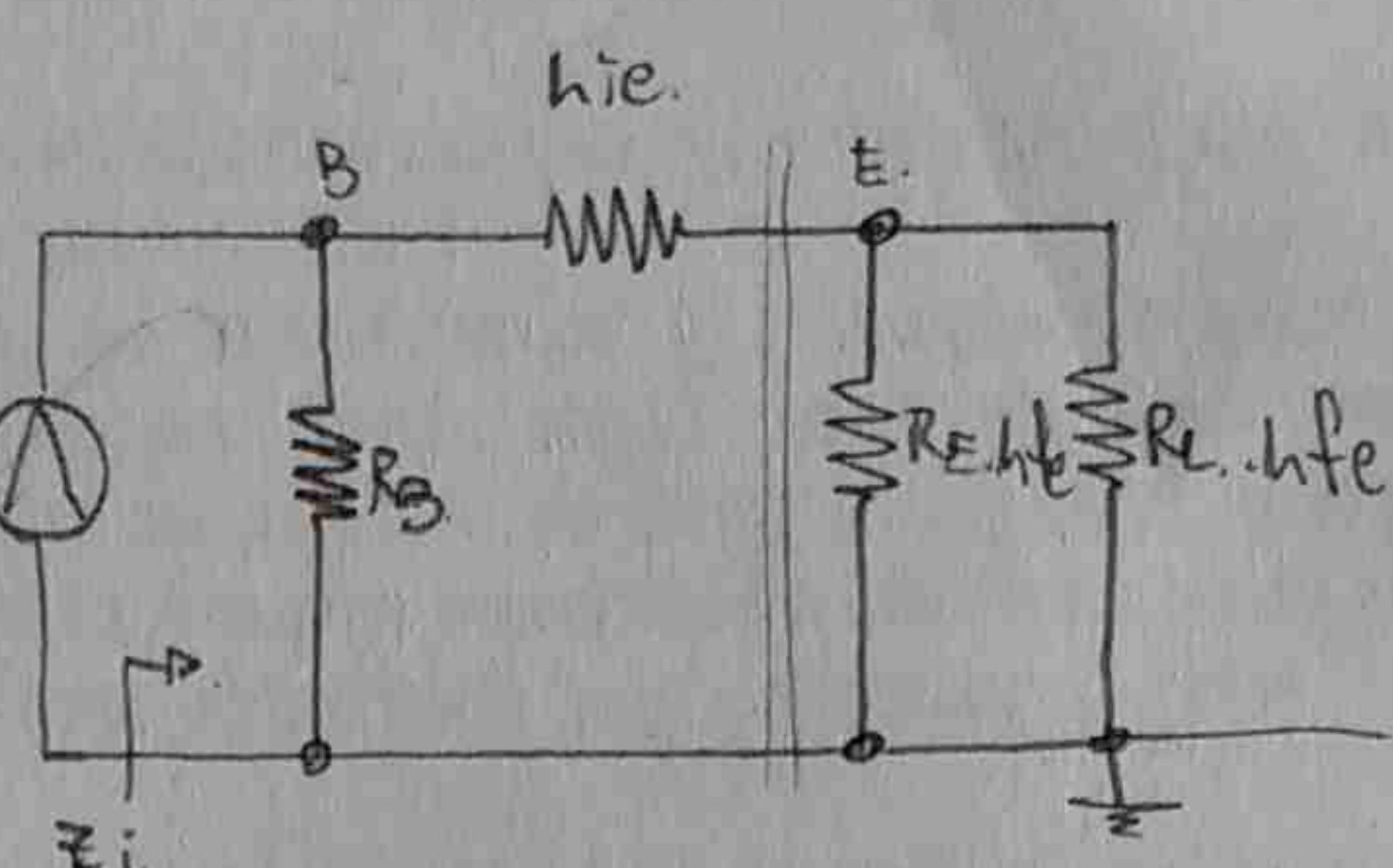
$$Z_{O1} = R_C.$$



$$R_{CA} = R_C \parallel R_{L1} + R_E \parallel R_{L2}$$

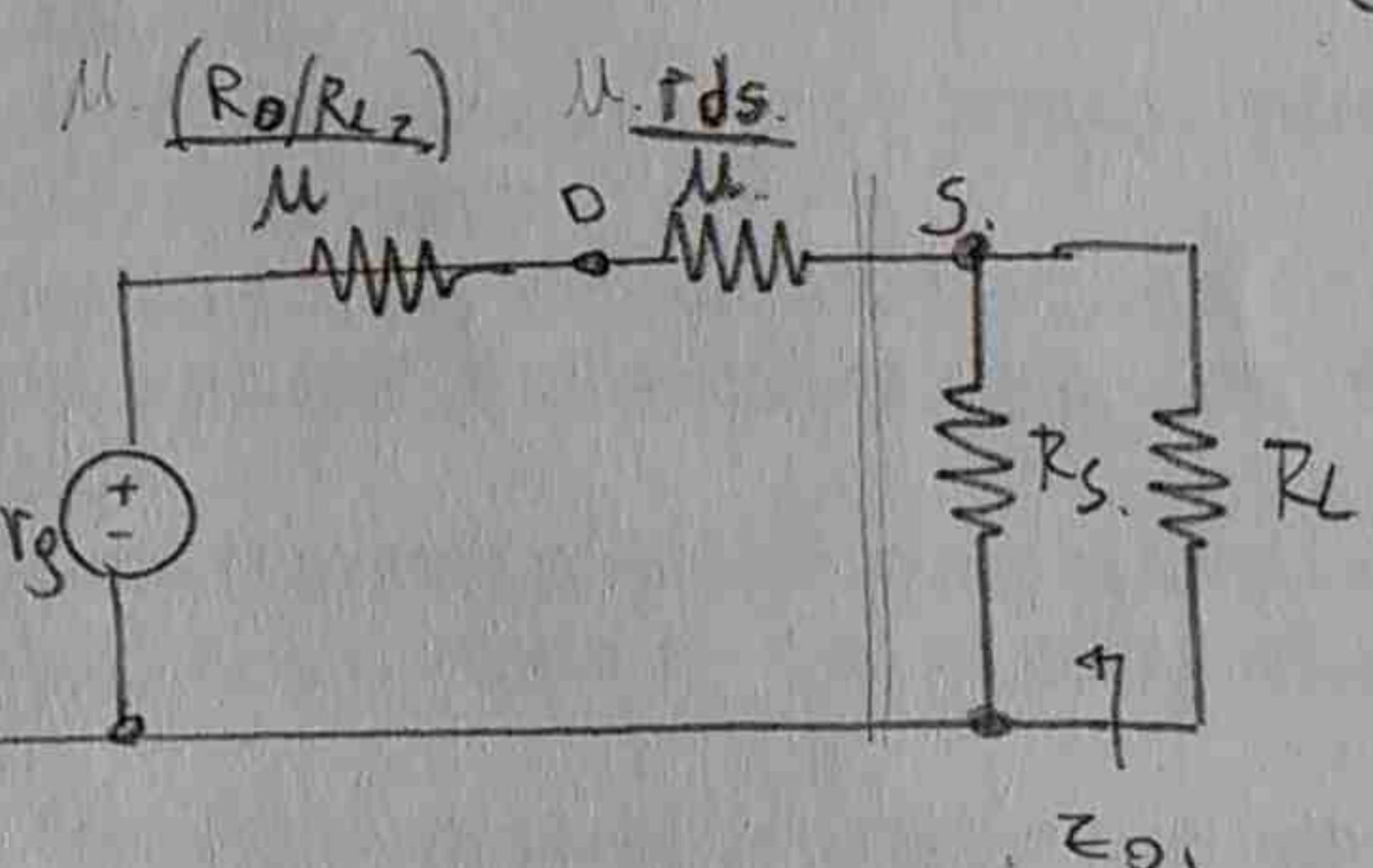
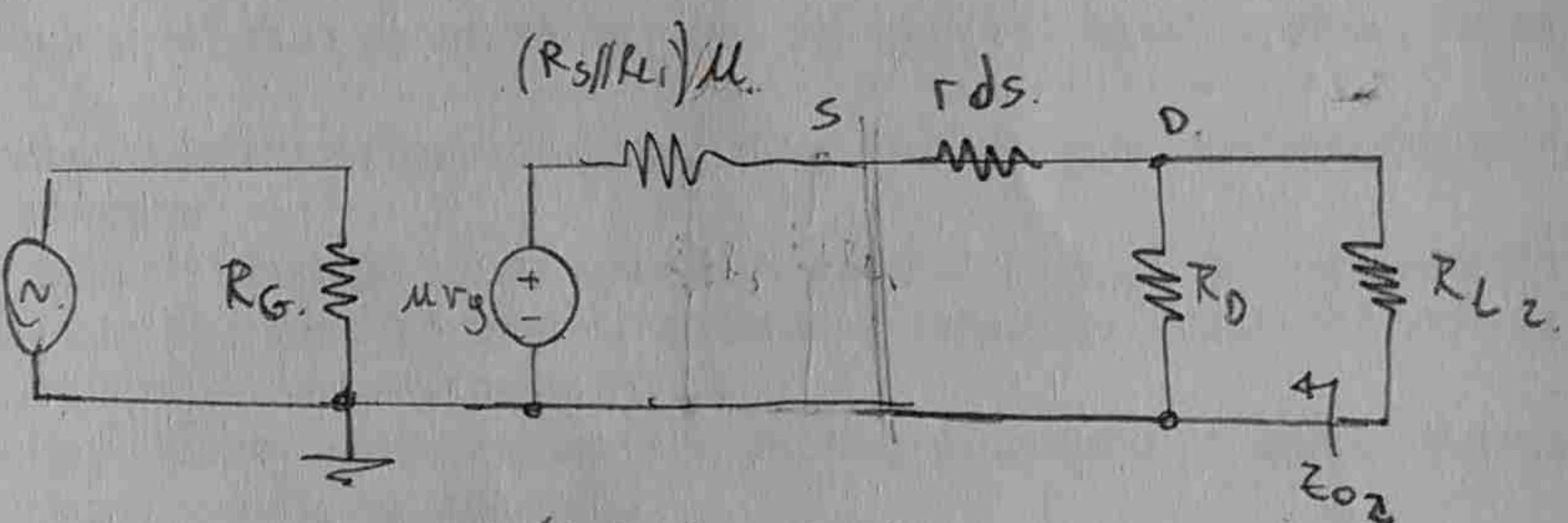
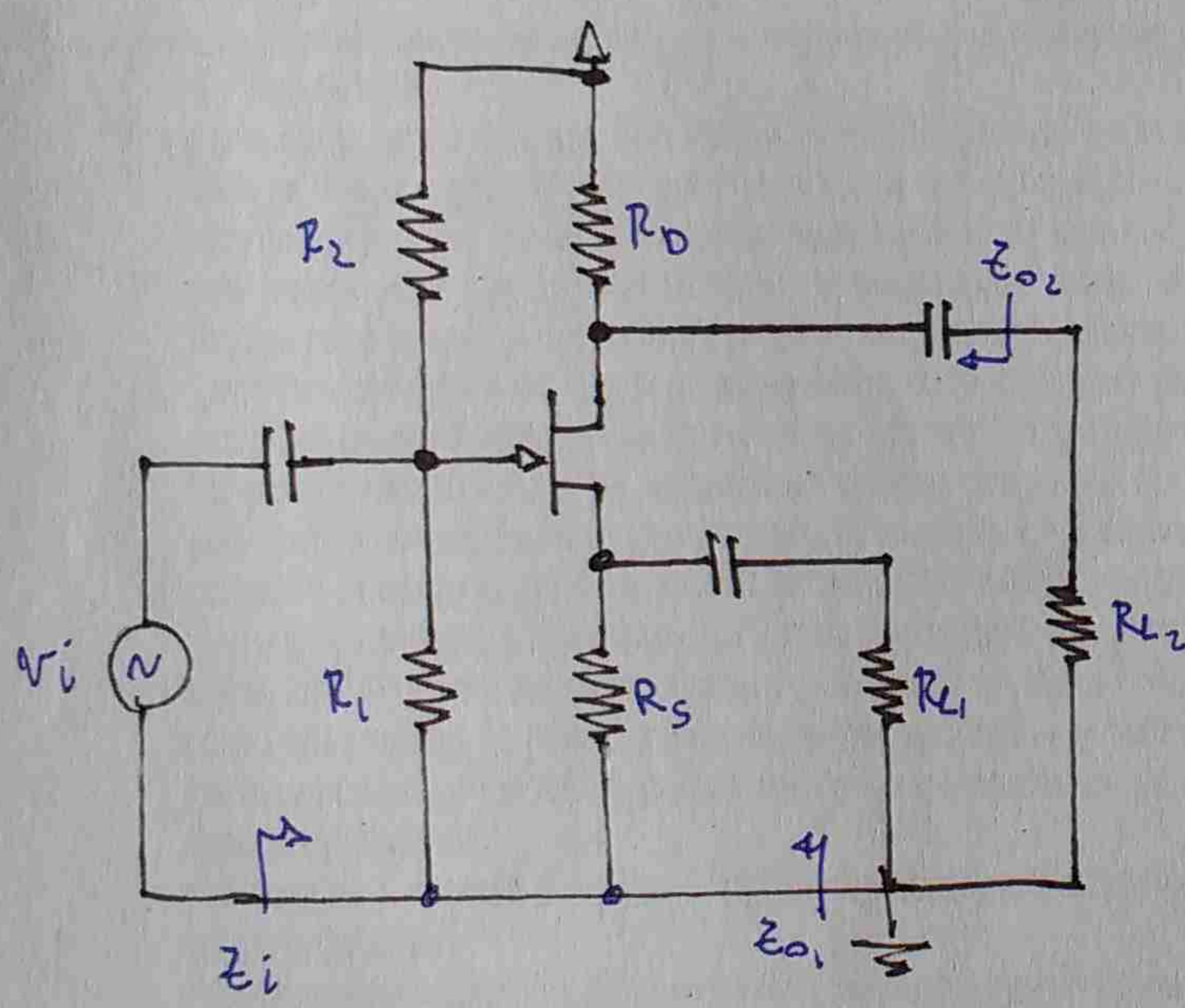
Inversor $R_C \parallel R_{L1} = R_E \parallel R_{L2}$.

$$R_{CA} = 2(R_C \parallel R_{L1})$$

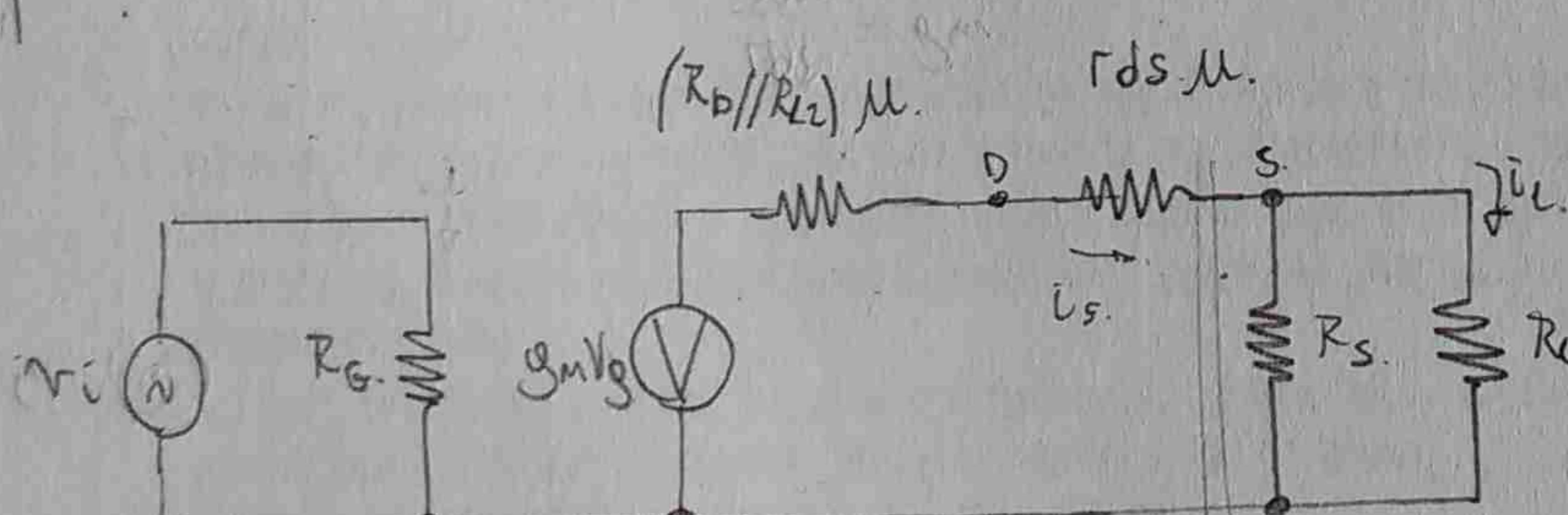


$$Z_i = R_B \parallel [h_{ie} + (R_E \parallel R_L) h_{fe}]$$

Inversor de fase JFET



|Ai1|



$$|A_{i1}| = \frac{i_o}{i_i} = \frac{i_D}{i_i} \cdot \frac{V_g}{V_g}$$

$$i_i = \frac{V_g}{R_g} \Rightarrow \frac{i_o}{V_g} = \frac{1}{R_g}$$

$$i_L = g_m V_g \cdot \frac{R_s}{R_s + R_{L1}} \Rightarrow \frac{i_L}{V_g} = g_m \cdot \frac{R_s}{R_s + R_{L1}}$$

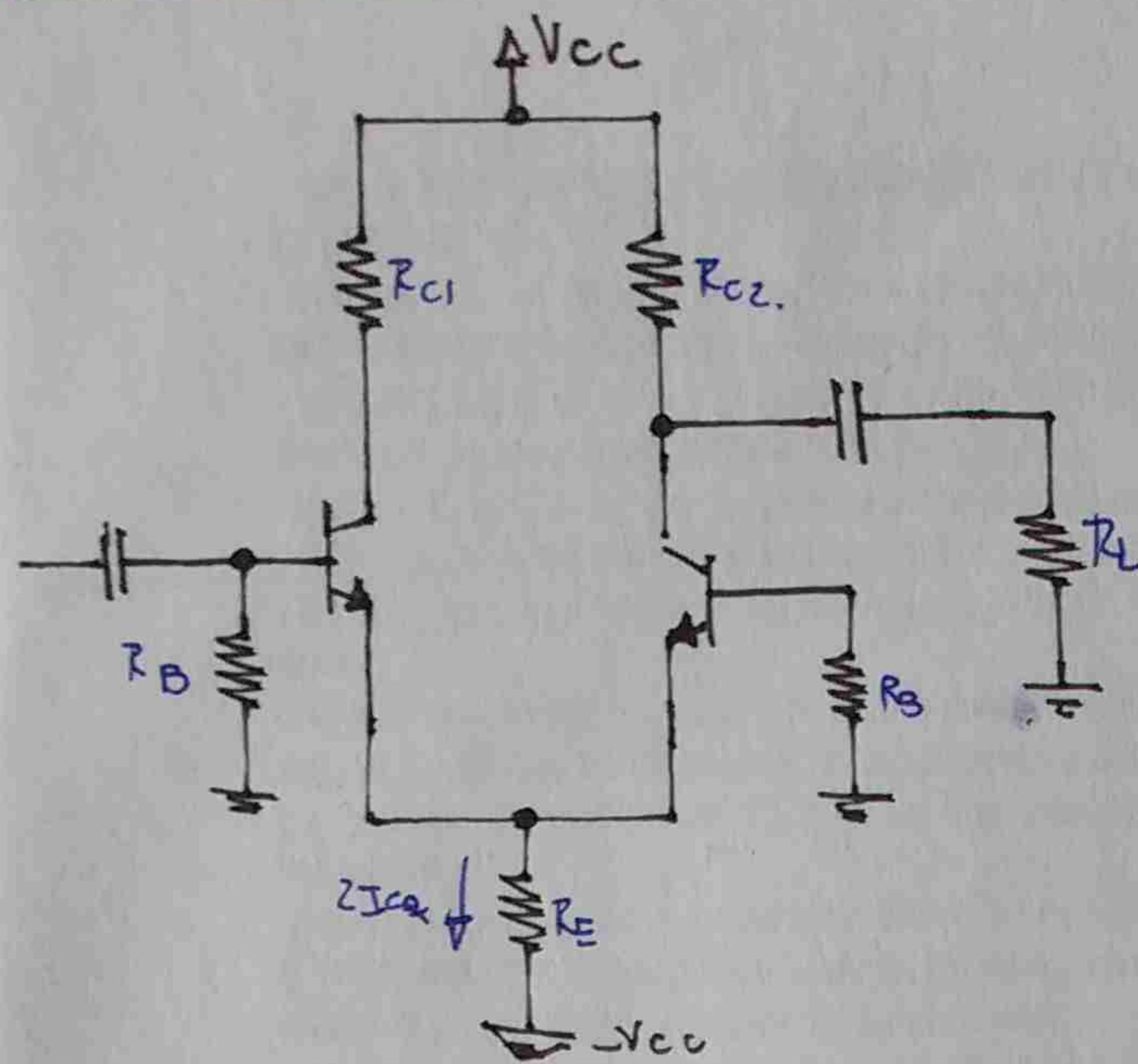
$$|A_{i1}| = \frac{1}{R_g} g_m \frac{R_s}{R_s + R_{L1}}$$

$$A_{i1} = A_v \cdot \frac{Z_i}{R_{L1}}$$

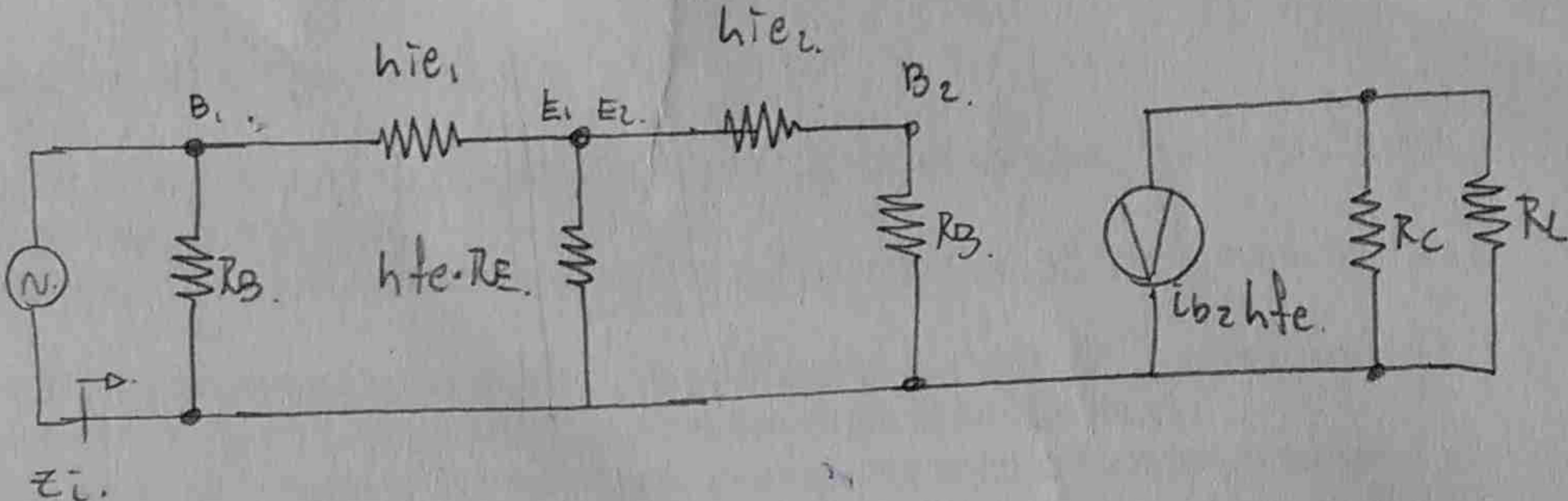
$$A_{i2} = A_v \cdot \frac{Z_i}{R_{L2}}$$

$R_{L1} \neq R_{L2}$.
No tiene
igual
ganancia

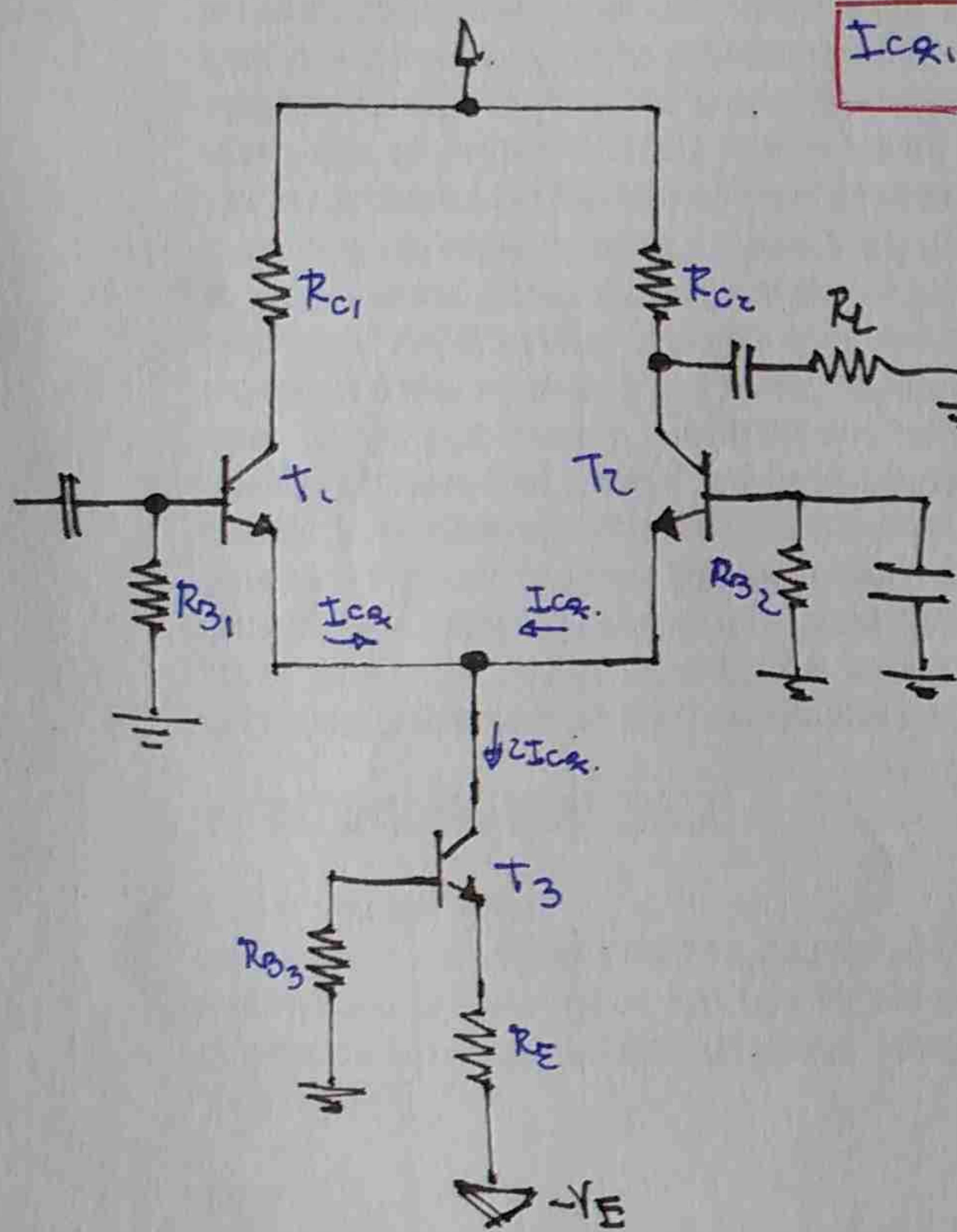
Amplificador diferencial (Asimétrico)



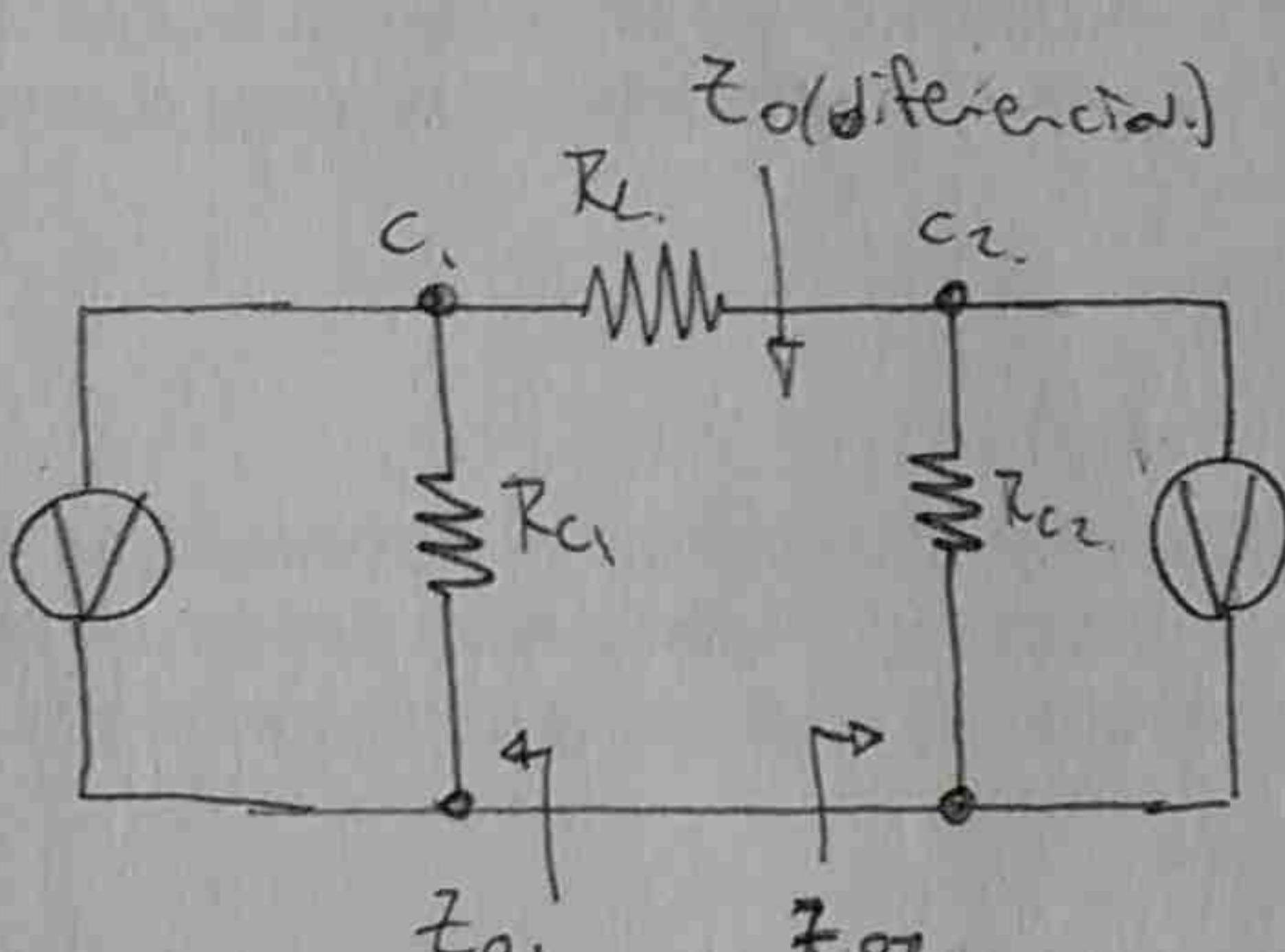
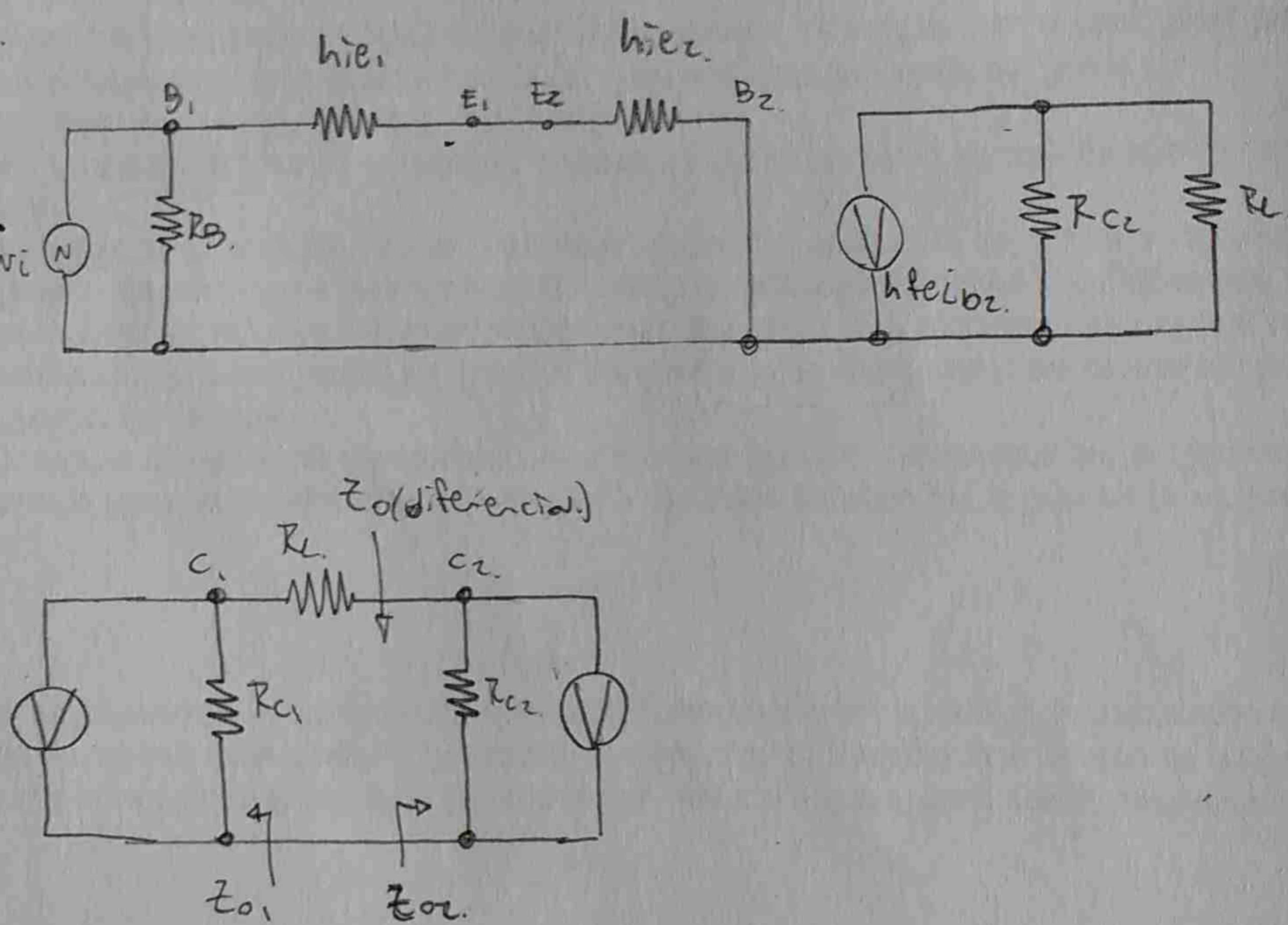
$$I_{CQ1} = I_{CQ2}$$



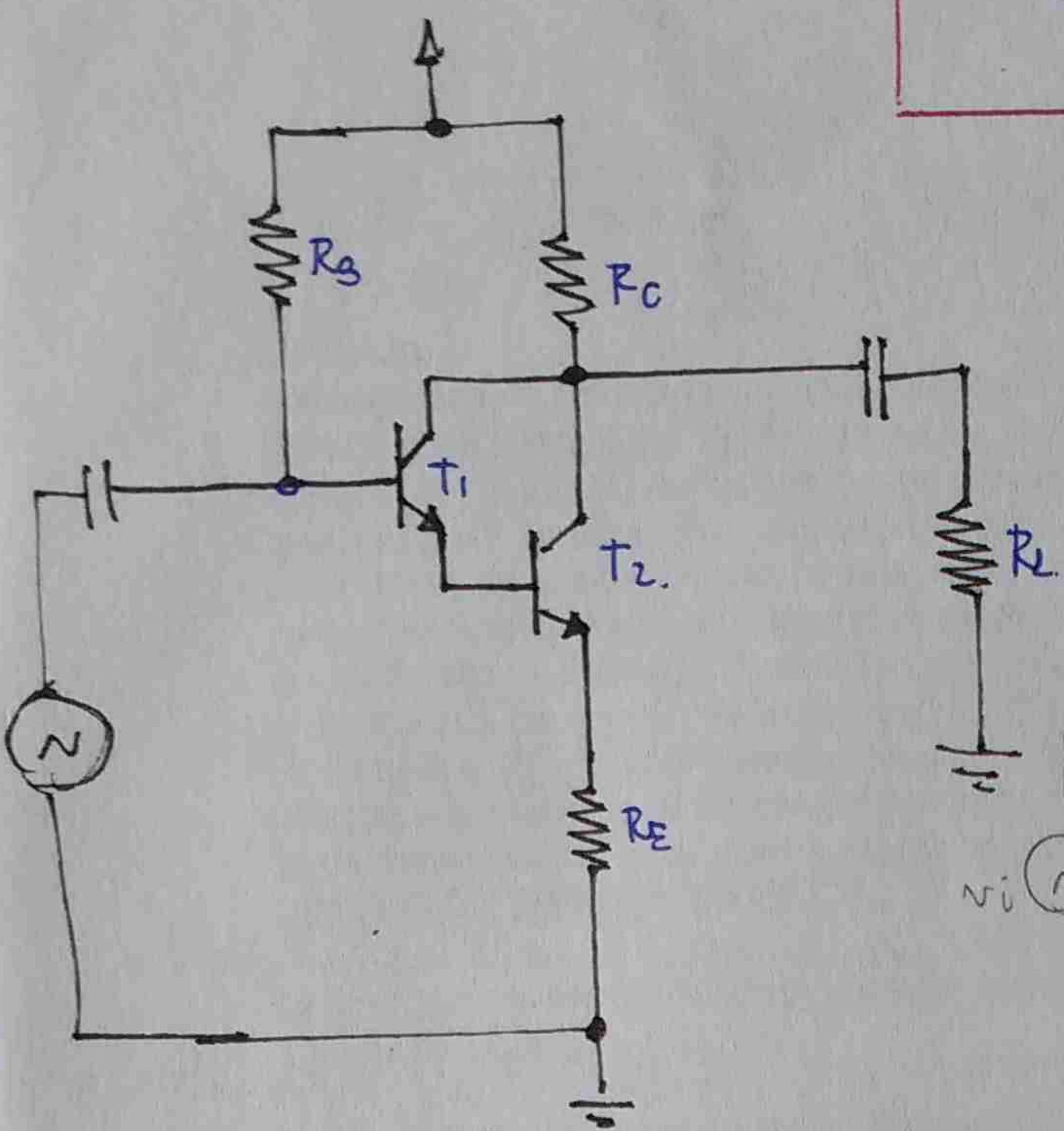
Ampl. Con 3º Transistor.



$$I_{CQ1} = I_{CQ2} = \frac{I_{CQ3}}{2}$$



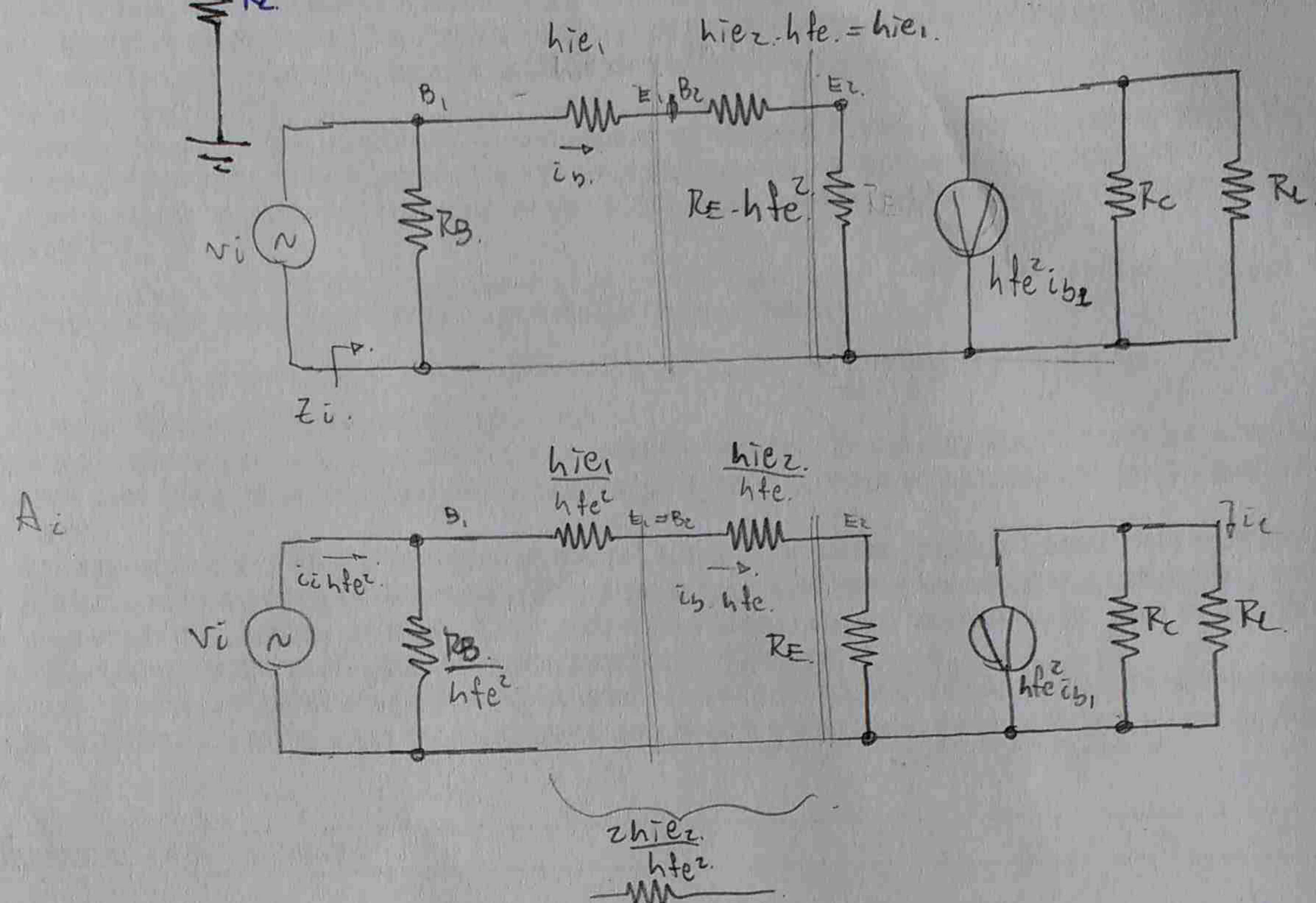
Par Darlington



$$h_{-ax} = \frac{P_{L-ax}}{P_{cc-ax}}$$

$$P_{L-ax} = \frac{1}{2} \left(\frac{I_{Cax}}{2} \right)^2 R_L$$

$$P_{cc} = V_{cc} \cdot I_{Cax}$$



$$\Delta I_{CQ} = S_V \Delta V_{BE} + S_I \Delta I_{CBO} + S_B \Delta B$$

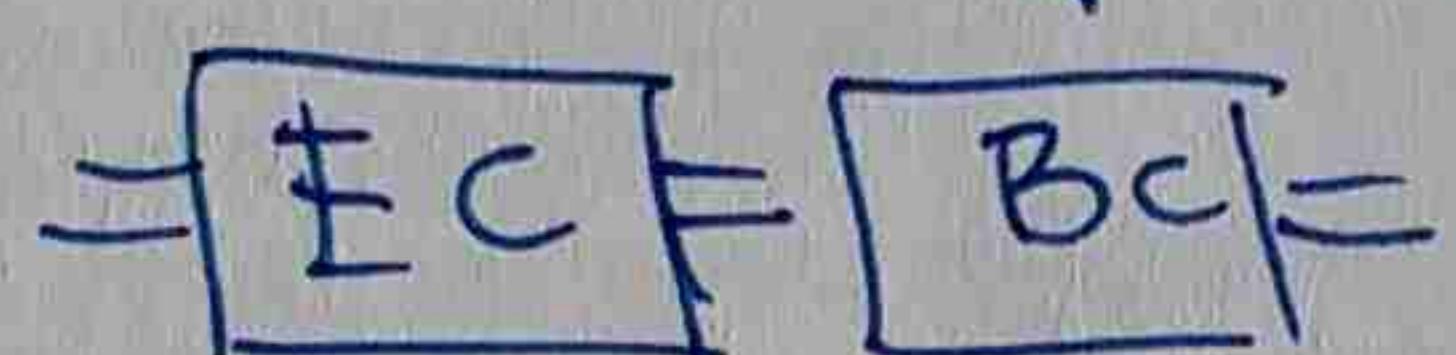
$$S_V = -\frac{1}{R_E} = \frac{\partial I_{CQ}}{\partial V_{BE}}$$

$$S_I = 1 + \frac{R_B}{R_E} = \frac{\partial I_{CQ}}{\partial I_{CBO}}$$

$$S_B = \frac{I_{CQ}}{B_1} \cdot \frac{R_B + R_E}{R_B + (B_2 + 1)R_E}$$

La polarización balanceada se utiliza cuando necesitamos mucha estabilidad en cambios de ΔT altos. Normalmente se aumenta R_E pero esto disminuye la I_{CQ} , perdiendo ganancia.

Amplificador cascode. Para evitar la disminución del ancho de banda debido a la realimentación por el capacitor interelectrónico
 ↴ Baja impedancia de entrada.



Rendimiento (Máx Posible)

$$\eta = \frac{P_L}{P_{CC}}$$

FM (Menor Posible)

$$FM = \frac{P_C - \alpha x}{P_L - \alpha x}$$

↑ Máxima potencia en el colector

↑ Max pot en la carga.

$$P_C = \frac{V_{CC}^2}{2R_L}$$

$$P_C = \frac{V_{CC}^2}{2R_L} - \frac{V_{CC}^2}{4R_E} - \frac{V_{CC}^2}{8R_E}$$

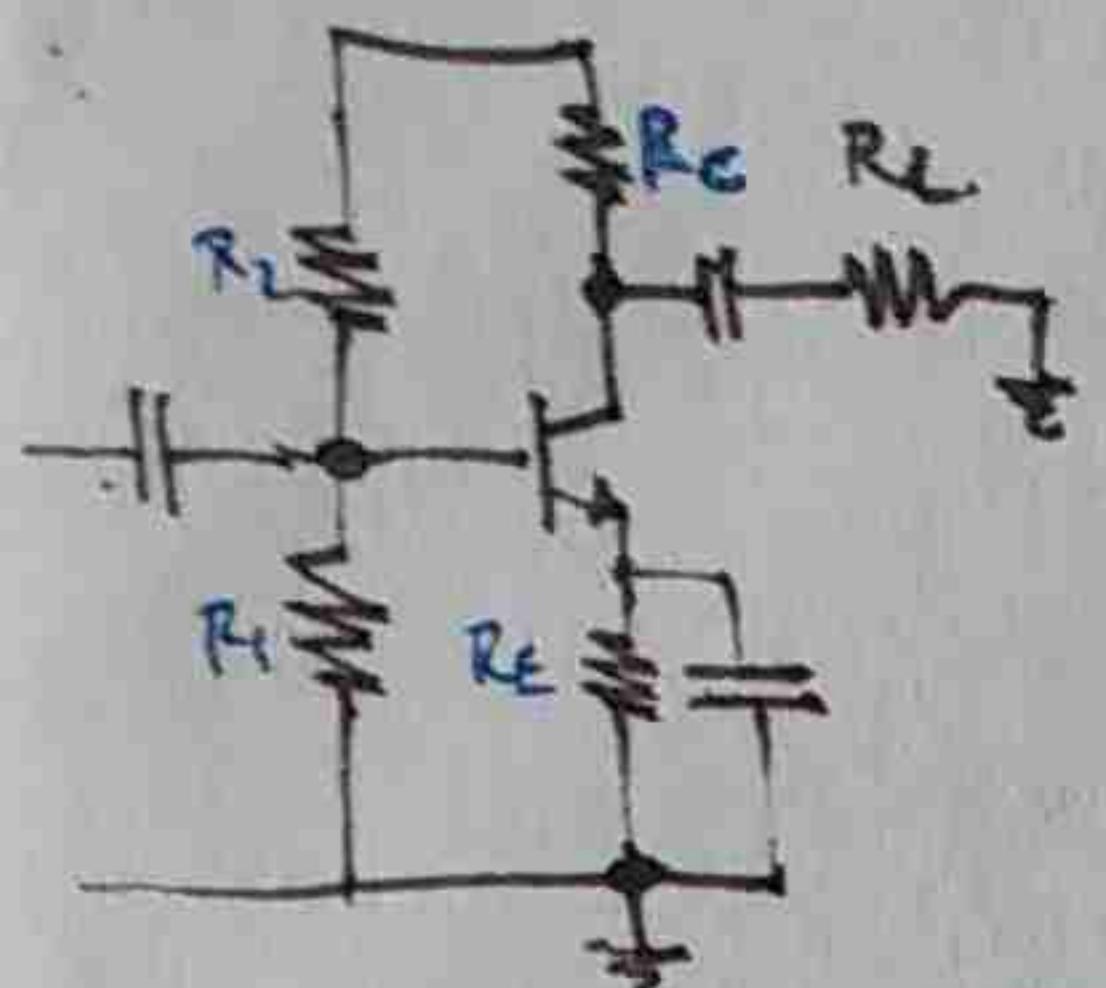
Señal CA.

$$P_{Cmax} (\text{sin señal}) = \frac{V_{CC}^2}{4R_L}$$

$$P_{C-in} (\text{señal max}) = \frac{V_{CC}^2}{8R_L}$$

Sin Inductor	con Inductor.
$FM = 2$	
$\eta = 0.25$	$\eta = 0.5$

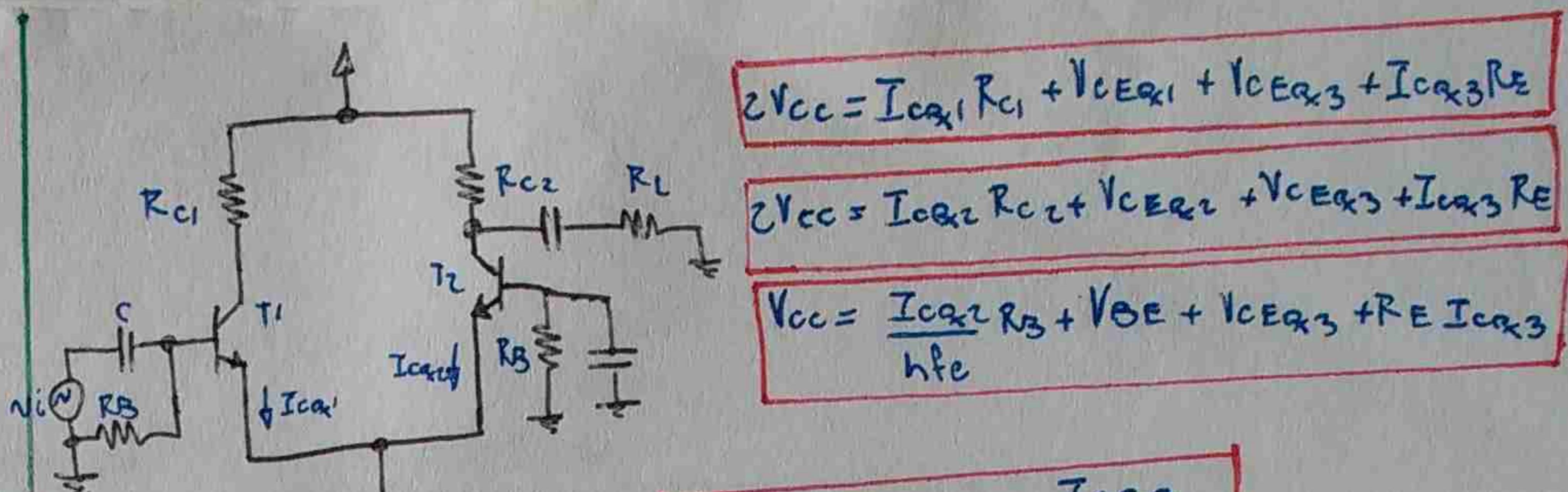
Entrar Co-va Carga desacoplo.



$$P_{L\text{max}} = \frac{I_{CQ}^2}{2} R_L$$

$$P_{CC\text{max}} = V_{CC} I_{CQ}$$

$$\hat{I}_{L\text{max}} = \frac{\hat{I}_{CQ\text{max}}}{2} = \frac{I_{CQ}}{2}$$



$$2V_{CC} = I_{CQ1} R_{C1} + V_{CEQ1} + V_{CEQ3} + I_{CQ3} R_E$$

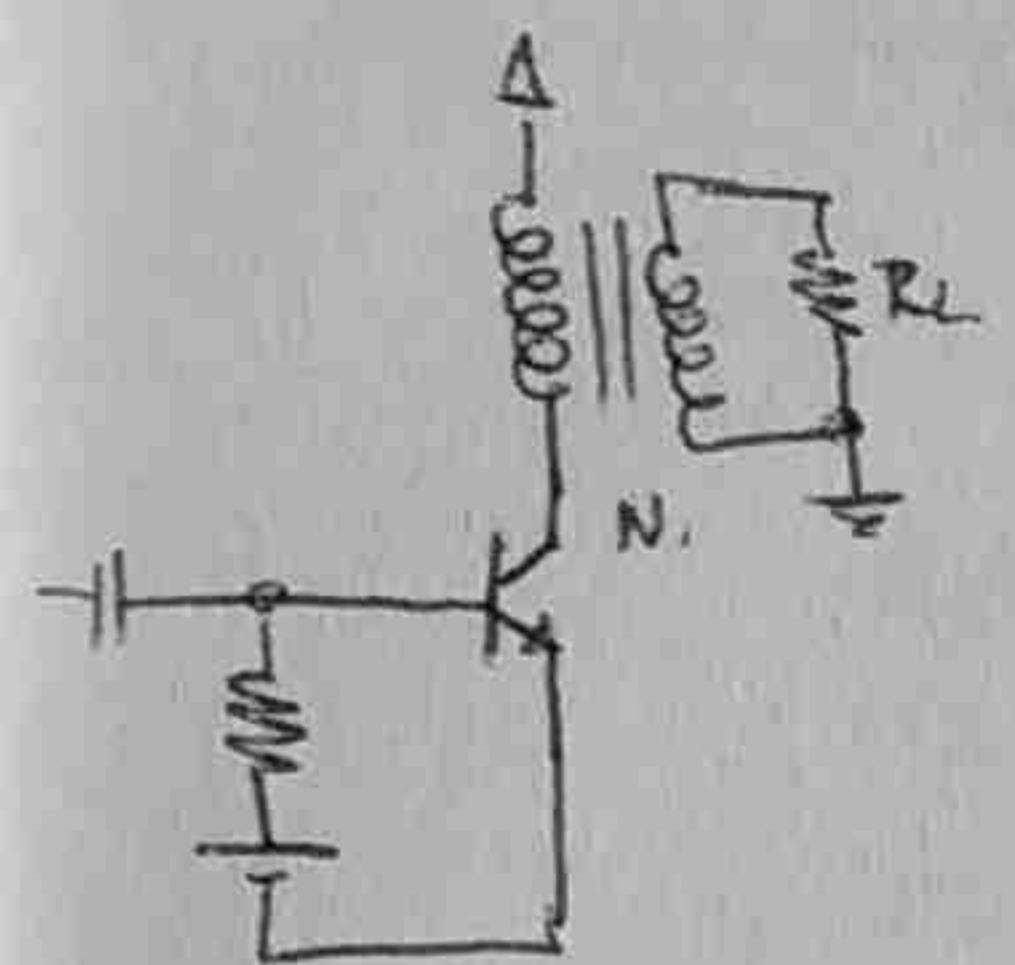
$$2V_{CC} = I_{CQ2} R_{C2} + V_{CEQ2} + V_{CEQ3} + I_{CQ3} R_E$$

$$V_{CC} = \frac{I_{CQ2} R_B + V_{BE} + V_{CEQ3} + R_E I_{CQ3}}{h_{FE}}$$

$$I_{CQ1} = I_{CQ2} = \frac{I_{CQ3}}{2}$$

En el circ. equiv. C pone a masa a B2

Circuito A Trafo

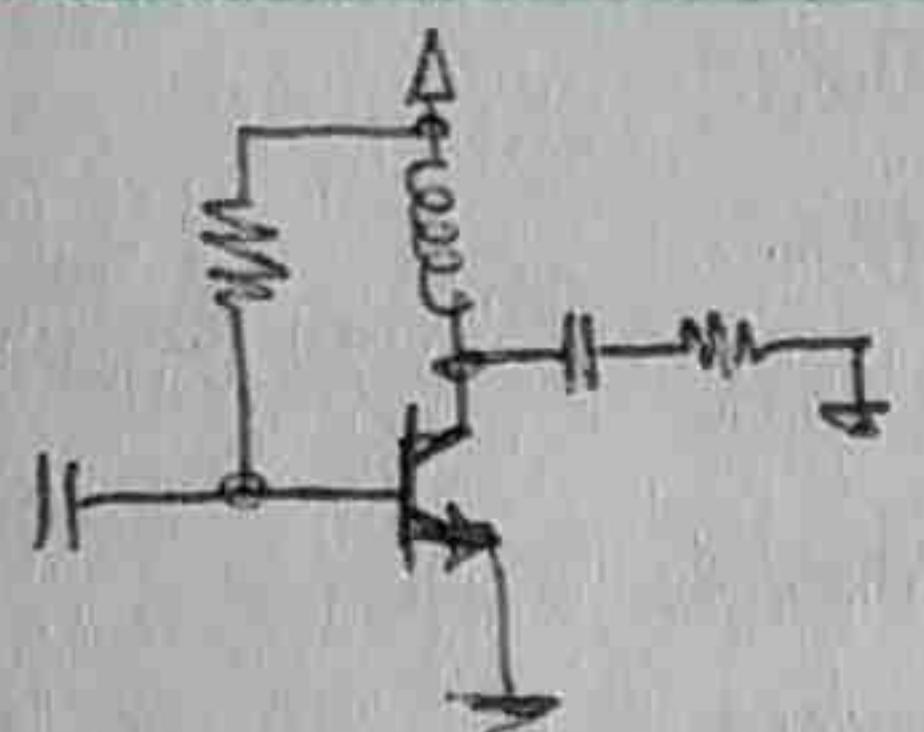


$$R'_L = N^2 R_L$$

$$P_{L\text{max}} = \frac{V_{CC}^2}{2R'_L}$$

$$P_{CC\text{max}} = V_{CC} I_{CQ}$$

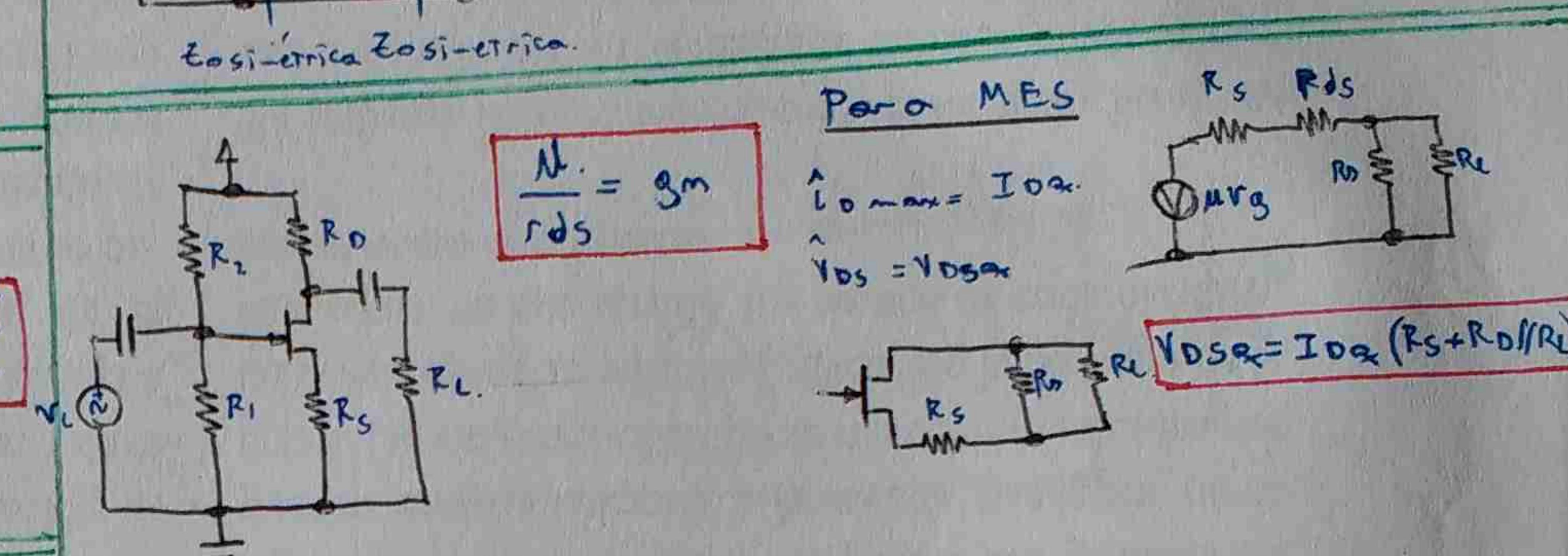
$$I_{CQ} = \frac{V_{CC}}{N^2 R_L}$$



$$K_M = Z = \frac{P_{C\text{max}}}{P_{L\text{max}}}$$

$$\frac{V_{CC}^2}{2R_L} = \frac{P_{C\text{max}}}{Z} \Rightarrow P_{C\text{max}} = \frac{V_{CC}^2}{R_L}$$

$$I_{CQ} = \frac{V_{CC}}{R_L}$$

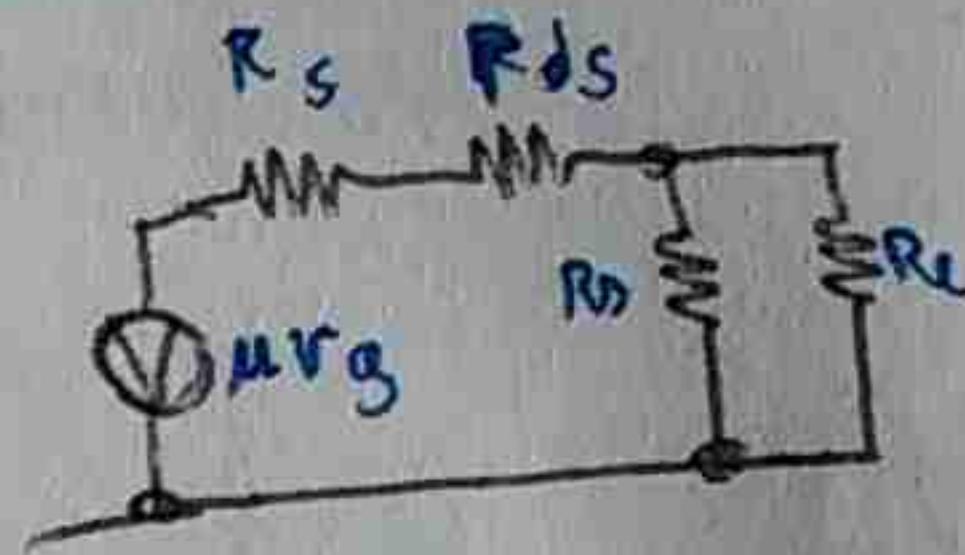


Para MES

$$\frac{N_r}{r_{DS}} = g_m$$

$$\hat{I}_{D\text{max}} = I_{D2}$$

$$V_{DSR} = V_{DS2}$$

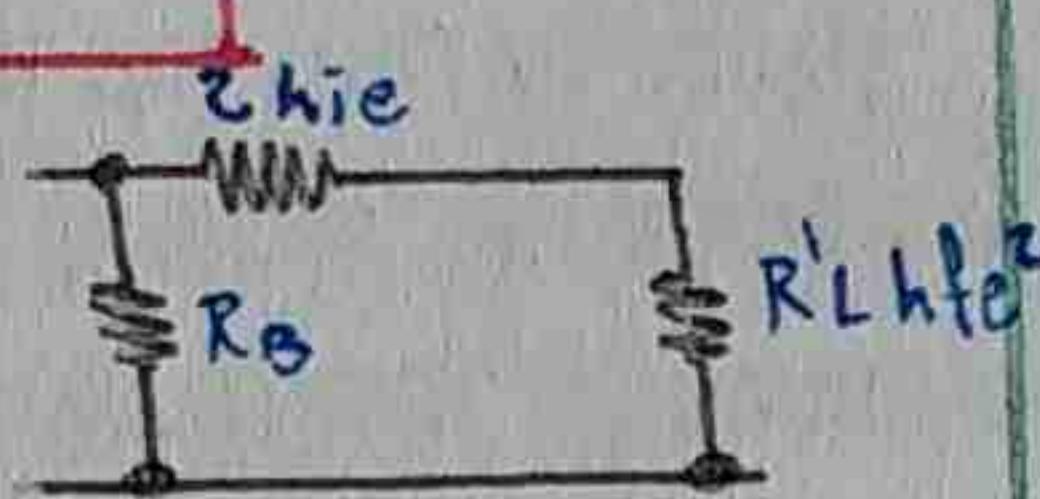


$$V_{DSR} = I_{D2} (R_S + R_D / (R_D))$$

$$V_{BB} = R_B \frac{I_{CQ}}{h_{FE}} + 2V_{BE}$$

$$V_{CEQ2} = V_{CC}$$

$$V_{CEQ1} = V_{CEQ2} - V_{BE}$$



espejo

$$I_{CQ1} = I_{CQ2} \quad I_{CQ2} = \frac{V_{CC} - V_{BE}}{R_B}$$

$$V_{CEQ1} = 0.7V$$

diodo

$$V_{CEQ2} = V_{CC} - I_{CQ2} R_E$$

$$\frac{\beta + 2}{\beta} = 1$$

MES En el punto

$$I_{CQ\text{MES}} = \frac{V_{CC}}{R_{CC} + R_{CQ}} \quad V_{CEQ2\text{MES}} = V_{CC} - I_{CQ\text{MES}} R_E$$

$$R_{B\text{MES}} = \frac{V_{CC} - V_{BE}}{I_{CQ\text{MES}}}$$

$$\Delta I_{CQ} = \frac{K_A T}{R_B}$$

$$V_{CC} = \left(\frac{2I_{CQ}}{h_{FE}} + I_{CQ} \right) R + \frac{I_{CQ}}{h_{FE}} R_B + V_{BE} + R_E I_{CQ}$$

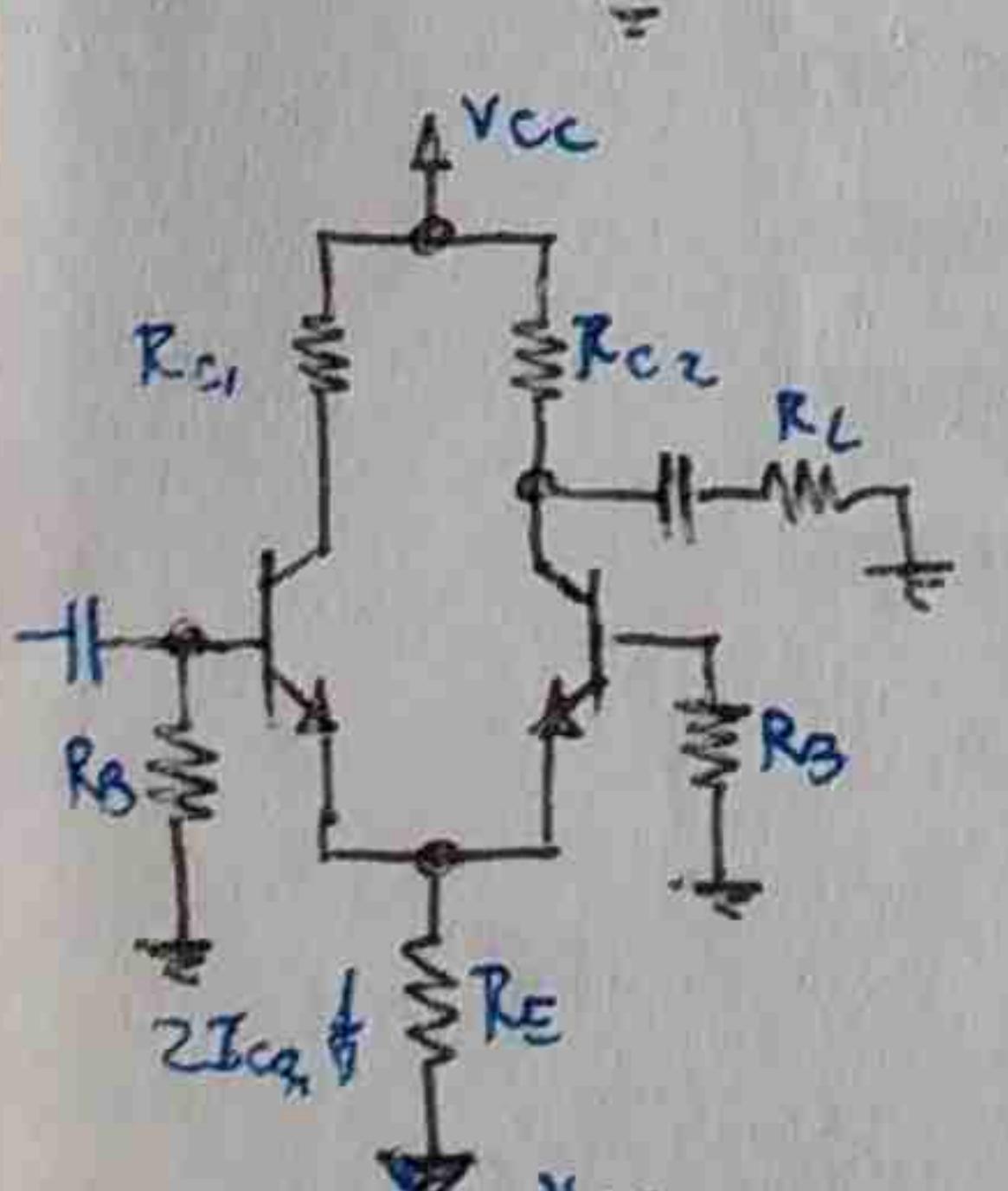
$$V_{CEQ2} = V_{CC} - I_{CQ} (R_L + R_E)$$

$$I_{CQ1} = I_{CQ2}$$

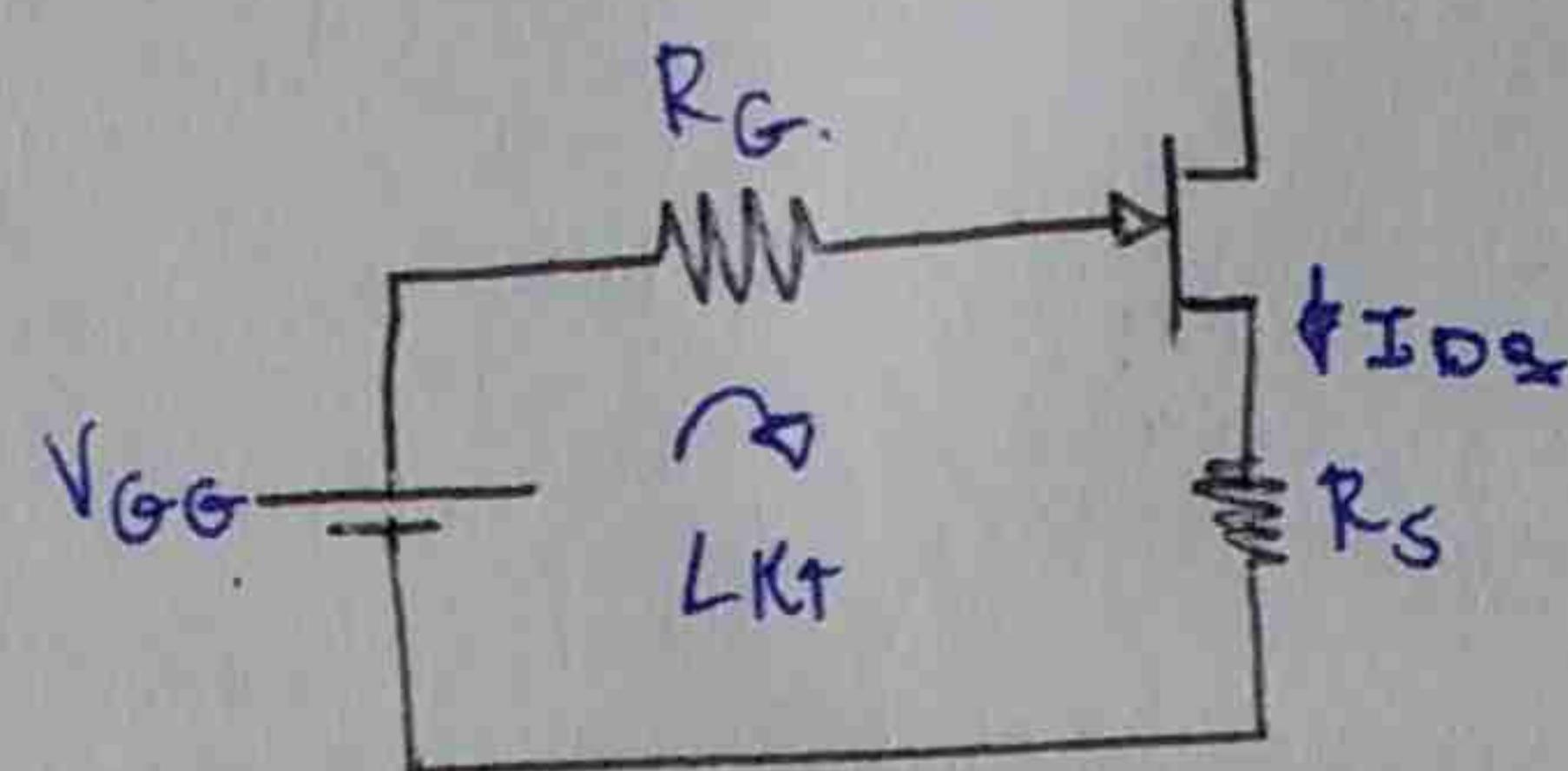
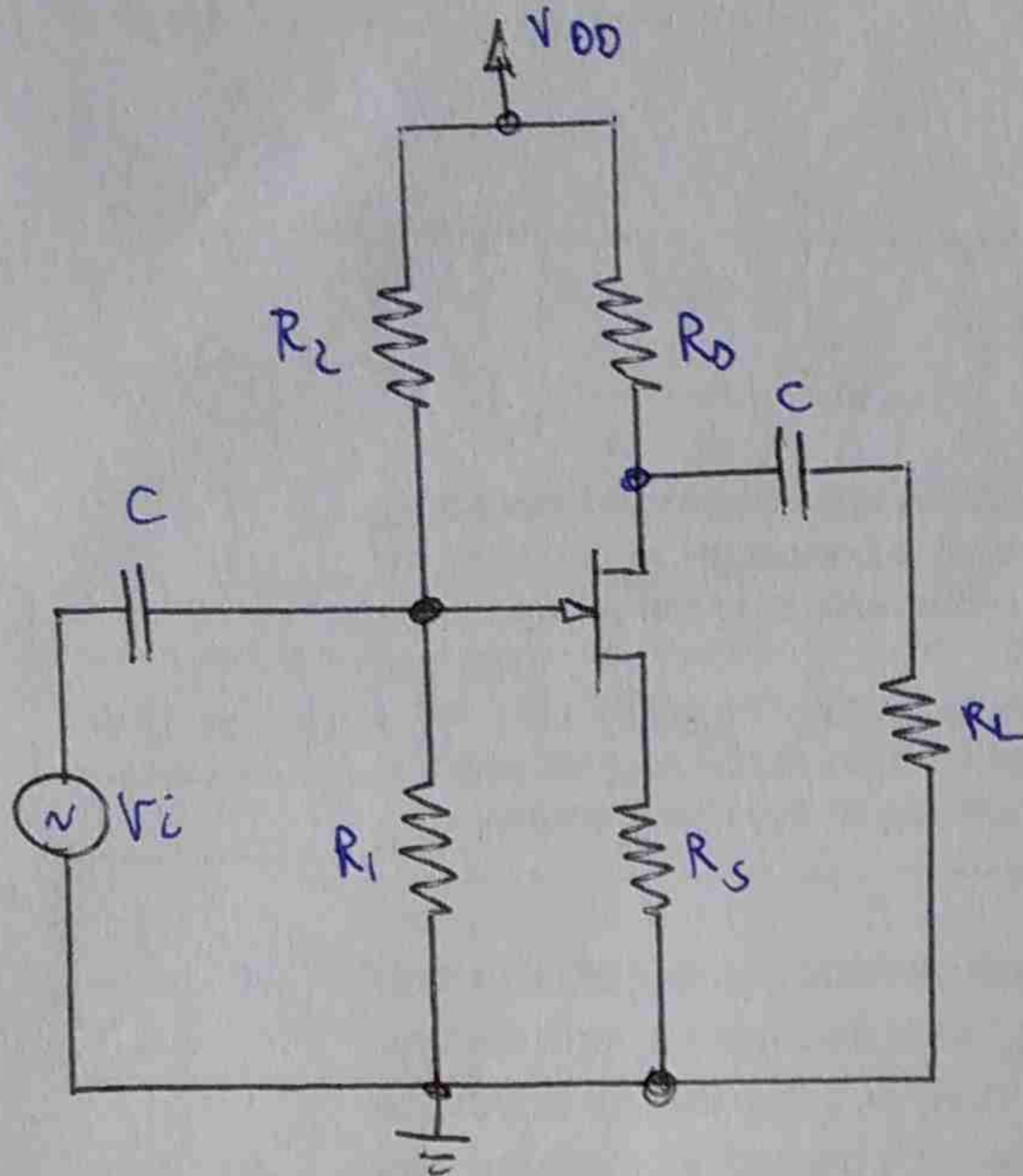
$$V_{CC} = \frac{I_{CQ}}{h_{FE}} \cdot R_B + V_{BE} + 2 I_{CQ} R_E$$

$$V_{CEQ1} = V_{CC} - I_{CQ} (R_{C1} + 2 R_E)$$

$$I_{CQ} = \frac{V_{EE} - V_{BE}}{\frac{R_B}{\beta} + 2 R_E}$$



Surtidor co-un sin cap de desacopl



$$V_{GG} = \frac{V_{DD}}{R_1 + R} \cdot R_1$$

$$R_G = R_1 // R_2$$

$$I_G = 0$$

LKT. $V_{GSQ} = V_{GG} - I_{DQ} \cdot R_S$

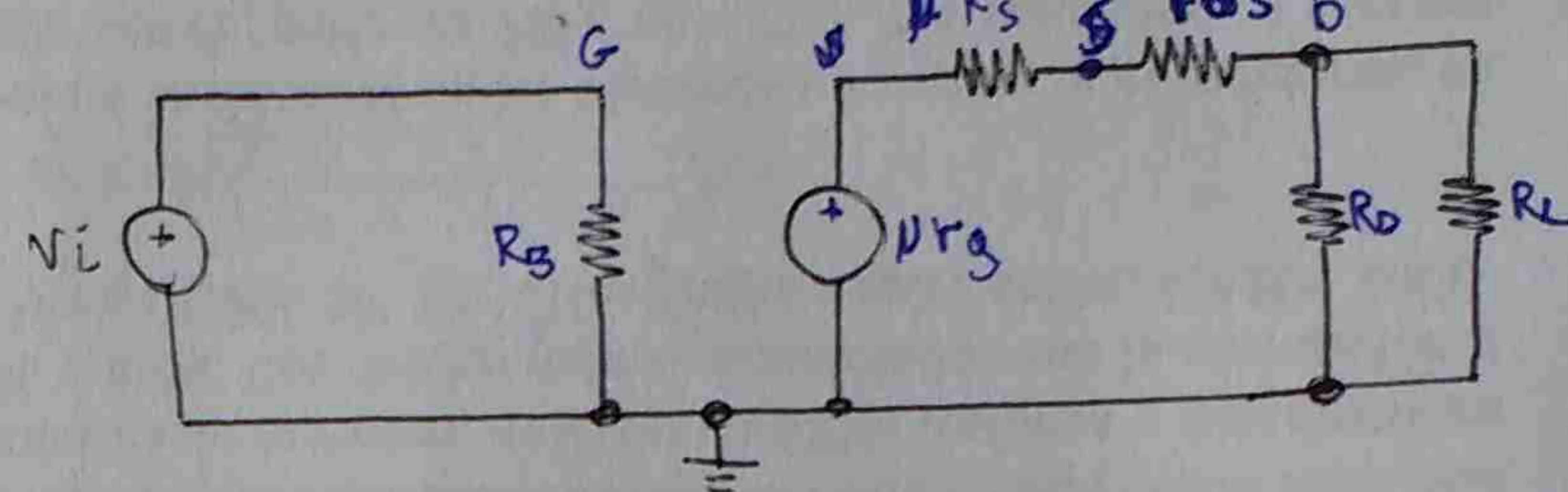
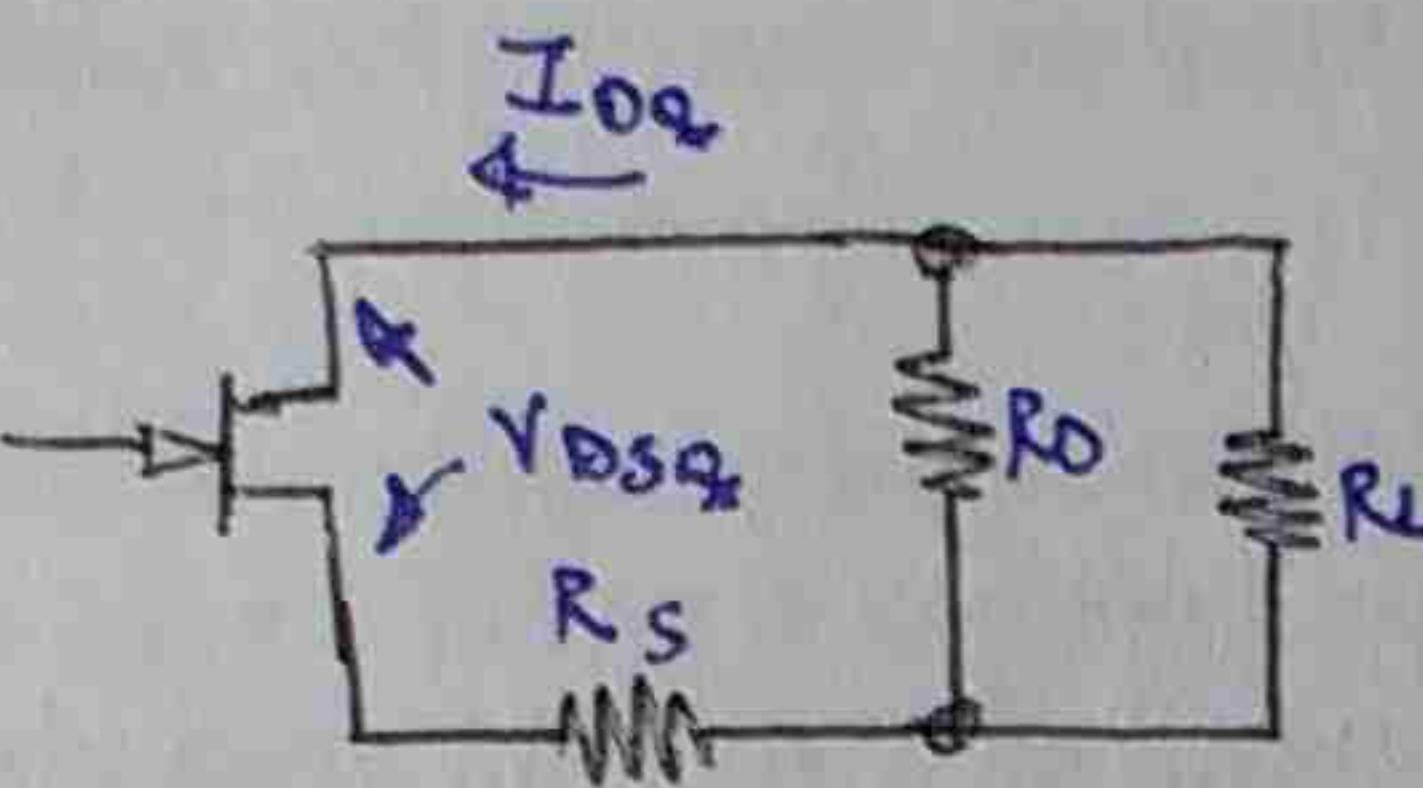
malla
sorrida

$$V_{DD} = V_{DSQ} + I_{DQ} (R_S + R_D)$$

Para MES:

$$I_{DQ_{\text{mes}}} = I_{DQ}$$

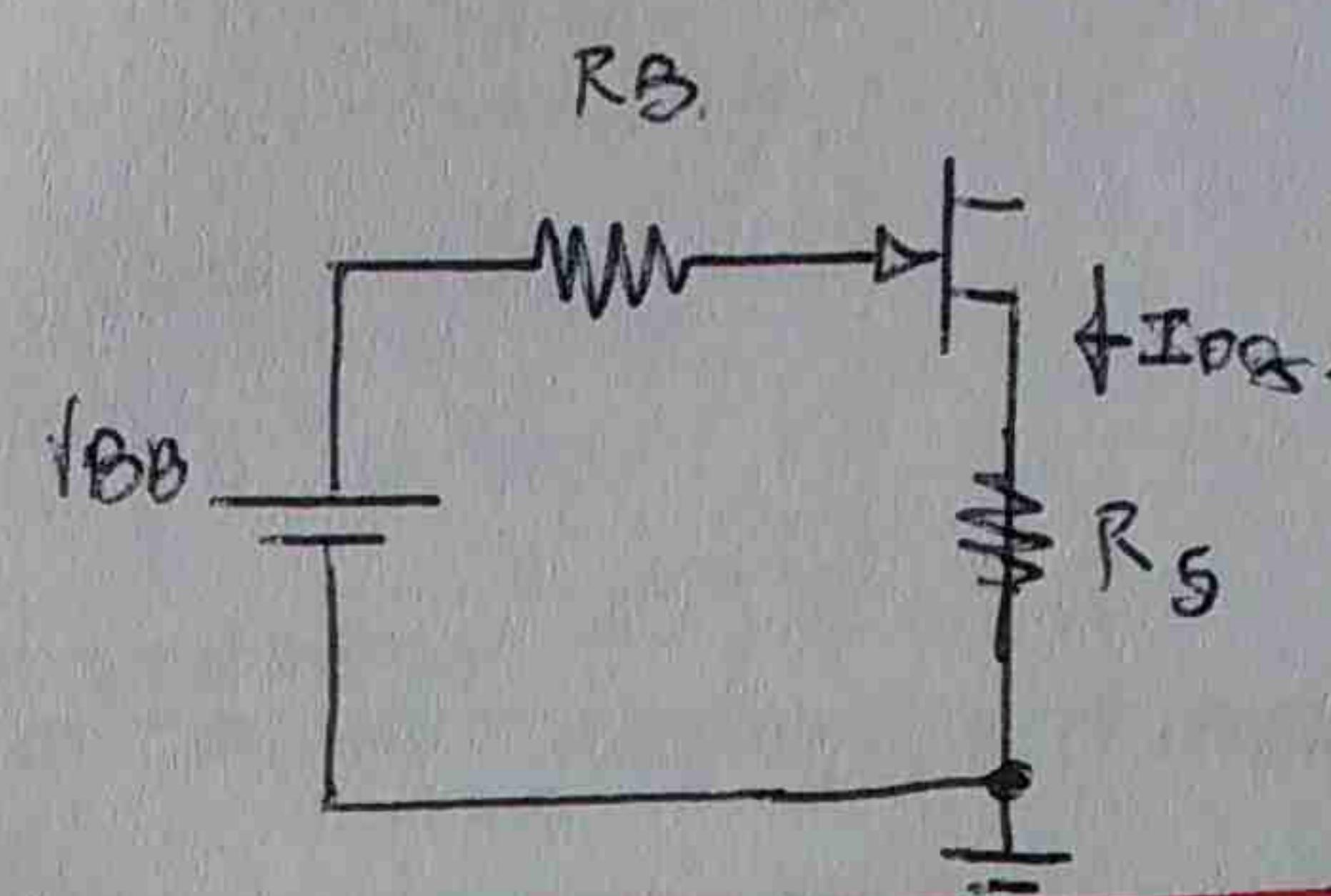
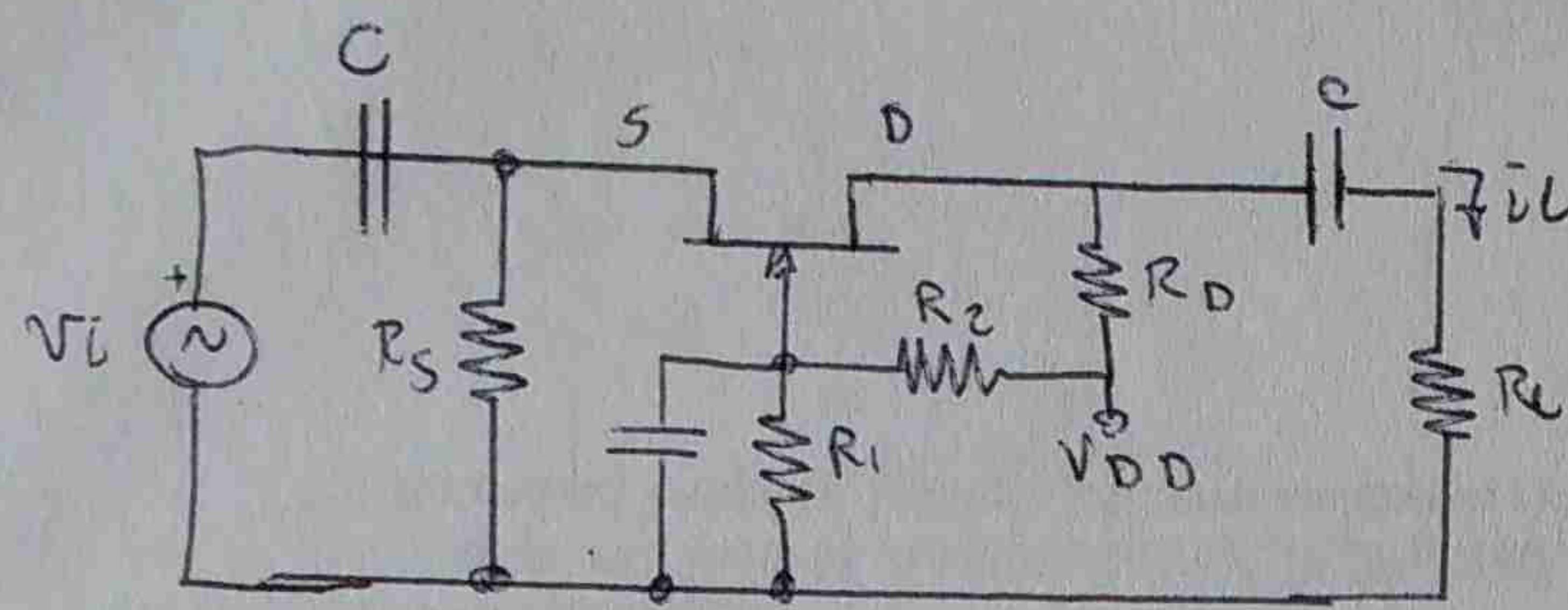
$$V_{DSQ_{\text{mes}}} = V_{DSQ}$$



caso para
MES sin/cap

$$V_{DSQ} = I_{DQ} [R_S + (R_D // R_L)]$$

Compuesto común

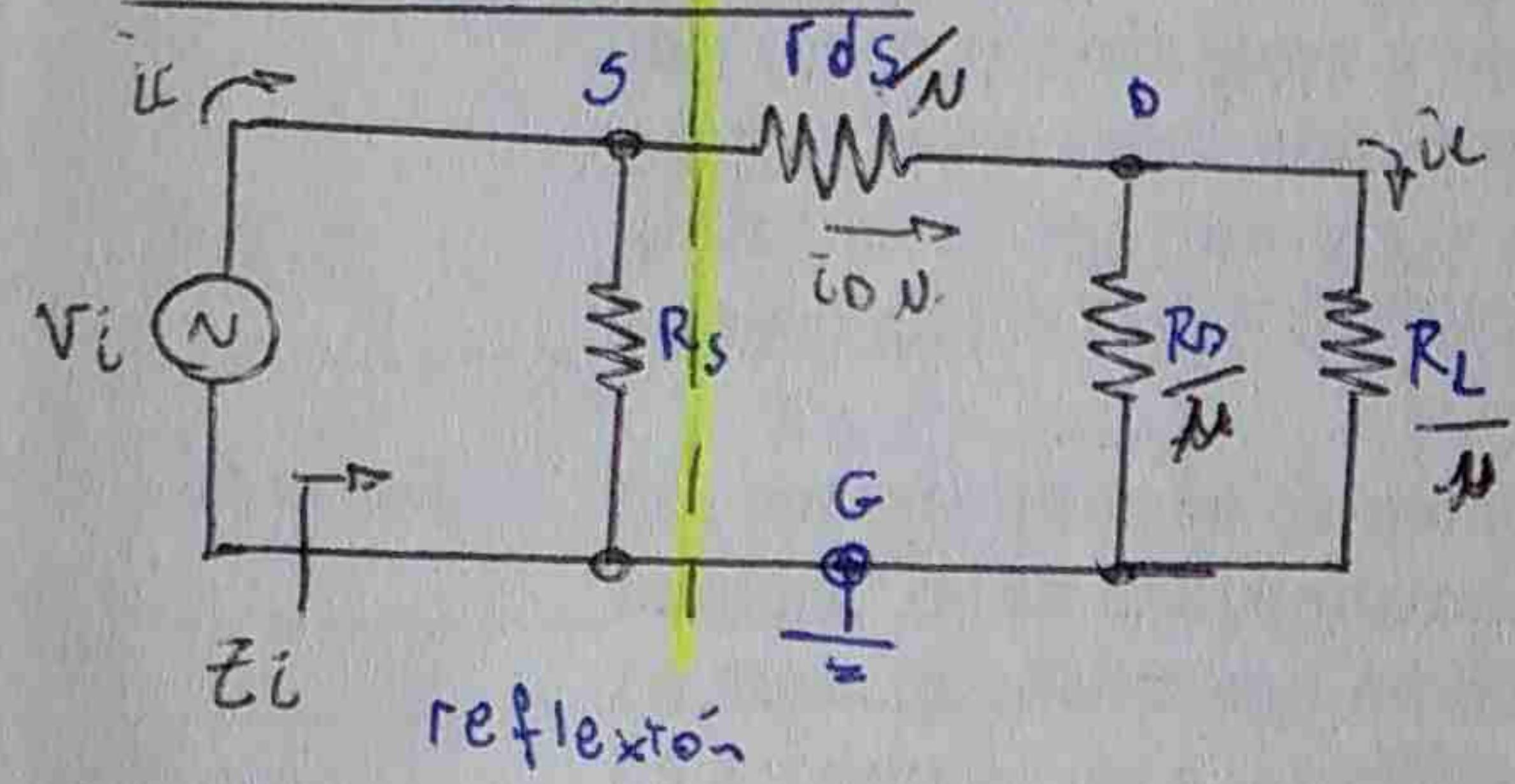


$$V_{DD} = V_{DSQ} + I_{DQ} (R_S + R_D)$$

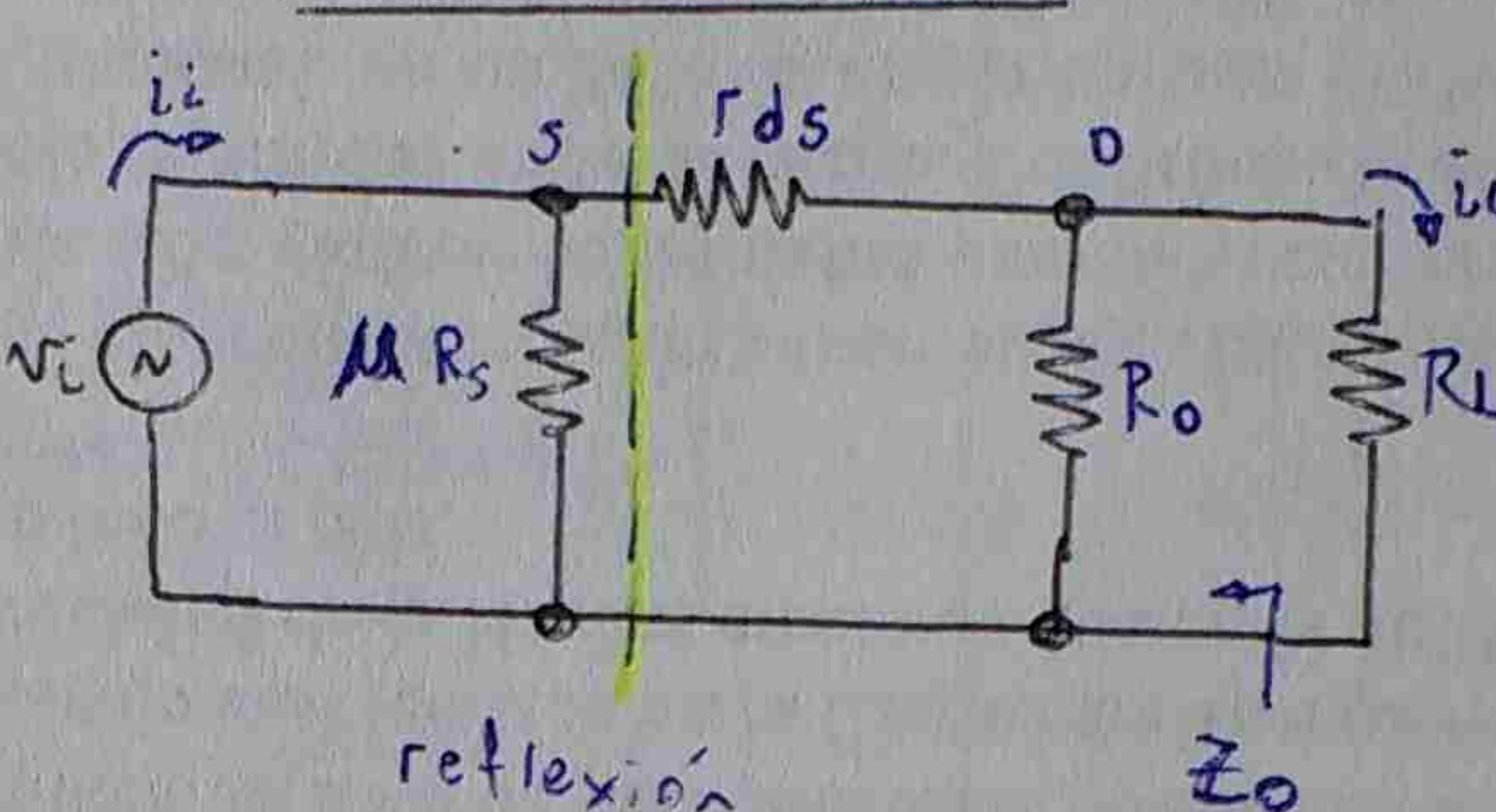
$$V_{BB} = V_{GSQ} + I_{DQ} R_S$$

$$\frac{N}{r_{ds}} = g_m$$

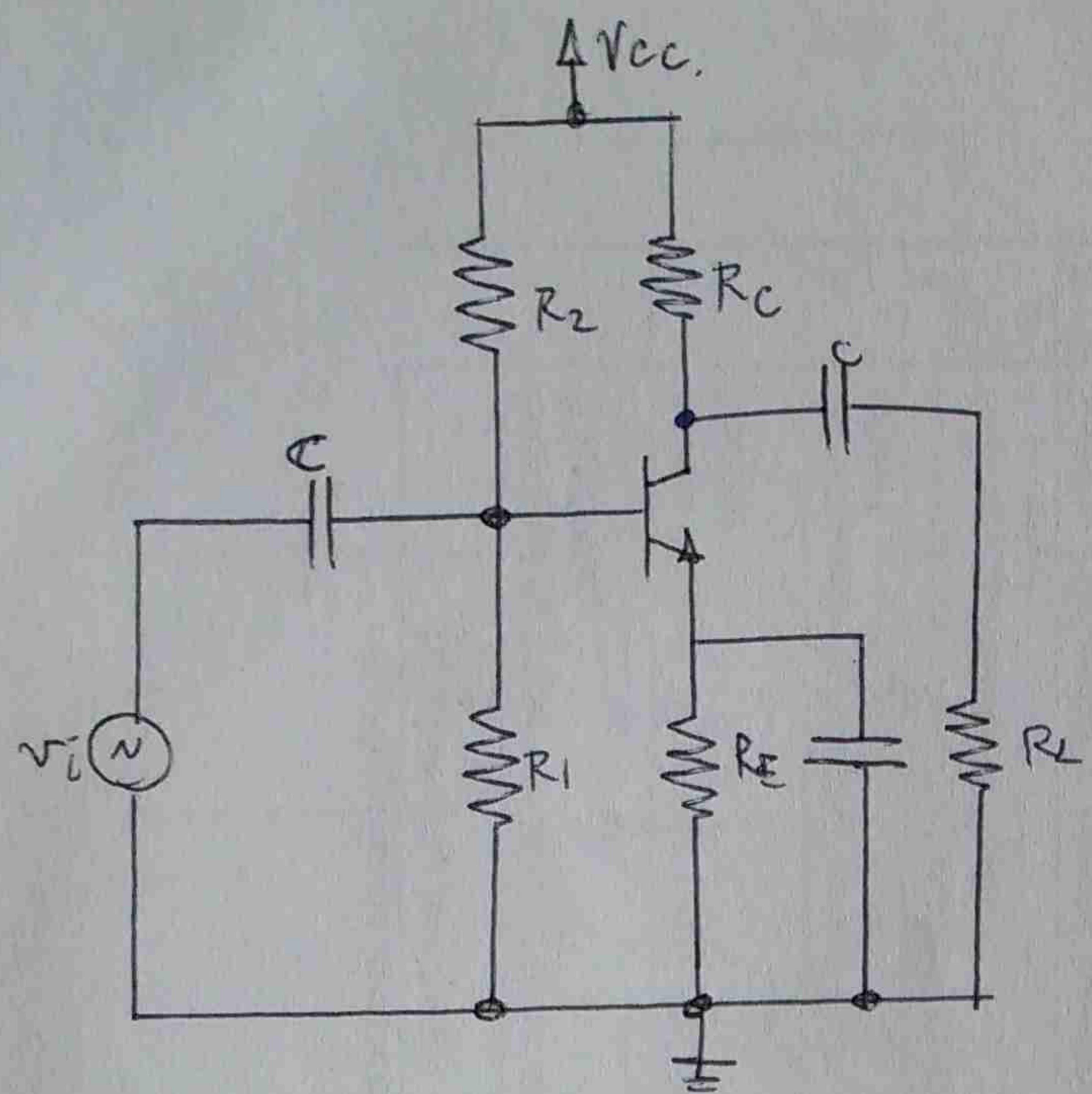
CIRCUITO ENREDADO.



CIRCUITO SALIDA.



Amplificador Emitter Coupled con Carga desacoplada



$$I_{CQ} = \frac{V_{BB} - V_{BE}}{\frac{R_B}{\beta} + R_E}$$

$$V_{CEQ} = V_{CC} - I_{CQ} (R_C + R_E)$$

$$h_{ie} = h_{fe} \frac{25mV}{I_{CQ}}$$

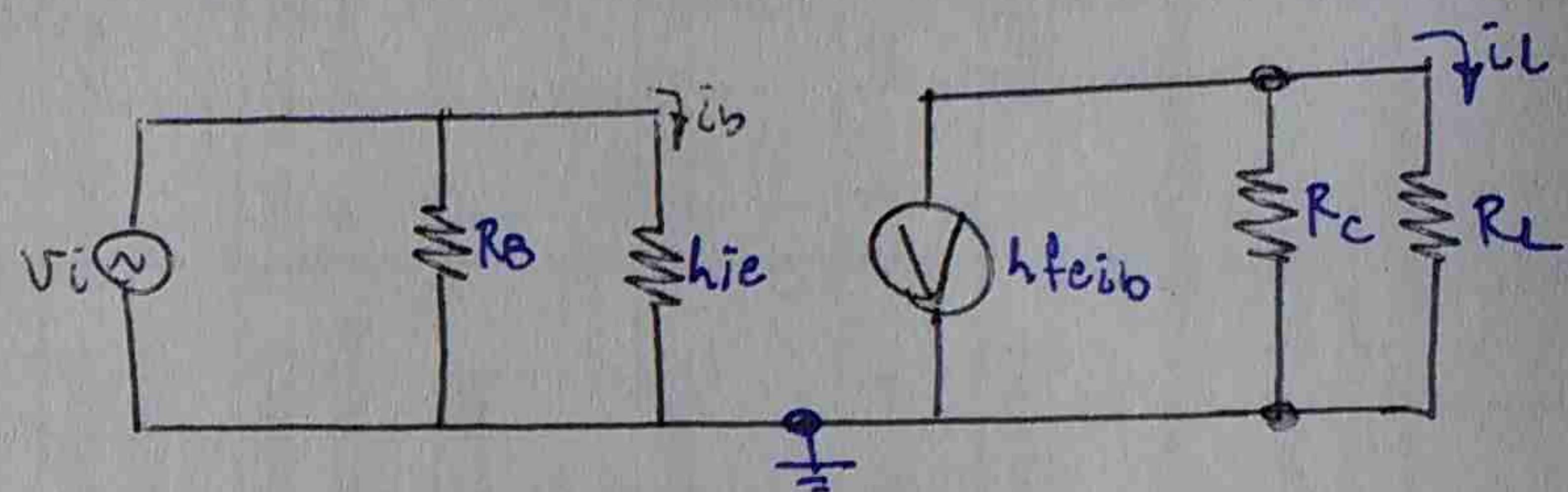
MES

$$I_{CQMES} = \frac{V_{CC}}{R_C + R_E + R_E // R_L}$$

$$P_{L-out} = \frac{I_{CQ}^2}{2} R_L$$

$$\tilde{C}_{L-out} = \frac{I_{CQ}}{2} = \frac{I_{CQ}}{2}$$

$$P_{CC-out} = V_{CC} I_{CQ}$$



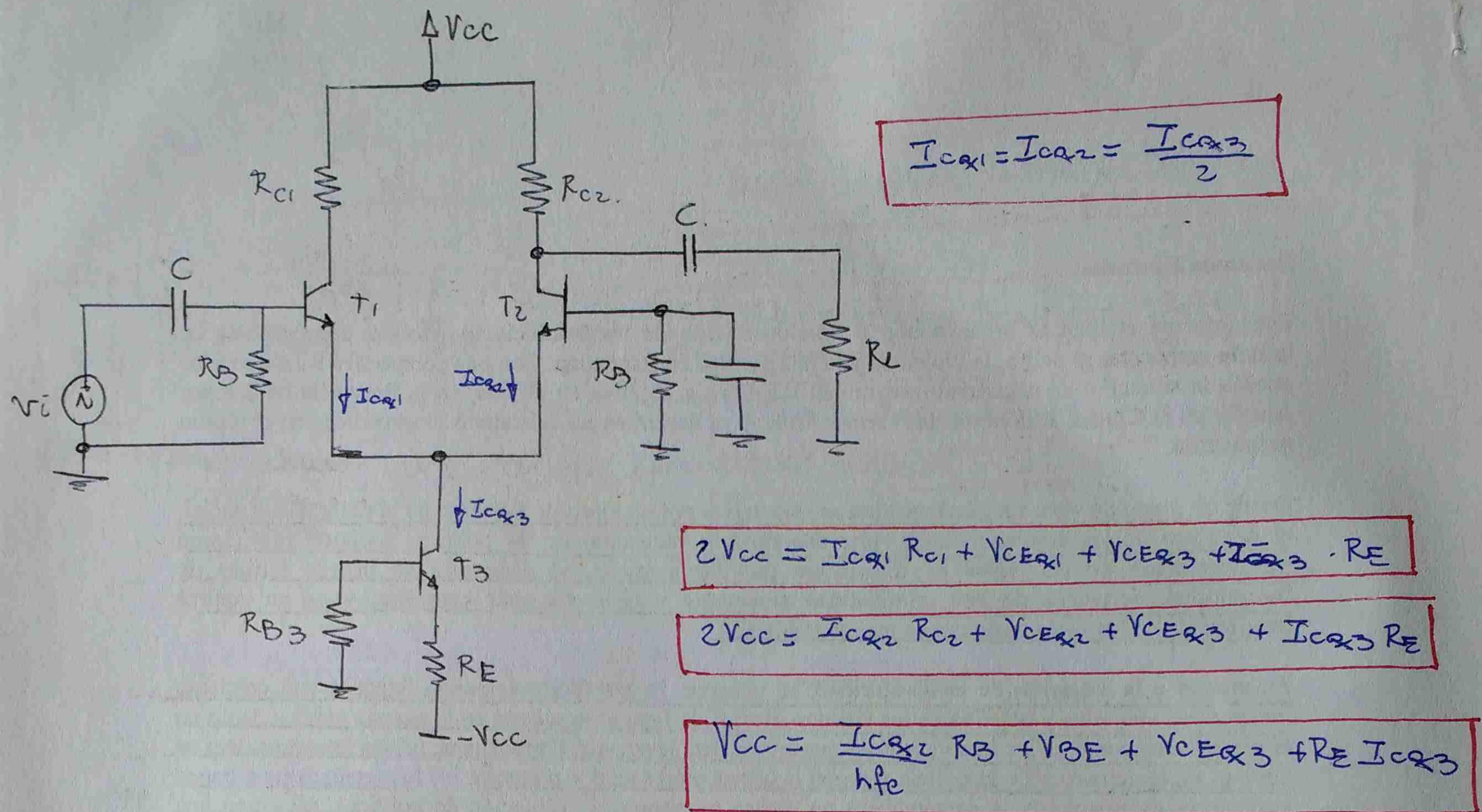
Parámetros estabilidad

$$S_V = -\frac{1}{R_E}$$

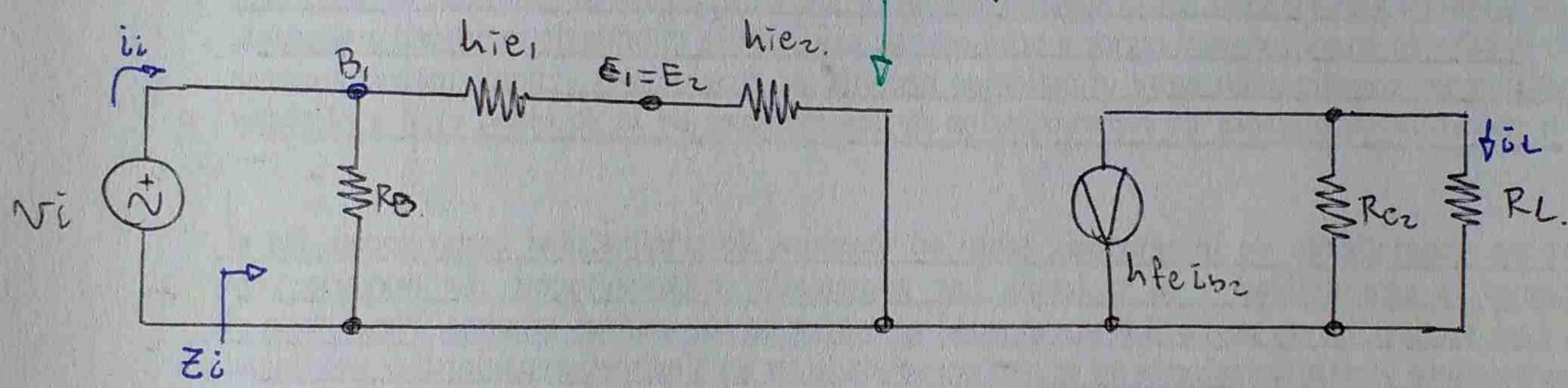
$$S_I = 1 + \frac{R_B}{R_C}$$

$$S_\beta = \frac{I_{CQ}}{\beta_i}$$

Amplificador Diferencial con 3 transistores



Circuito equivalente entrada.



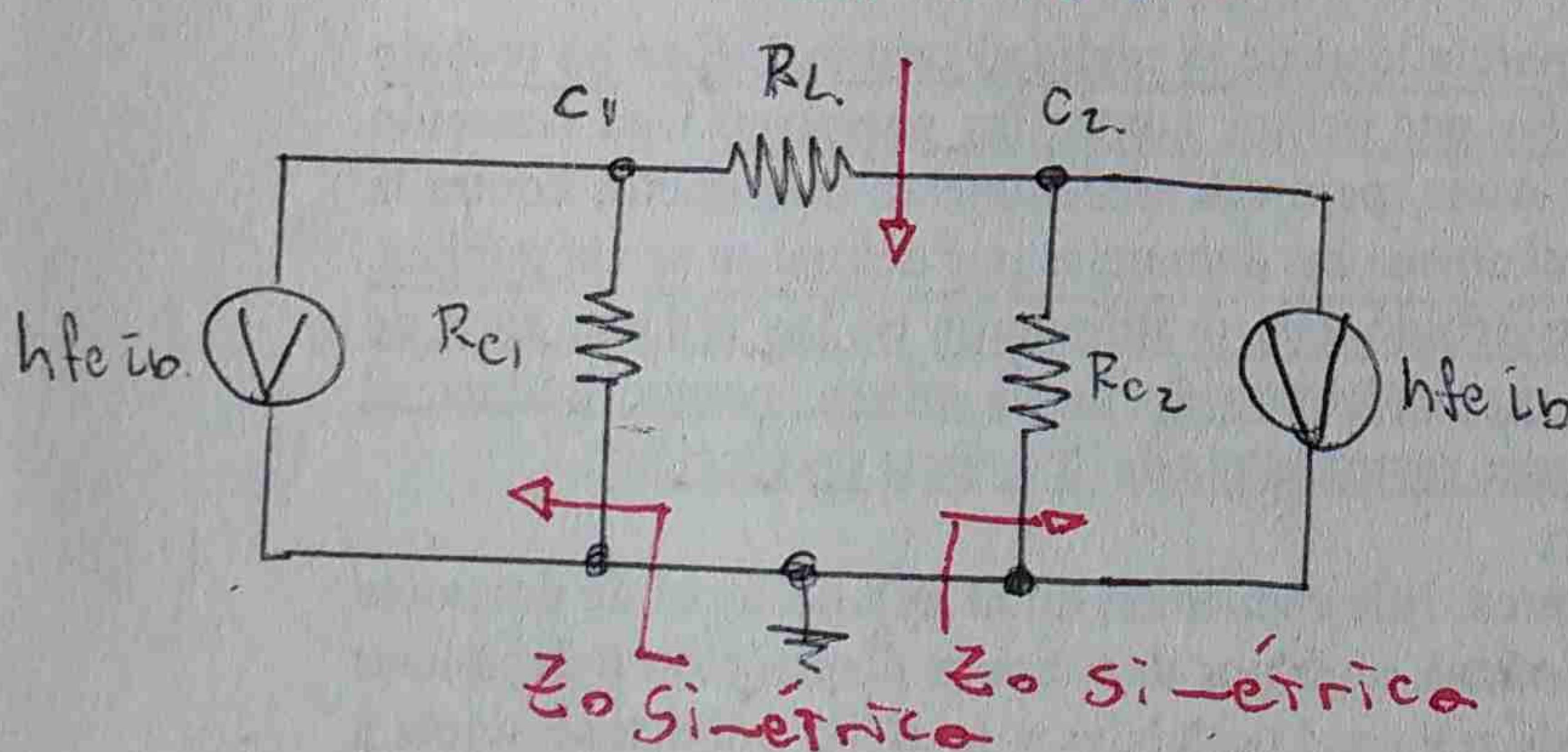
Ganancia modo común

Ganancia modo dif.

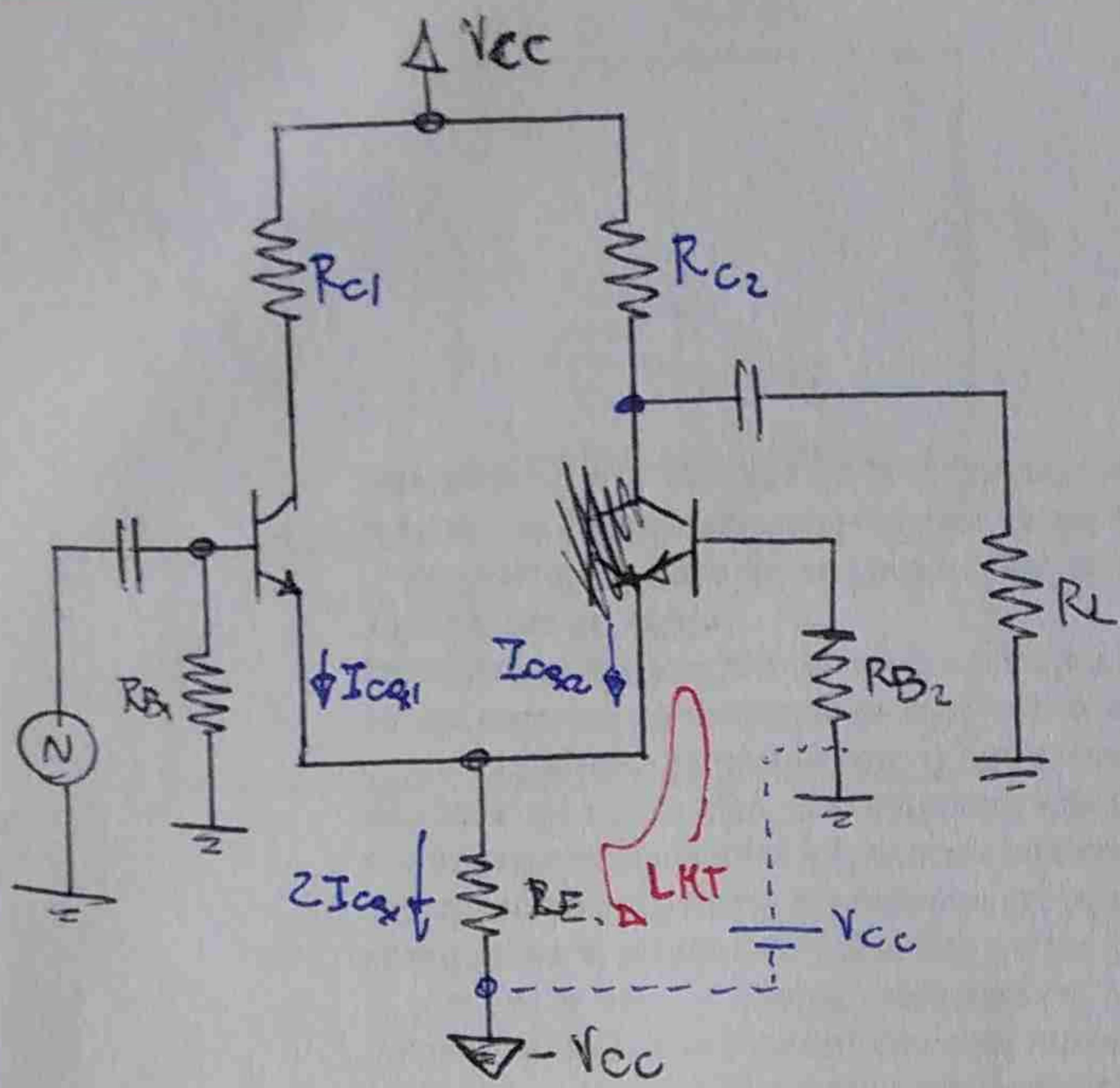
$$i_L = \Delta_C i_C + \Delta_d i_d$$

Corriente modo común

$$RRMC = \frac{\Delta_d}{\Delta_C}$$



Amplificador Diferencial



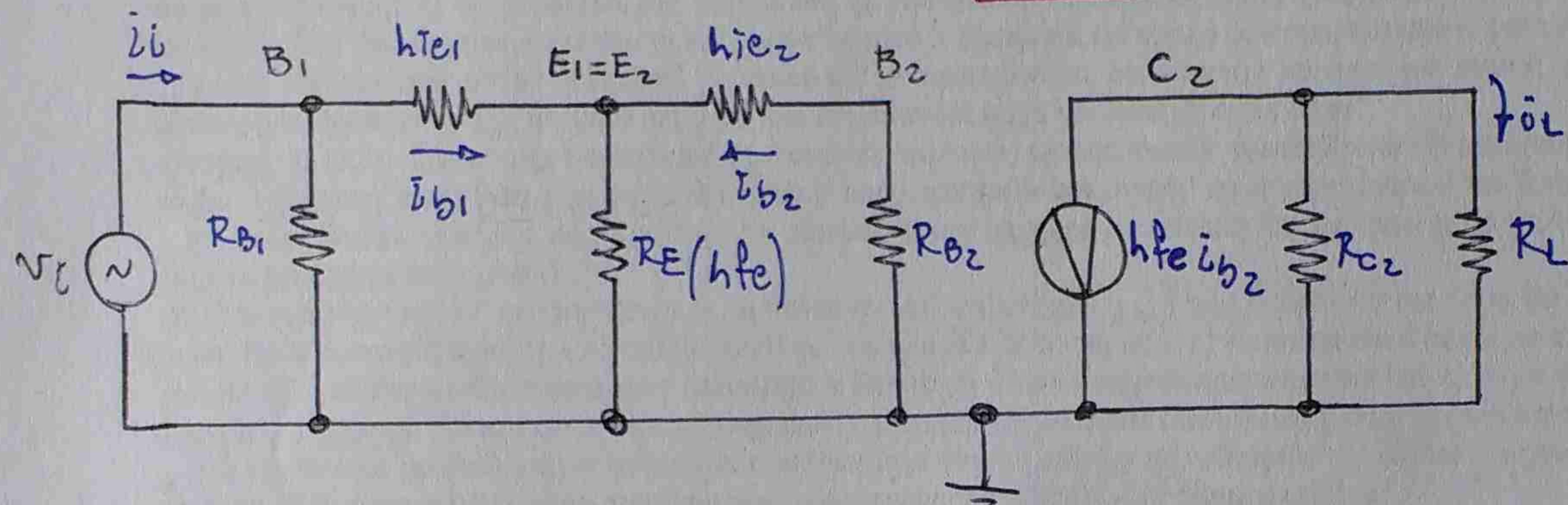
$$I_{CQ1} = I_{CQ2}$$

$$V_{CC} = \frac{I_{CQ}}{\beta} \cdot R_{B2} + V_{BE} + 2 I_{CQ} R_E$$

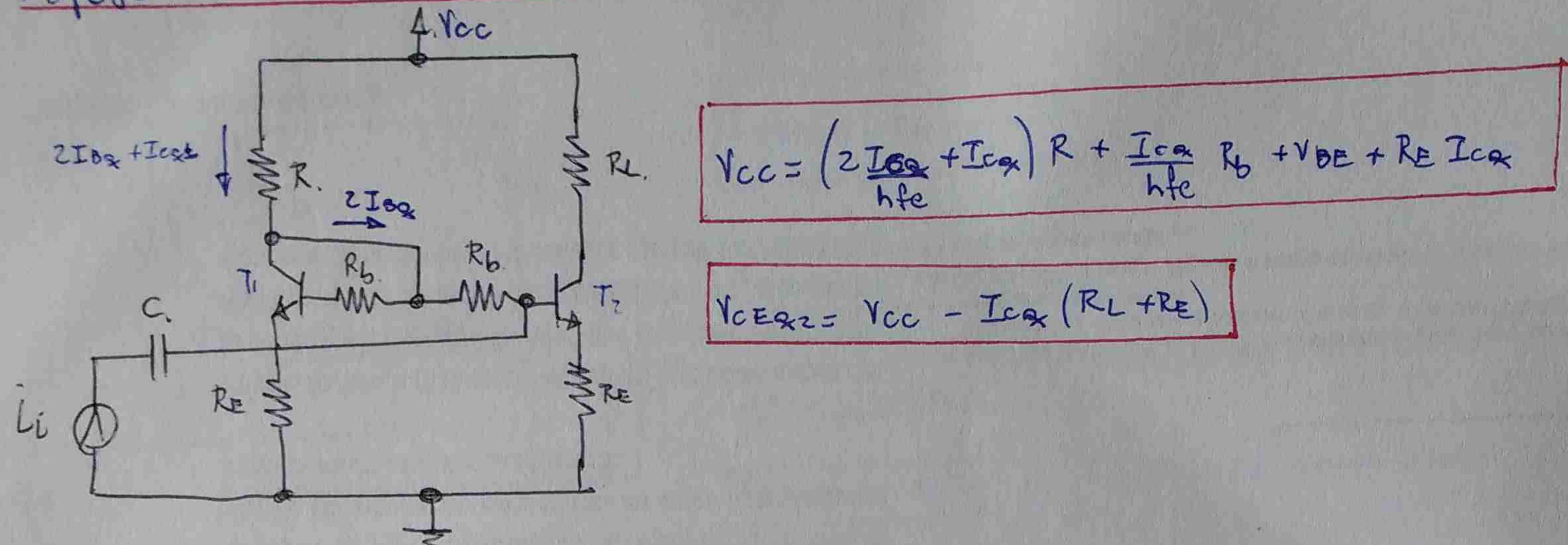
$$V_{CEQ1} = 2V_{CC} - I_{CQ} (R_{C1} + 2R_E)$$

$$V_{CEQ2} = 2V_{CC} - I_{CQ} (R_{C2} + 2R_E)$$

$$I_{CQ} = \frac{V_{EE} - V_{BE}}{\frac{R_B}{\beta} + 2R_E}$$

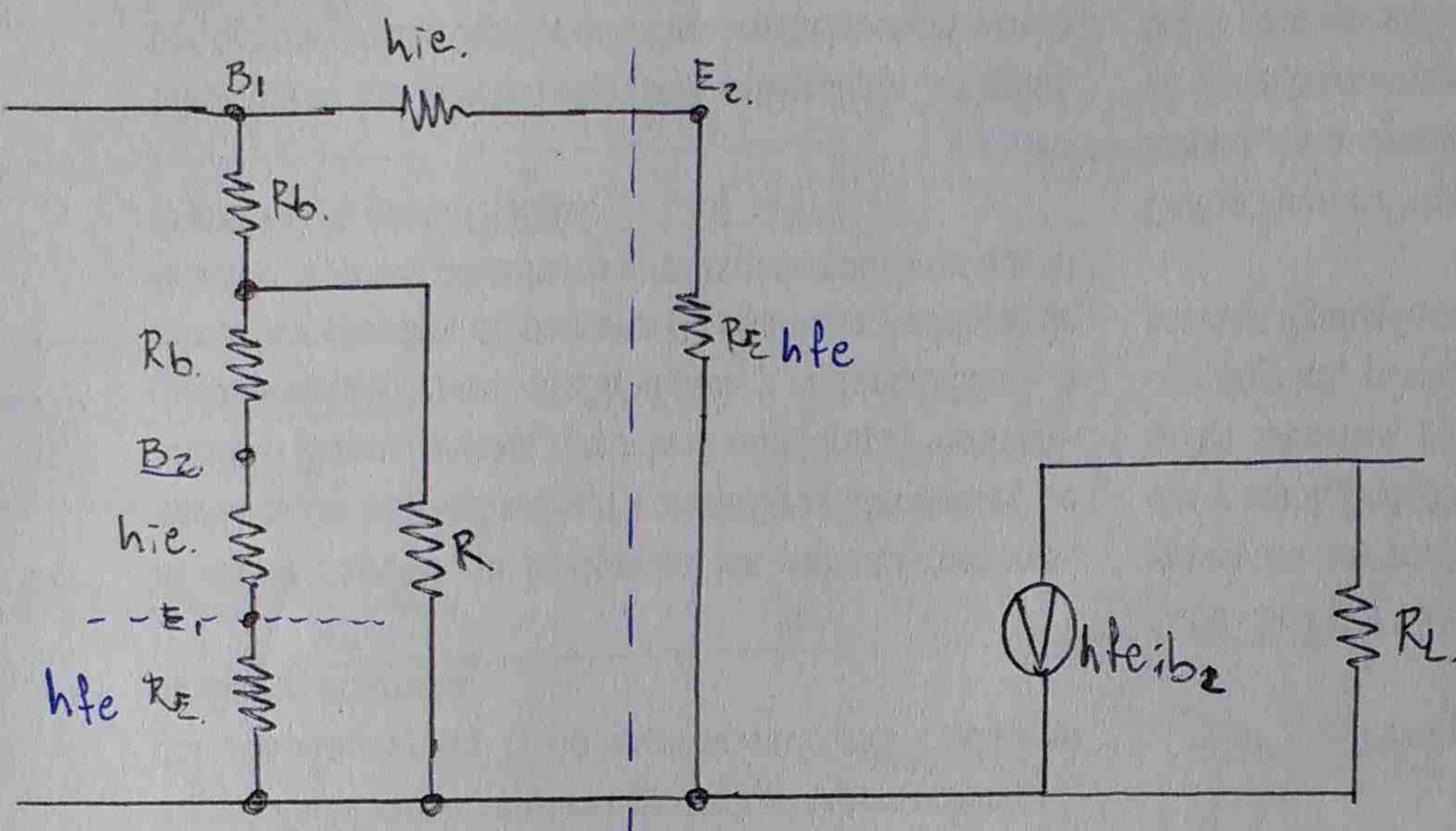


Espejo carrie. con Res.

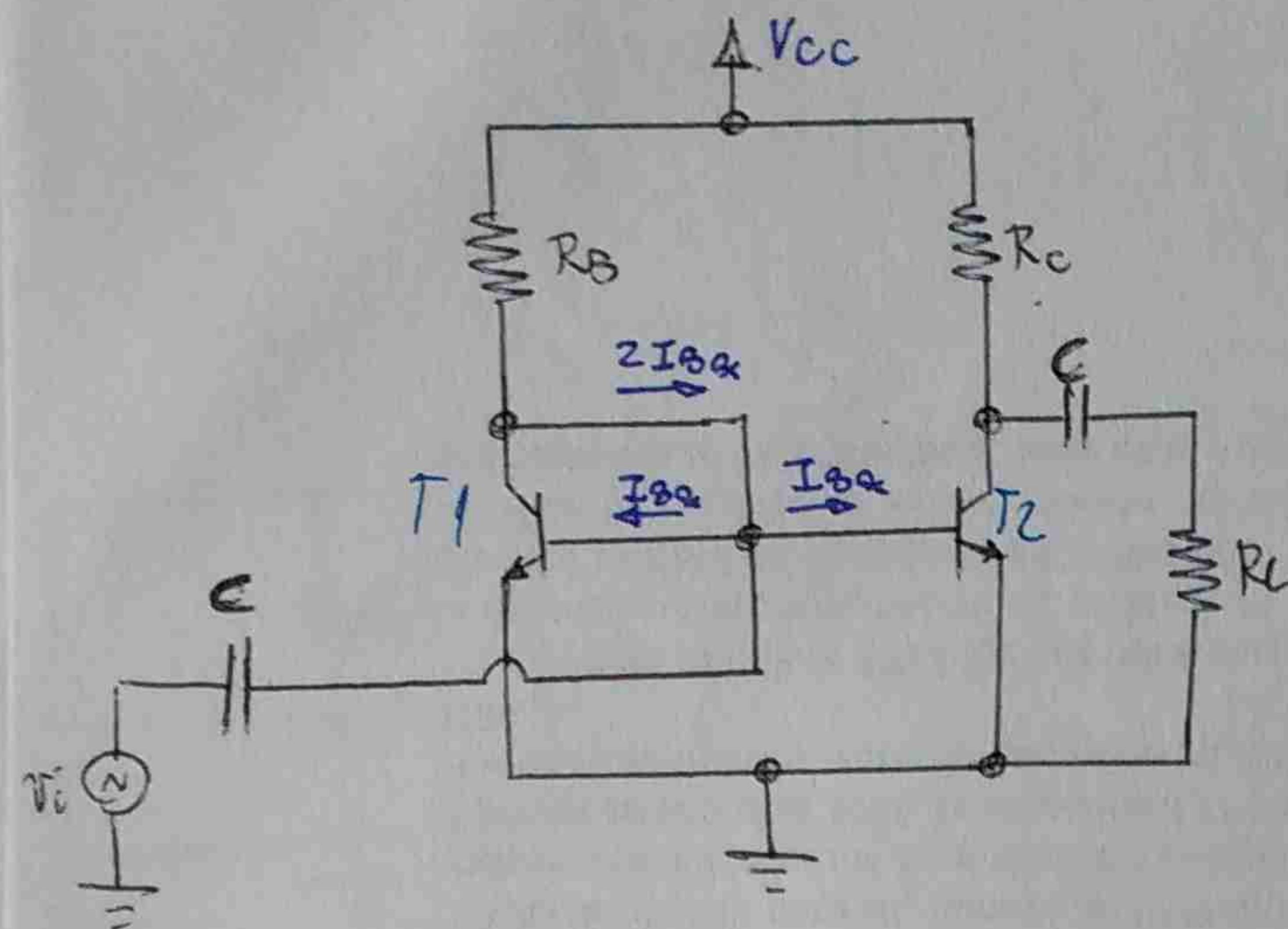


$$V_{CC} = \left(2 \frac{I_{BQ}}{h_{FE}} + I_{CQ} \right) R + \frac{I_{CQ}}{h_{FE}} R_b + V_{BE} + R_E I_{CQ}$$

$$V_{CEQ2} = V_{CC} - I_{CQ} (R_L + R_E)$$



Polarización Balanceada en circuitos integrados



$$I_{CQ2} = \frac{V_{CC} - V_{BE}}{R_B}$$

$$V_{CEQ2} = V_{CC} - I_{CQ2} R_C$$

$$I_{CQ1} = I_{CQ2}$$

$$V_{CEQ1} = 0.7$$

Espejo de corrientes

Lo utilizo como diodo

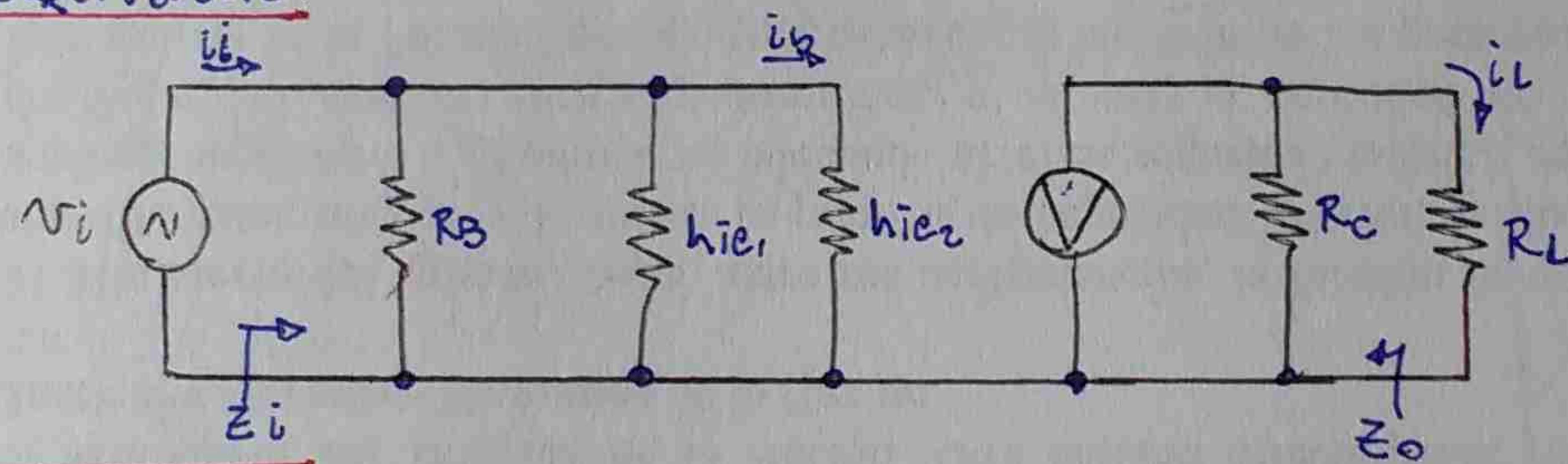
REBISERIO PARA MES

$$I_{CQMES} = \frac{V_{CC}}{R_{CC} + R_{CA}} = \frac{V_{CC}}{R_C + R_C // R_L}$$

$$V_{CEQ2MES} = V_{CC} - I_{CQMES} R_C$$

$$R_{BMES} = \frac{V_{CC} - V_{BE}}{I_{CQMES}}$$

CIRCUITO EQUIVALENTE.



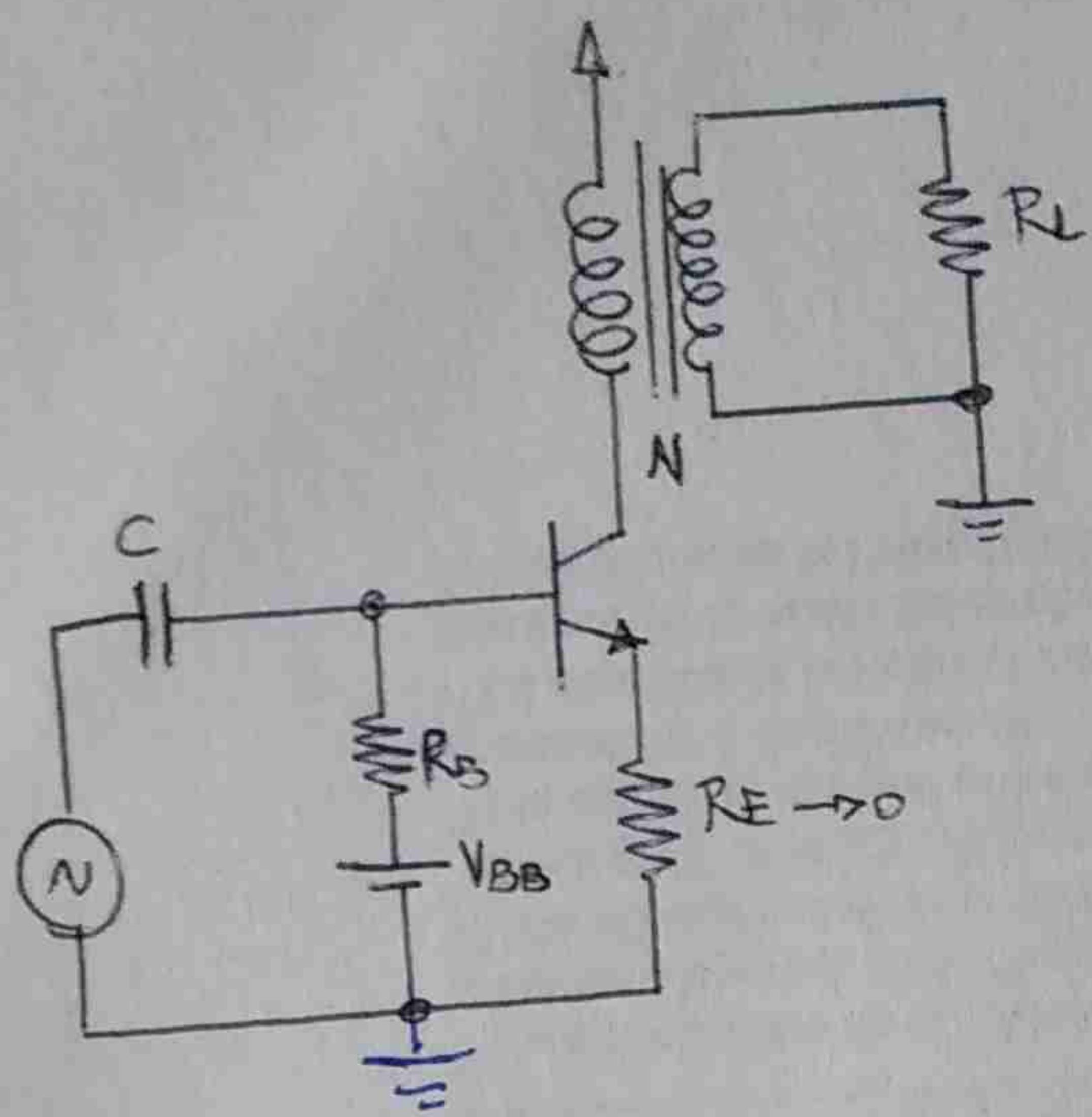
$$hie_1 = \frac{25mV}{I_{CQ1}}$$

$$Z_i = R_B // \frac{h_{ie}}{2}$$

$$A_i = \frac{i_L}{i_b} = \frac{i_L}{i_b} \frac{i_b}{i_b} = - \frac{R_C}{R_C + R_L} \cdot h_{fe} \cdot \frac{R_B // h_{ie_1}}{R_B // h_{ie_1} + h_{ie_2}}$$

$$\Delta I_{CQ} = \frac{K \Delta T}{R' B}$$

Amplificador clase A con oclavos para Transfer-odar



$$R'_L = N^2 R_L$$

$$h = 50\%$$

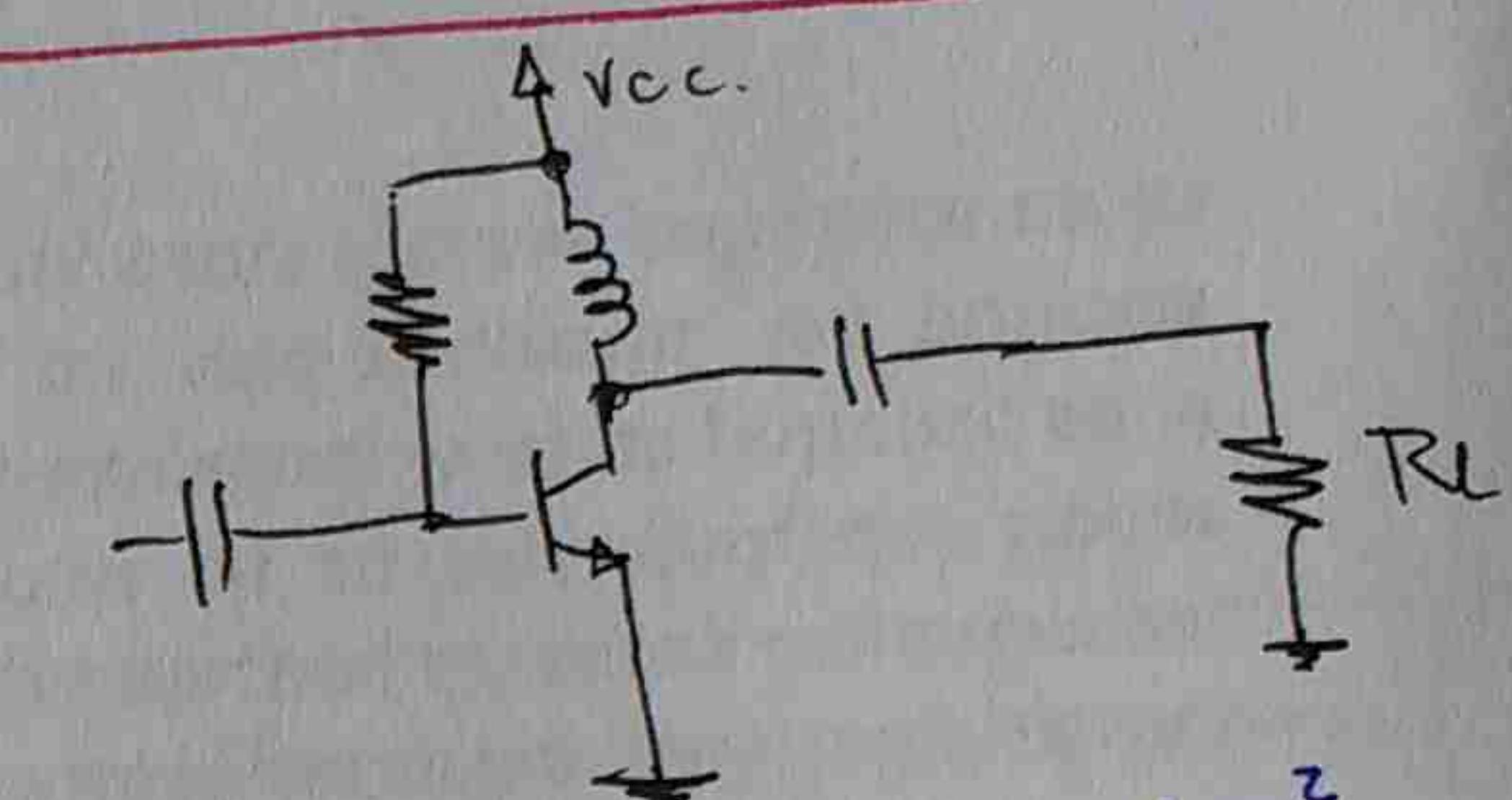
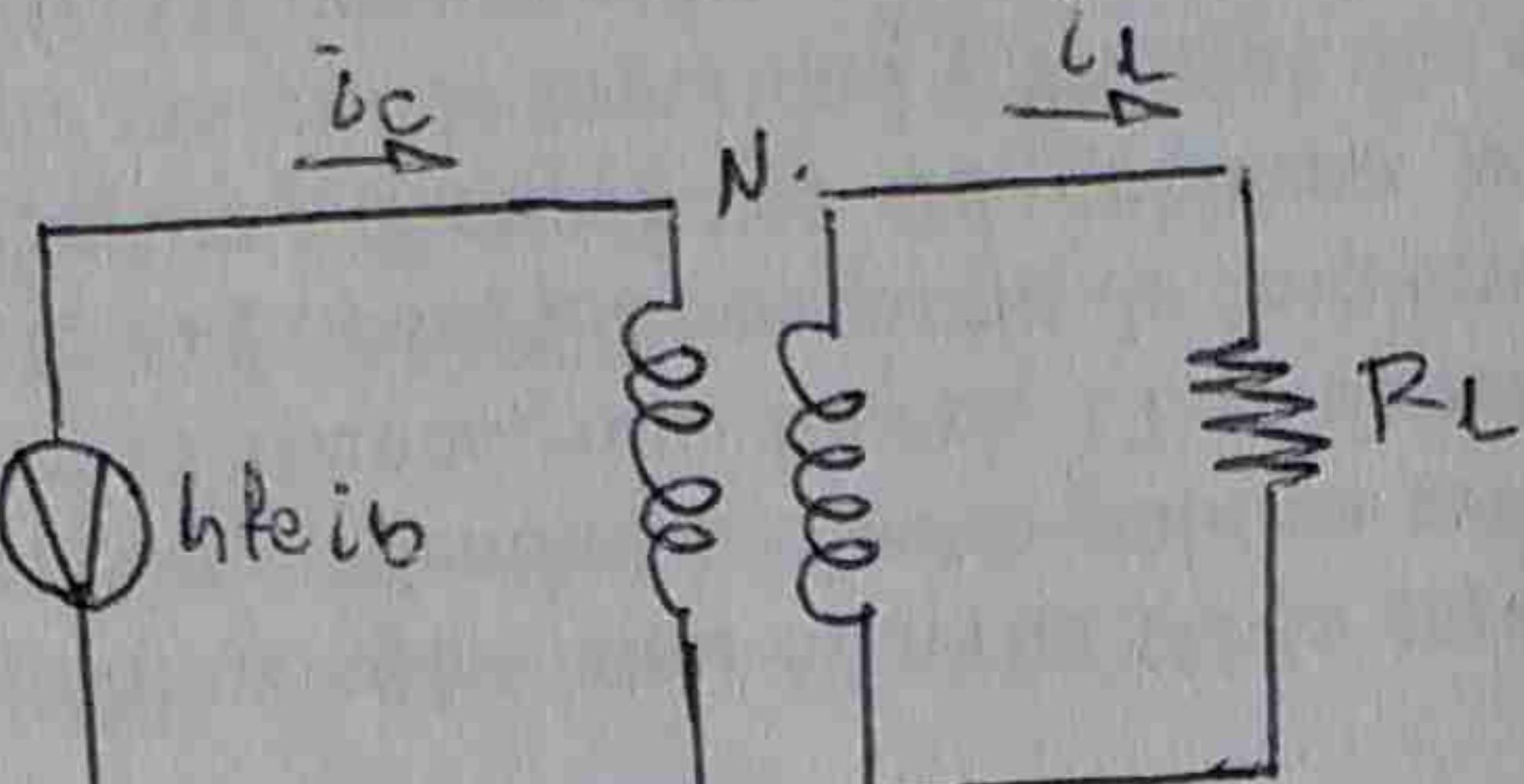
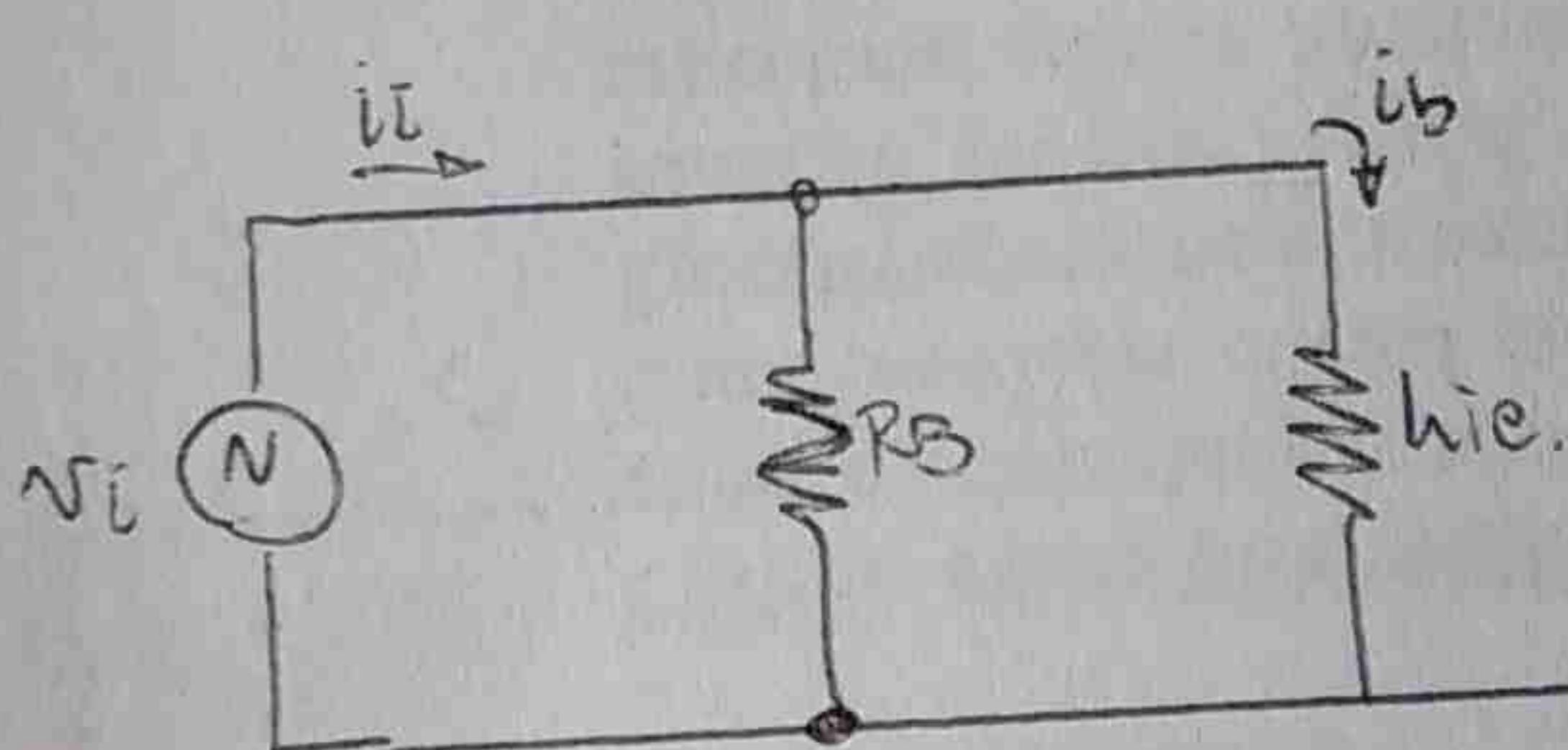
$$R_B = \left(\frac{V_{CC} - V_{BE}}{I_{CQ}} \right) \beta$$

$$P_{L_{MAX}} = \frac{V_{CC}^2}{2N^2 R_L}$$

$$P_{C_{MAX}} = V_{CC} I_{CQ}$$

$$I_{CQ} = \frac{V_{CC}}{N^2 R_L}$$

$$I_{CQ} = \frac{25mV}{h_{ib}}$$



$$F_M = 2 = \frac{P_{C_{MAX}}}{P_{L_{MAX}}} \Rightarrow \frac{V_{CC}^2}{2RL} = \frac{P_{C_{MAX}}}{2}$$

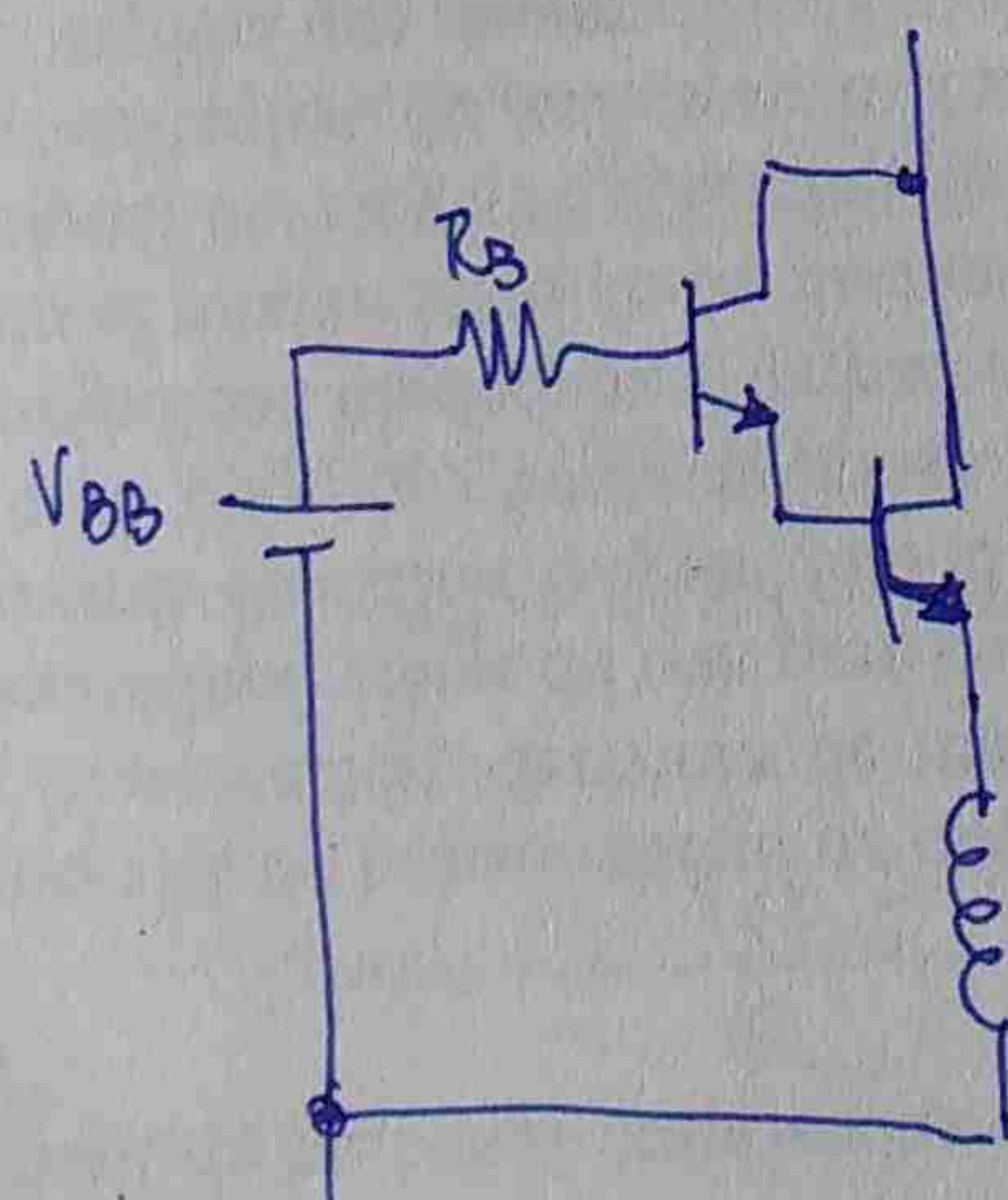
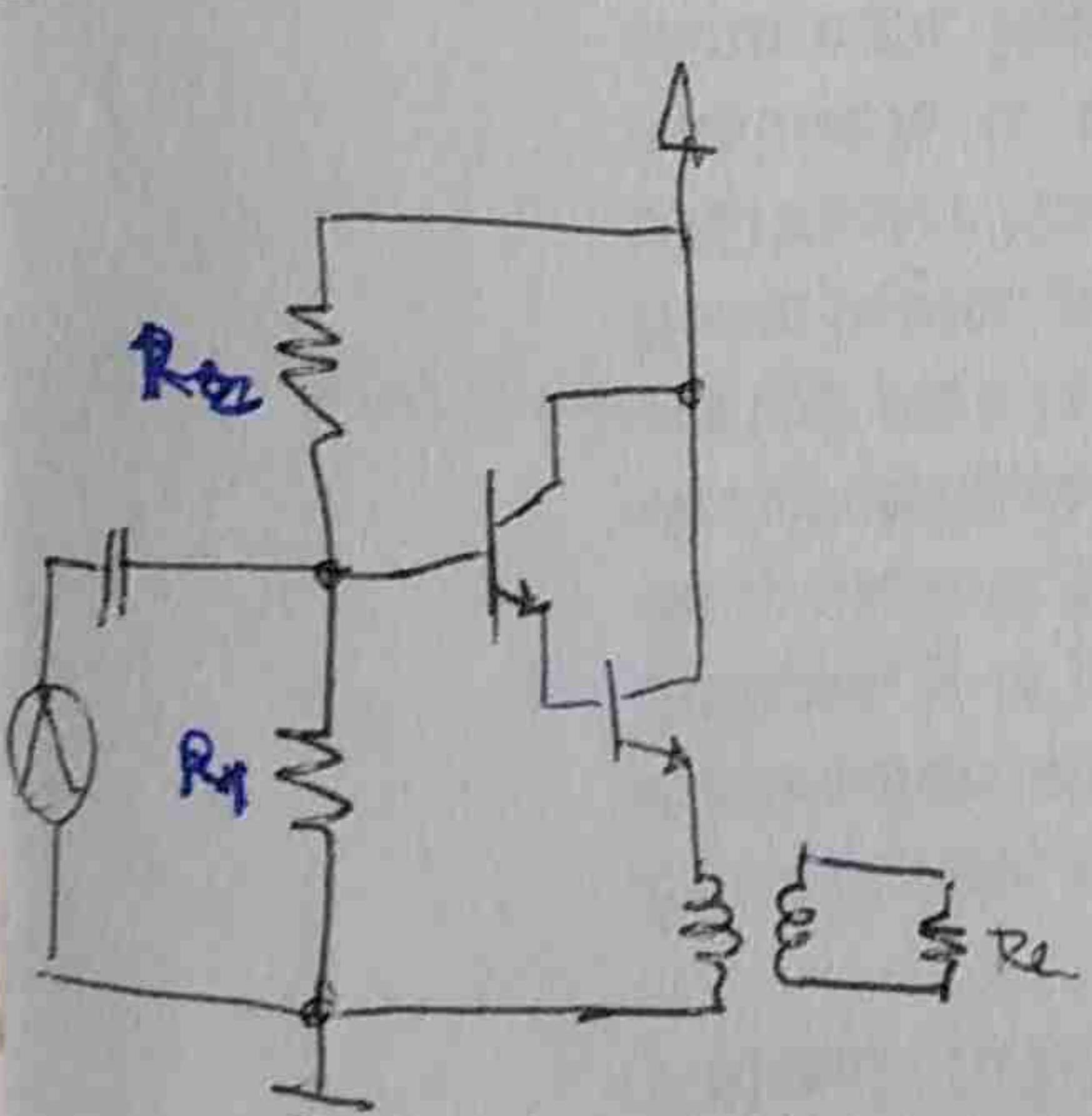
$$P_{C_{MAX}} = \frac{V_{CC}^2}{RL}$$

$$I_{CQ} = \frac{V_{CC}}{RL}$$

$$V_L = \frac{V_C}{N} \Rightarrow \frac{V_L}{V_C} = \frac{1}{N}$$

$$V_C = h_{fe} i_b R' L \Rightarrow \frac{V_C}{i_b} = h_{fe} R' L$$

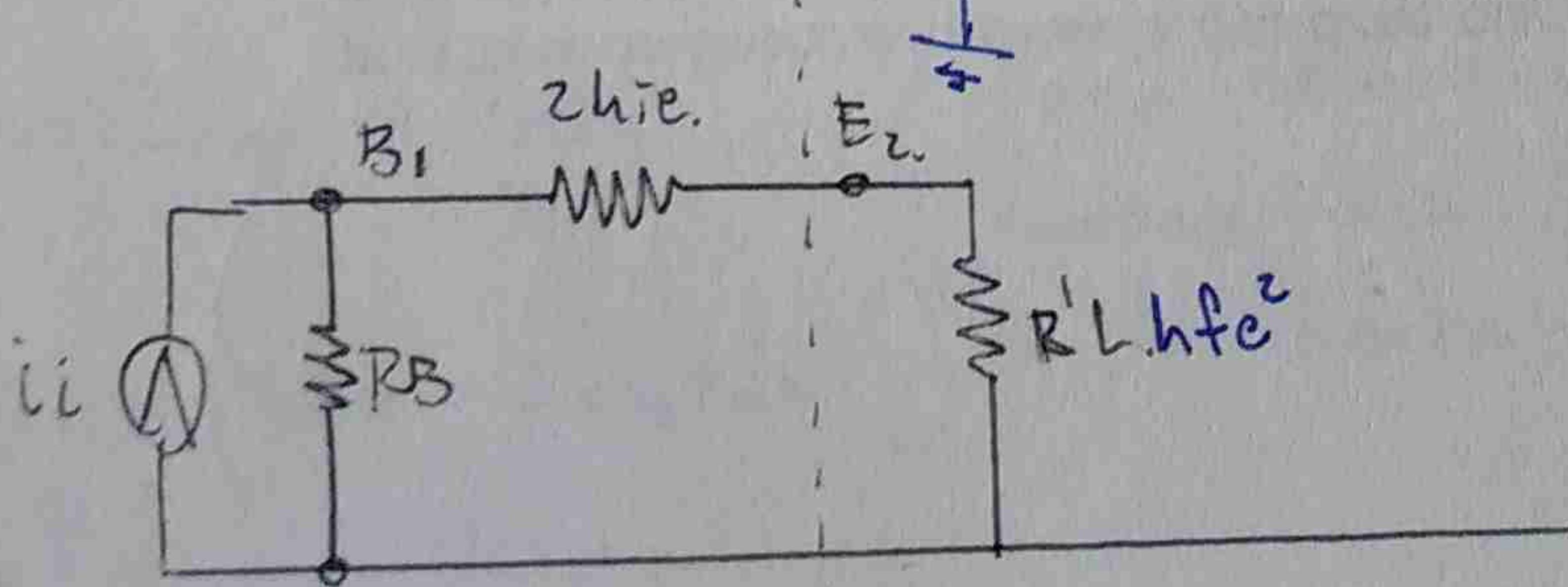
$$i_b = \frac{V_i}{h_{ie}} \Rightarrow \frac{i_b}{V_i} = \frac{1}{h_{ie}} = \frac{1}{h_{fe} h_{ib}}$$



$$V_{BB} = R_B \frac{I_{CQ2}}{h_{fe}^2} + 2V_{BE}$$

$$V_{CEQ2} = V_{CC}$$

$$V_{CEQ1} = V_{CEQ2} - V_{BE}$$



$$\alpha = \frac{\beta}{\beta + 1}$$

$$\beta = \frac{\alpha}{1 - \alpha}$$

$$I_c = \alpha I_E + I_{CBO} \rightarrow I_E = \frac{I_c - I_{CBO}}{\alpha}$$

$$I_E = I_c + I_S$$

(1)

$$I_B = I_E - I_c = I_E - \alpha I_E - I_{CBO}$$

$$I_B = \frac{I_c - I_{CBO}}{\alpha} (1 - \alpha) - I_{CBO}$$

$$= \frac{I_c}{\alpha} (1 - \alpha) - \frac{I_{CBO}}{\alpha} (1 - \alpha) - I_{CBO}$$

$$= I_c \frac{1 - \alpha}{\alpha} - I_{CBO} \left(\frac{1 - \alpha + \alpha}{\alpha} \right)$$

$$I_B = I_c \left(\frac{1 - \alpha}{\alpha} \right) - \frac{I_{CBO}}{\alpha}$$

MES: El punto que se encuentra en la mitad del recto de carga de Alterno (CA)

• Si está diseñado para MES puede no estar funcionando para MES

• Si está funcionando para MES, es porque fue diseñado para MES

$$E_{CC} \quad V_{CC} = V_{CEQ} + I_{CQ} R_{CE}$$

$$CA \quad V_{CEQ} = I_{CQ} R_{CE}$$

$$\begin{cases} I_{CQ} = I_{CQ} \\ V_{CEQ} = V_{CEQ} \end{cases}$$

$$V_{CEQ, MES} = I_{CQ, MES} R_{CE}$$

Reemplazo en ①

$$V_{CC} = I_{CQ, MES} R_{CE} + I_{CQ, MES} R_{CE}$$

$$I_{CQ, MES} = \frac{V_{CC}}{R_{CE} + R_{CE}}$$

Formula General

Emissor Co-án

$$I_{CQ, MES} = \frac{V_{CC}}{R_{CE} + R_E + R_C // R_L}$$

Si $V_{CESAT} \neq 0$

$$\begin{cases} I_{CQ, MES} = I_{CQ} \\ V_{CEQ, MES} = V_{CEQ} - V_{CESAT} \end{cases}$$

$$I_{CQ, MES} = \frac{V_{CC} - V_{CESAT}}{R_{CE} + R_{CE}}$$

$$I_C = I_{CQ} + \frac{V_{CEQ}}{R_{CE}}$$

$$V_{CE} = V_{CEQ} + I_{CQ} R_{CE}$$

para encontrar los cortes con los ejes, de la Recta de CA



maxima señal en alterno

(2)

Potencia proedio

$$P(t) = V_{AV} I_{AV} + \frac{1}{T} \int_0^T V(t) i(t) dt$$

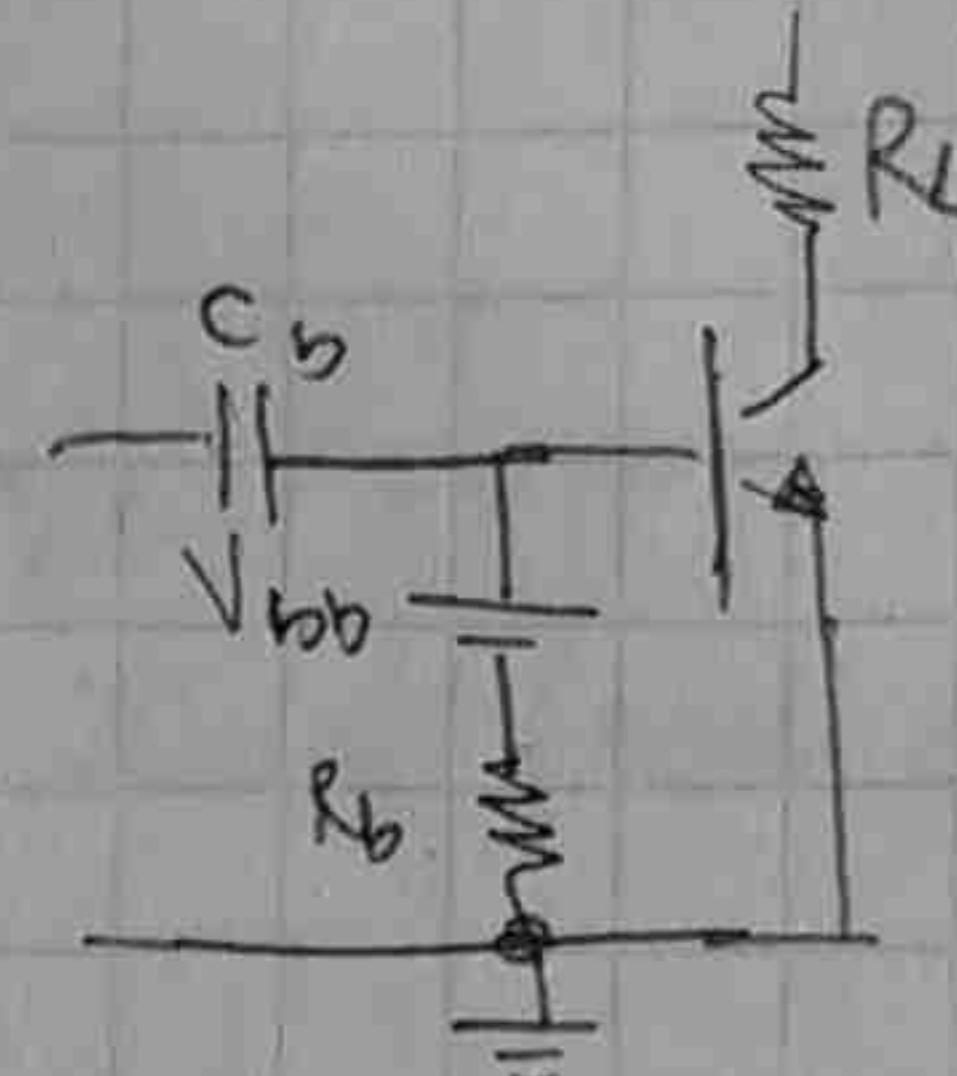
$$P_{CC} = V_{CC} I_{CC}$$

Para mes.

$$P_{CC\text{ max}} = \frac{V_{CC}^2}{2RL}$$

Potencia en la carga

$$P_L(CA) = \frac{1}{2} i_o^2 RL$$

Rendimiento:

$$\eta = \frac{P_L}{P_{CC}}$$

Potencia útil en la carga

Potencia de la fuente de alimentación

Para la config anterior

$$P_{L\text{ max}} = \frac{V_{CC}^2}{8RL}$$

$$P_{CC\text{ max}} = \frac{V_{CC}^2}{2RL}$$

$$\eta = 0.25 = 25\%$$

Factor

Factor de Mérito

$$F_M = \frac{P_{\text{Cmax}}}{P_{L\text{-máx}}}$$

Potencia máxima disipada en el colector
 " " " " la carga
 (3)

$P_C\text{-máx}$ ocurre sin señal

$P_{L\text{-máx}}$ con señal máxima

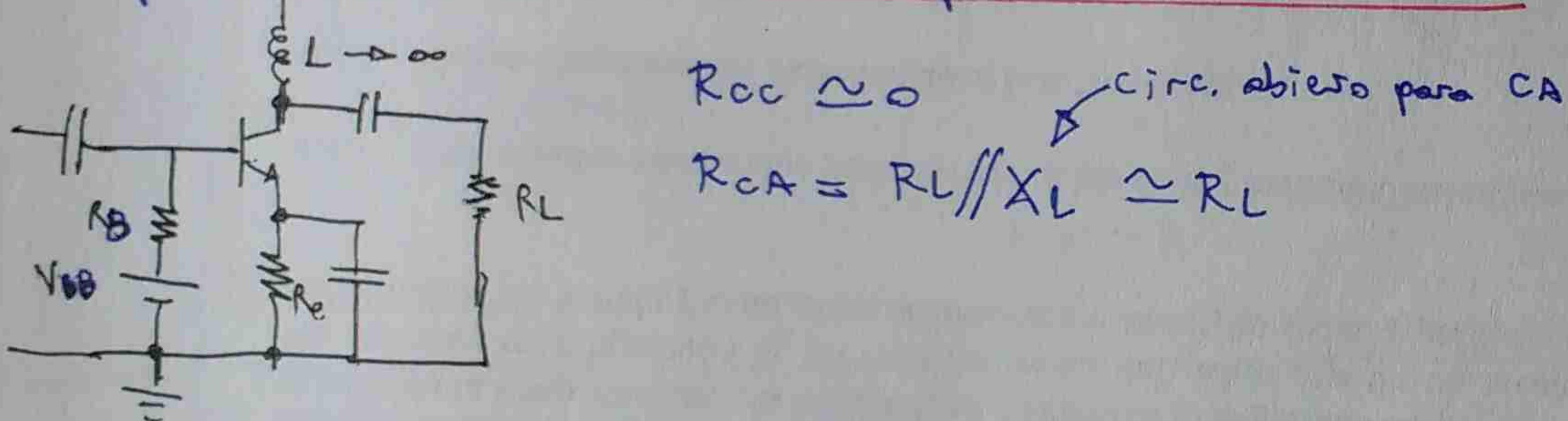
Para MES

$$F_M = \frac{\frac{V_{CC}^2}{4R_L}}{\frac{V_{CC}^2}{8R_L}} = 2$$

Teniendo como dato $P_{L\text{-máx}}$ y utilizando el OVS (25%) como voltaje máximo para MES y también conociendo V_{CC} , se despeja el I_{CQ} (que será para MES y máximo rendimiento)

$$\eta_{\text{max}} = \frac{P_{L\text{-máx}}}{P_{C\text{-máximo}}} = 0.25 \Rightarrow P_{C\text{max}} = \frac{P_{L\text{-máx}}}{0.25} = V_{CC} I_{CQ\text{MES}} \Rightarrow I_{CQ\text{MES}} = \frac{P_{L\text{-máx}}}{0.25 V_{CC}}$$

Amplificador clase A con acoplamiento por inductor



Si $R_E \rightarrow 0$, ¿quier limita a I_{CQ} ?

$$I_{CQ} = \frac{V_{BB} - V_{BE}}{\frac{R_B}{\beta} + R_E}$$

R_B limita a I_{CQ}

Antes.

$$2V_{CEQ} \leq V_{CC}$$

$$V_{BCEO} < V_{CC}$$

Ahora.

$$V_{BCEO} < 2V_{CC}$$

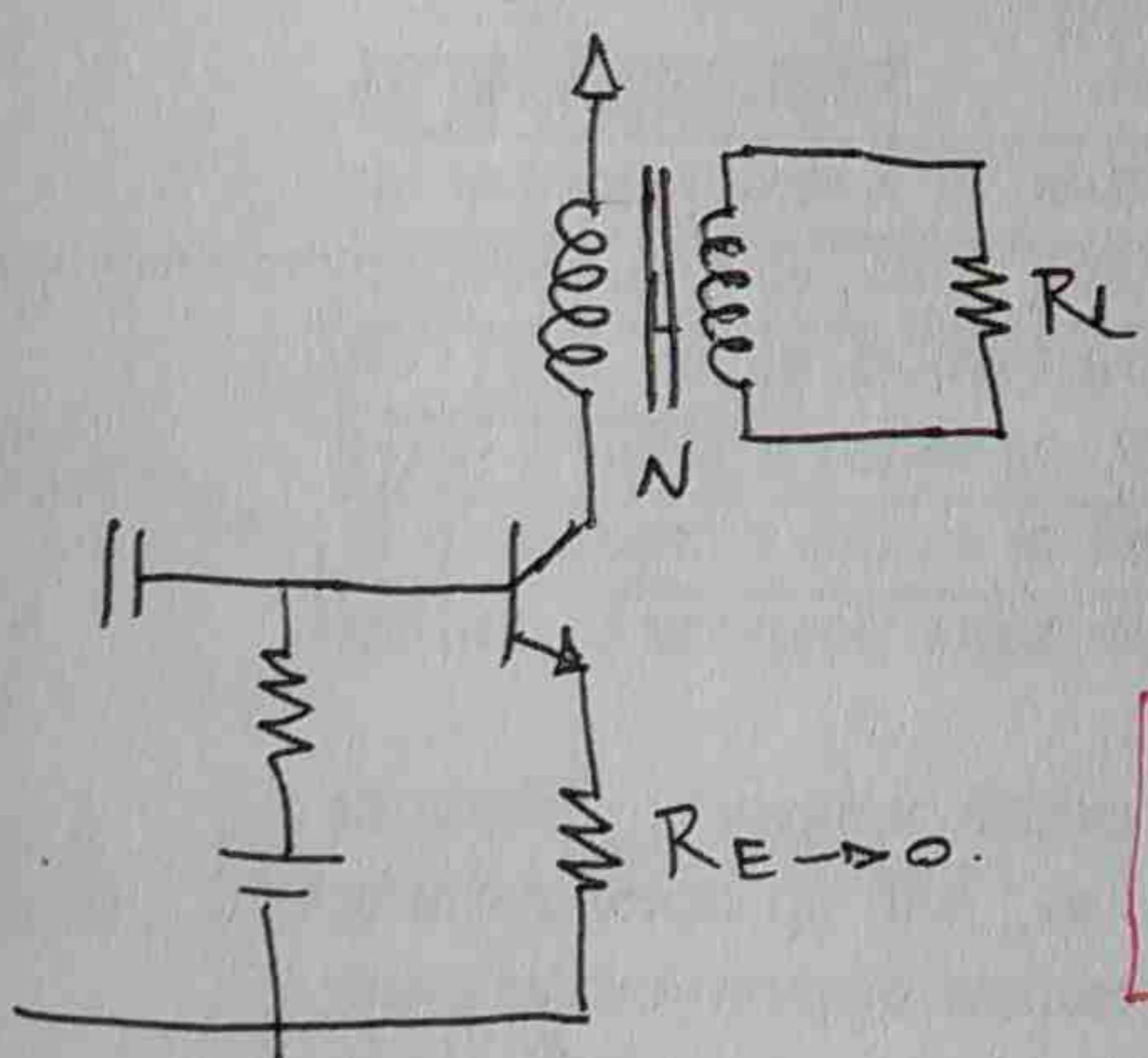
$$V_{CC} < \frac{V_{BCEO}}{2}$$

4

Máxima Potencia

$C/RL = R_C$	$C/Choque Bobina$
$P_{CC} = V_{CC} \cdot I_{CC}$	
$P_{CC-\max} = \frac{V_{CC}^2}{2RL}$	$P_{CC-\max} = \frac{V_{CC}^2}{RL}$
$P_{LCA-\max} = \frac{V_{CC}^2}{8RL}$	$P_{LCA-\max} = \frac{V_{CC}^2}{2RL}$
$P_C = P_{CC} - P_{LCA} - P_{LCA}$	$P_C = P_{CC} - P_{LCA}$
$P_C-\max = \frac{V_{CC}^2}{4RL}$	$P_C-\max = \frac{V_{CC}^2}{RL}$
$P_{C-in} = \frac{V_{CC}^2}{8RL}$	$P_{C-in} = \frac{V_{CC}^2}{2RL}$
$h_{\max} = 25\%$	$h_{\max} = 50\%$
	$F_M = 2$

A-amplificador clase A por oscilación par indutor transfer-odar



Es igual al anterior solo que

$$R'_L = N^2 RL$$

N debe estar entre determinados valores.

$$N_{\max} = \frac{1}{I_{CQ1}} \sqrt{\frac{2P_{L\max}}{RL}}$$

$$N_{in} = \frac{1}{I_{CQ2}} \sqrt{\frac{2P_{L\max}}{RL}}$$

$$V_{CEQ1} = \frac{V_{BCEO}}{2} \rightarrow I_{CQ1} = \frac{P_{C\max}}{V_{CEQ1}}$$

$$N = \frac{N_{\max} + N_{in}}{2}$$

$$I_{CQ2} = \frac{I_{C\max}}{2}$$

$$V_{CC} = N \sqrt{2P_{L\max} RL} = V_{CEQ}$$

$$R_b = \left(\frac{V_{CC} - V_{BE}}{I_{CQ}} \right) \beta$$

Estabilidad Polarización (carpeta)

Análisis de los factores de estabilidad

Cuanto menores sean los factores de estabilidad, mayor será la estabilidad ΔI_{CQ} (5)

$$\frac{\partial I_{CQ}}{\partial T} = \frac{\partial I_{CQ}}{\partial V_{BE}} \frac{\partial V_{BE}}{\partial T} + \frac{\partial I_{CQ}}{\partial I_{CBO}} \frac{\partial I_{CBO}}{\partial T} + \frac{\partial I_{CQ}}{\partial \beta} \frac{\partial \beta}{\partial T} + \dots$$

$$\frac{\Delta I_{CQ}}{\Delta T} = \frac{\Delta I_{CQ}}{\Delta V_{BE}} \frac{\Delta V_{BE}}{\Delta T} + \frac{\Delta I_{CQ}}{\Delta I_{CBO}} \frac{\Delta I_{CBO}}{\Delta T} + \frac{\Delta I_{CQ}}{\Delta \beta} \frac{\Delta \beta}{\Delta T}$$

$$\Delta I_{CQ} = S_V \Delta V_{BE} + S_I \Delta I_{CBO} + S_\beta \Delta \beta$$

Factores de estabilidad

Si $\alpha = 1$. (de la fórmula general)

$$I_{CQ} = \frac{V_{BB} - V_{BE}}{R_E} + I_{CBO} \left(1 + \frac{R_B}{R_E} \right)$$

$$S_V = \frac{\partial I_{CQ}}{\partial V_{BE}} = -\frac{1}{R_E}$$

$$S_I = \frac{\partial I_{CQ}}{\partial I_{CBO}} = 1 + \frac{R_B}{R_E}$$

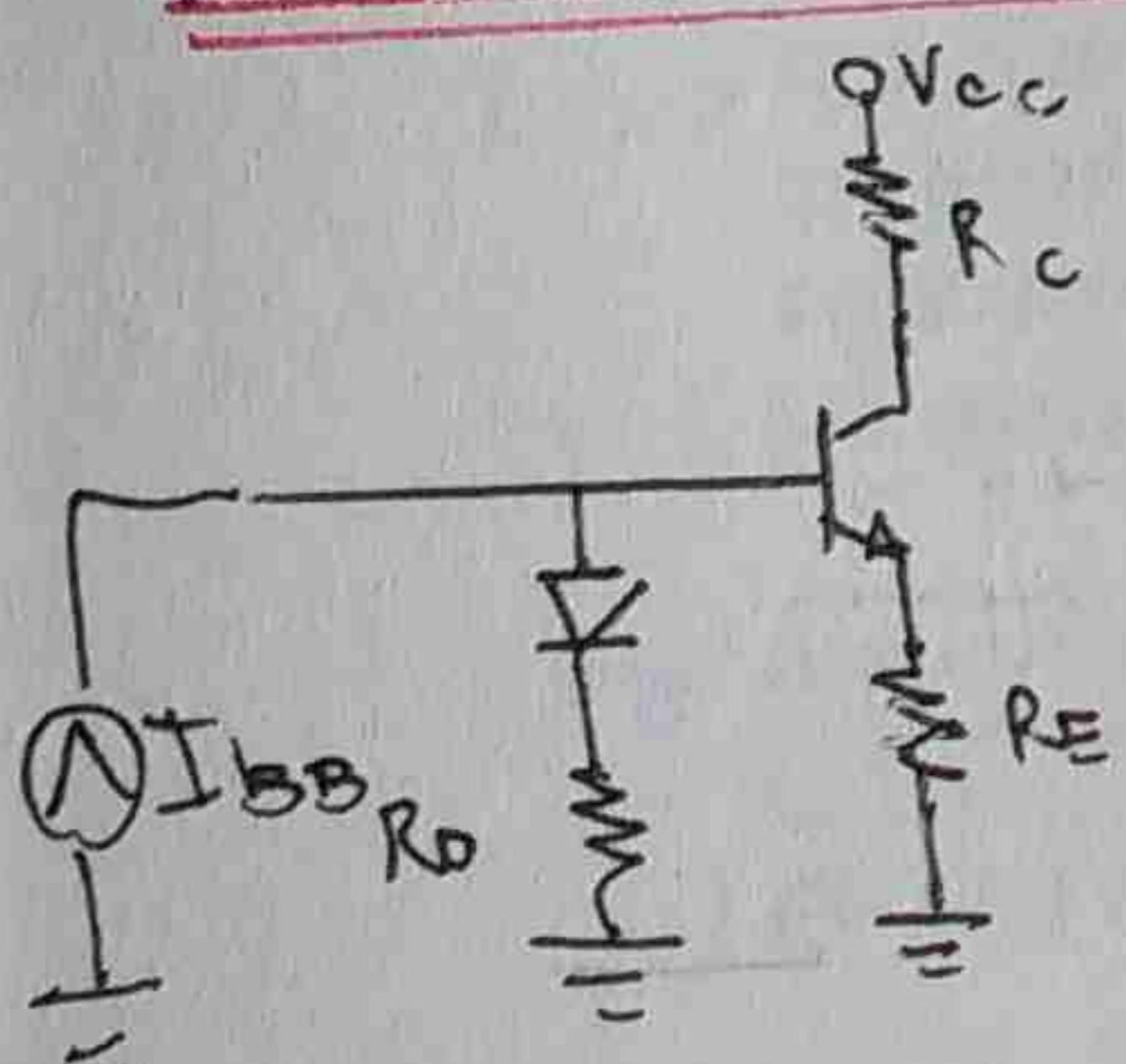
$$S_\beta = \frac{\Delta I_{CQ}}{\beta_1} \frac{R_B + R_E}{R_B + (\beta_2 + 1) R_E}$$

Si $R_E \rightarrow 0$ $I_{CQ} \rightarrow \infty$

$R_E \rightarrow \infty$ (m.e) $I_{CQ} \rightarrow 0$ Poca ganancia

Para solucionar esto se recurre a la polarización por diodo.

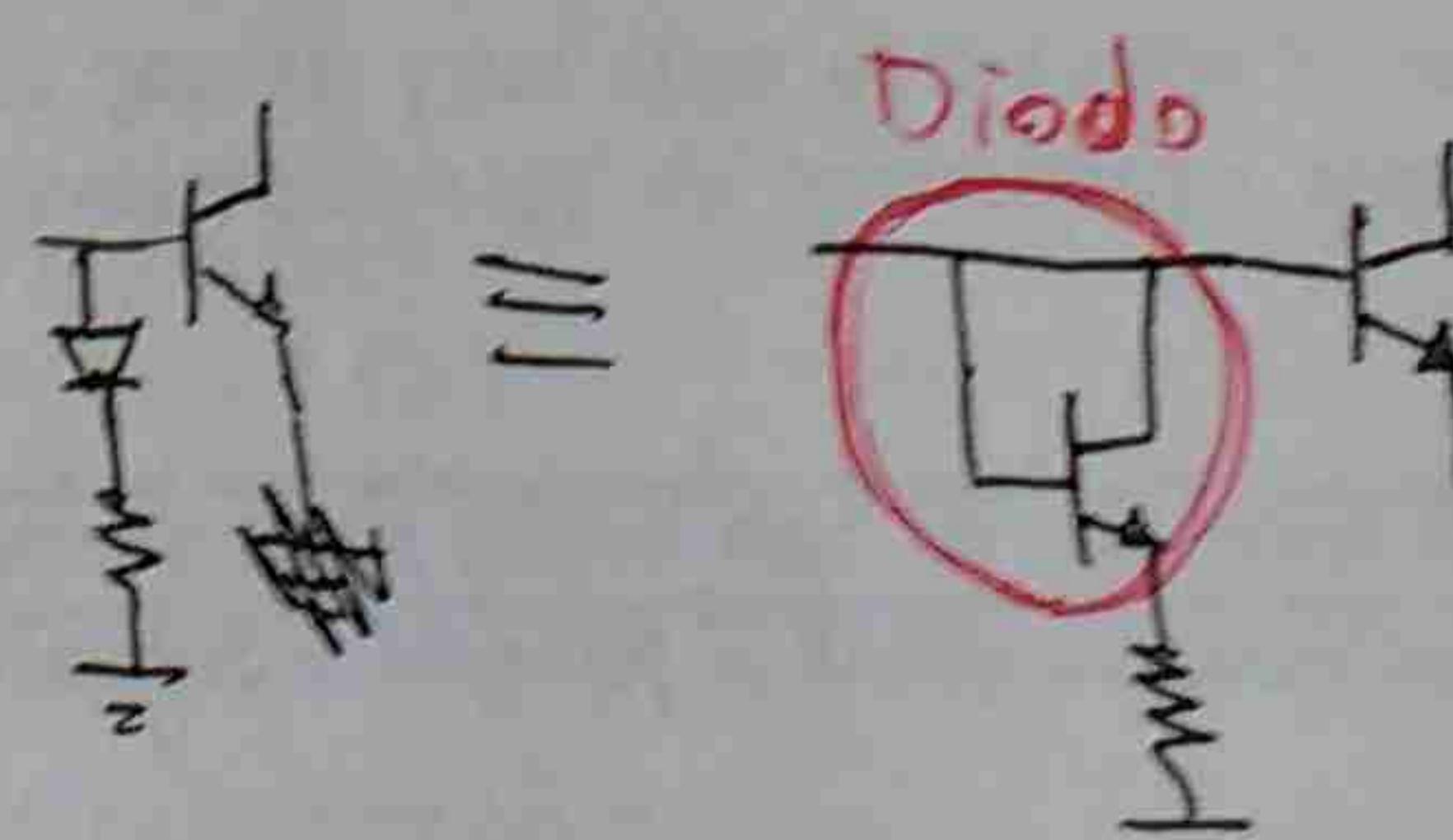
Polarización por diodo



c/ S_V (factor estabilidad)

$$\frac{\Delta V_D}{\Delta T} = \frac{\Delta V_{BE}}{\Delta T}$$

siempre que el diodo y el trans. sean del mismo material



c/diodo (ideal)

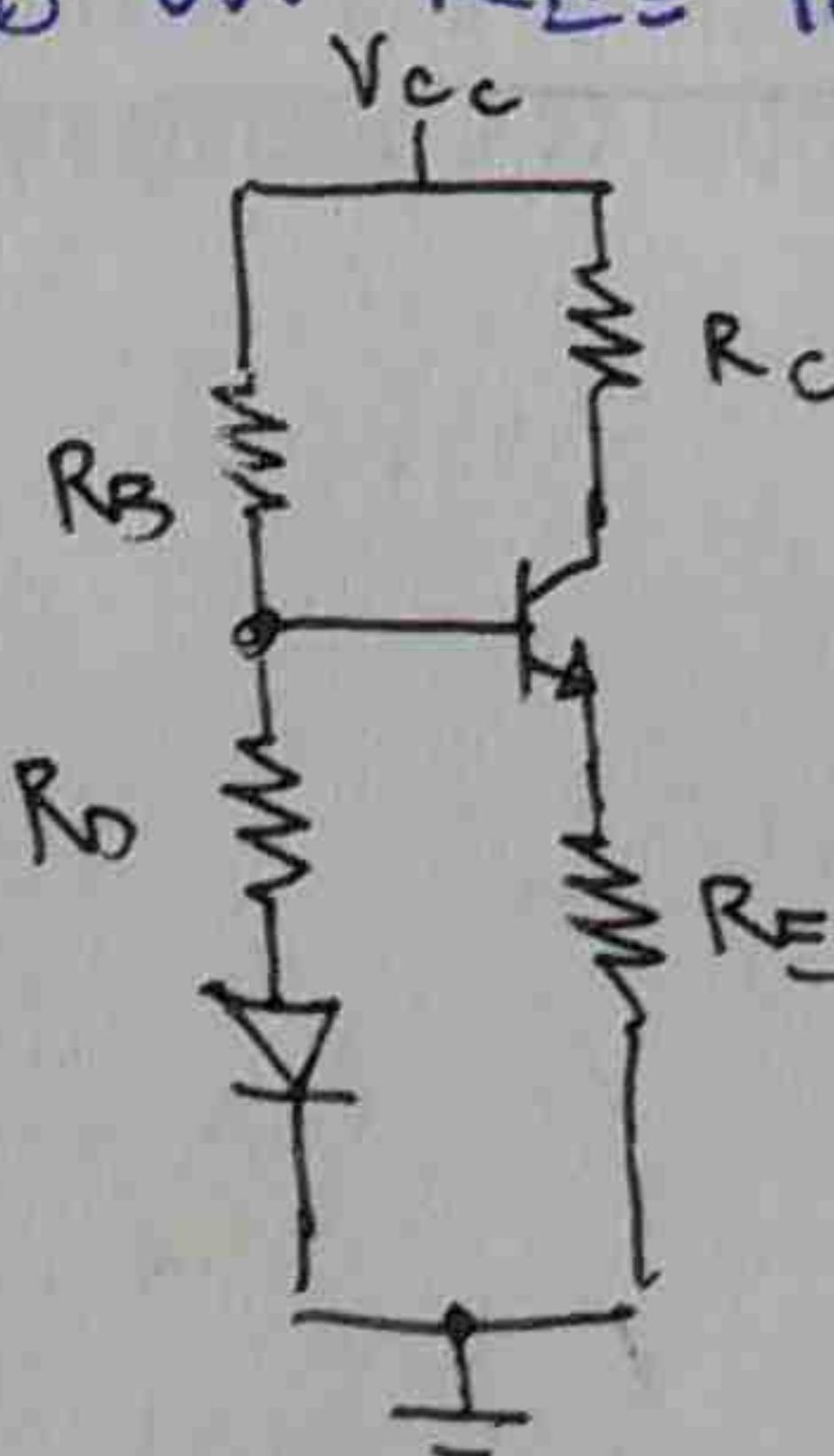
c/diodo Real

$$\frac{\Delta I_{CQ}}{\Delta T} = \frac{k}{R_E}$$

$$\frac{\Delta I_{CQ}}{\Delta T} = 0$$

$$\frac{\Delta I_{CQ}}{\Delta T} = \frac{k}{R_E} + \frac{1}{1 + \frac{R_B}{R_D}}$$

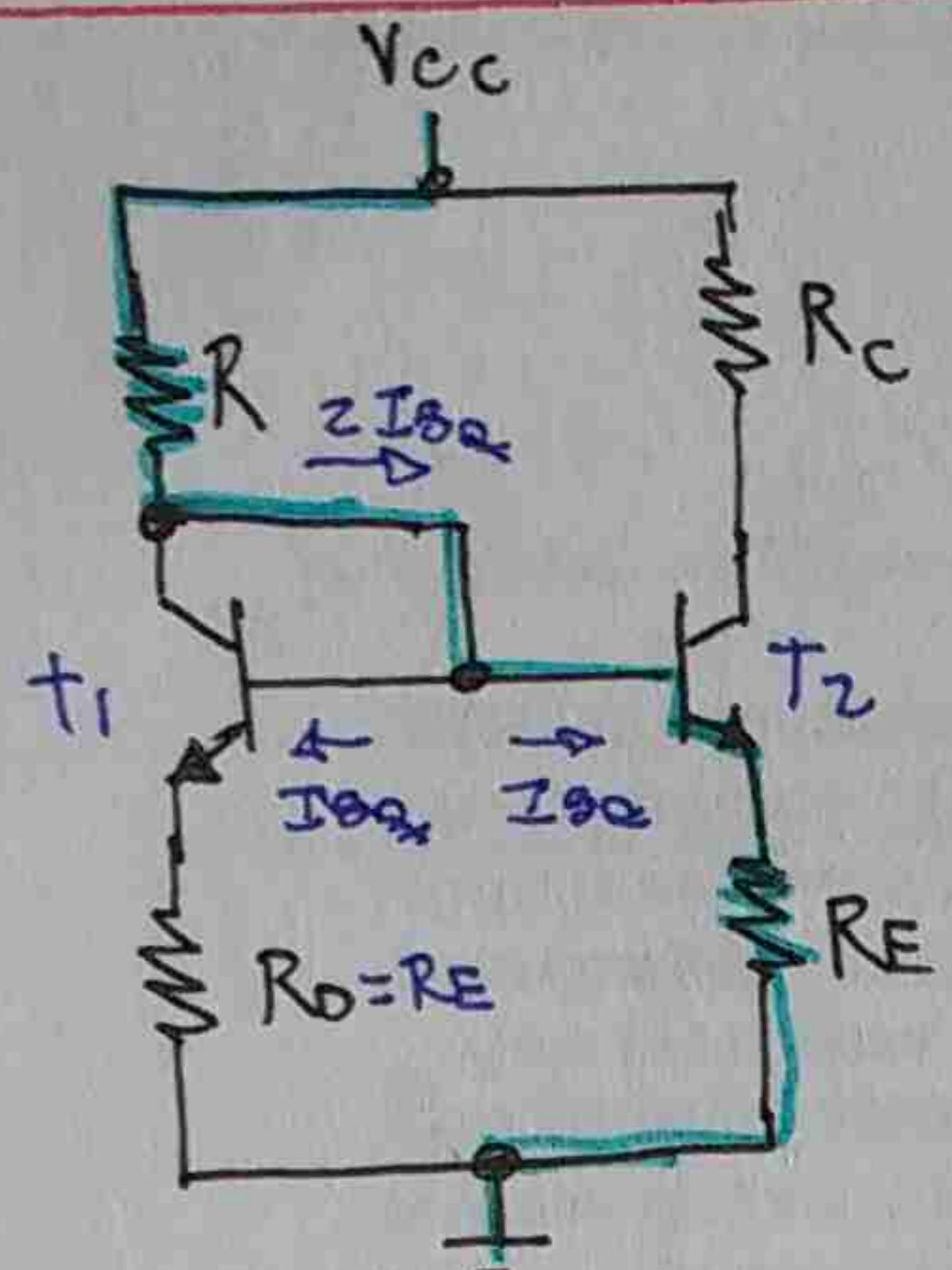
Si necesito un $R_E = 10k$, lo logro con R_B y R_D (sinó I_{CQ} disminuye)



$$I_{CQ} = \frac{(V_{CC} - V_{BE}) R_D}{R_E (R_B + R_D)}$$

Polarización Bajo cedado (Espejo de corriente)

(6)



LKT

$$V_{CC} = I_{CQ} + \frac{2I_{CQ}}{\beta} R + V_{BE} + I_{CQ} R_E = I_{CQ} \left(1 + \frac{2}{\beta} R + V_{BE} + I_{CQ} R_E \right)$$

$$V_{CC} = I_{CQ} \left[\left(\frac{\beta+2}{\beta} R + R_E \right) + V_{BE} \right]$$

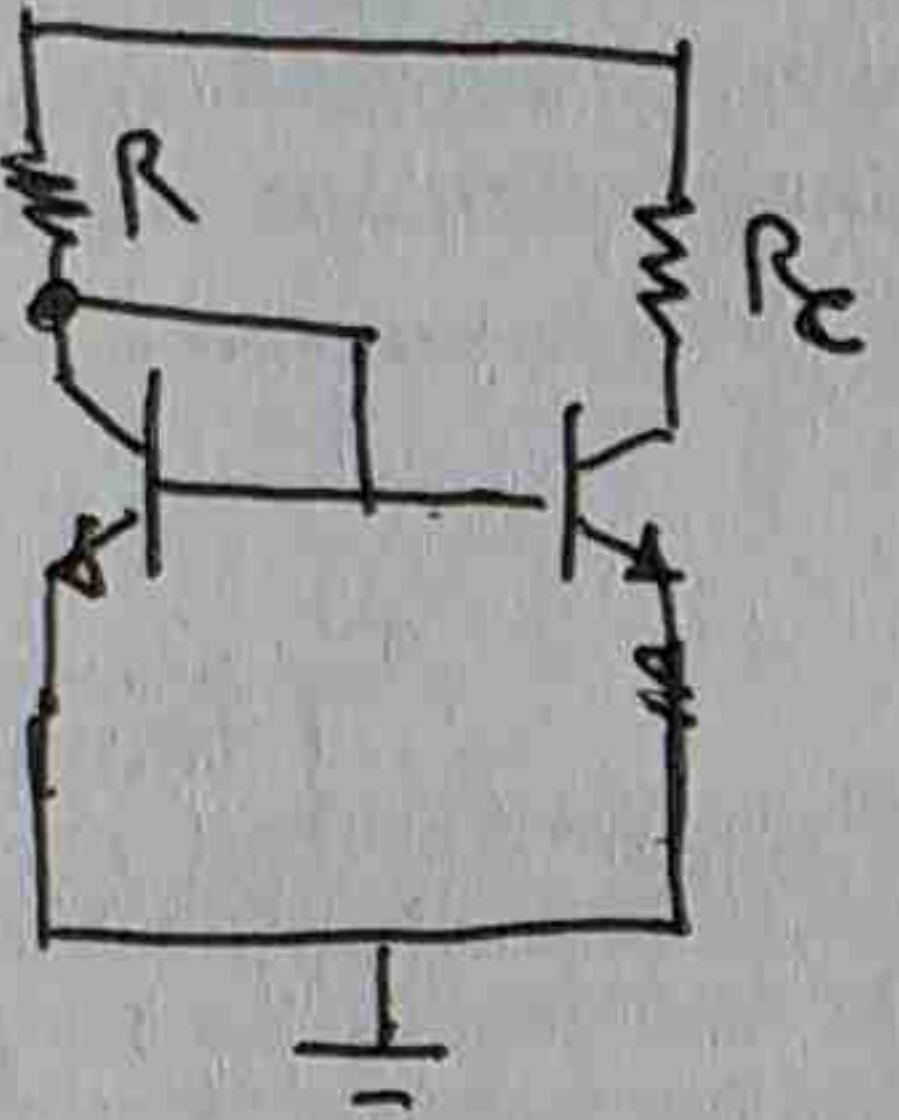
Si $\beta \gg 2$

$$I_{CQ} = \frac{V_{CC} - V_{BE}}{R + R_E}$$

Se llama espejo de corriente porque V_B es el mismo y I_{B1} e I_{B2} son iguales

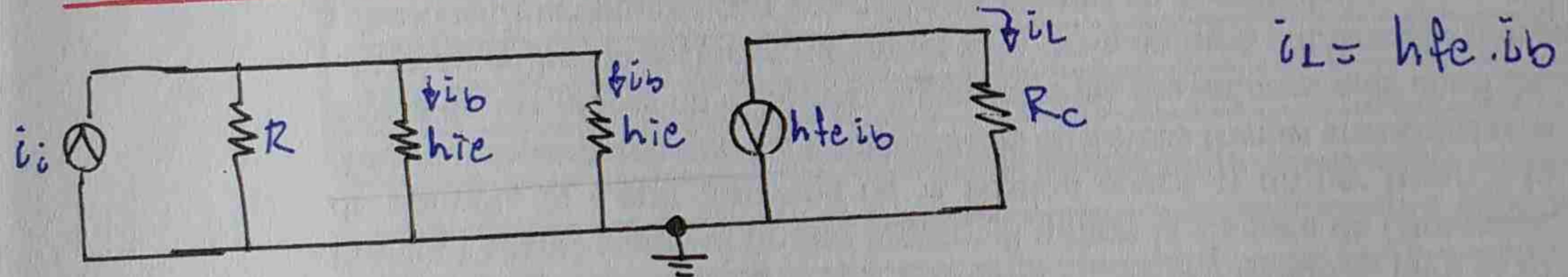
Para circuitos integrados

$$R_d = R_E = 0$$



$$I_{CQ} = \frac{V_{CC} - V_{BE}}{R}$$

Circuito equivalente de CA



$$i_L = h_{FE} i_b$$

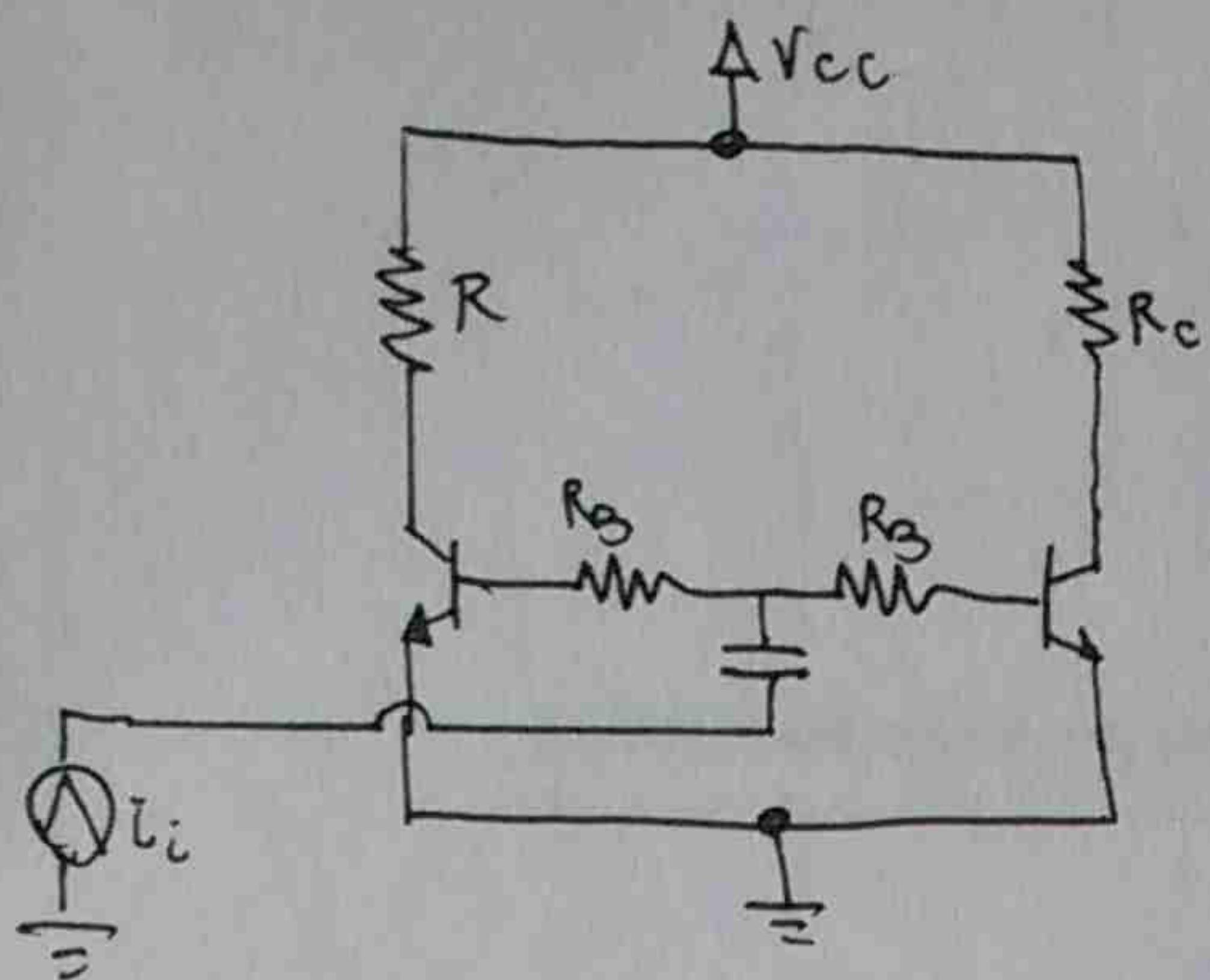
Si $R > h_{ie}$

$$i_o = 2i_b$$

$$i_b = \frac{i_o}{2}$$

$$\Delta i_o = \frac{i_o}{i_i} = \frac{i_L}{i_b} \quad \frac{i_b}{i_i} = h_{FE} \cdot \frac{1}{2} = \frac{h_{FE}}{2}$$

7



$$V_{CC} = \left(I_{CQ} + \frac{2I_{CQ}}{\beta} \right) R + \frac{I_{CQ}}{\beta} R_B + V_{BE}$$

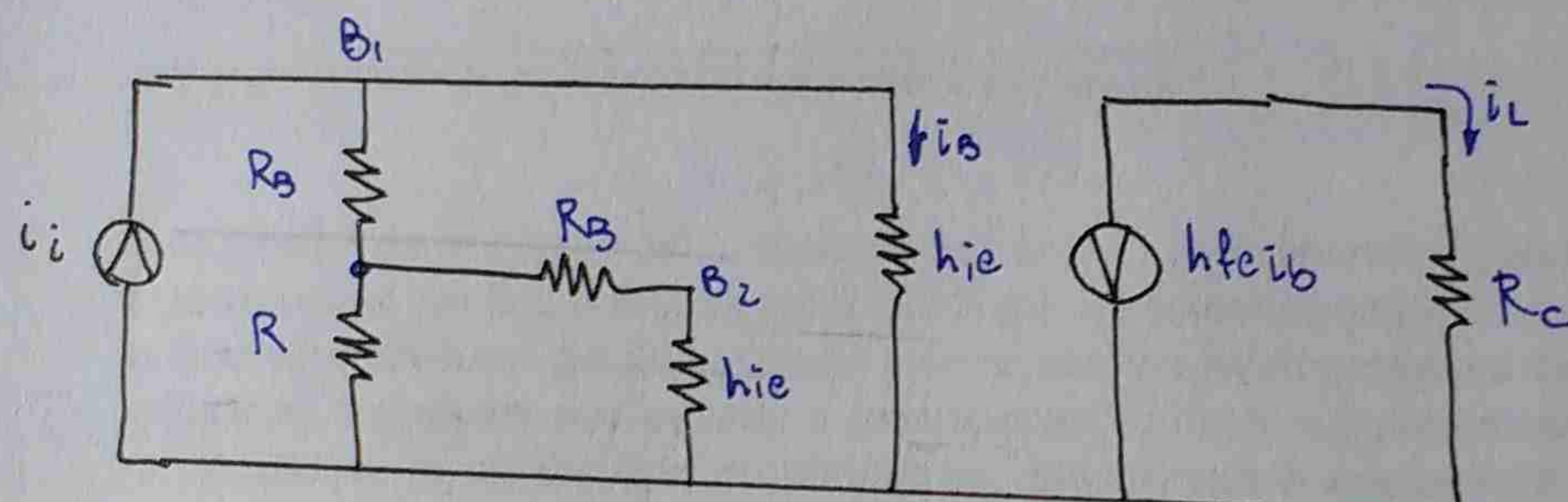
$$V_{CC} = V_{BE} = I_{CQ} \left[\left(1 + \frac{2}{\beta} \right) R + \frac{R_B}{\beta} \right]$$

$$I_{CQ} = \frac{V_{CC} - V_{BE}}{\frac{\beta+2}{\beta} R + \frac{R_B}{\beta}}$$

$$\text{Si: } \frac{R_B}{\beta} \ll R$$

$$I_{CQ} = \frac{V_{CC} - V_{BE}}{R}$$

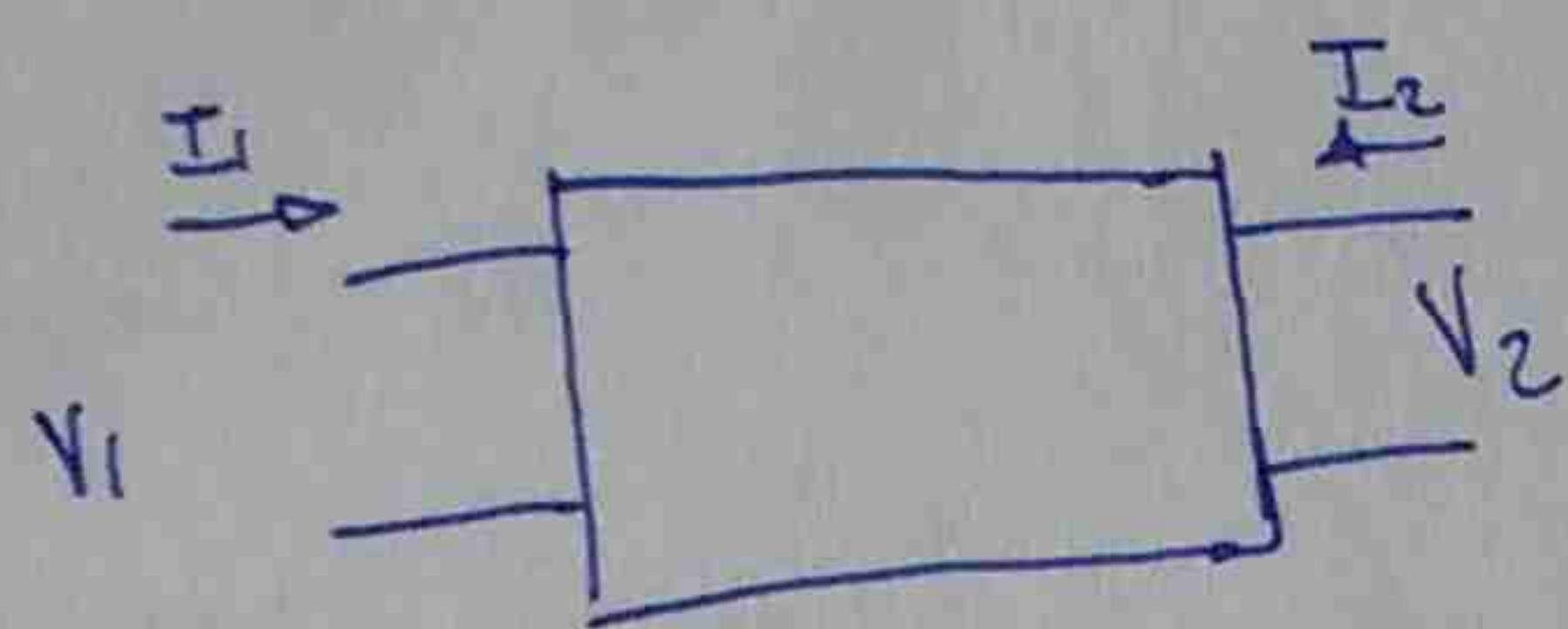
La ganancia es el doble del anterior



$$\text{Si: } R_B \gg h_{ie}$$

$$A_i = \frac{i_L}{i_i} = \frac{i_L}{i_b} \cdot \frac{i_b}{i_i} = h_{fe} \approx 100$$

Parámetros Híbridos



$$V_1 = h_{11} i_1 + h_{12} V_2$$

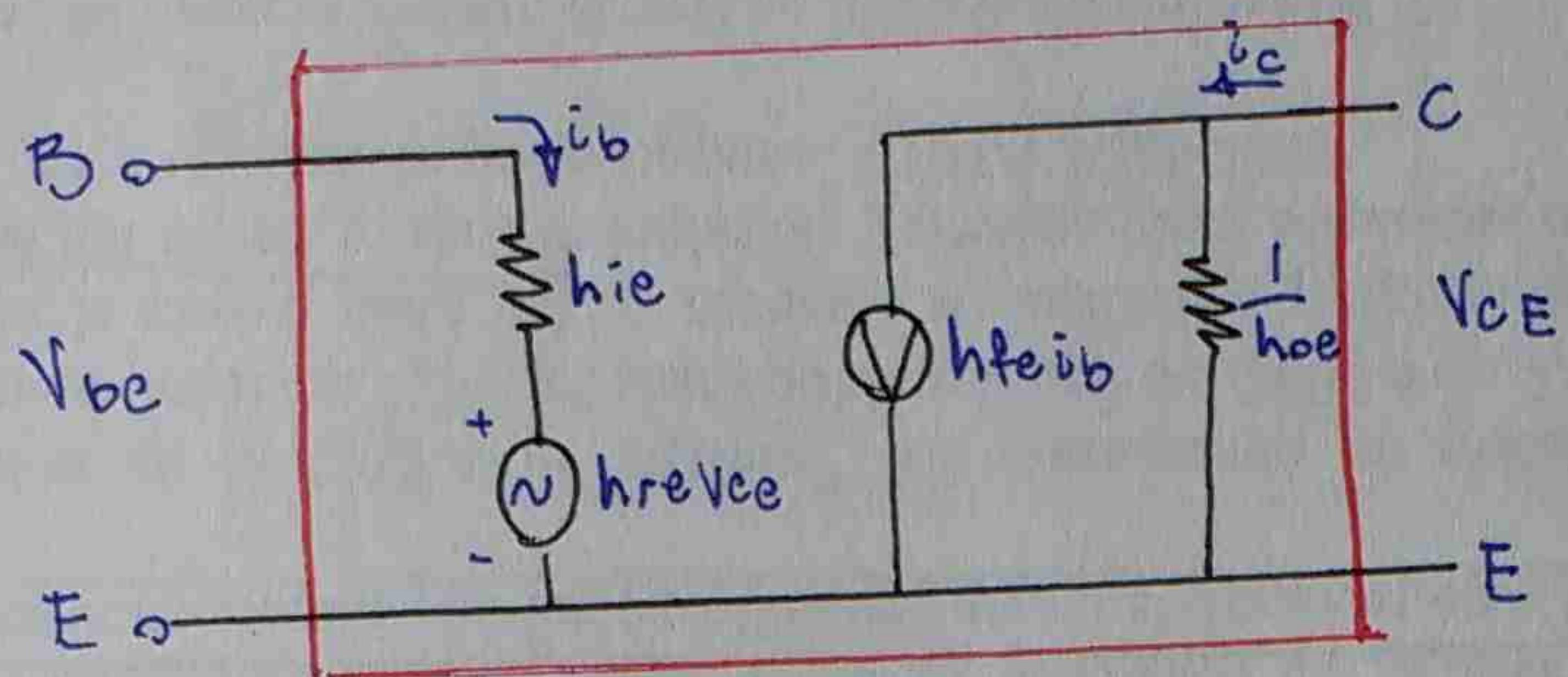
$$i_2 = h_{21} i_1 + h_{22} V_2$$

(8)

$$V_1 = h_{11} i_1 + h_{12} V_2$$

$$i_2 = h_{21} i_1 + h_{22} V_2$$

$$\begin{bmatrix} h_{11} & h_{12} \\ h_{21} & h_{22} \end{bmatrix} \begin{bmatrix} I_1 \\ V_2 \end{bmatrix} = \begin{bmatrix} V_1 \\ I_2 \end{bmatrix}$$



Fórmula no convencional de calcular I_{CQ}

$$h_{ie} = \frac{25mV \cdot h_{fe}}{I_{CQ}}$$

$$h_{ie} \ll R_b \ll \beta R_E$$

Estabilidad
Garantía

En Base Común

$$h_{ib} = \frac{h_{ie}}{h_{fe} + 1}$$

$$h_{rb} \rightarrow 0$$

$$h_{fb} = \frac{h_{fe}}{h_{fe} + 1} \approx 1$$

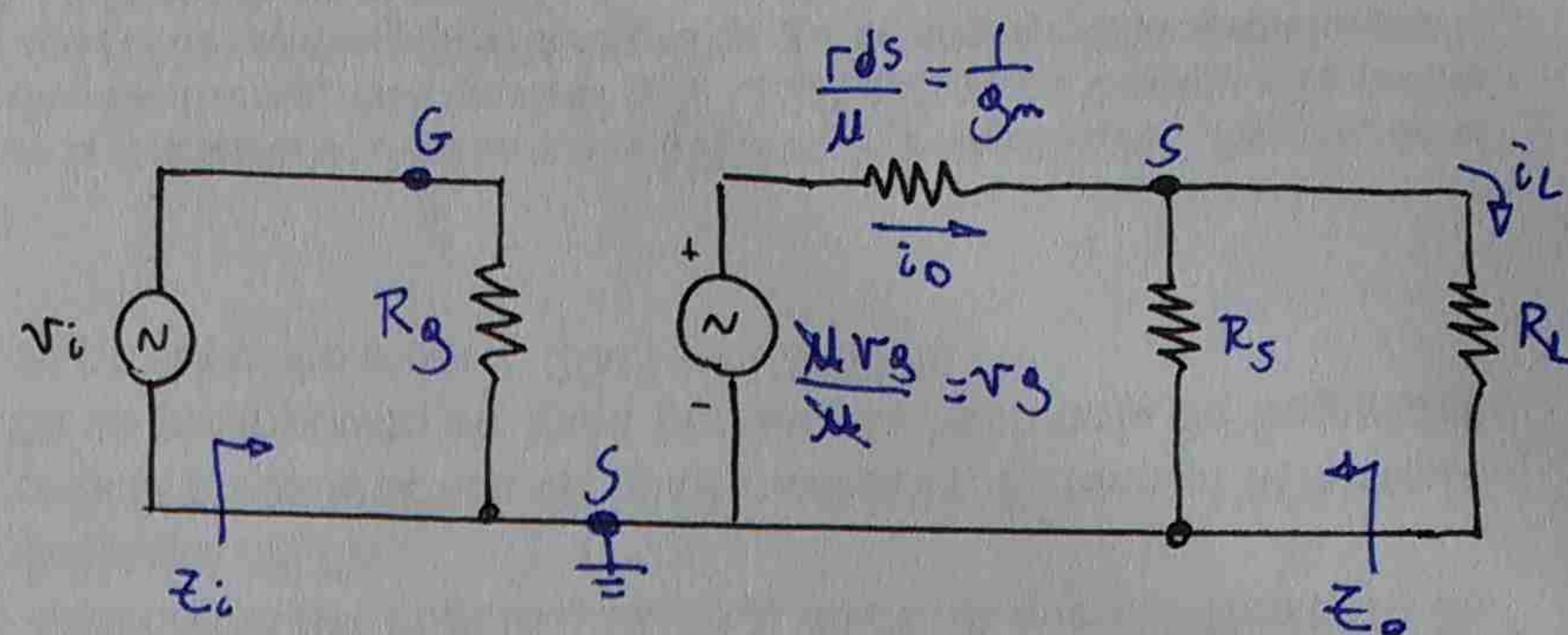
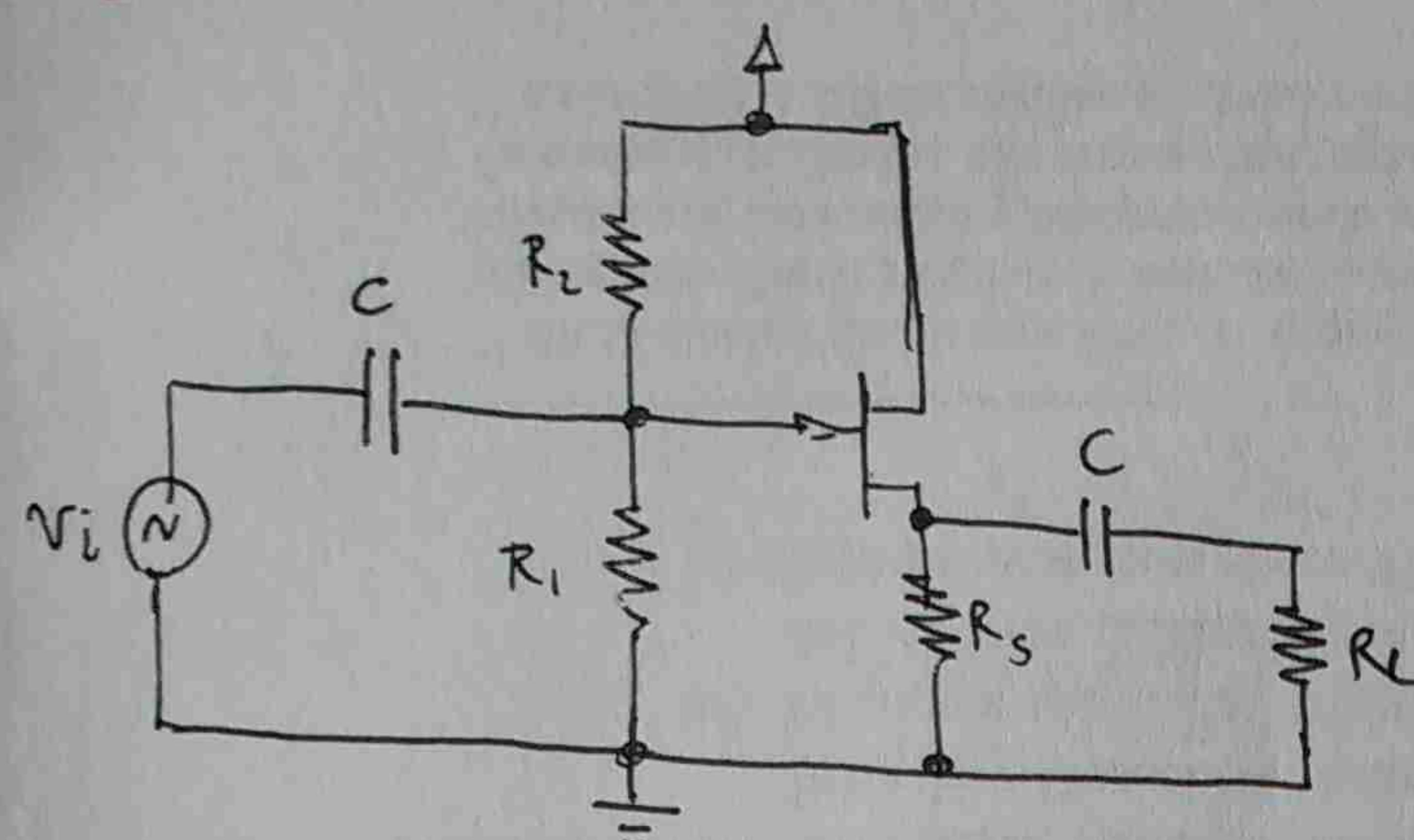
$$h_{ob} = \frac{h_{oe}}{h_{fe} + 1}$$

Parámetros internos del FET

(9)

$$r_{ds} \approx g_m = \mu$$

Drenador Co-un



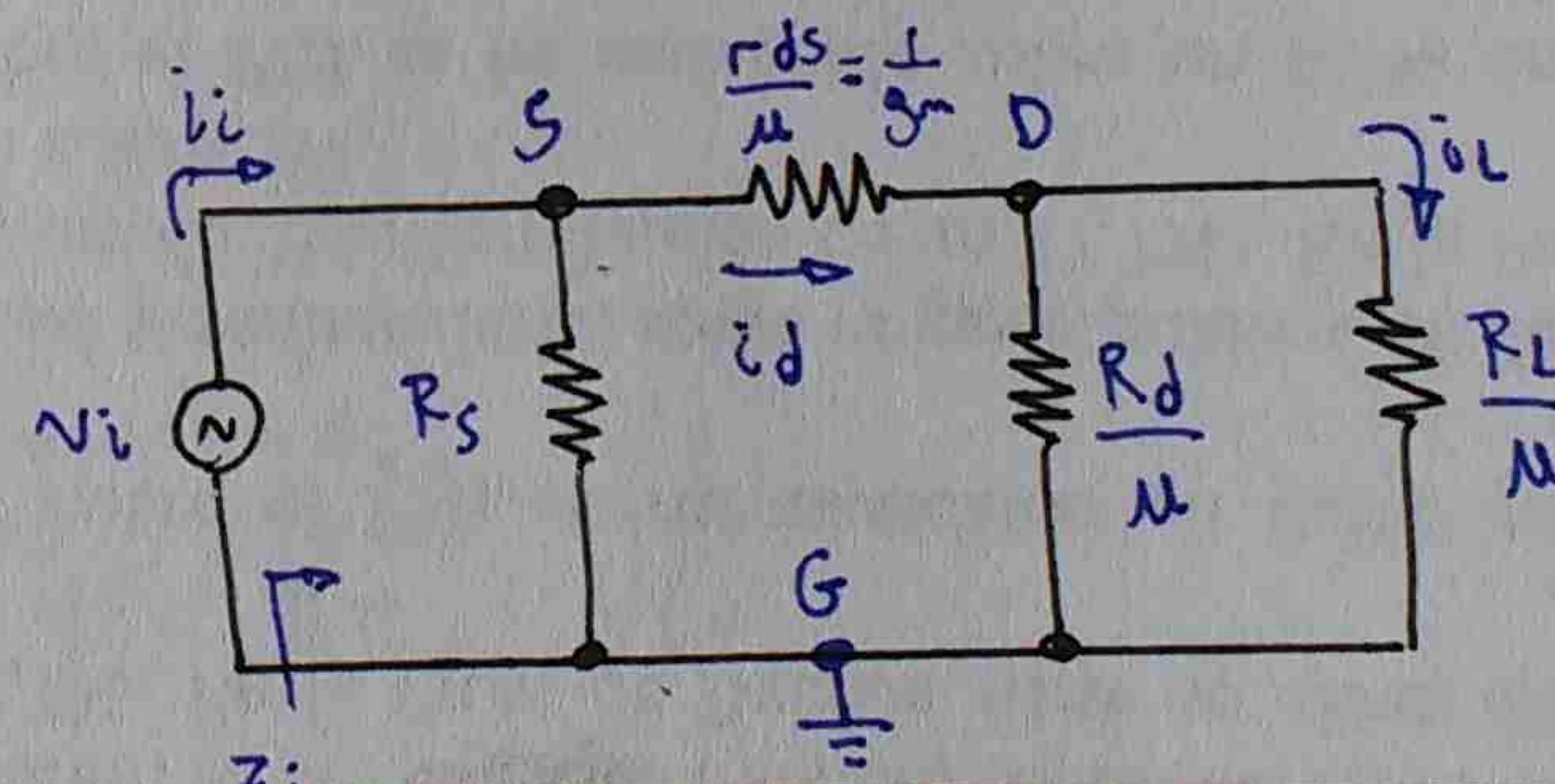
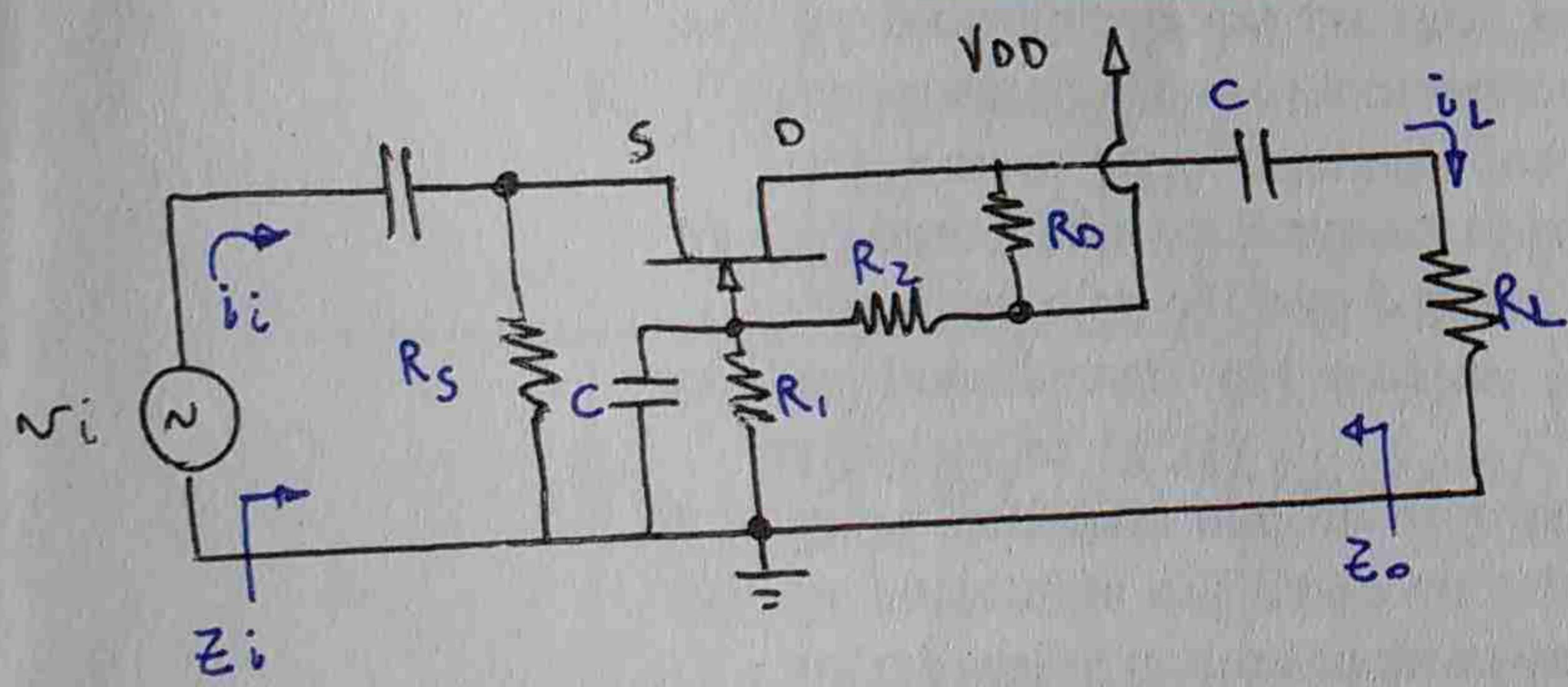
$$Z_i = R_g$$

$$Z_o = R_s \parallel \frac{1}{g_m}$$

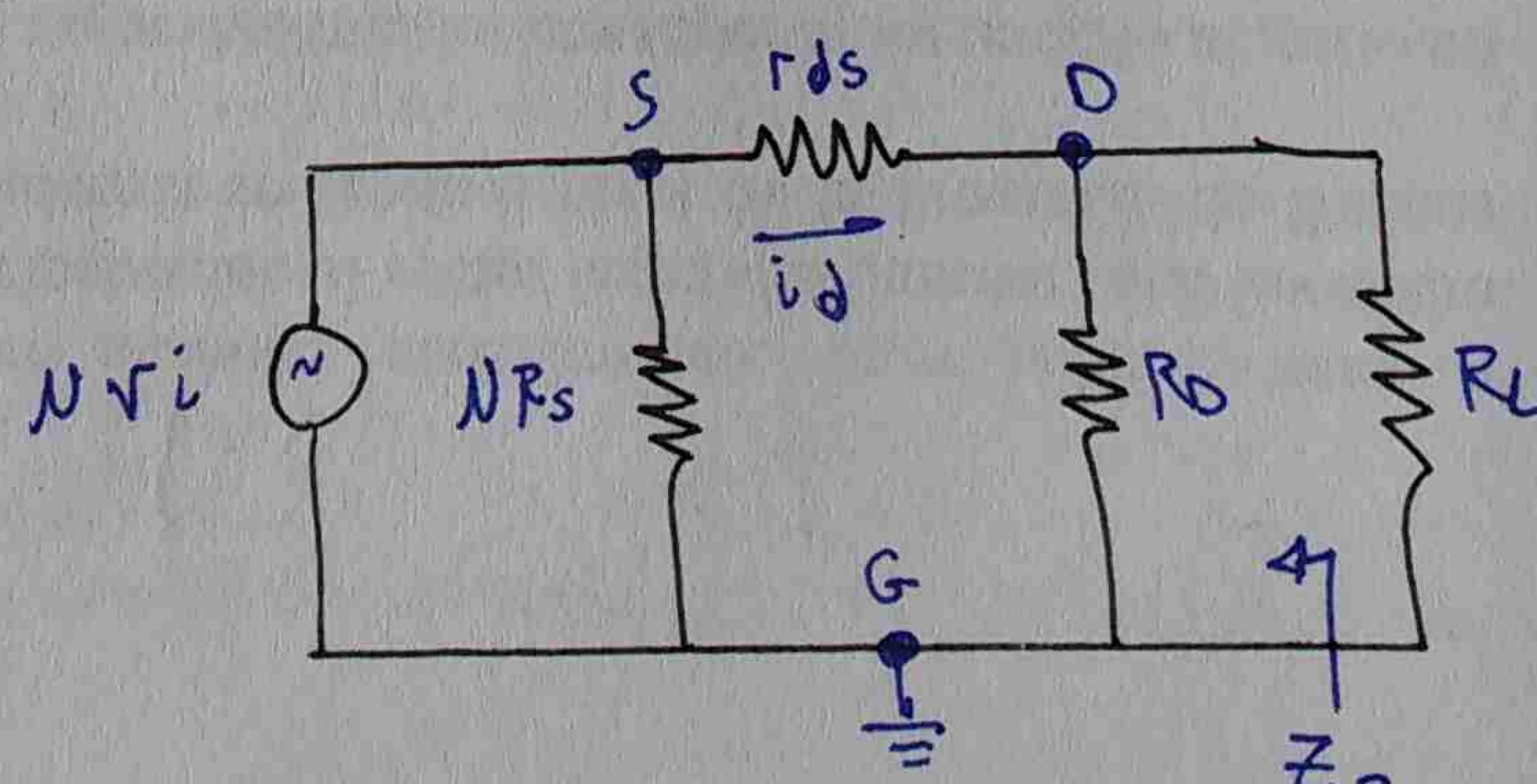
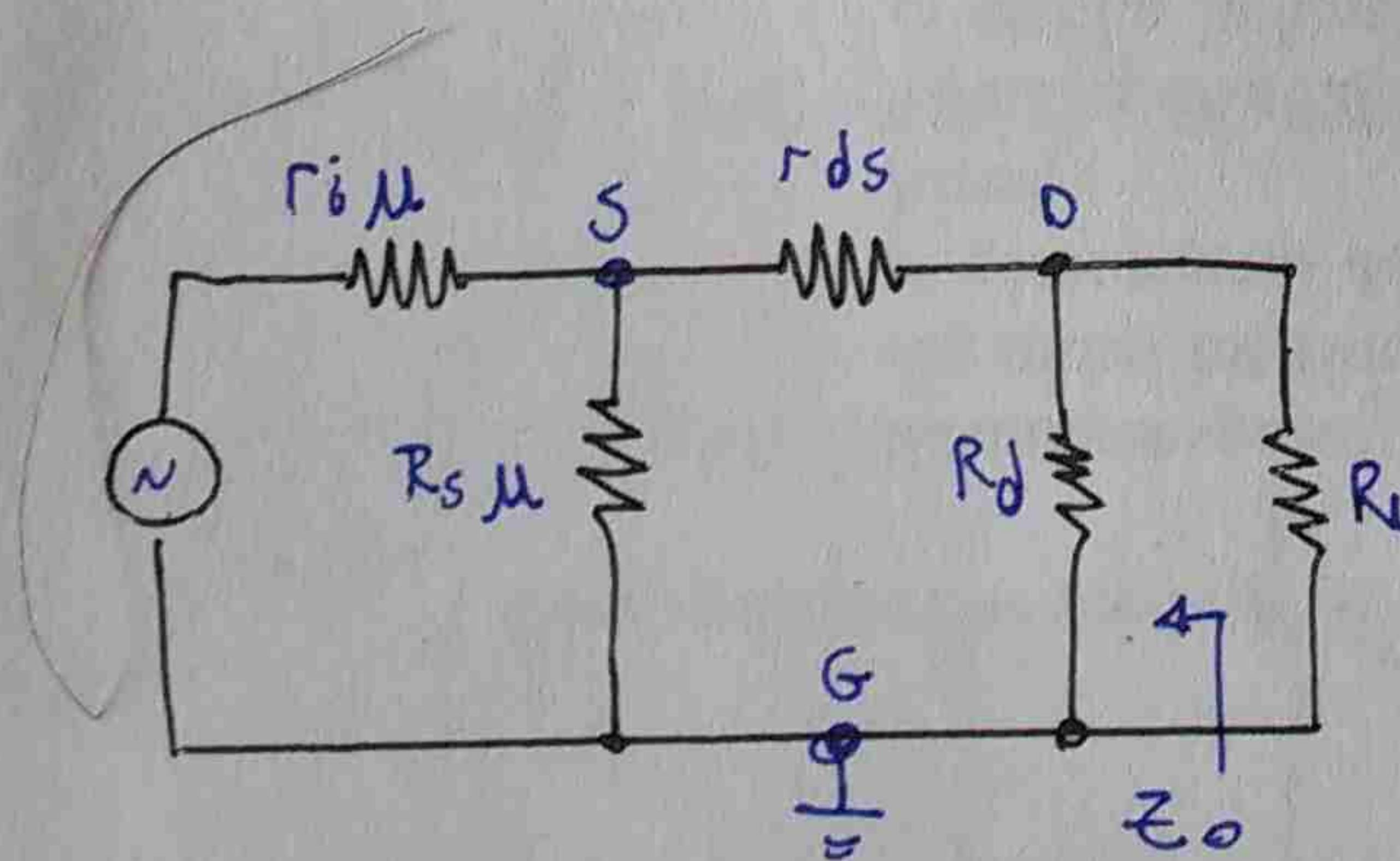
$$A_v = \frac{V_L}{V_i} = \frac{V_L}{I_D} \cdot \frac{I_D}{v_g} = \frac{r_s}{r_i} = R_s \parallel R_L \quad \frac{1}{\frac{r_{ds}}{\mu} + R_s/R_L}$$

$$A_{it} = A_v \frac{Z_i}{R_L} = \frac{R_s}{R_s + R_L} \frac{1}{\frac{1}{g_m} + R_s/R_L} R_g$$

Co-puerto Co-un



$$Z_i = R_s \parallel \left(\frac{r_{ds} + R_d \parallel R_L}{\mu} \right)$$



$$Z_o = R_d \parallel [r_{ds} + (r_i \parallel R_s) \mu]$$

CON R_i ≠ 0

$$Z_o = R_d \parallel r_{ds}$$

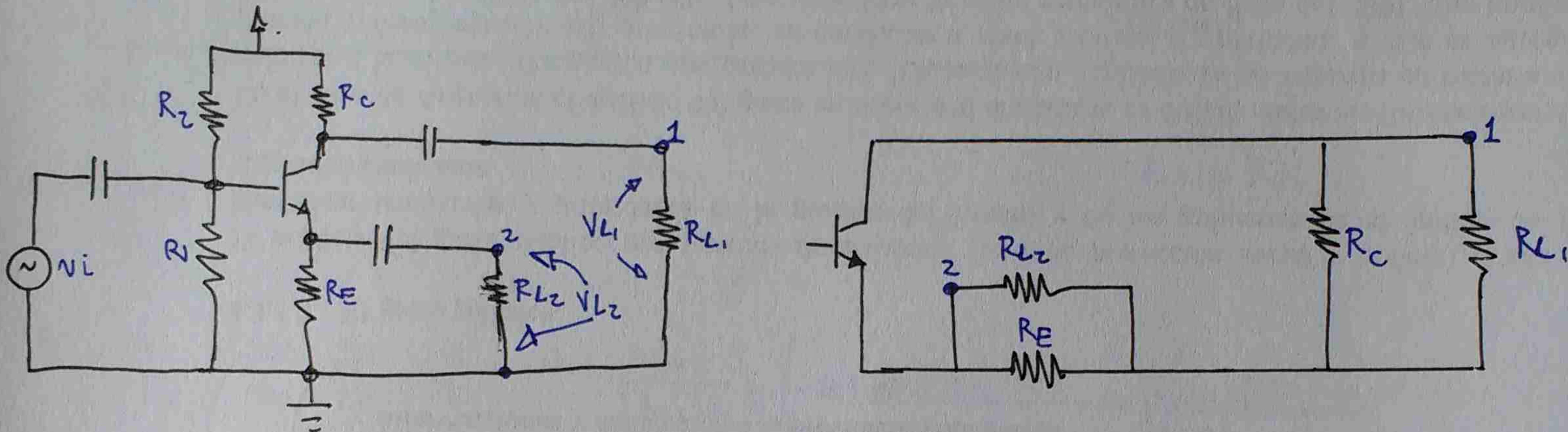
10

$$A_i = \frac{i_L}{i_O} = \frac{i_L}{i_D} \frac{i_D}{i_O} = \frac{R_d}{R_d + R_L} \frac{N R_s}{N R_s + r_{ds} + R_d // R_L}$$

$$A_v = A_i \frac{R_L}{Z_i} = (R_d // R_L) \frac{\frac{N R_s}{N R_s + r_{ds} + R_d // R_L}}{\frac{R_s // (r_{ds} + R_d // R_L)}{N R_s + r_{ds} + R_d // R_L}} \frac{1}{N}$$

$$A_v = \frac{N (R_d // R_L)}{r_{ds} + R_d // R_L}$$

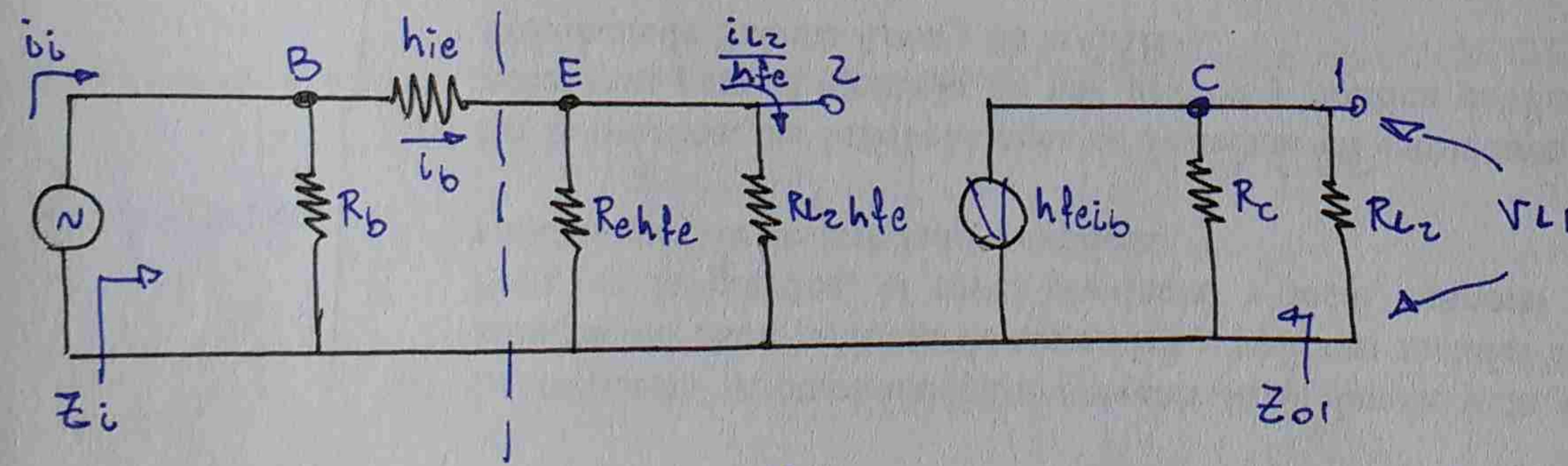
Inversor de fase con Transistor Bipolar



$$|V_{L1}| = |V_{L2}|$$

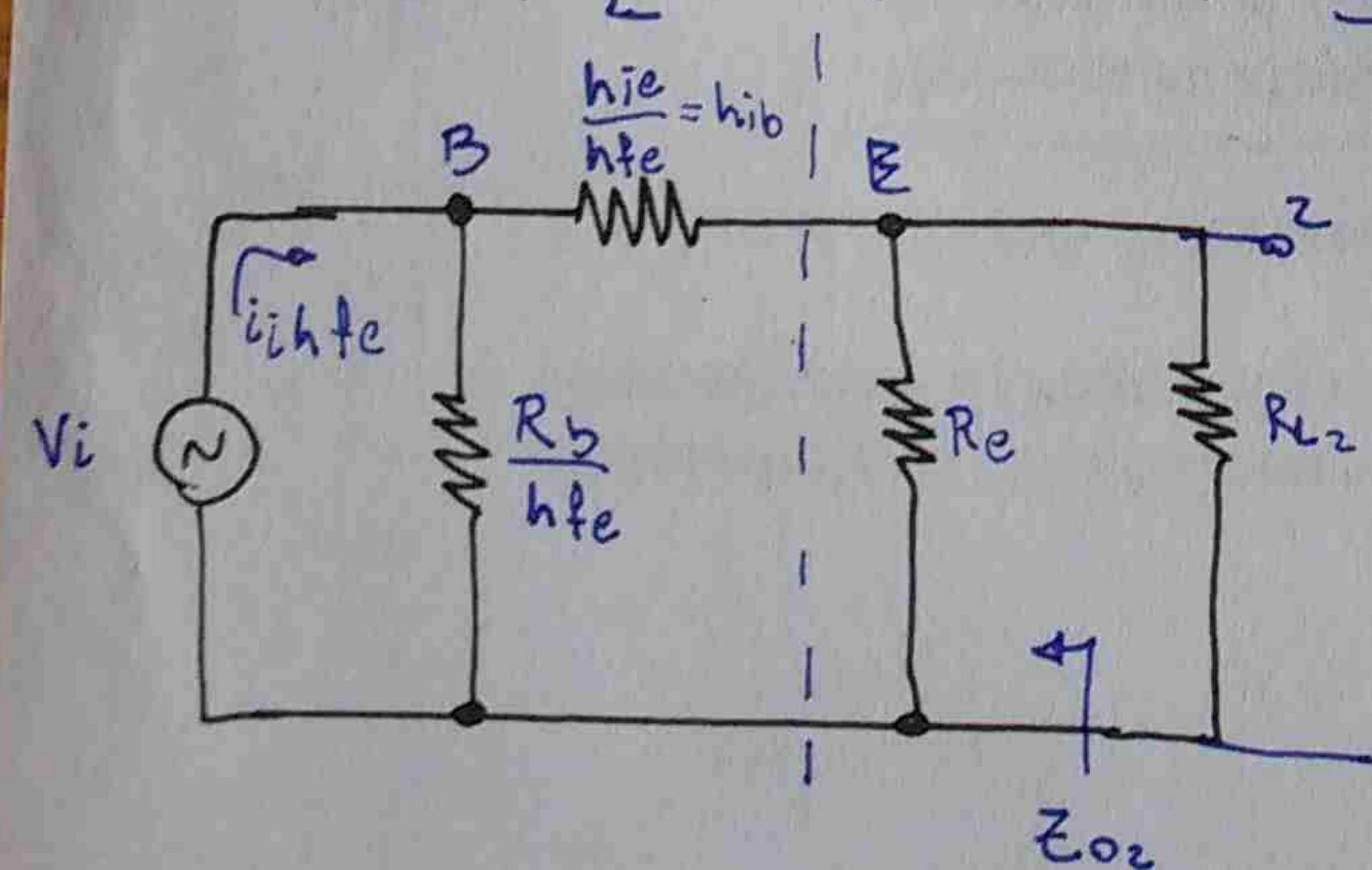
Condición de invertir de fase

$$R_C // R_{L1} = R_{L2} // R_E$$



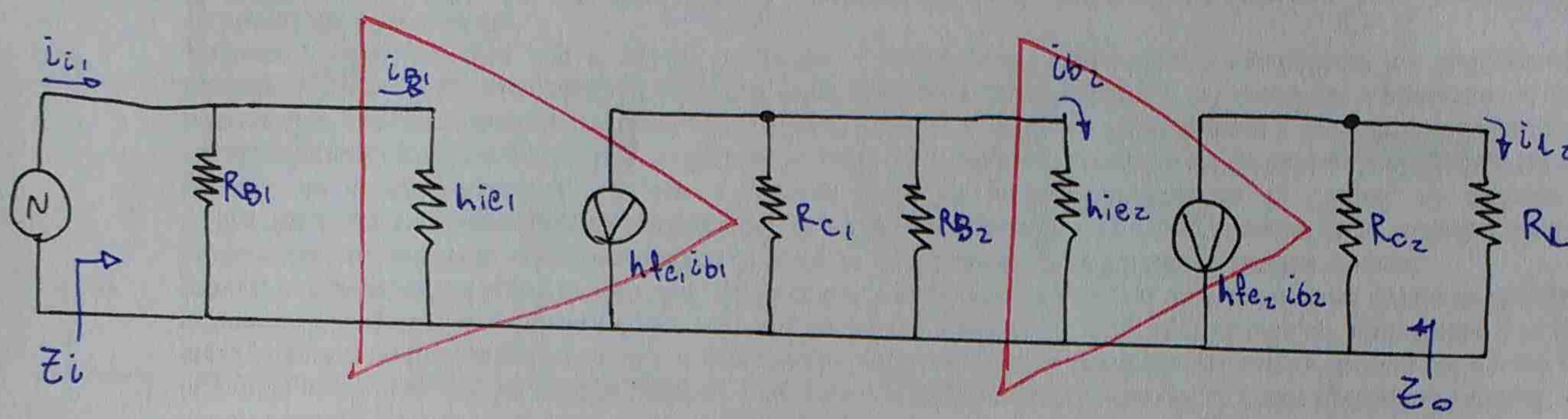
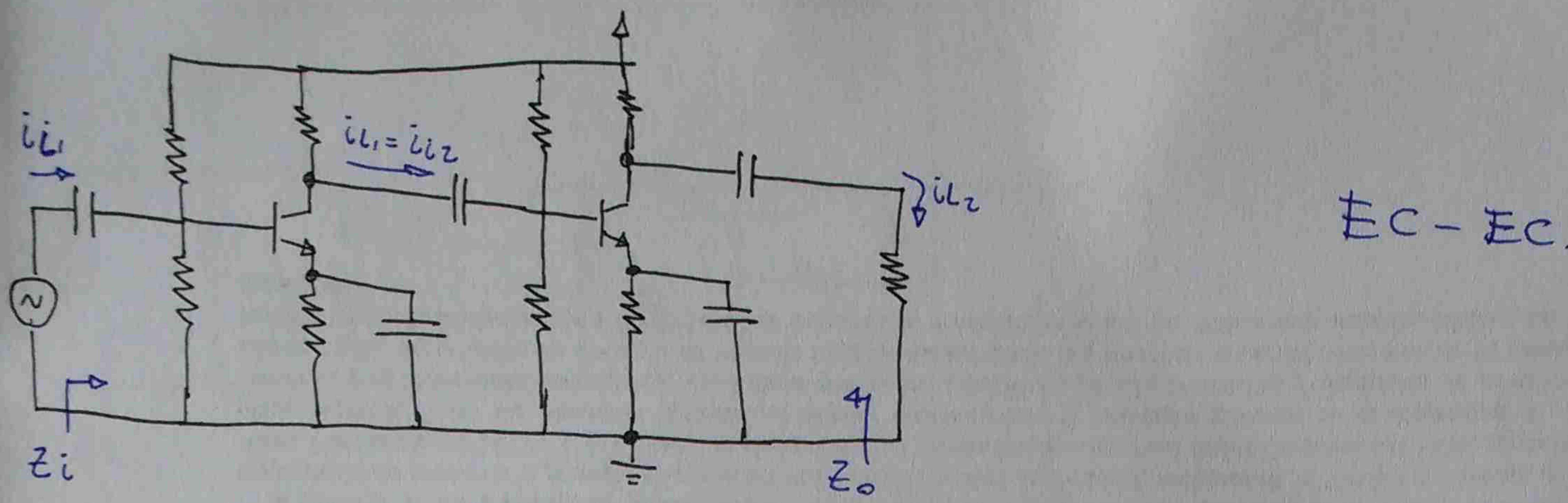
$$Z_i = R_b // [h_{ie} + (R_E // R_{L2}) h_{fe}]$$

$$Z_{O1} = R_C$$



Amplificadores Multietapa:

(11)

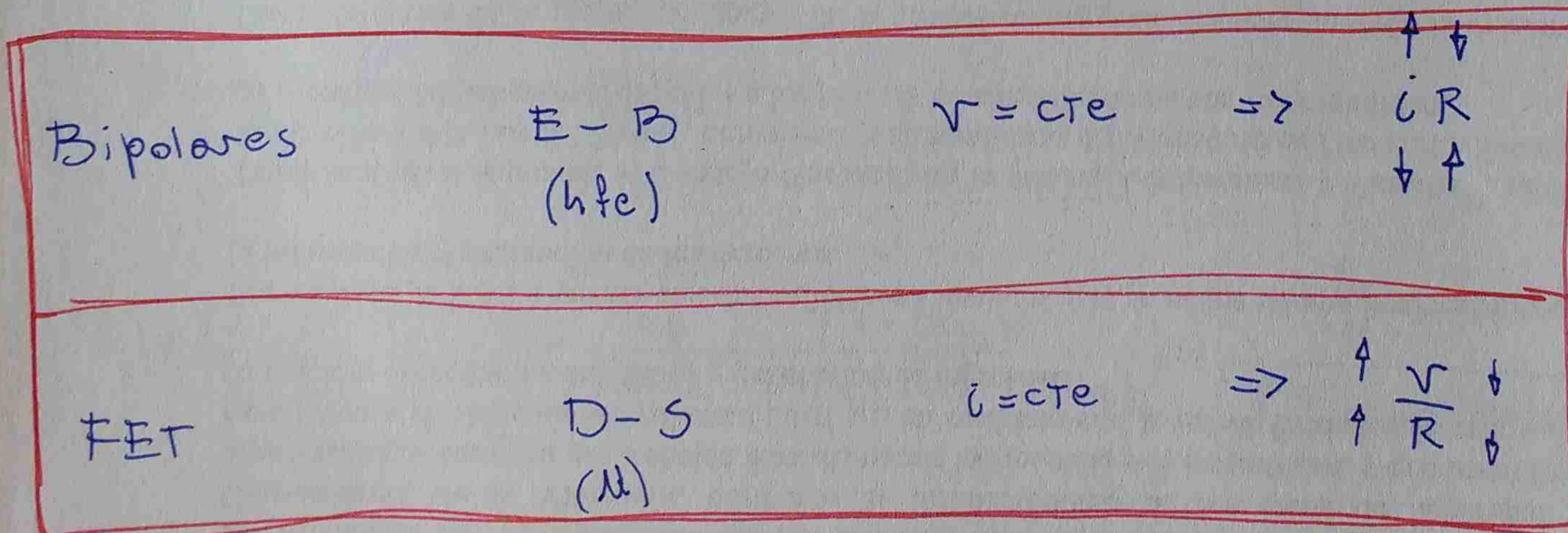


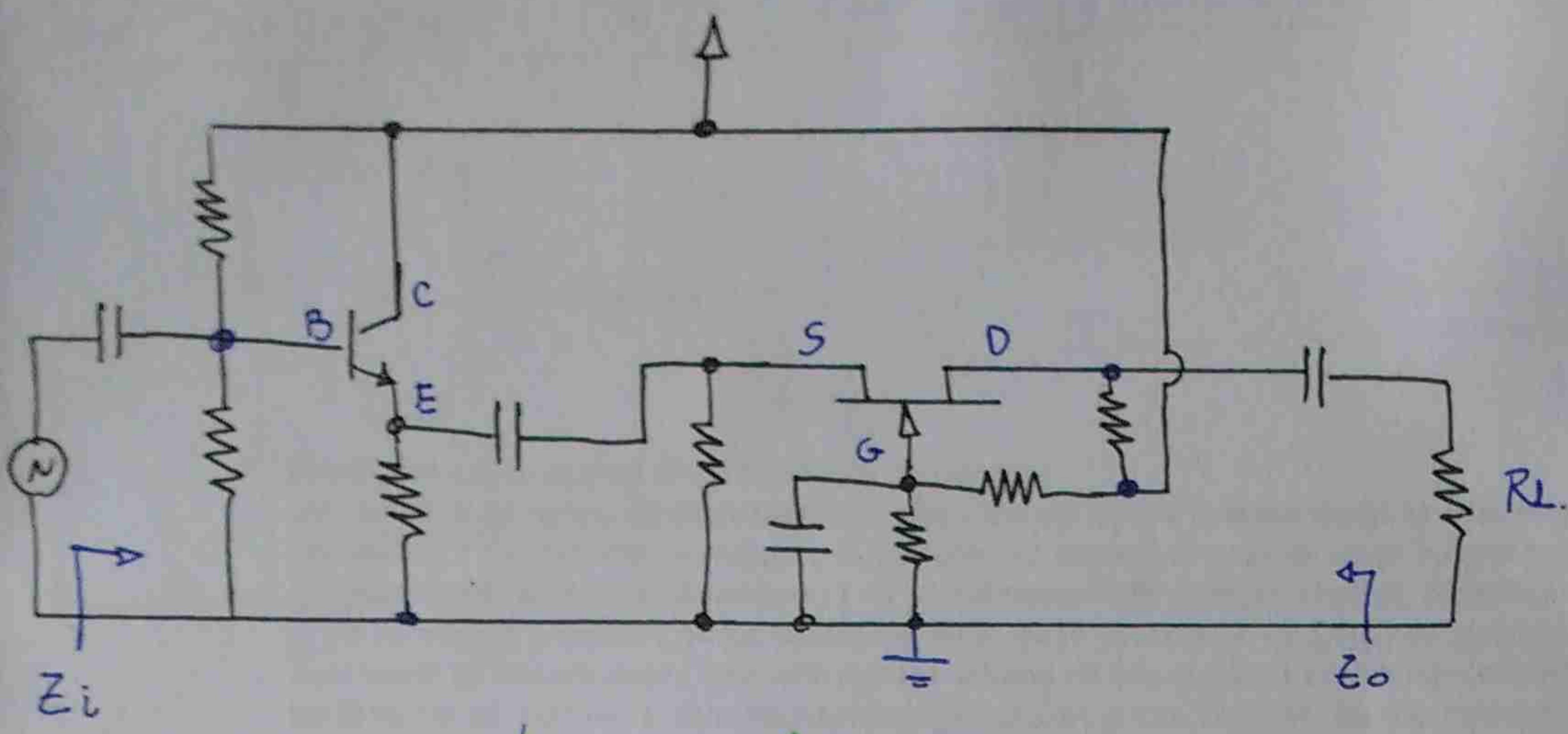
$$Z_i = R_{B1} // h_{ie1}$$

$$Z_o = R_{C2}$$

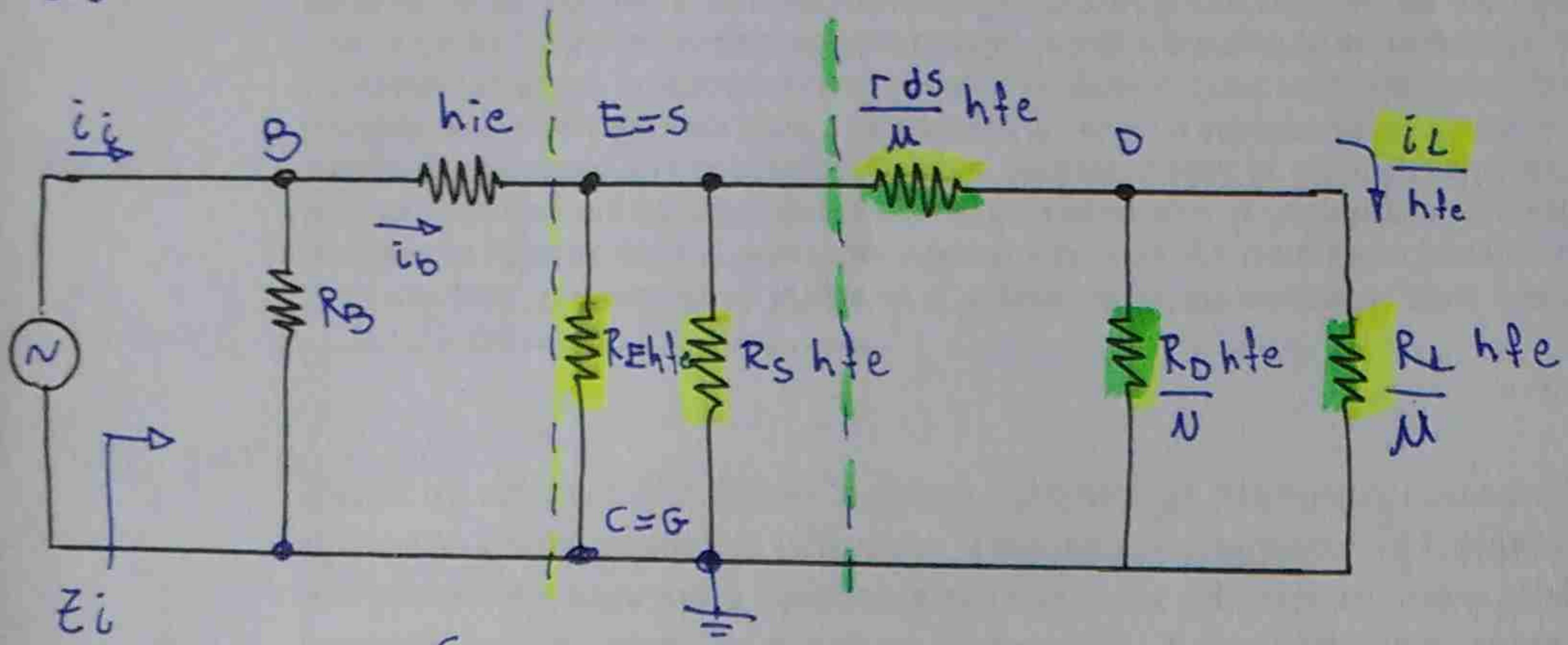
$$A_i = \frac{i_L}{i_i} = \frac{i_L}{i_{B2}} \cdot \frac{i_{B2}}{i_{B1}} \cdot \frac{i_{B1}}{i_i} = -h_{fe} \left(\frac{R_{C2}}{R_{C2} + R_L} \right) \left(-h_{fe} \frac{R_C // R_{B2}}{R_{C1} // R_{B2} + h_{ie2}} \right) \left(\frac{z_{B1}}{R_{B1} + h_{ie1}} \right)$$

$$A_v = A_i \frac{R_L}{Z_i}$$

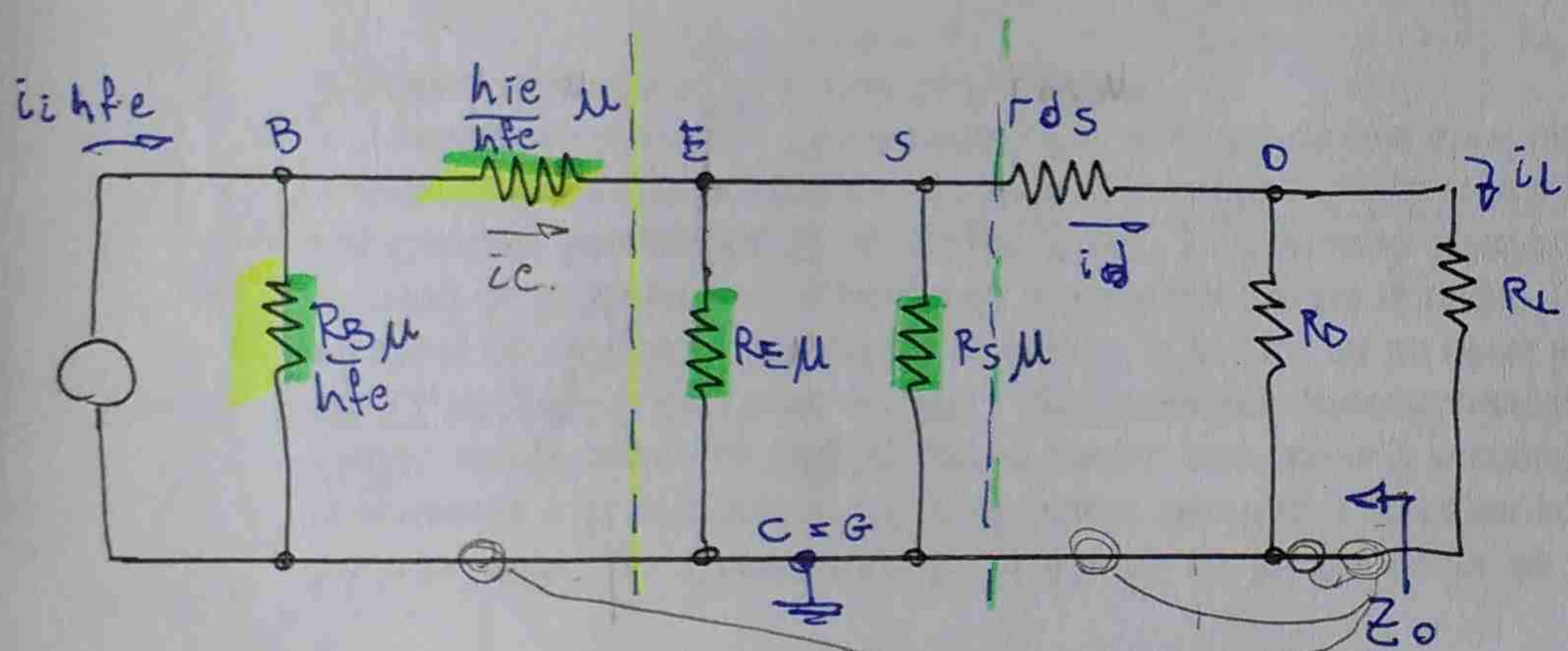




12

Bip. B-E $v = c \cdot R_E \cdot i_C$ FET S-D $i = c \cdot R_E \cdot \frac{v}{R}$

$$Z_i = R_B \left/ \left\{ h_{ie} + (R_E \parallel R_s) h_{fe} \left/ \left[\left(\frac{r_{ds}}{\mu} + R_D \parallel R_E \right) h_{fe} \right] \right. \right\}$$

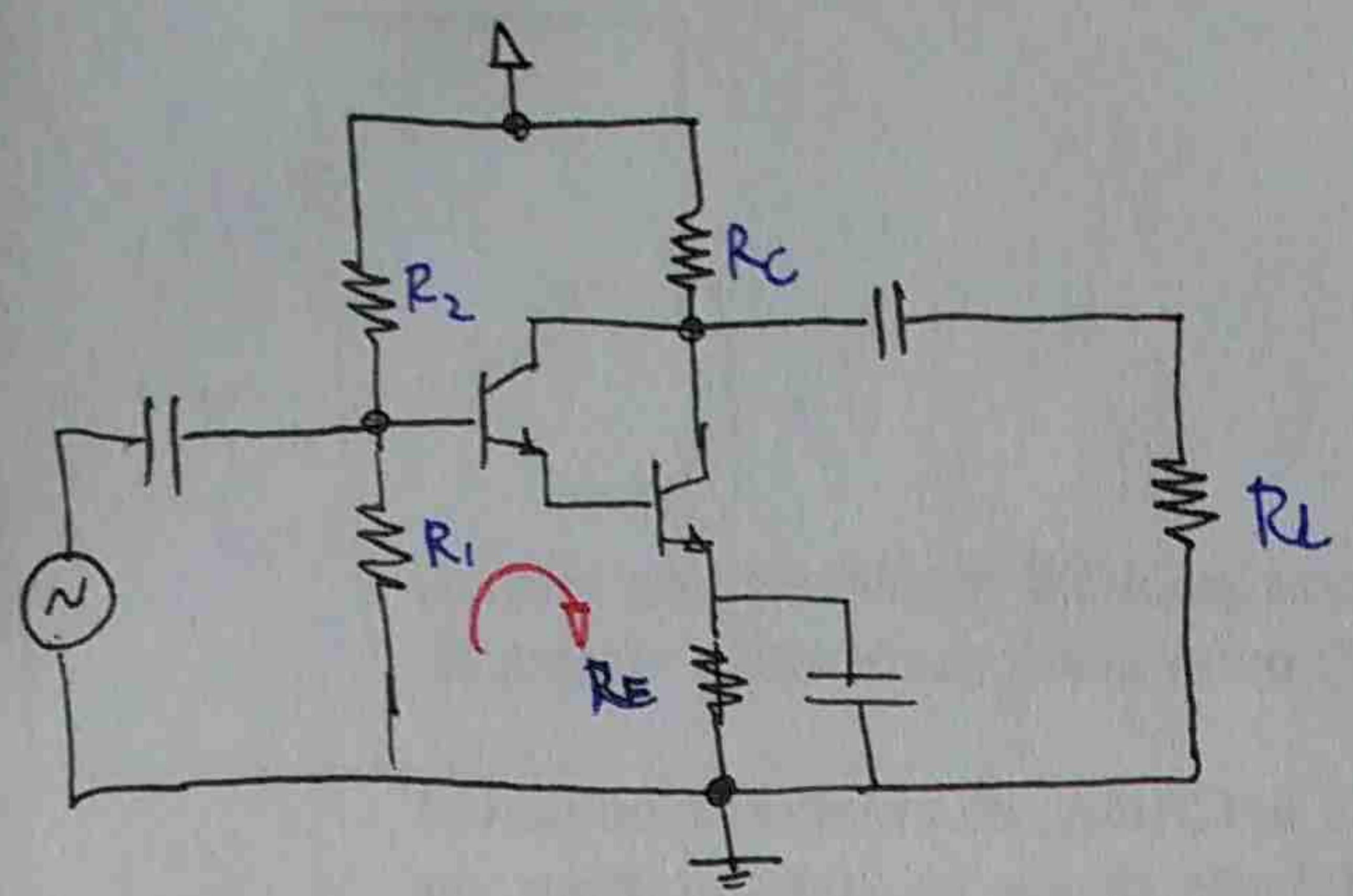


$$Z_o = R_D \left/ \left\{ r_{ds} + \left[(R_E \parallel R_s \parallel h_{ib}) \mu \right] \right\}$$

$$A_i = \frac{i_L}{i_i} = \frac{i_L}{i_d} \frac{i_d}{i_c} \frac{i_c}{i_i} = \frac{R_B}{R_D + R_L} \frac{(R_E \parallel R_s) \mu}{(R_E \parallel R_s) \mu + r_{ds} + R_D \parallel R_L} \left\{ h_{fe} \frac{\frac{R_B}{h_{fe}} \mu}{\left[\frac{R_B}{h_{fe}} \mu + h_{ib} + (R_E \parallel R_s) \mu \right] \left/ \left[r_{ds} + (R_D \parallel R_E) \right] \right.} \right\}$$

Par Darlington PD y Par complementario

(13)



Kirchoff

$$I_{CQ2} = \frac{V_{bb} - 2V_{BE}}{\frac{R_B}{\beta} + R_E}$$

$$I_{BQ2} = \frac{I_{CQ2}}{\beta} \approx \cancel{RE} \simeq I_{CQ1}$$

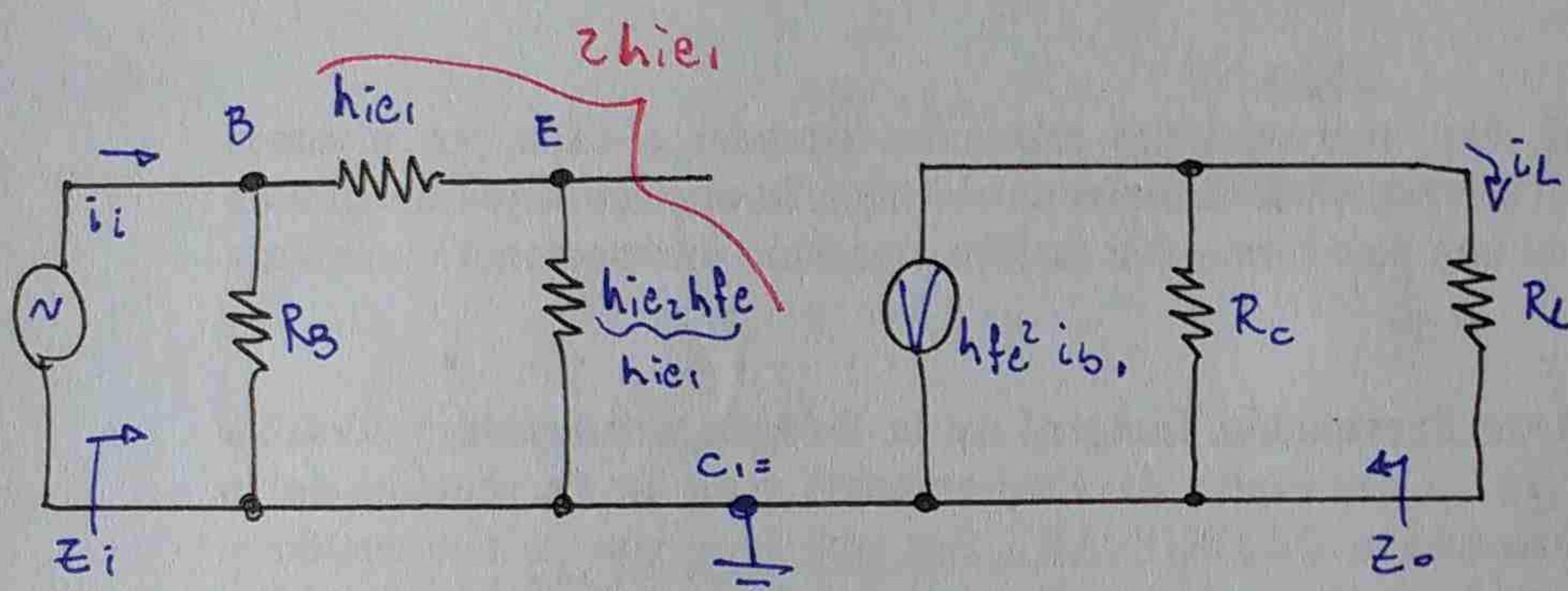
$$V_{CEQ2} = V_{CC} - I_{CQ2}(R_C + R_E)$$

$$V_{CEQ1} = V_{CEQ2} - V_{BE}$$

R_B para diseño

$$R_B = \frac{\beta^2 R_E}{10}$$

$$V_{BB} = I_{CQ2} \left(\frac{R_B}{\beta^2} + R_E \right) + 2V_{BE}$$



si no existiera el capacitor de desacoplamiento por lo tanto que circula i_b1 habria que sumarle $R_E h_{FE}^2$

$$Z_i = R_B // z_{hie1}$$

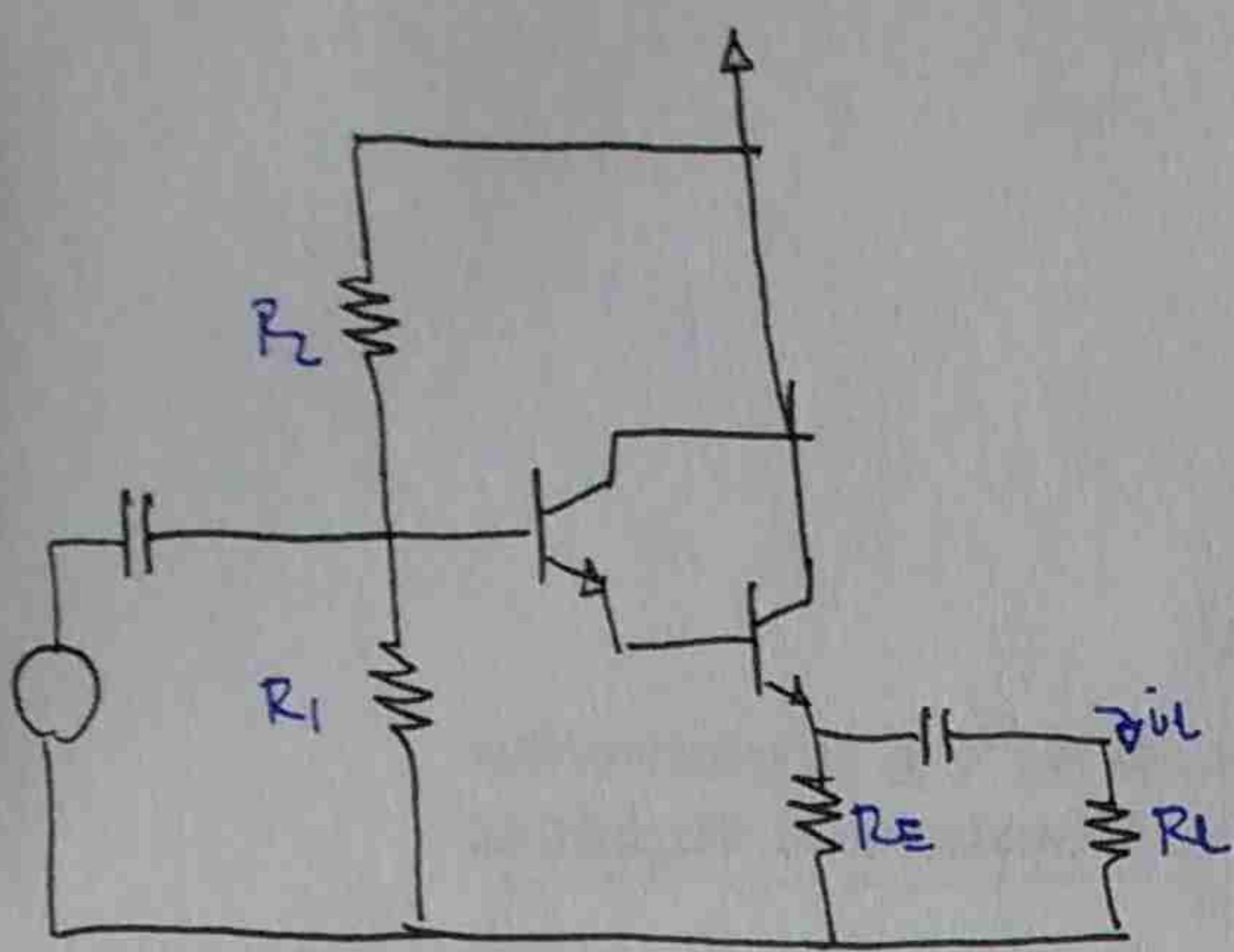
$$z_{hie1} = \frac{25mV}{I_{CQ1}} h_{FE}$$

$$Z_i = R_B // z_{hie1}$$

$$z_{hie2} = \frac{25mV}{I_{CQ2}} h_{FE}$$

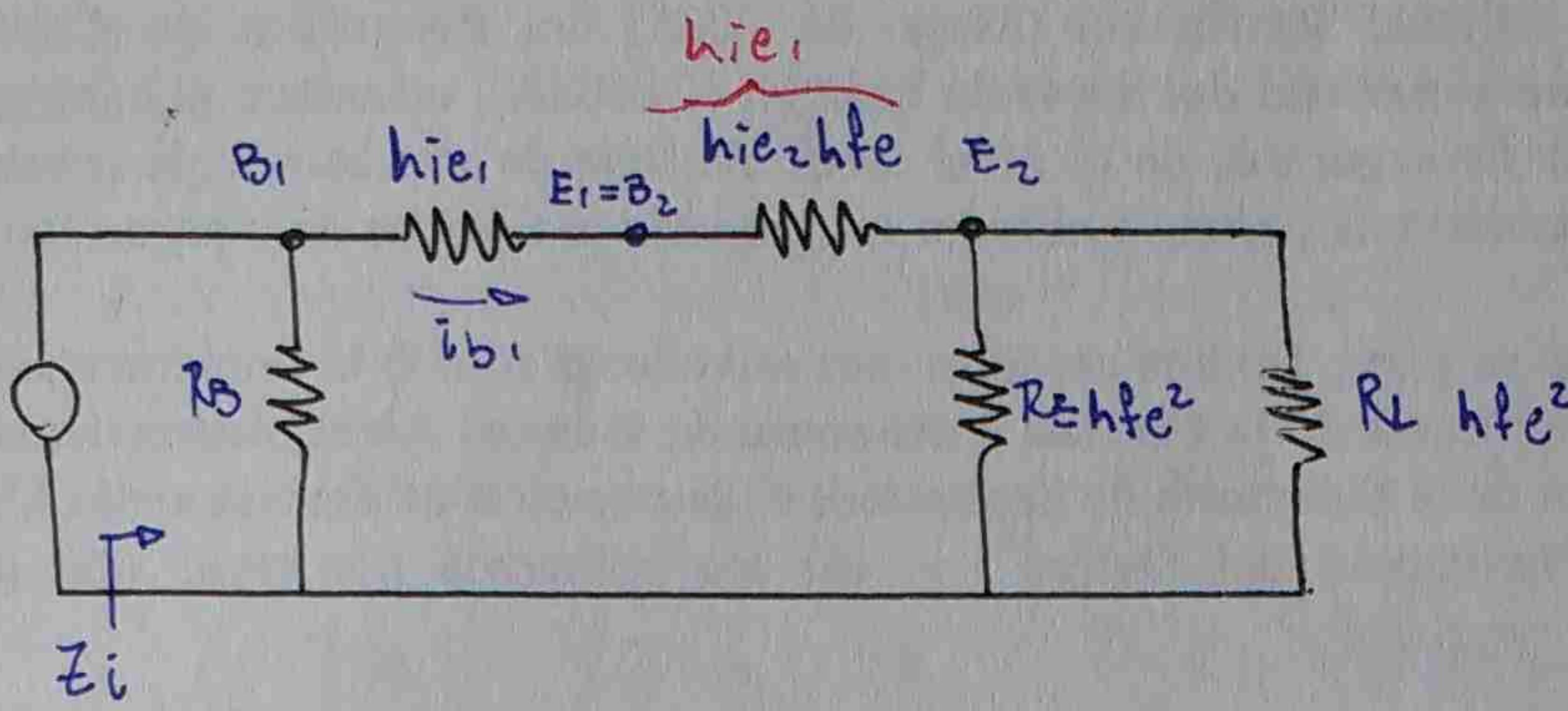
$$Z_o = R_C$$

$$A_i = -h_{FE}^2 \frac{R_C}{R_C + R_L} \frac{R_B}{R_B + z_{hie1}}$$



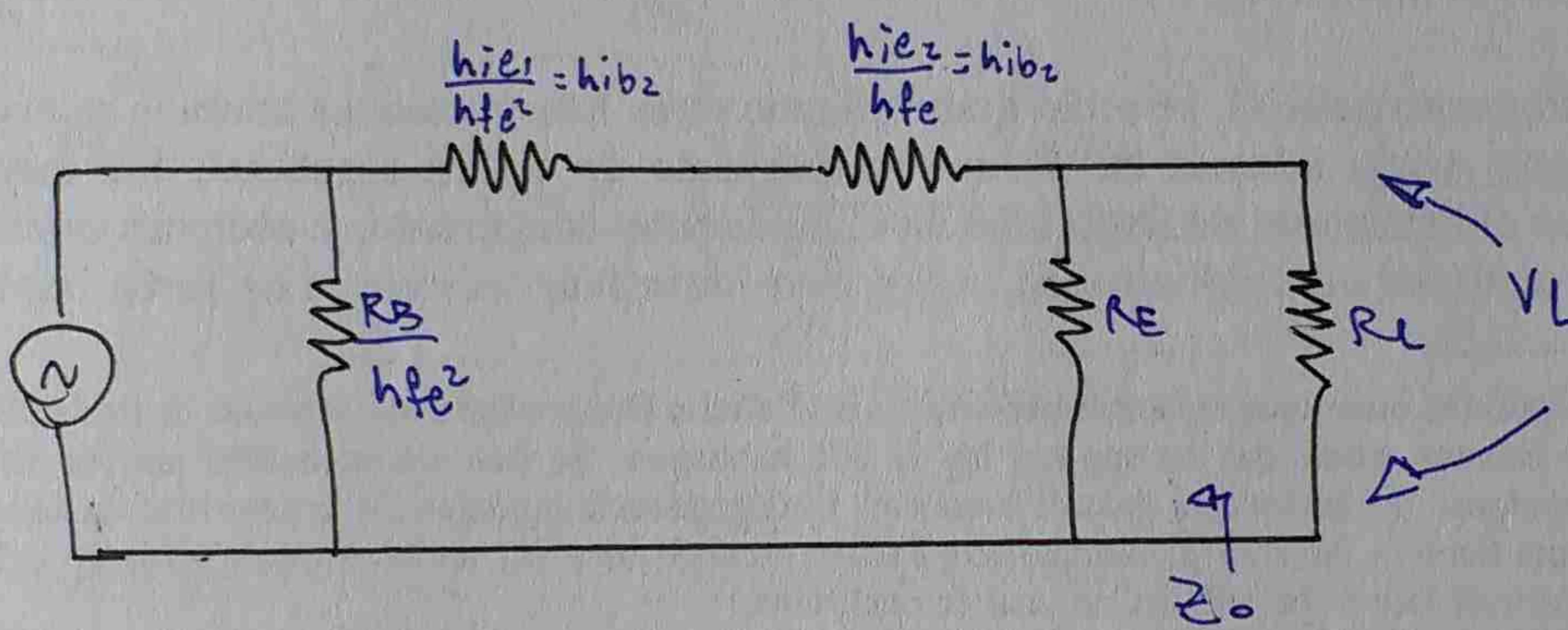
$\Rightarrow \boxed{cc} \Rightarrow \boxed{cc} \Rightarrow$

Entrada:



$$Z_i = R_B \parallel \left[z_{hie1} + (R_E \parallel R_L) h_{fe}^2 \right]$$

Saida:



$$Z_o = R_E \parallel z_{hib2}$$

Con R_b muy grande se tiene

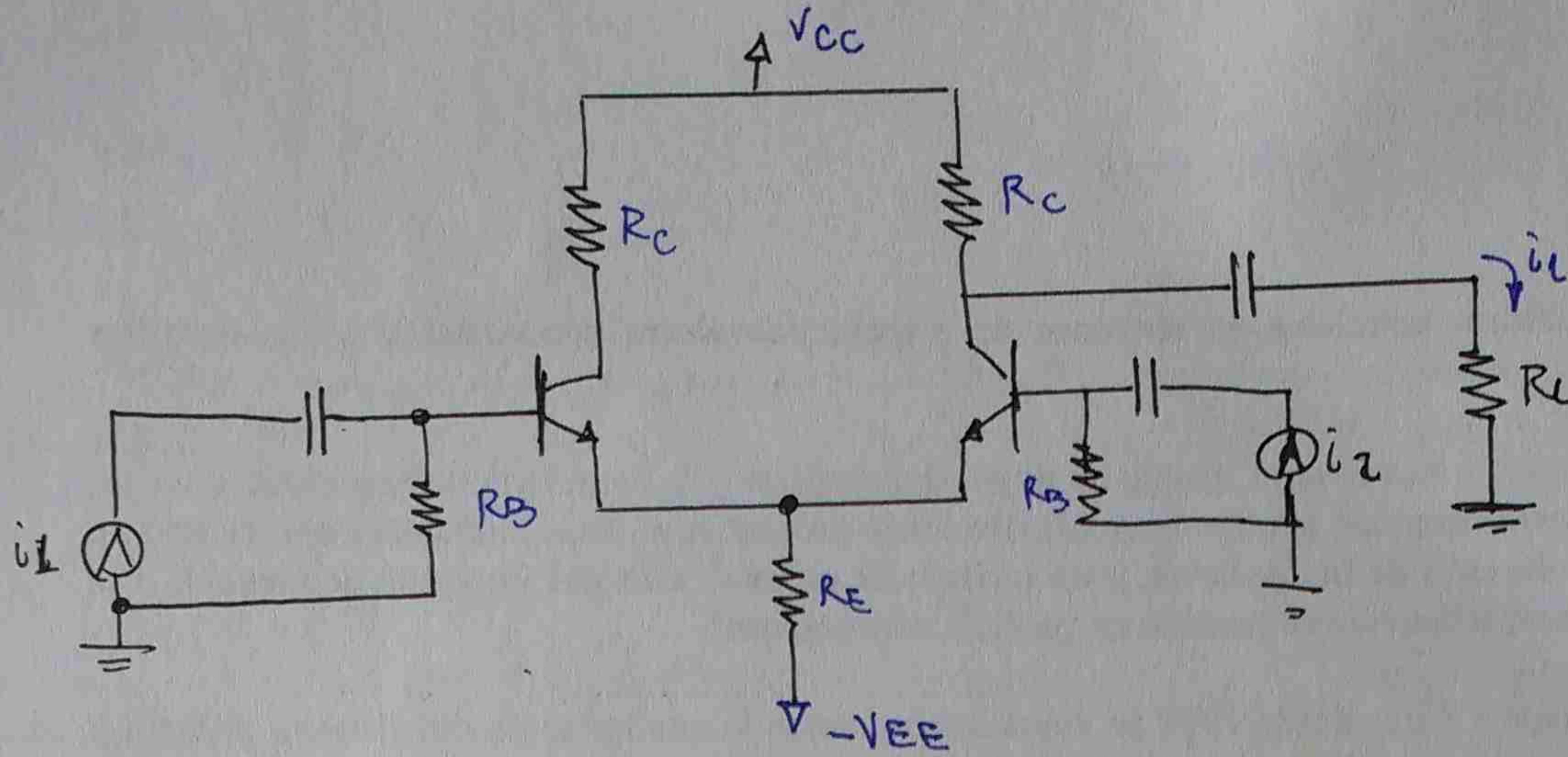
$$+ \left(R_i \parallel \frac{R_b}{h_{fe}^2} \right)$$

$$A_v = \frac{V_L}{V_i} = \frac{V_L}{\frac{V_i}{h_{fe}^2}} \cdot \frac{i_{C2}}{V_i} = R_E \parallel R_L \cdot \frac{1}{z_{hib2} + R_E \parallel R_L}$$

$$A_i = \Delta v \frac{Z_i}{R_L}$$

Amplificador Diferencial

(15)



$$I_{RE} = I_{CQ1} + I_{CQ2} = 2I_{CQ1} = 2I_{CQ2}$$

$$V_{RE} = 2I_{CQ2} R_E = I_{CQ2} \cancel{R_E}$$

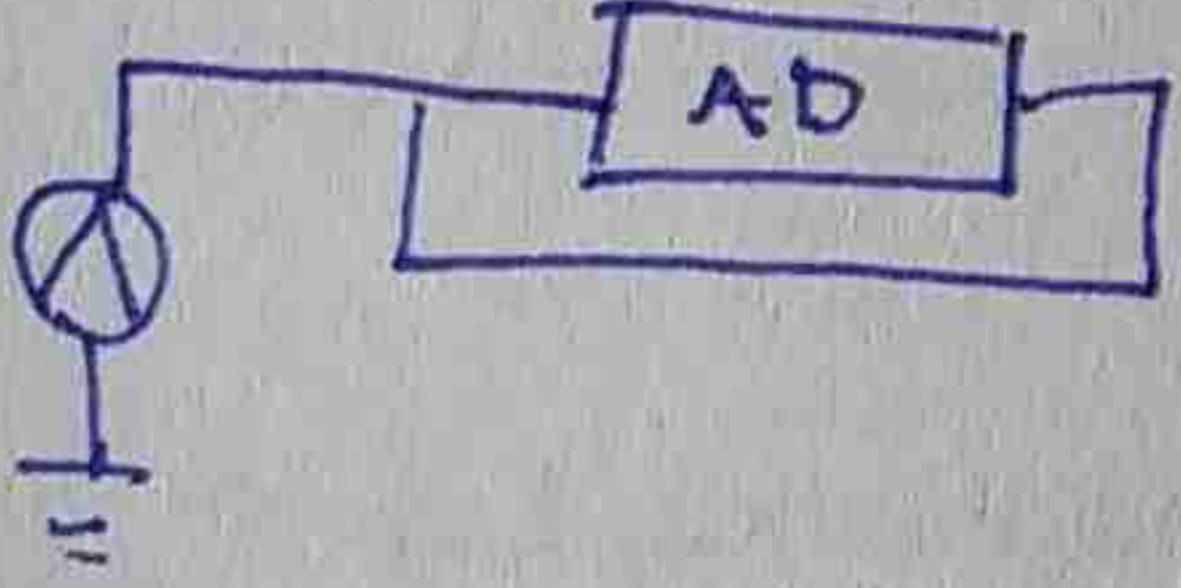
LKT

$$V_{EE} = \frac{I_{CQ2}}{\beta} R_B + V_{BE} + I_{CQ2} R_E$$

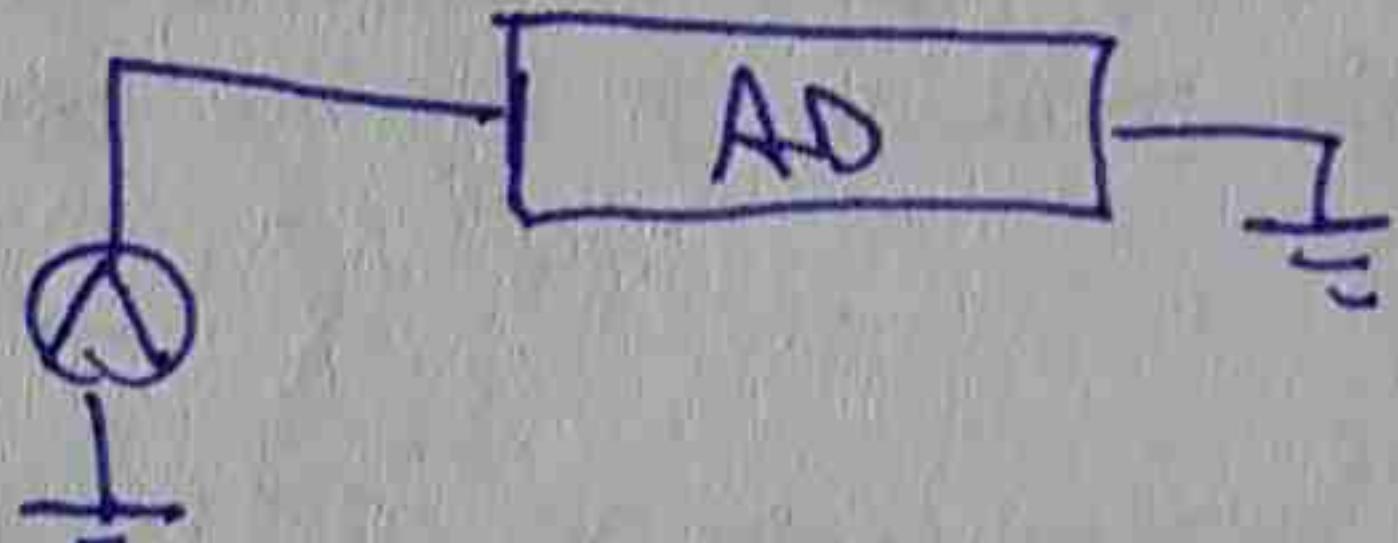
$$I_{CQ2} = \frac{V_{EE} - V_{BE}}{\frac{R_B}{\beta} + 2R_E}$$

Modos de conexión

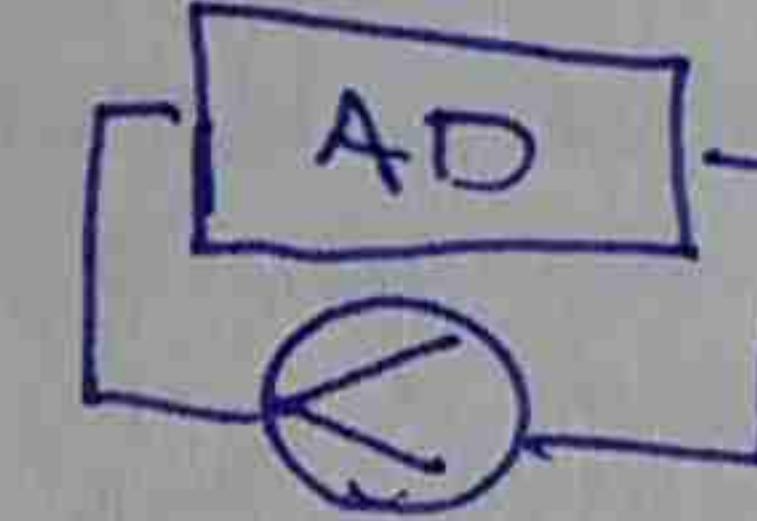
común



Asimétrico



Diferencial



Relación de Rechazo en modo común

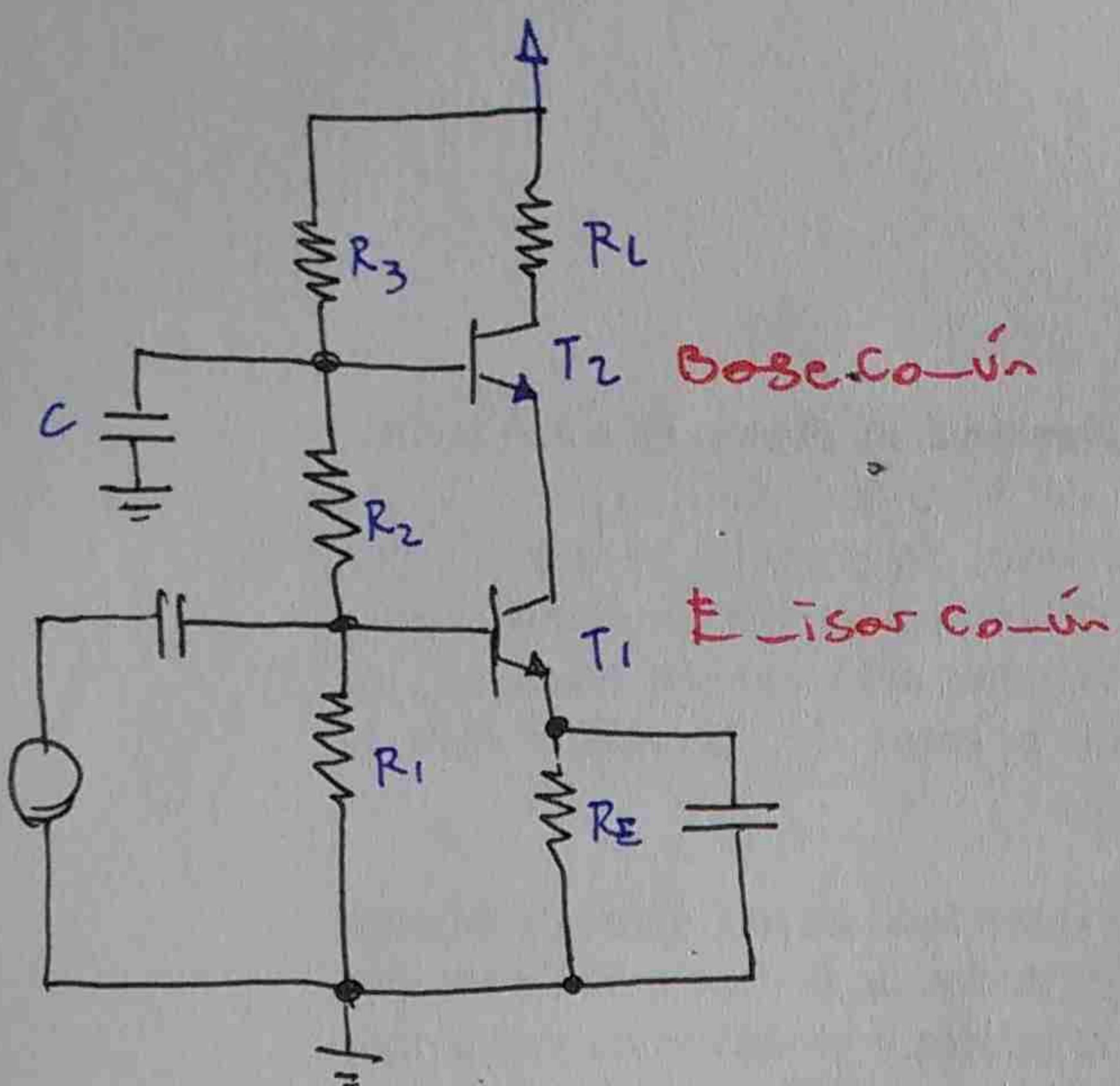
$$RR_{MC} = \frac{\Delta d}{\Delta c}$$

Δd = ganancia en modo diferencial

Δc = ganancia en modo común

Amplificador Cascode.

16



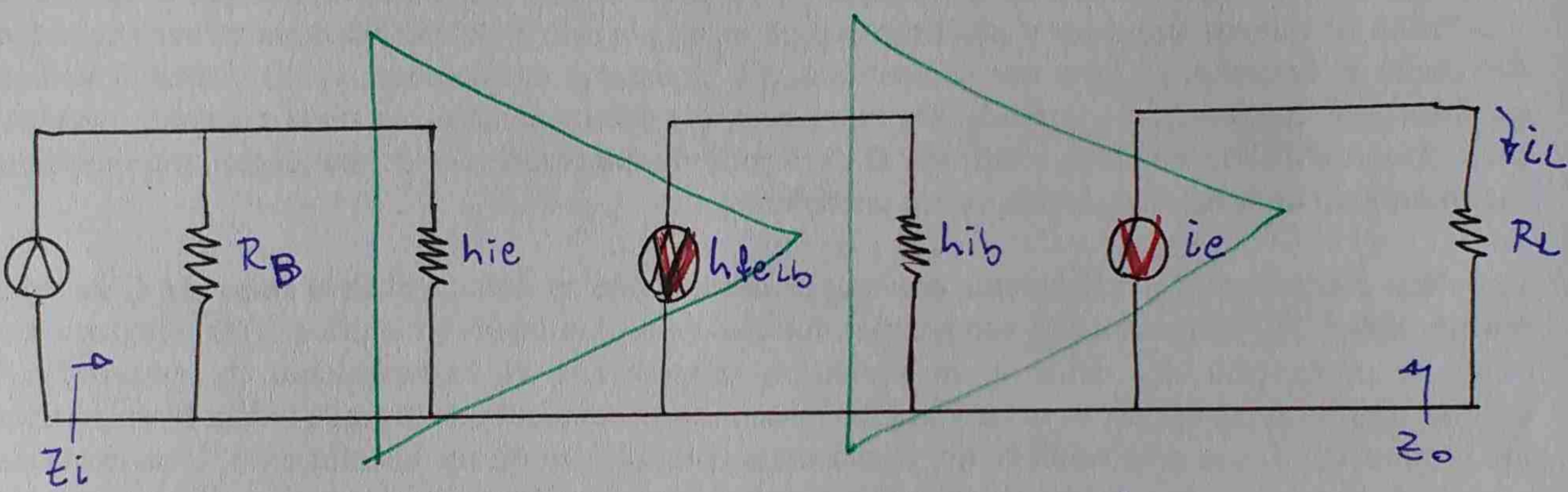
$$V_{B2} = \frac{V_{CC}}{R_1 + R_2 + R_3} (R_1 + R_2)$$

$$V_{B1} = \frac{V_{B2}}{R_1 + R_2} R_1$$

$$I_{CQ2} = \frac{V_{B1} - V_{BE}}{R_E}$$

$$V_{CEQ2} = V_{B2} - V_{BE} - I_{CQ1} R_E$$

$$V_{CEQ1} = V_{CC} - V_{CEQ1} - I_{CQ1} (R_L + R_E)$$



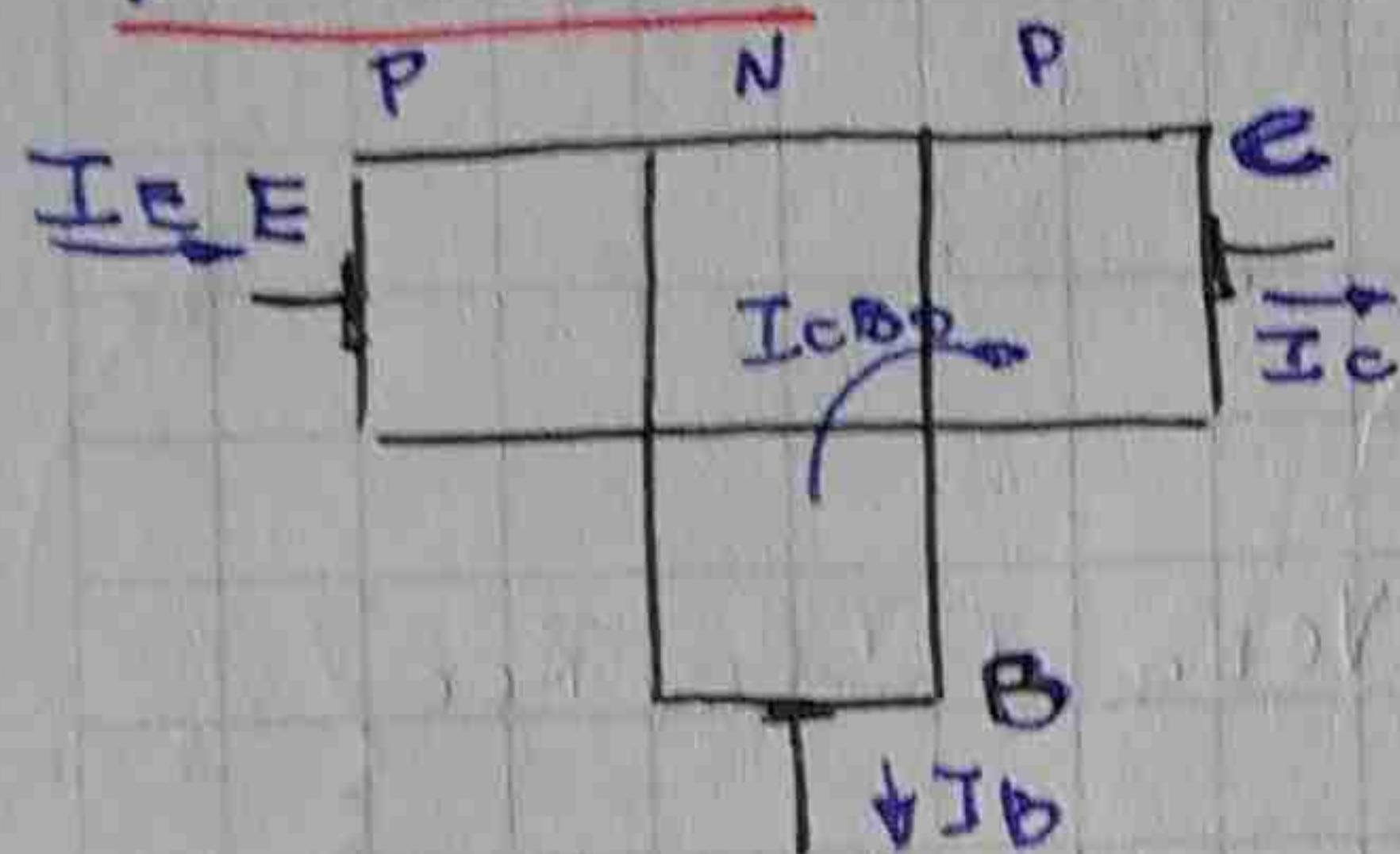
$$Z_i = R_B // h_{ie}$$

$$Z_o = \frac{1}{h_{ob}}$$

$$A_i = \frac{i_L}{i_i} = \frac{i_L}{i_C} \frac{i_C}{i_b} \frac{\dot{i}_b}{\dot{i}_i} = (-1) h_{fe} \frac{R_B}{R_B + h_{ie}}$$

El Cascode preserva una impedancia de salida (salida) al emisor común muy baja

①

Transistor.

I_{CBO} = Carrilero inverso con el emisor y el colector abiertos

$$I_E = I_C + I_S$$

$$\beta = \frac{I_C}{I_S} \quad (\text{Ganancia } E_C)$$

$$\alpha = \frac{I_C}{I_E} = \frac{I_C}{I_C + I_S} \quad (\text{Ganancia } B_C)$$

$$\alpha = \frac{I_C}{I_E} = \frac{I_C}{I_C + I_S} = \frac{\frac{I_C}{I_S}}{\frac{I_C}{I_S} + 1} = \frac{\beta}{\beta + 1}$$

$$\beta = \frac{I_C}{I_B} = \frac{I_E}{I_E - I_S} = \frac{\frac{I_C}{I_E}}{1 - \frac{I_S}{I_E}} = \frac{\alpha}{1 - \alpha}$$

$$I_C = \alpha I_E + I_{CBO} \quad \left. \begin{array}{l} \\ \end{array} \right\} \text{Igual a } I_E$$

$$I_E = I_C + I_S$$

$$I_S = I_C \left(\frac{1 - \alpha}{\alpha} \right) - \frac{I_{CBO}}{\alpha}$$

$$\beta = \frac{I_C}{I_B} \quad \underbrace{\beta}_{\text{Despreciable.}}$$

$$h_{FE} = \frac{i_C}{i_B} = \frac{\Delta i_C}{\Delta i_B} = \beta \frac{\Delta i_B}{\Delta i_B} + i_B \frac{\Delta \beta}{\Delta i_B} = \beta \Rightarrow h_{FE} = \beta \quad h_{FB} = \alpha$$

E.C. Diseño

$$\textcircled{1} \quad V_{CC} < \beta V_{CEO}$$

$$\textcircled{2} \quad R_E$$

$$\textcircled{3} \quad R_C = \frac{V_{CC} - V_{CEO}}{I_{CQ}} - R_E$$

$$\textcircled{4} \quad R_B = \frac{\beta R_E}{10}$$

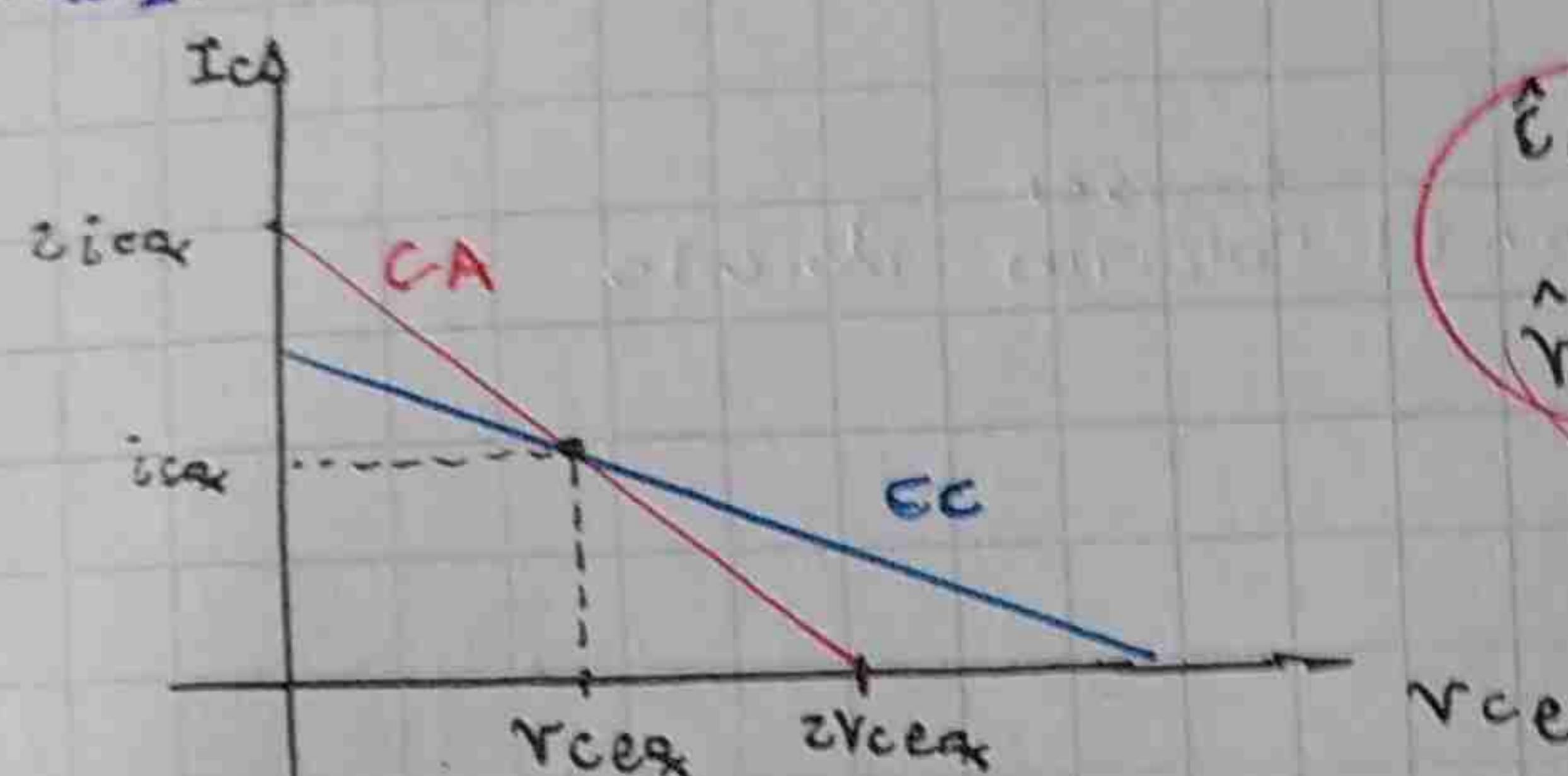
$$\textcircled{5} \quad V_{BB} = \frac{I_{CQ}}{\beta} R_B + V_{BE} + I_{CQ} R_E$$

$$\textcircled{6} \quad R_I = \frac{R_B}{1 - \frac{V_{BB}}{V_{CC}}} \quad R_O = \frac{R_C}{\frac{V_{BB}}{V_{CC}}}$$

Entrada Directa

Salida Inversa

Maxima excursión simétrica



$$I_{cmax} = I_{cq}$$

$$\hat{V}_{ce_{max}} = V_{ceq}$$

$$I_{cmax_{MES}} = \frac{V_{cc}}{R_{cc} + R_{ca}}$$

Fórmula General

De la otra:

$$CC \rightarrow V_{cc} = V_{ceq} + I_{cq} R_{cc} \quad \left. \begin{array}{l} \text{igual } V_{ceq} \\ \text{igual } V_{ceq} \end{array} \right\}$$

$$CA \rightarrow (\hat{V}_{ce})_{max} = \hat{I}_{cq} \rightarrow R_{ca}$$

Puntos extremos

$$\hat{I}_c = I_{cq} + \frac{V_{ceq}}{R_{ca}}$$

$$V'_{ce} = V_{ceq} + I_{cq} R_{ca}$$

Si:

$$I_{cq} = \frac{V_{ceq}}{R_{ca}}$$

MES (esta para)

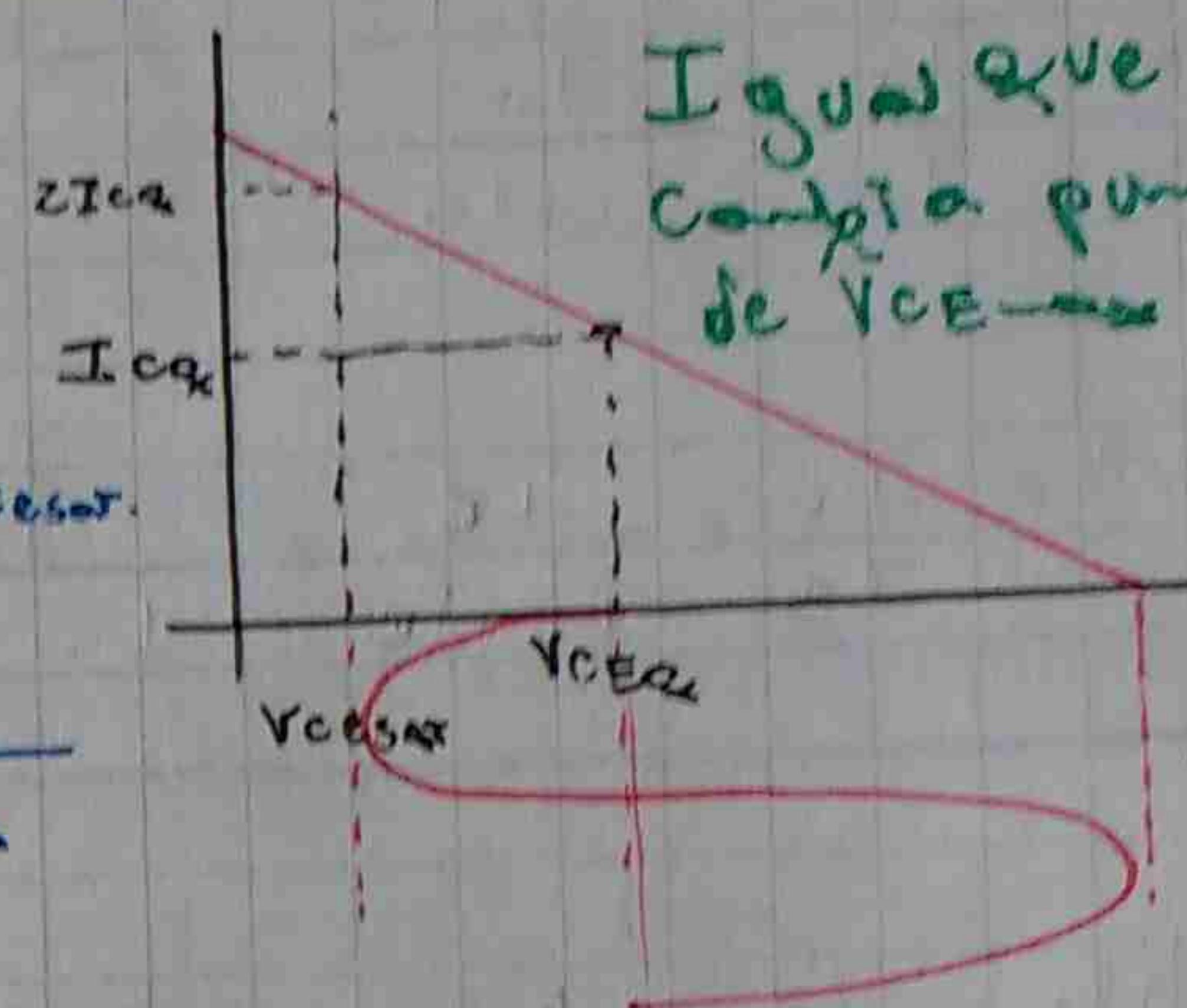
$V_{ce_{sat}} \neq 0$

$$\hat{I}_{c_{max}} = I_{cq}$$

$$\hat{V}_{ce_{max}} = V_{ceq} - V_{cesat}$$

$$I_{cq_{max}} = \frac{V_{cc} - V_{cesat}}{R_{cc} + R_{ca}}$$

Igual que antes
Cambia punto extremo
de $V_{ce_{max}}$

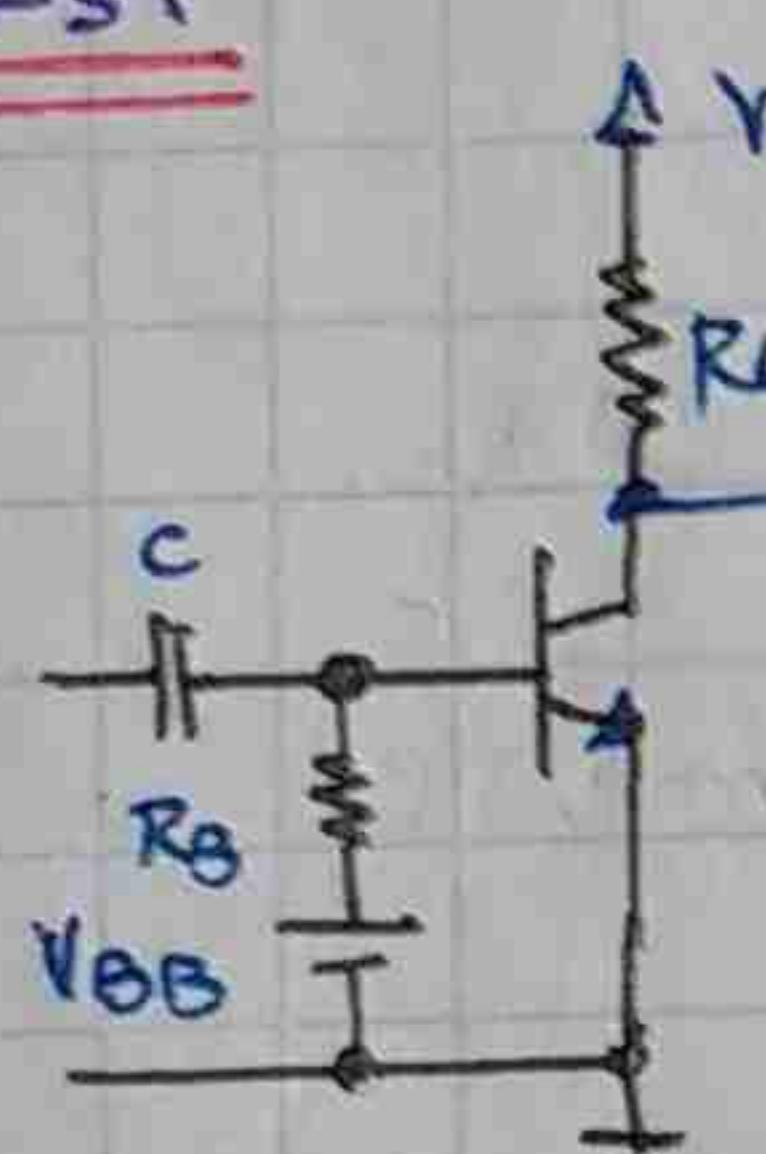


Puntos extremos
que pasa en CC y en CA

Ejemplo puntos extremos

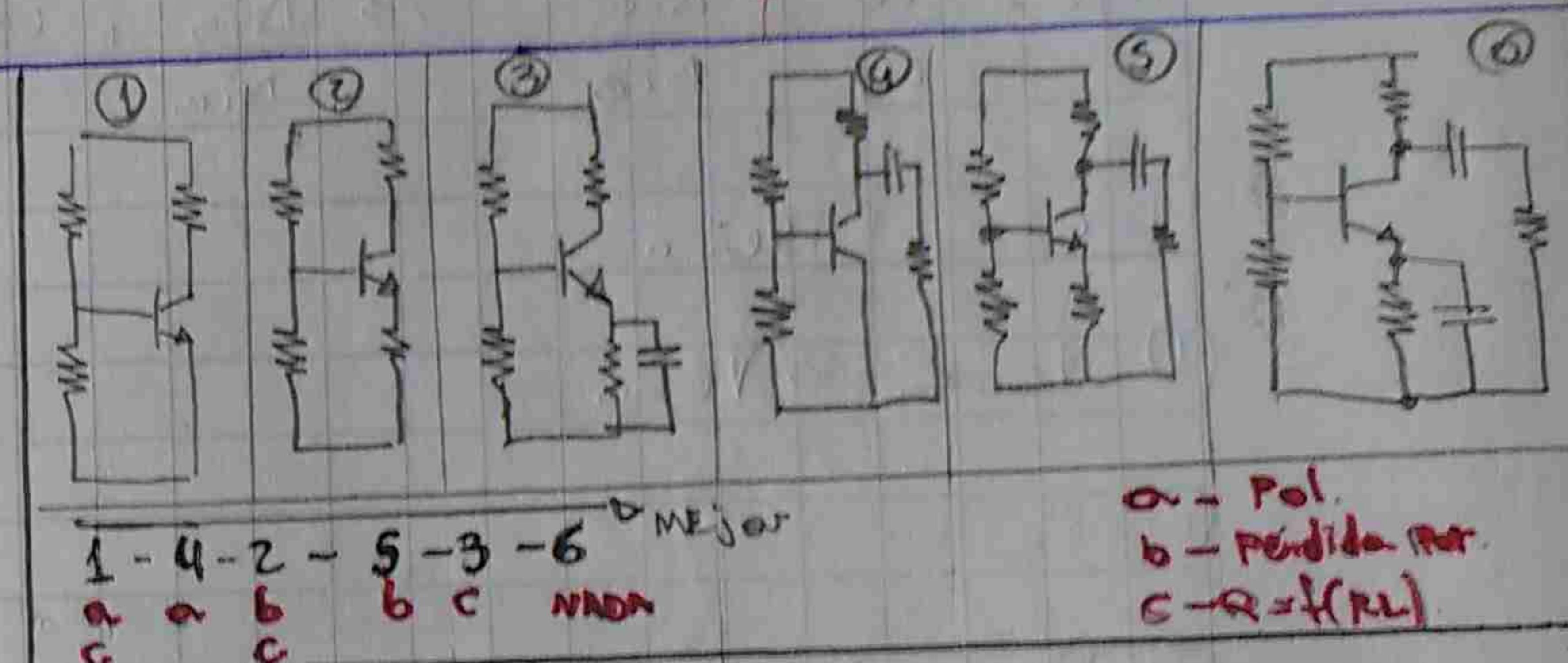
Igual V_{ceq}
Despejo I_{cq} .

Potencias:



$R_{cc} \ll R_L \quad (R_L \rightarrow \infty)$

$$I_{c(E)} = I_{cq} + \hat{I}_c \cos(\omega t)$$



En general

$$P = \frac{1}{T} \int_0^T V_{cc} i_c(t) dt = \frac{1}{T} \int_0^T V_{cc} (I_{cq} + \hat{I}_c \cos \omega t) dt = \frac{1}{T} V_{cc} I_{cq} T$$

Potencia por la fuente

$$P_{cc} = V_{cc} I_{cq}$$

barrido

Para MES.

$$I_{cq_{mes}} = \frac{V_{cc}}{2RL}$$

$$P_{cc_max} = \frac{V_{cc}^2}{2RL}$$

$$P_{L_max} = \frac{V_{cc}^2}{8RL}$$

$$P_{L_max} = \frac{1}{2} \frac{I_{cq}^2}{4} RL$$

Pot pro-disipado en la carga (CA)

$$P_{L(CA)} = \frac{1}{T} \int_0^T \hat{I}_c^2 RL dt = \frac{1}{T} \hat{I}_c^2 RL \int_0^T \cos^2(\omega t) dt = \dots = \frac{1}{2} \frac{\hat{I}_c^2 RL}{2} \quad \text{Sólo la parte de ALTO}$$

$$P_{L(CA)} = \frac{1}{2} \hat{I}_c^2 R_L$$

Potencia pro-edio disipada en el colector del transistor

$$V_{ce} = V_{cc} - I_{c} R_L$$

$$i_E = I_{cq} + i_c$$

$$i_c = \hat{I}_c \cos(\omega t)$$

$$P_C = V_{cc} I_{cq} - I_{cq}^2 R_L - \frac{1}{2} \hat{I}_c^2 R_L$$

Deducir desde la máxima menos las pérdidas (colector, carga (C), (CA))

$$P_C = V_{cc} I_{cq} - \frac{V_{cc}^2}{4RL} - \frac{V_{cc}^2}{8RL}$$

PARA MES

$$P_C = \frac{V_{cc}^2}{2RL} - \frac{V_{cc}^2}{4RL} - \frac{V_{cc}^2}{8RL}$$

$$\hat{I}_{c_max} = I_{cq}$$

$$I_{cq} = \frac{V_{cc}}{2RL}$$

$$P_{c_max} = P_C \Big|_{s/seg} = \frac{V_{cc}^2}{4RL}$$

$$P_{c_in} = P_C \Big|_{c/seg max} = \frac{V_{cc}^2}{8RL}$$

(2)

Rendimiento

Menor valor posible →

$$h = \frac{P_L}{P_{CC}}$$

Pot útil en la carga

Pot suministrada por fuente de salida

$$h_{max} = \frac{P_{Lmax}}{P_{CCmax}} = 25\%$$

P_{CCmax}

Factor de Mérito

Menor valor posible →

$$FM = \frac{P_{Cmax}}{P_{Lmax}}$$

Ocurren en dist. máximos

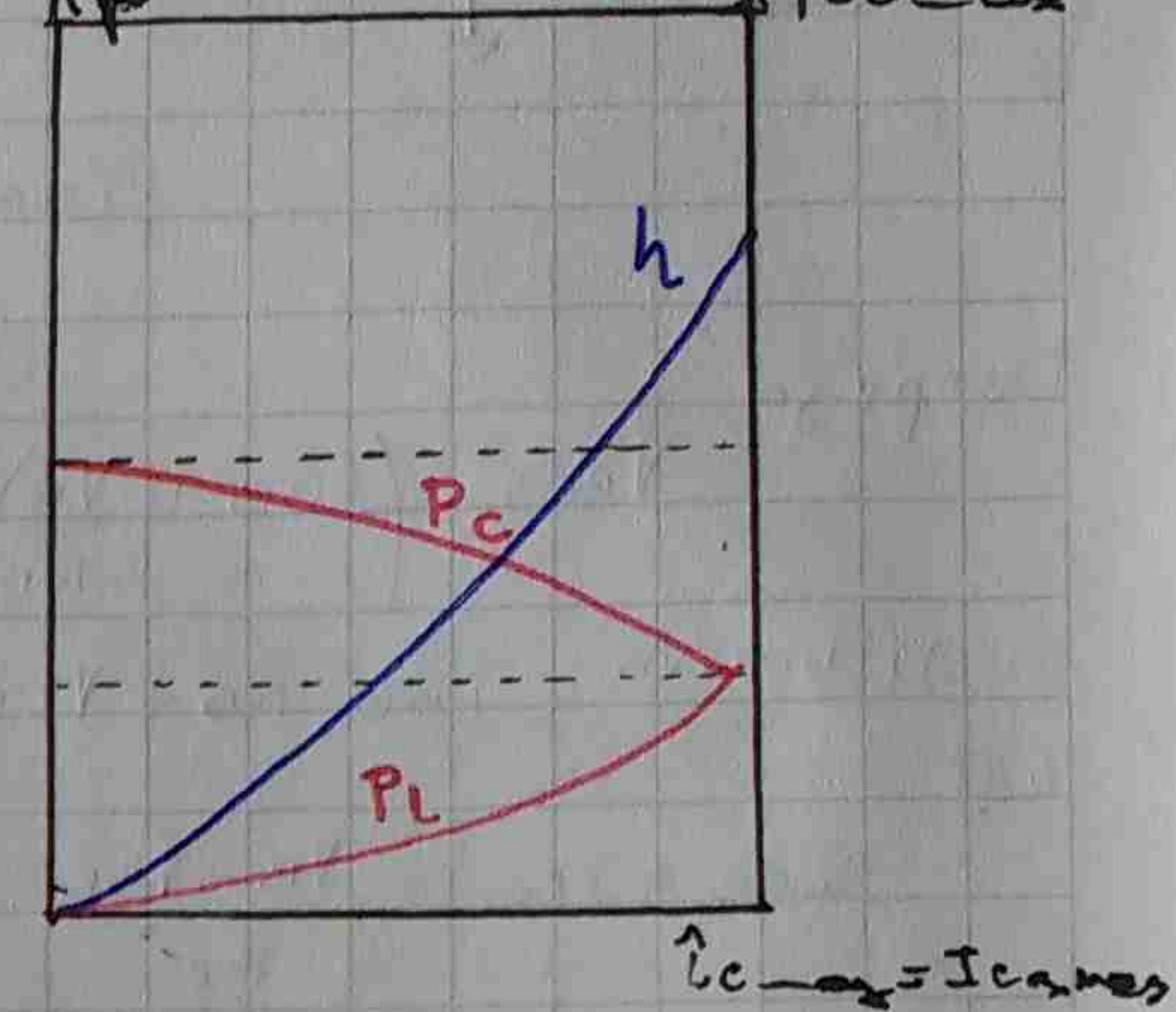
+ Max pot dissip. colector

→ " " " carga

Si no estuviera para MES

FM > 2 Trans es más

$$\begin{aligned} P/mes \\ FM=2 \end{aligned}$$



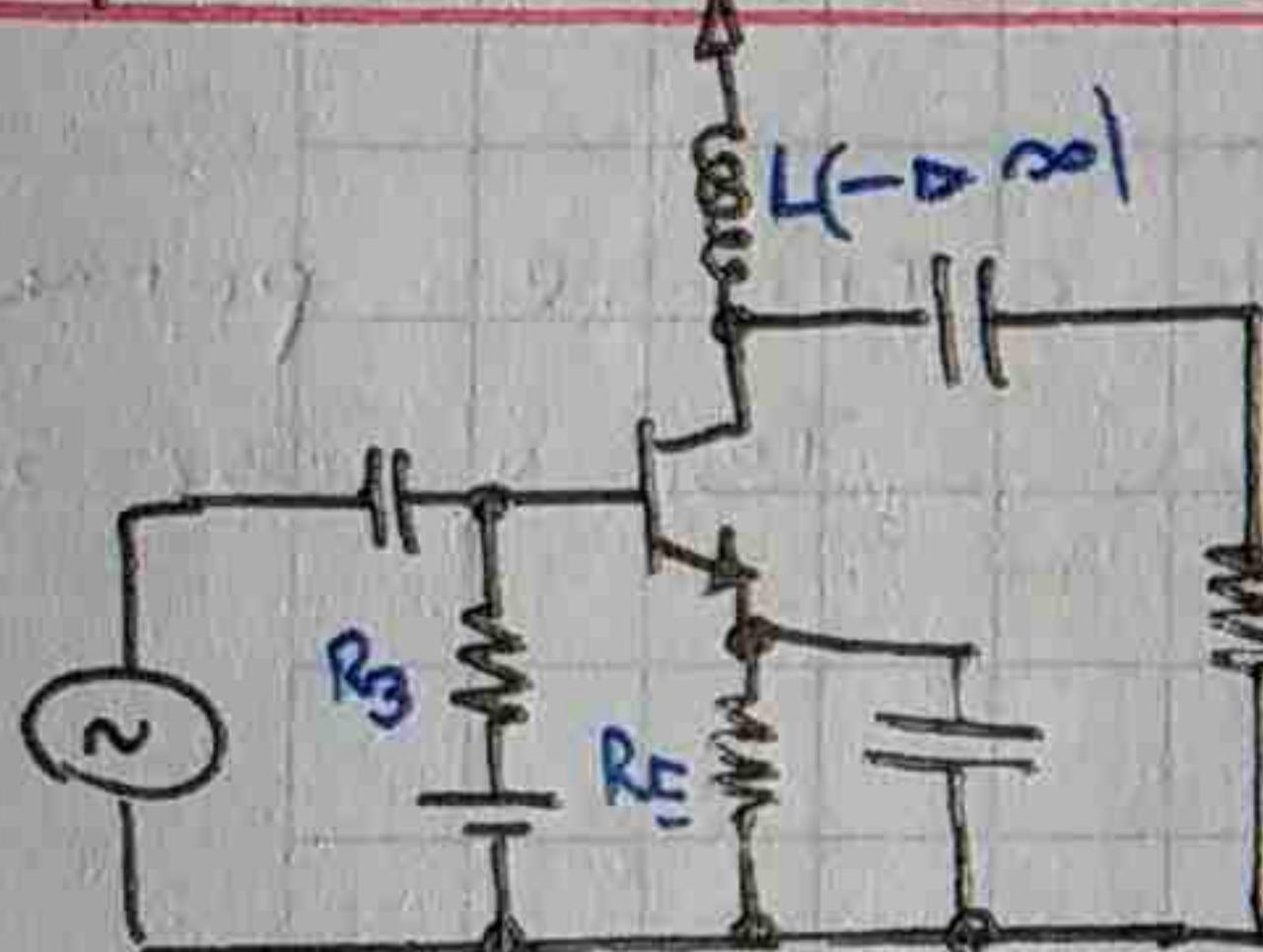
Con $h = 25\%$

$$P_{CCmax} = \frac{P_{Lmax}}{0.25} = V_{CC} [I_{Cmax} \text{ mes.}]$$

Con $FM=2$

$$P_{Cmax} = 2P_{Lmax}$$

Amplificador clase A con acoplamiento por inductores (EC)

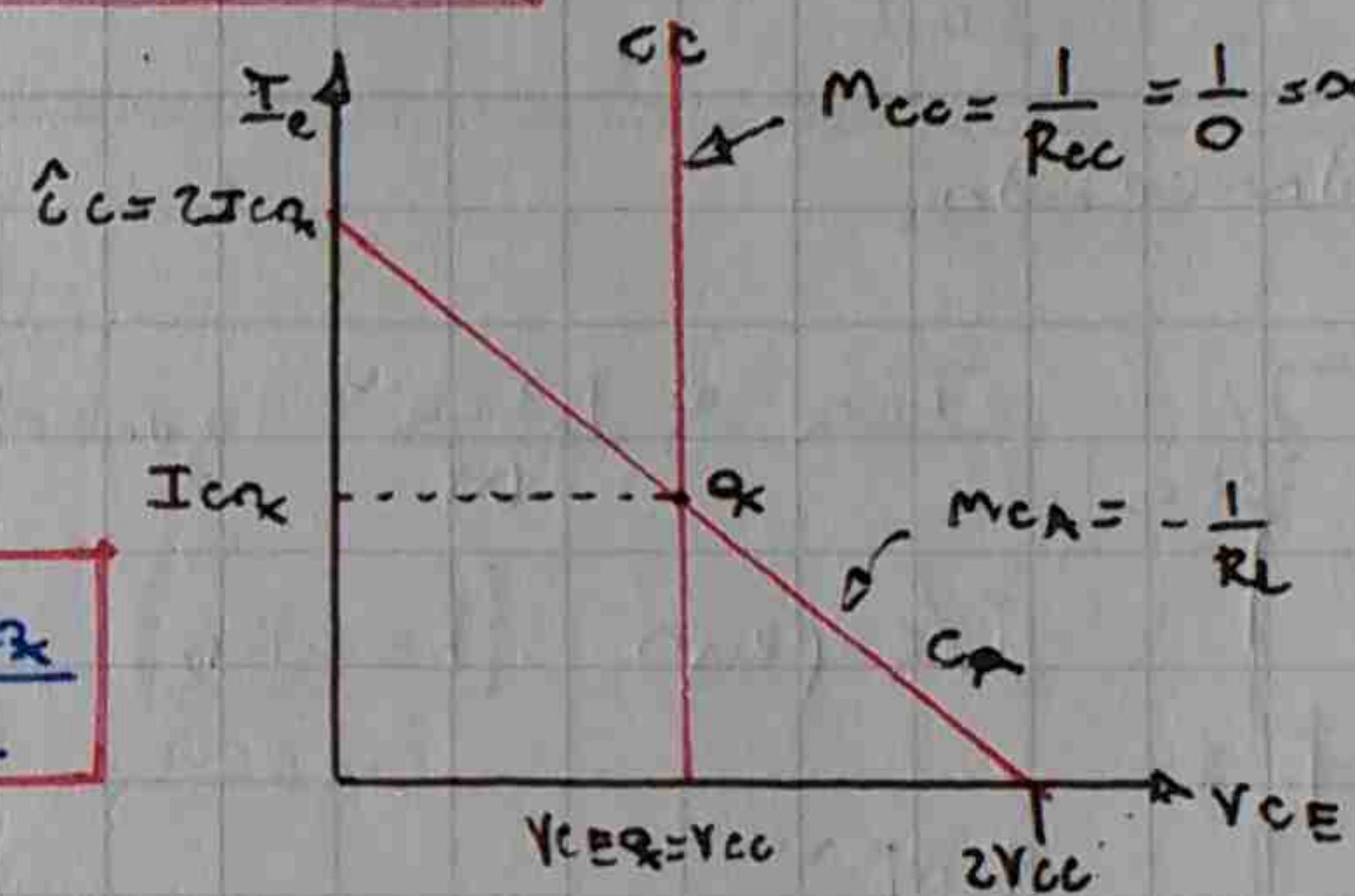


$R_E \rightarrow 0$

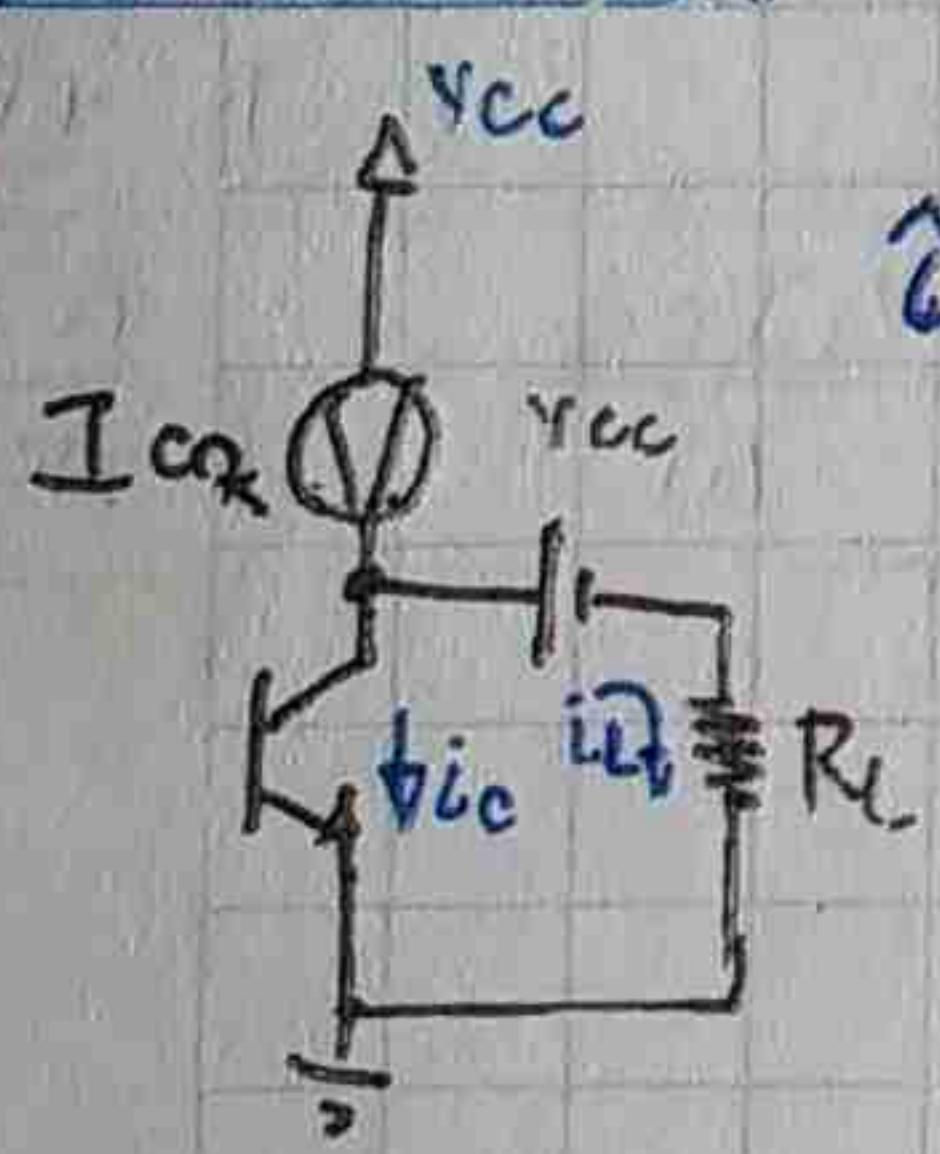
$R_{CC} \approx 0$

$R_{CA} = RL // XL = RL$

$$I_{Cmax} \text{ mes.} = \frac{V_{CC}}{RL} = \frac{V_{CEQ}}{RL}$$



Funcionamiento



$$\hat{I}_L = -\hat{I}_C$$

$$\bullet P/i_C = 0$$

$$V_{CE} = V_{CC} + \hat{I}_C R_E$$

$$V_{CE} = V_{CC} + I_{Ceq} R_E$$

$$V_{CE} = 2V_{CC}$$

$$\bullet P/i_C = 2I_{Ceq}$$

$$V_{CE} = V_{CC} - I_{Ceq} R_E$$

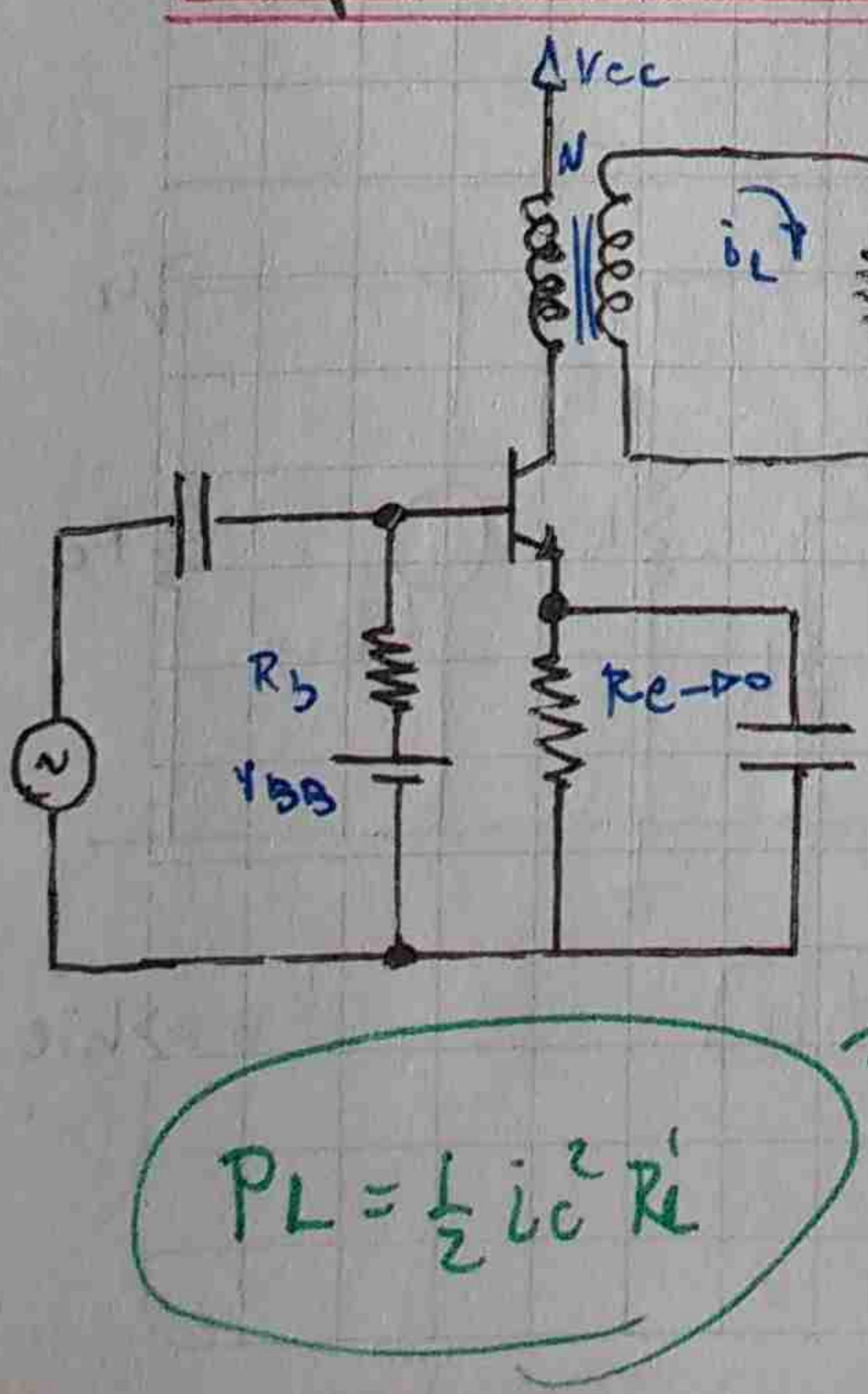
$$V_{CE} = 0$$

Análisis de Potencia

$$P_{CCmax} = \frac{V_{CC}^2}{RL} \quad P_{Cmax} = \frac{V_{CC}^2}{RL} \quad \left. \begin{array}{l} h_{max} = 50\% \\ FM = 2 \end{array} \right\}$$

$$P_{L(max)} = \frac{V_{CC}^2}{2RL} \quad P_{Cin} = \frac{V_{CC}^2}{2RL} \quad \left. \begin{array}{l} h_{max} = 50\% \\ FM = 2 \end{array} \right\}$$

Amplificador clase A (Acoplamiento por transformador)



$$i_C R' L = i_E R_L$$

Se reemplaza RL por $R' L$

$$N = \sqrt{\frac{Z_P}{Z_S}} = \sqrt{\frac{R' L}{R_L}}$$

$$R' L = N^2 R_L$$

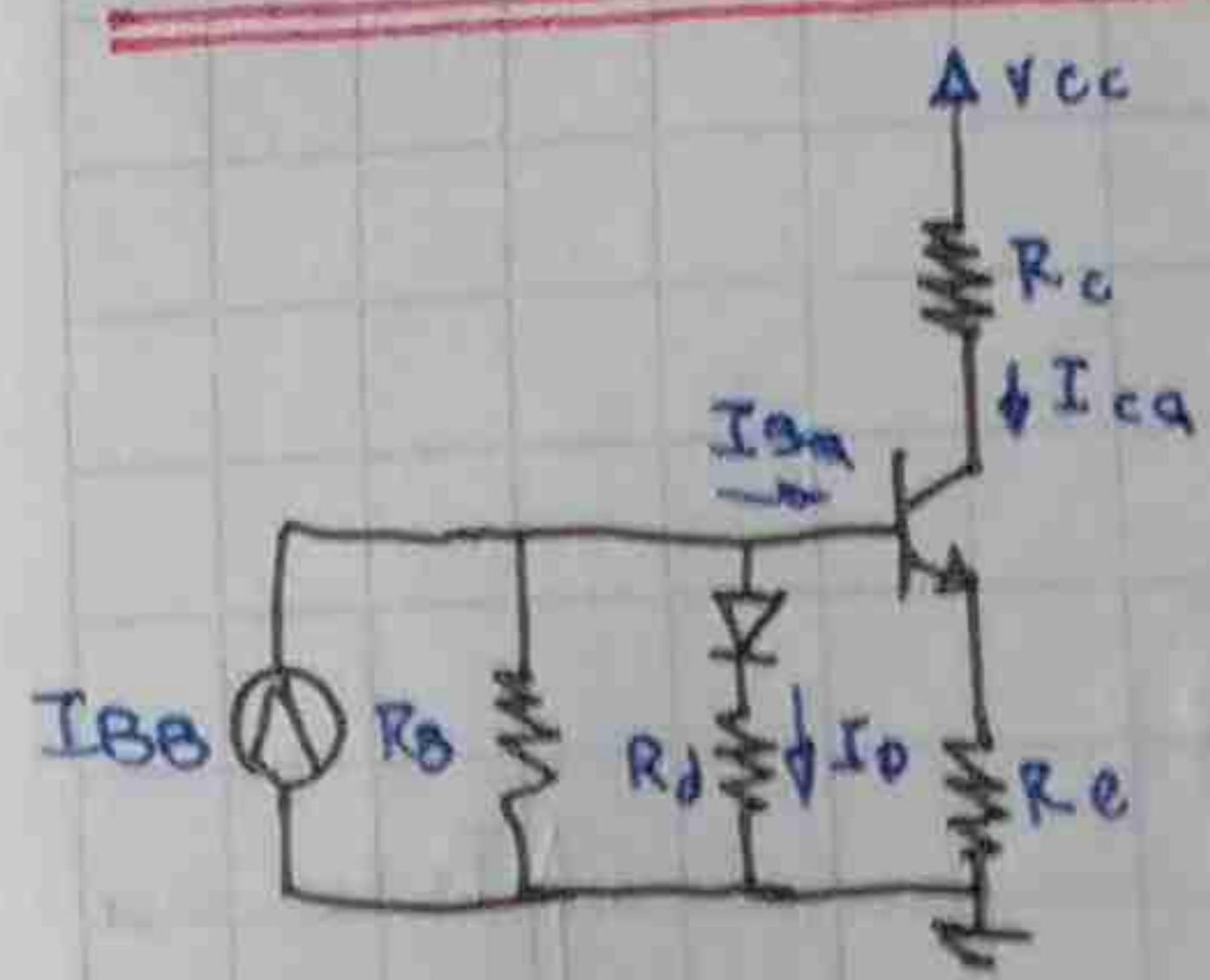
$$I_{Ceq1} = \frac{P_{Lmax}}{V_{CEQ1}}$$

$$I_{Ceq2} = \frac{i_{Cmax}}{2}$$

$$\left. \begin{array}{l} N_{max} = \frac{1}{I_{Ceq1}} \sqrt{\frac{2P_{Lmax}}{RL}} \\ N_{in} = \frac{1}{I_{Ceq2}} \sqrt{\frac{P_{Lmax}}{RL}} \end{array} \right\} N = \frac{N_{max} - N_{in}}{2}$$

$$P_L = \frac{1}{2} i_C^2 R'_L$$

Polarización par diodo o transistor



$$\frac{\Delta V_D}{\Delta T} = \frac{\Delta V_{BE}}{\Delta T} = -K$$

$$I_{BB} = \frac{V_B}{R_B} + \frac{V_B - V_D}{R_D} + I_{B2}$$

$$I_{BB} = V_B \left(\frac{R_B + R_D}{R_B - R_D} \right) - \frac{V_D}{R_D}$$

Despejo

$$V_B = \left(I_{BB} + \frac{V_D}{R_D} \right) R_B / R_D$$

Distributiva $I_{BB} R_B = V_{CC}$

LKT

$$I_{CR} \approx I_{B2} = \frac{V_B - V_{BE}}{R_C}$$

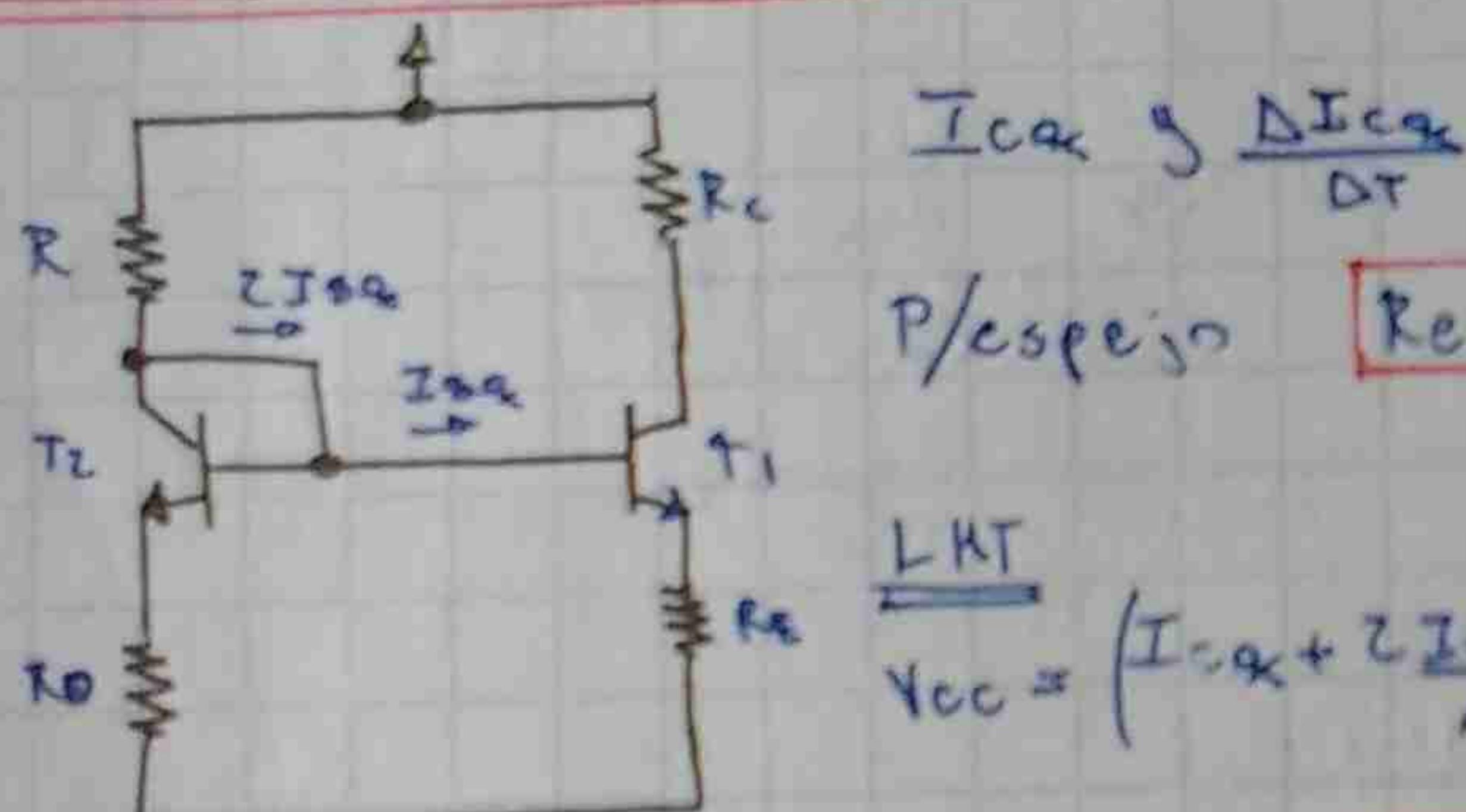
ΔI_{CQ} con respecto a ΔT

$$\frac{\Delta I_{CQ}}{\Delta T} = \frac{K}{R_E} \cdot \frac{1}{1 + \frac{R_B}{R_D}}$$

$$I_{CQ} = \frac{1}{R_E(R_B + R_D)} (V_{CC} R_D + V_D R_B - V_{BE} R_B - V_{BE} R_D)$$

$$I_{CQ} \approx \frac{(V_{CC} - V_{BE}) R_D}{(R_B + R_D) R_E}$$

Polarización Balanceada



I_{CQ} y $\frac{\Delta I_{CQ}}{\Delta T}$ igual al diodo

P/cspejo $R_E = R_D$

LKT

$$V_{CC} = \left(I_{CQ} + 2 \frac{I_{CQ}}{\beta} \right) R + V_{BE} + I_{CQ} R_E = I_{CQ} \left[\frac{\beta + 2}{\beta} R + R_E \right] + V_{BE}$$

Haciendo $R_E = R_D = 0$

$$I_{CQ} = \frac{V_{CC} - V_{BE}}{R}$$

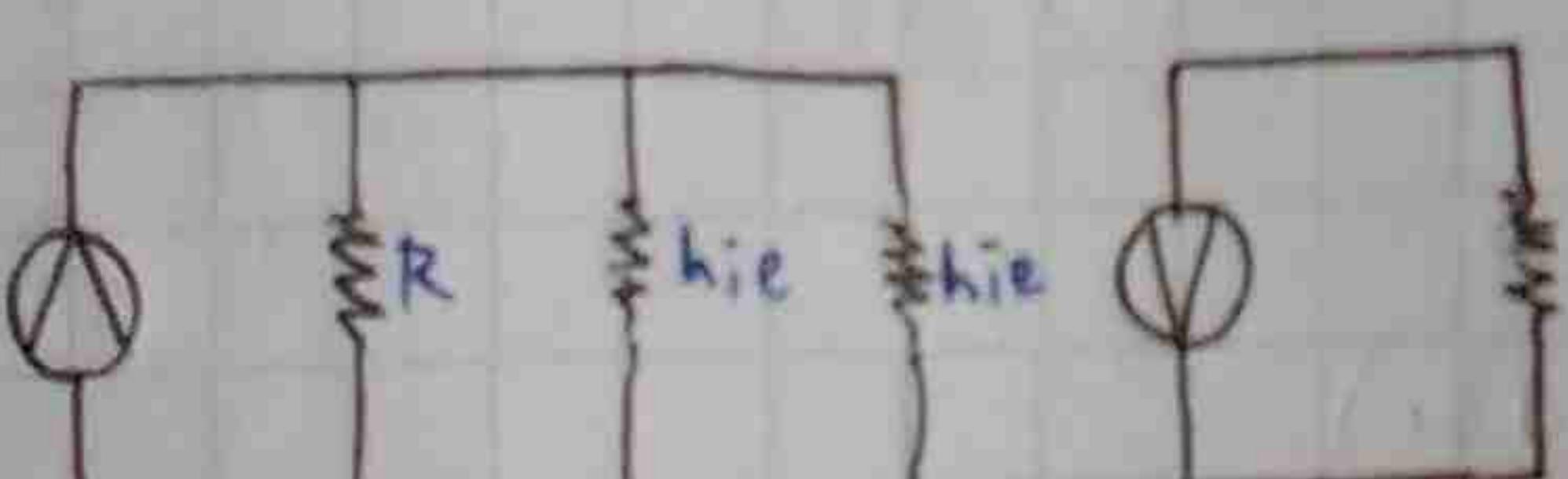
$$\frac{\Delta I_{CQ}}{\Delta T} = \frac{K}{R}$$

Espejo de corriente porque I_B es el mismo a I_{B1} y I_{B2} son iguales

Si $\beta \gg 2$

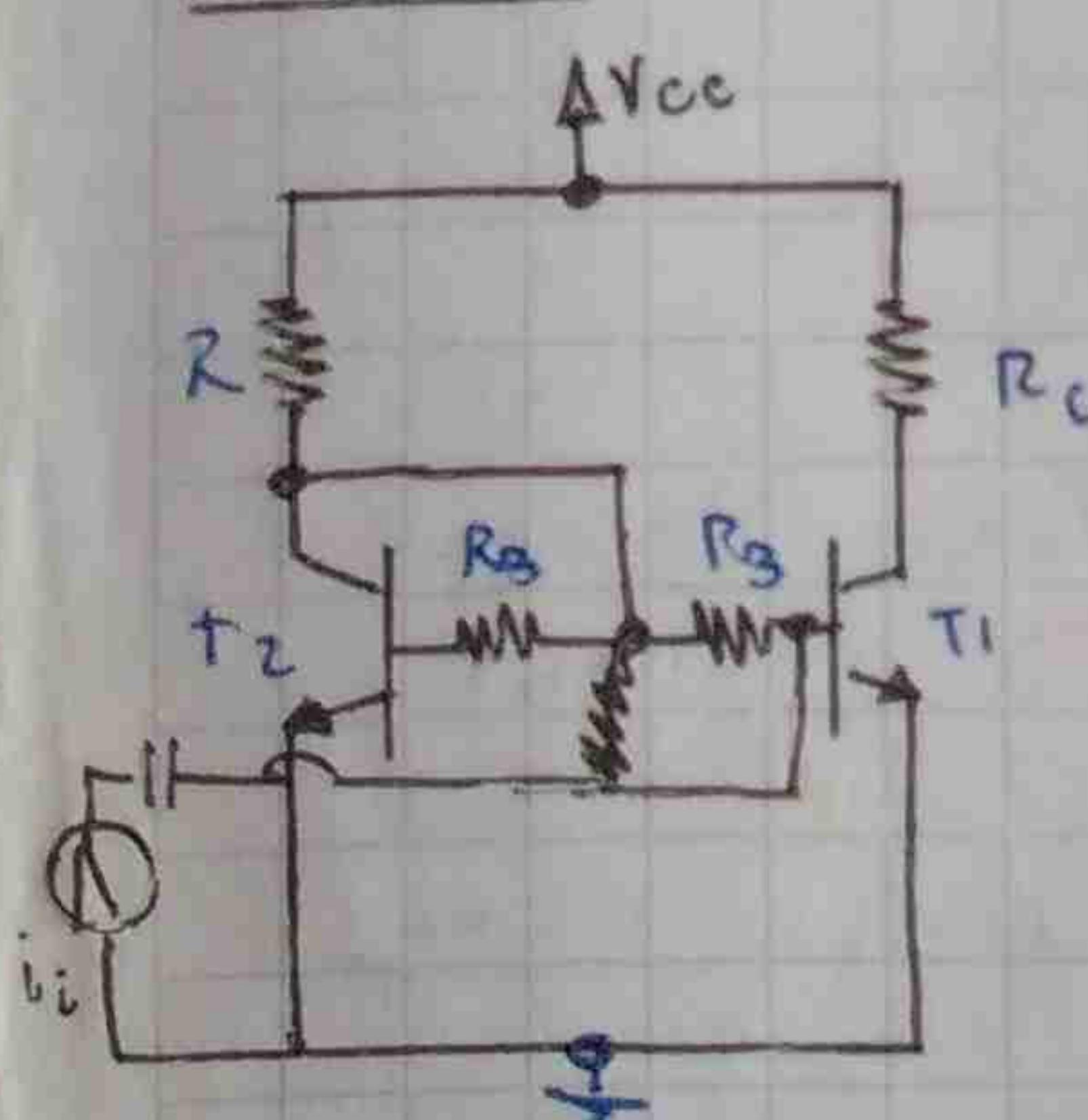
$$I_{CQ} = \frac{V_{CC} - V_{BE}}{R + R_E}$$

$$\frac{\Delta I_{CQ}}{\Delta T} = \frac{K}{R + R_E}$$



$$\left. \begin{array}{l} R \gg h_{ie} \\ i_L = z i_b \end{array} \right\} A_i = \frac{i_L}{i_b} \frac{i_b}{i_i} = \frac{h_{fe}}{z}$$

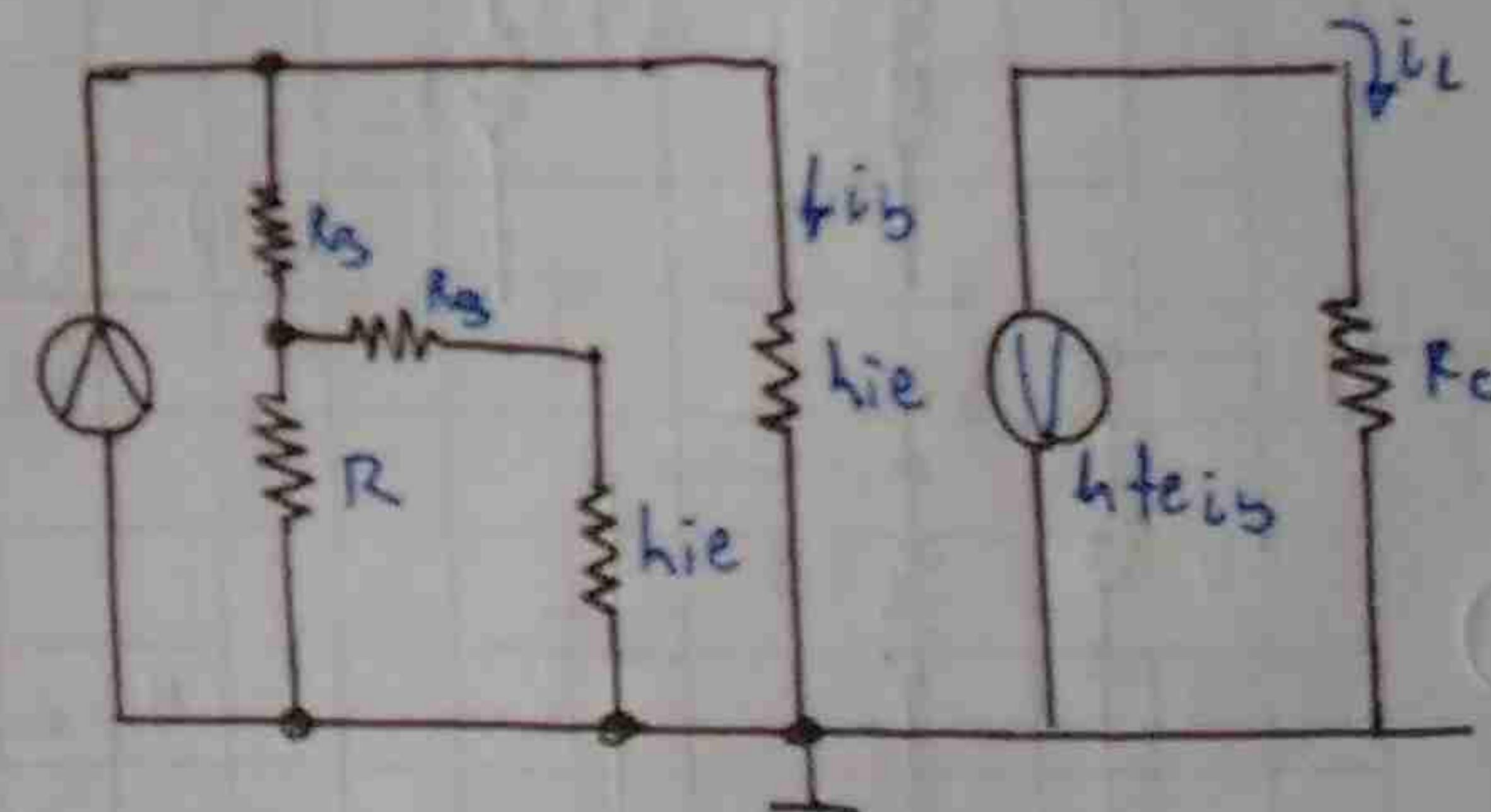
Mejora



$$V_{CC} = \left(I_{CQ} + 2 \frac{I_{CQ}}{\beta} \right) R + \frac{I_{CQ}}{\beta} R_B + V_{BE}$$

$$I_{CQ} = \frac{V_{CC} - V_{BE}}{\left(\frac{\beta + 2}{\beta} R + \frac{R_B}{\beta} \right)}$$

Si $\frac{R_B}{\beta} \ll R$ igual que antes.



$$A_i = h_{fe}$$

$$R_B \gg h_{ie}$$

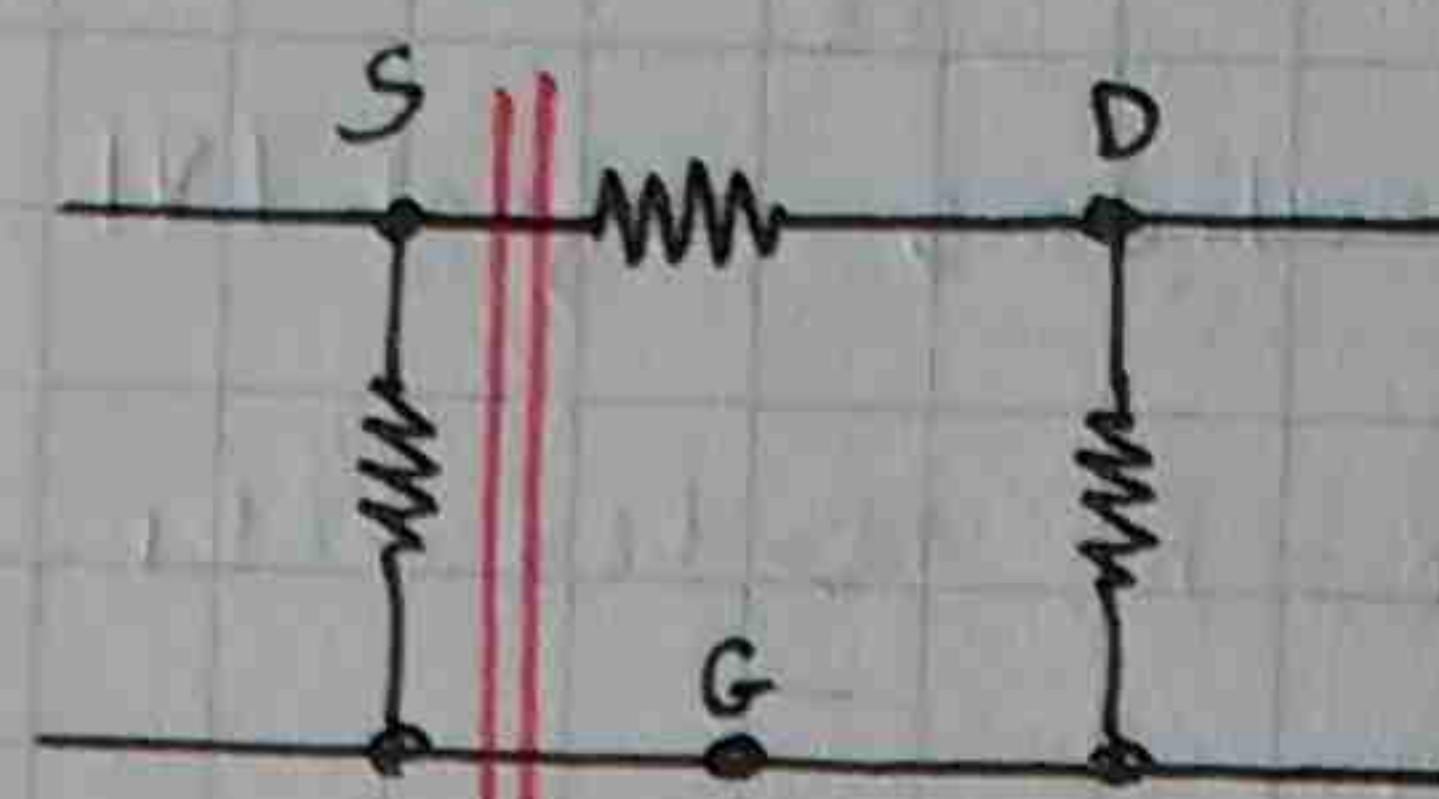
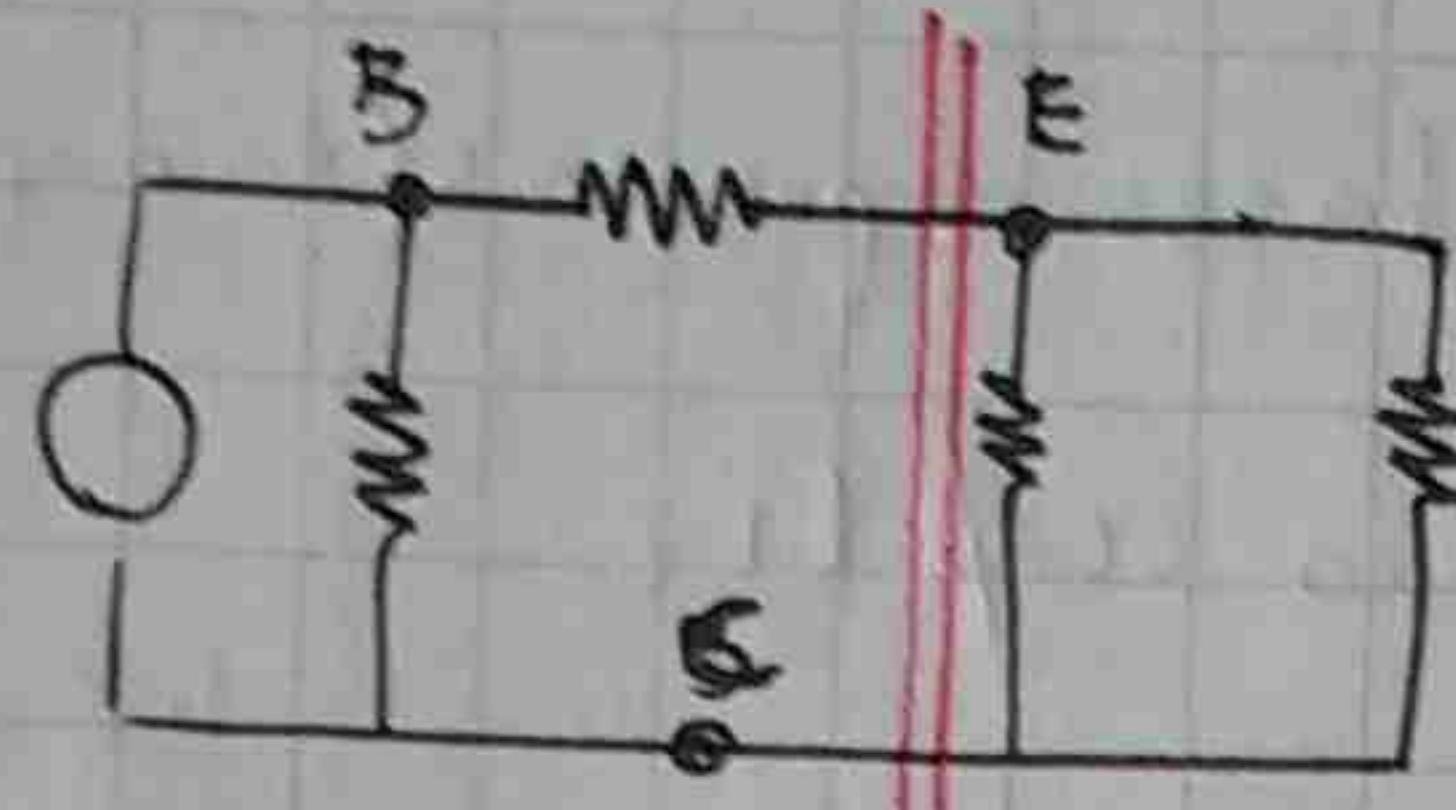
(3)

Transistores Bipolares \rightarrow retl imp \rightarrow E-B

$i_e \gg i_b$

$$r = c_{te} = \frac{i}{R}$$

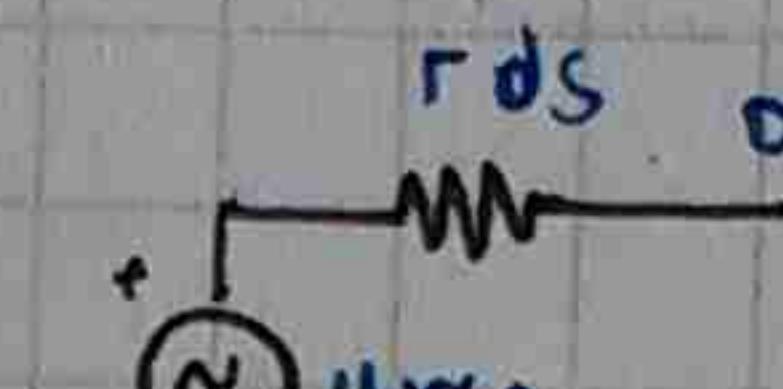
h_{fe}



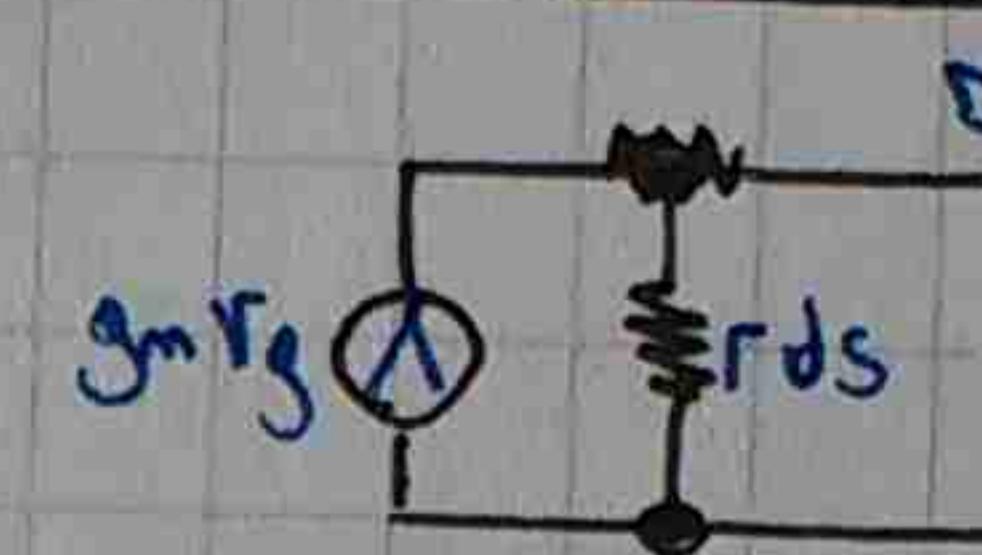
Transistor efecto campo

$$\text{MOSFET} \quad i_D = I_{DSS} \left(1 + \frac{V_{GS}}{V_{PO}} \right)^2$$

$$\text{JFET} \quad i_D = I_{DSS} \left[1 + \frac{3V_{GS}}{V_{PO}} + 2\left(-\frac{V_{GS}}{V_{PO}}\right)^{3/2} \right]$$



Nrg



$gmrg$

$$M = rds \ gm$$

Parámetros

$$rgs = \frac{r_{gs}}{ig} = \infty$$

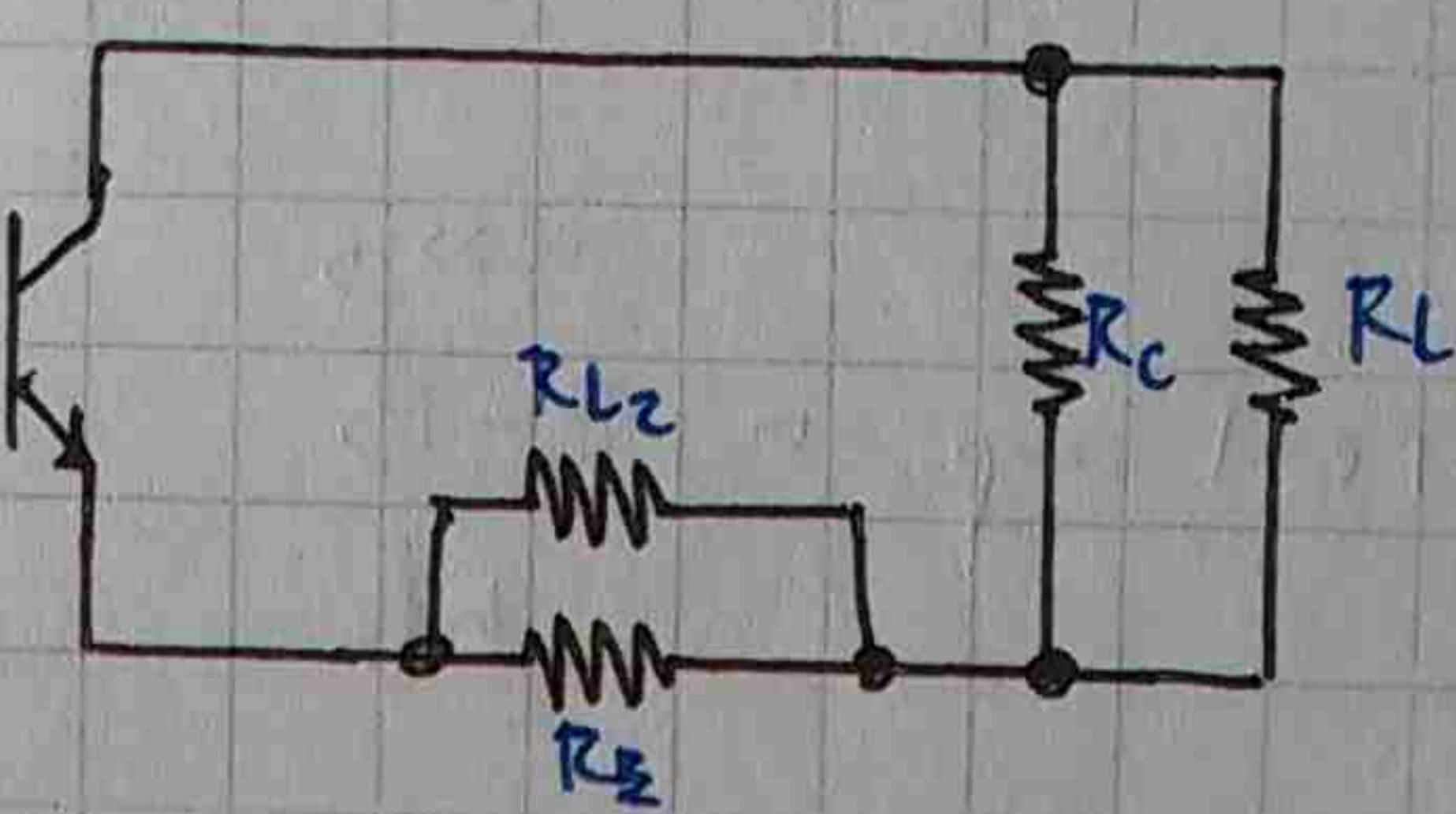
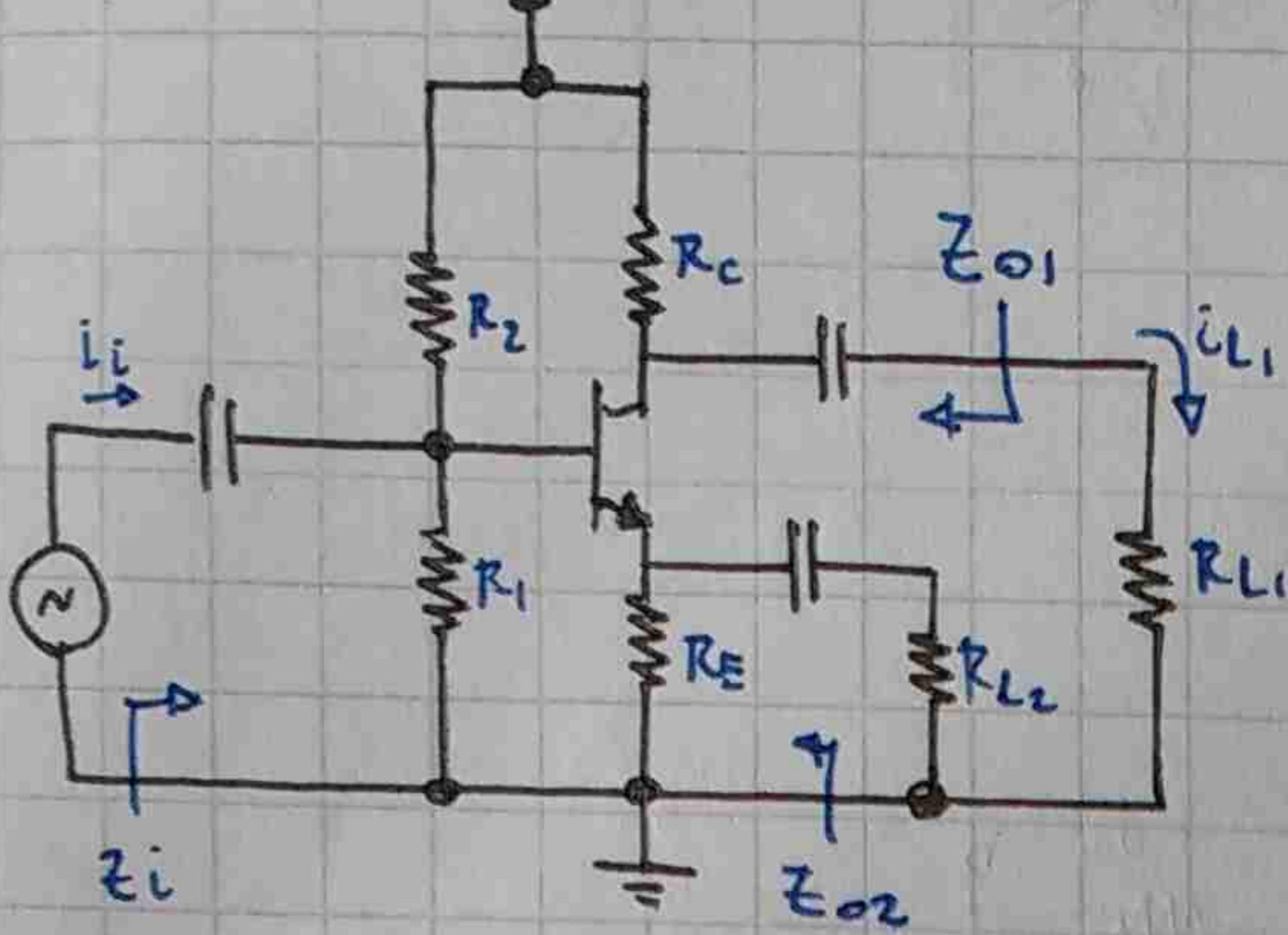
$$N = \frac{r_{ds}}{V_{GS}} \Big|_{I_{DS}}$$

$$r_{ds} = \frac{V_{DS}}{i_D} \Big|_{V_{GS}=0}$$

$$gm = \frac{i_D}{V_{GS}} \Big|_Q$$

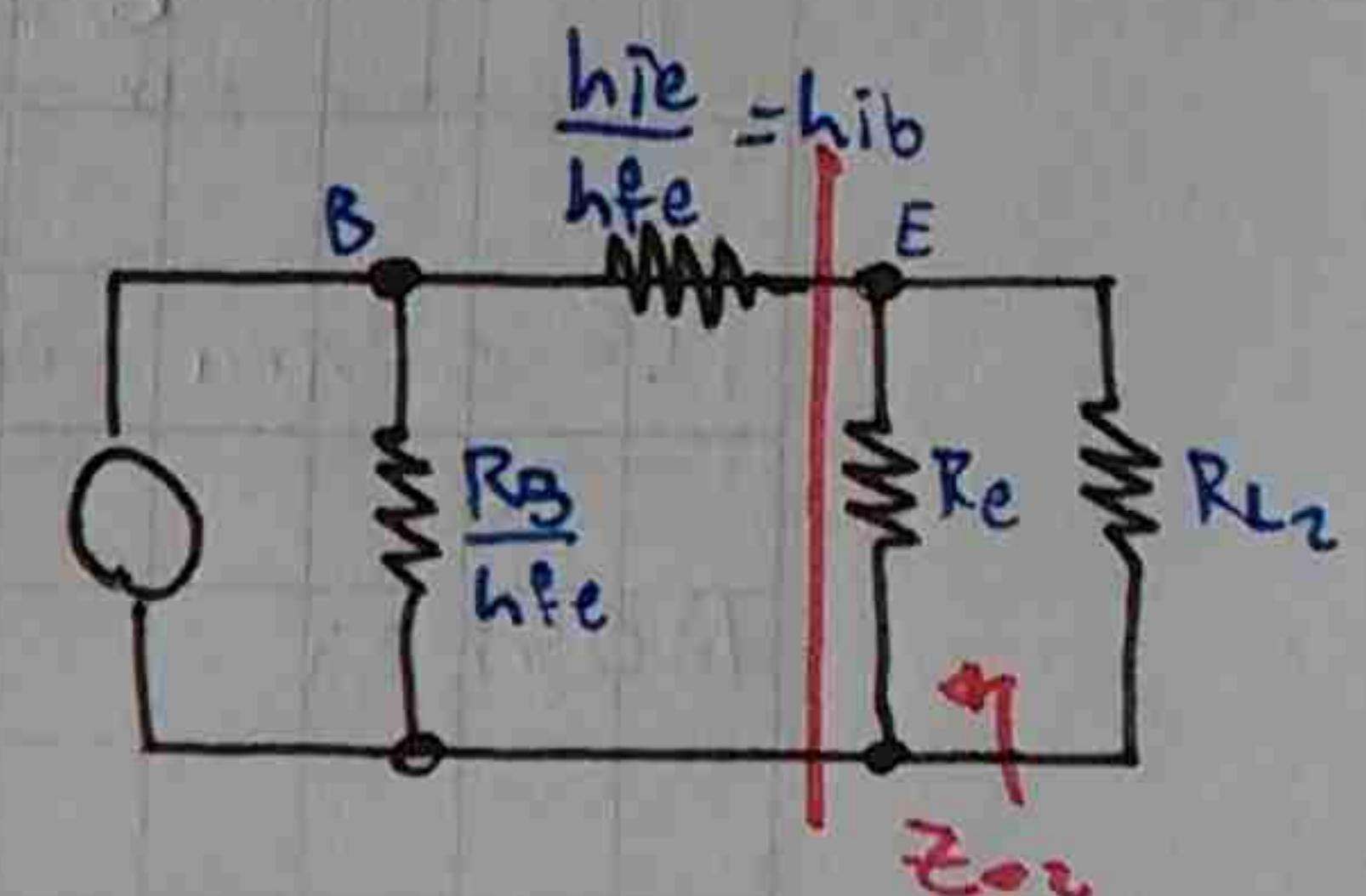
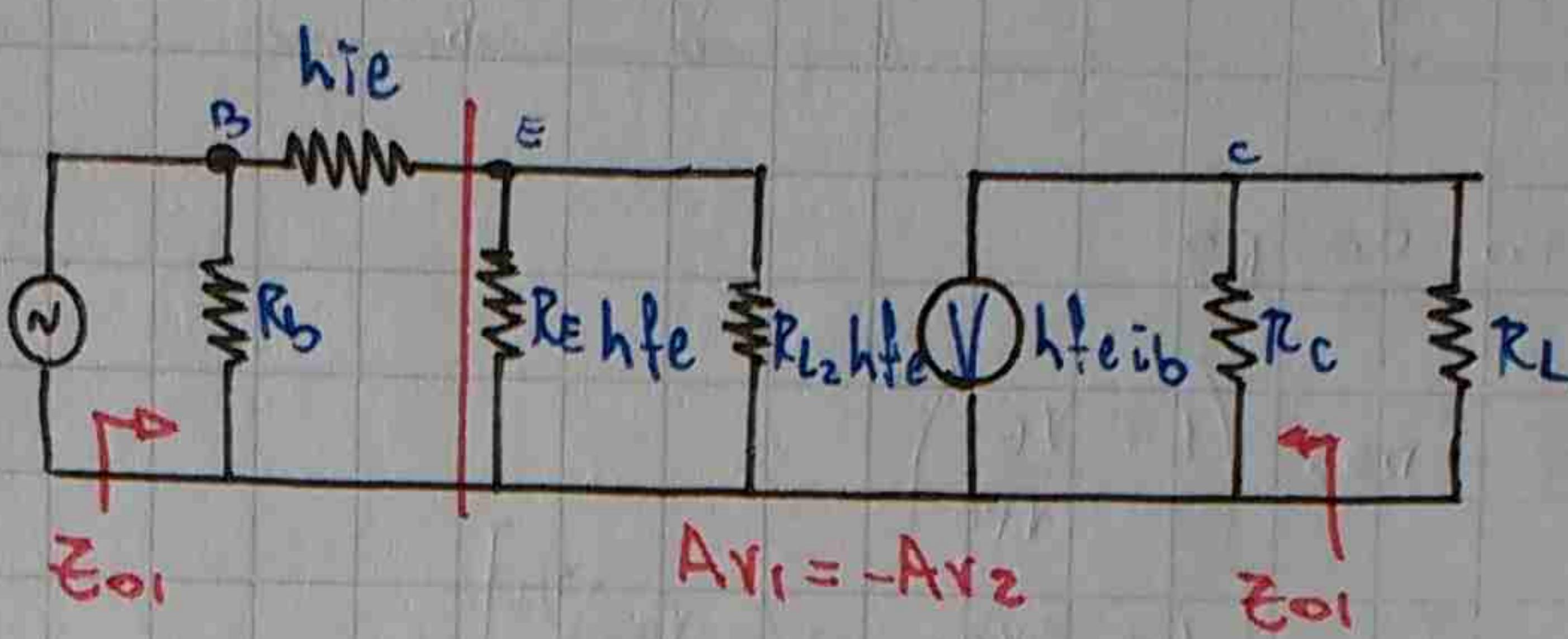
Inversor de fase.

Bipolar



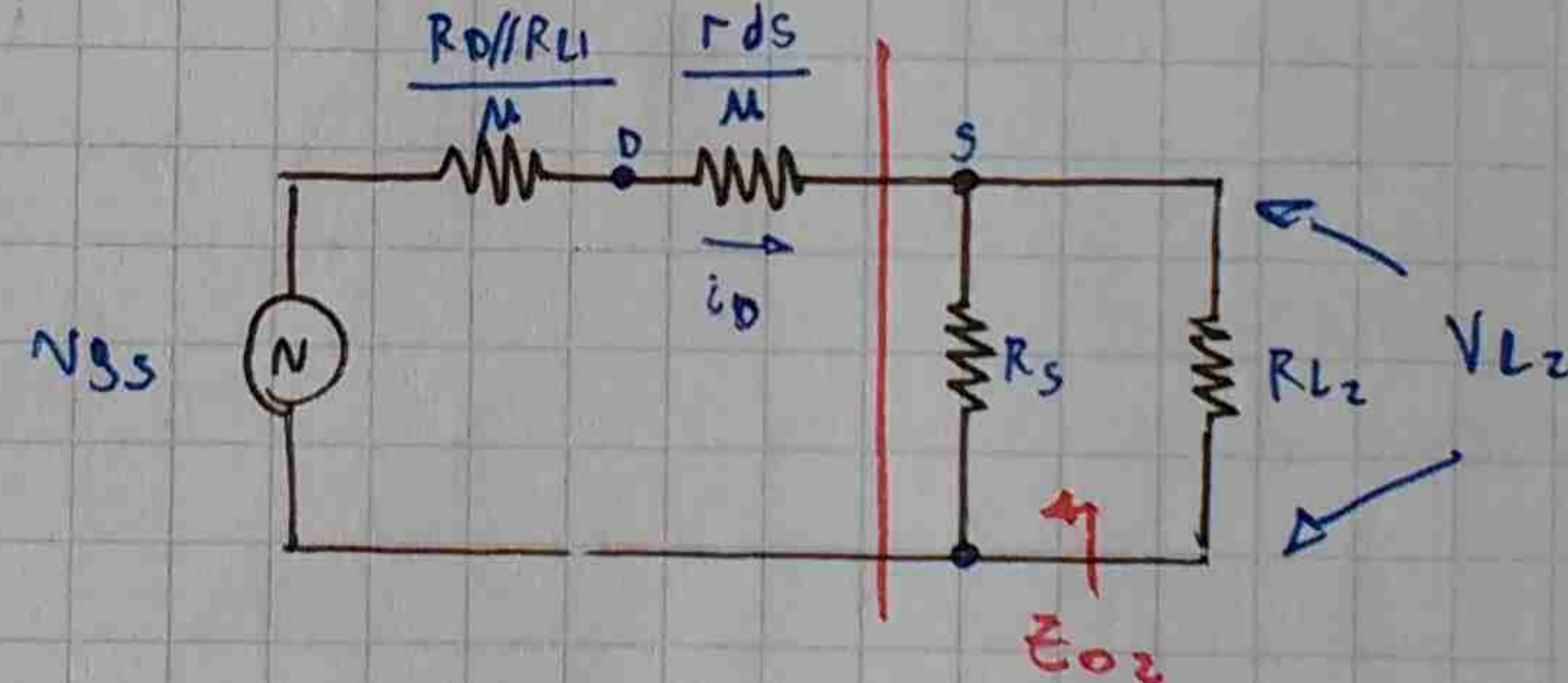
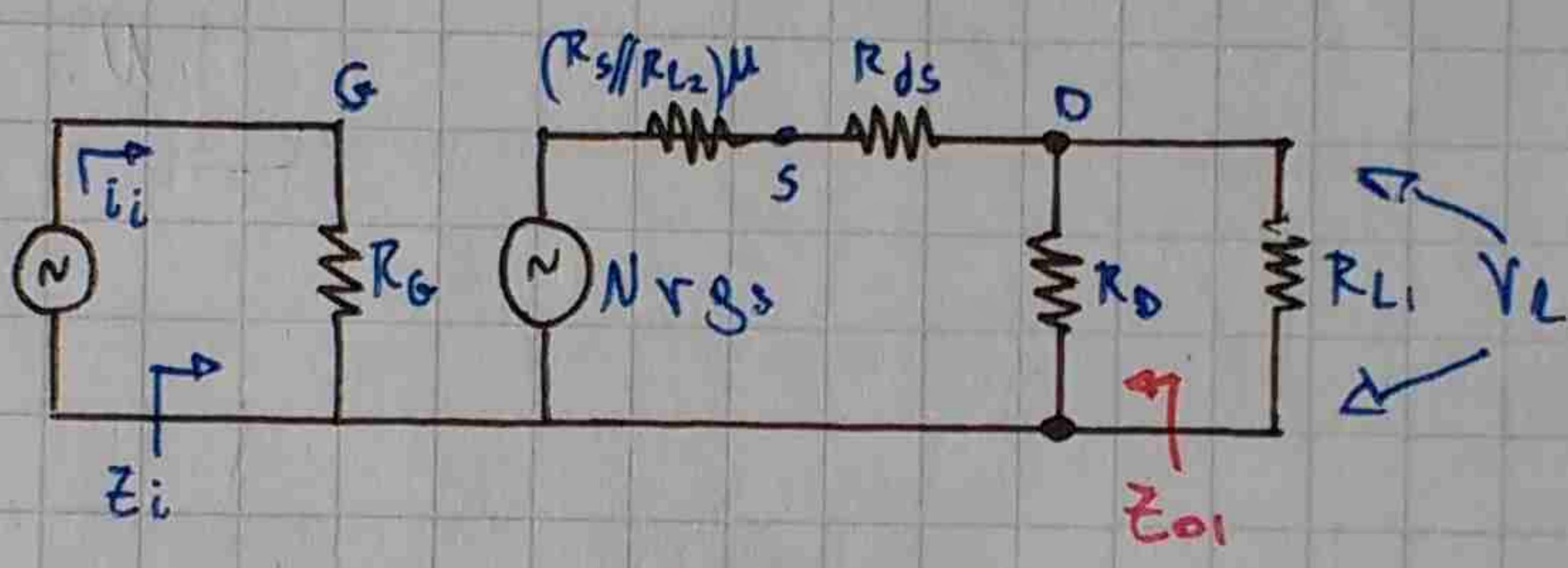
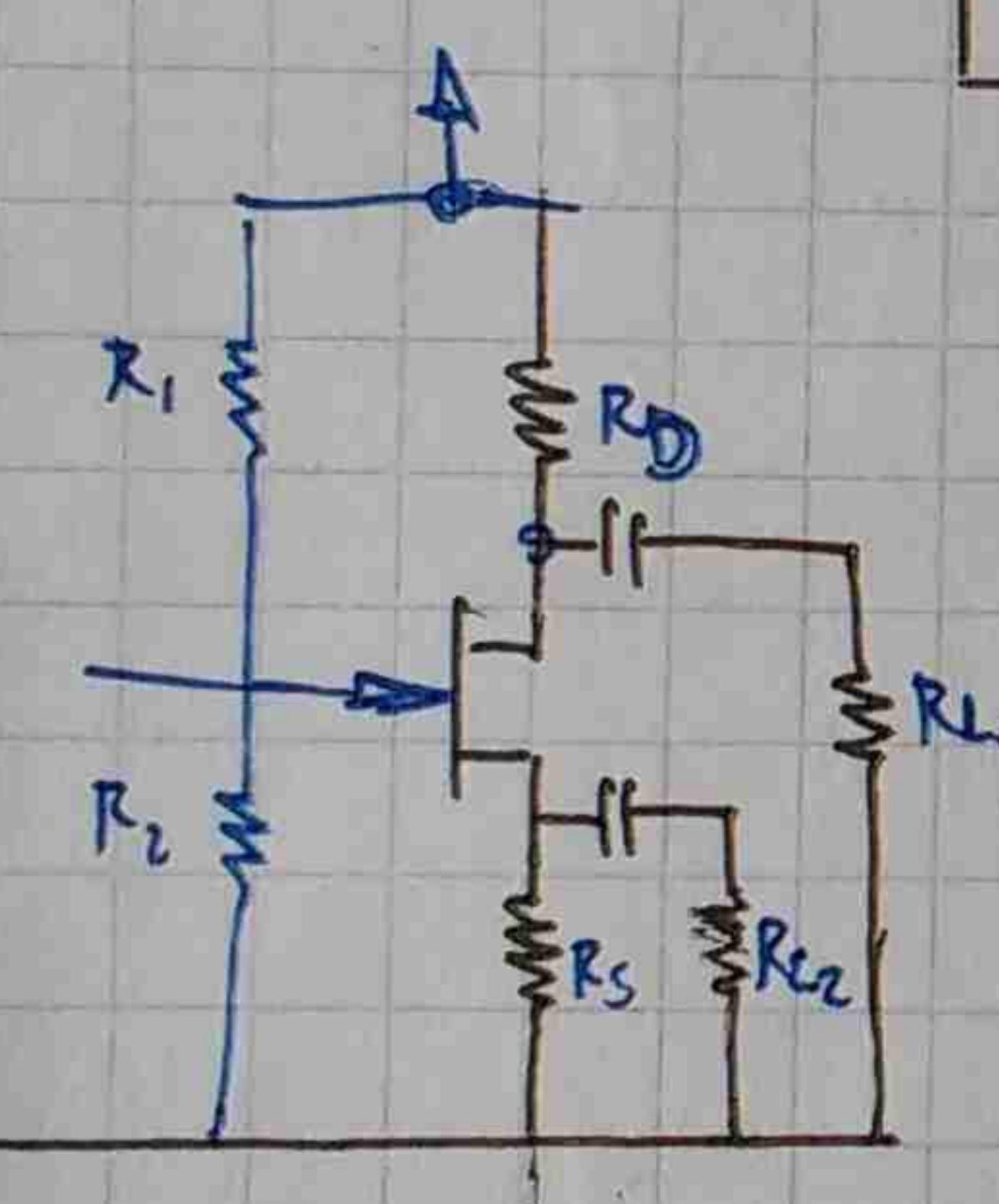
$$R_C \parallel R_{L1} = R_{L2} \parallel R_E$$

- Dos salidas, igual $|V|$ pero fases opuestas (No amplifica tensión)
- Si $R_C = R_E \Rightarrow i_{L2} = i_{L1}$ // sino $i_{L2} \neq i_{L1}$

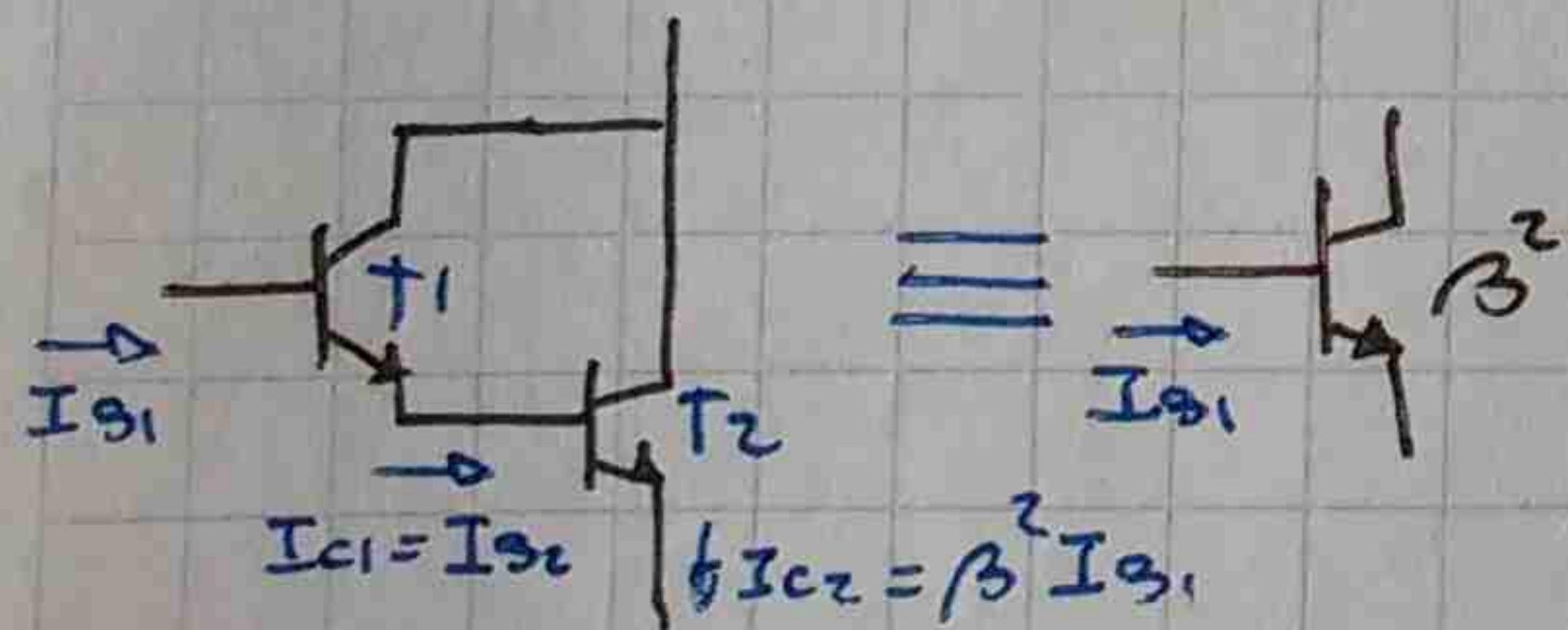


FET

Mismo circuito.



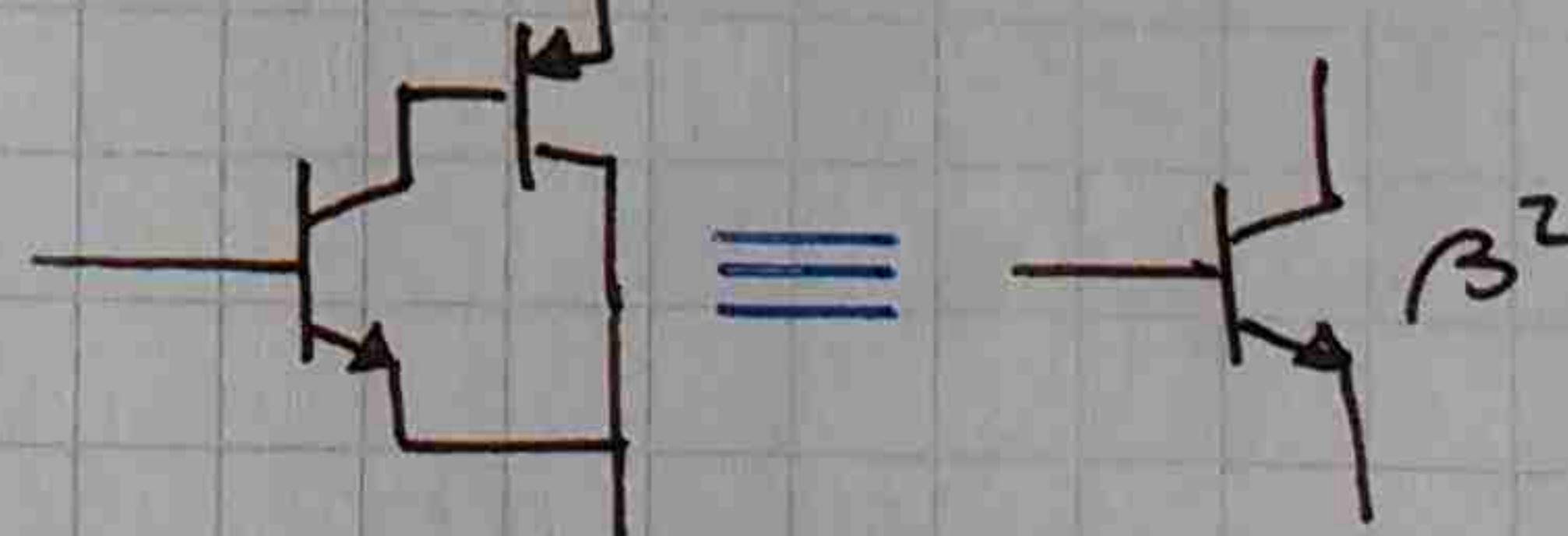
Par Darlington



Los dos transistores pueden ser iguales. Siempre que T1 sea igual a T2

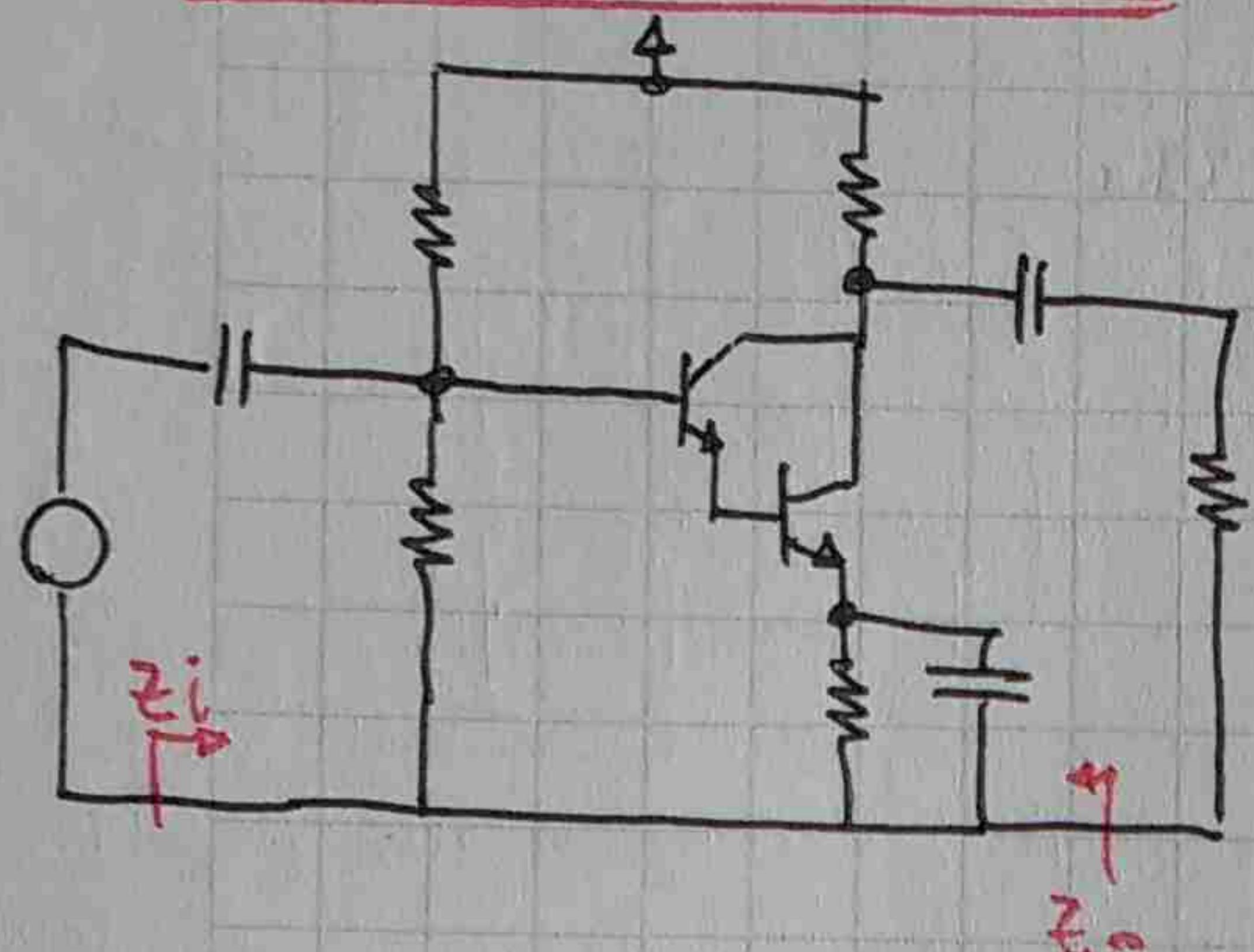
Si son iguales $T_1 + T_2$ trabaja al doble.

Par Complementario



9

Salida por Colector



$$\beta_1 = \beta_2 \\ h_{fe1} = h_{fe2}$$

$$= C_C = E_C \Rightarrow$$

Diseño

$$R_B = \frac{\beta^2 R_E}{10}$$

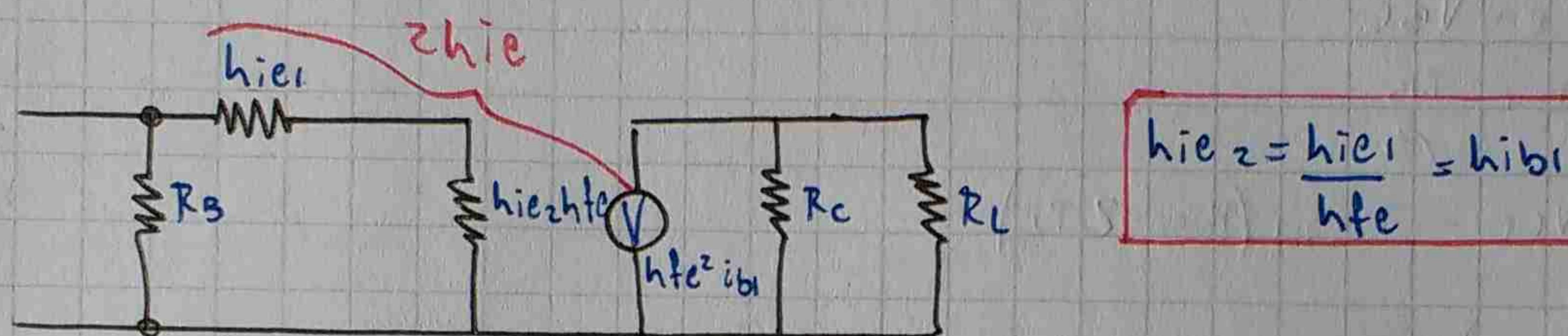
$$I_{CQ2} = \frac{V_{BB} - V_{BE}}{R_E + \frac{R_B}{\beta^2}}$$

$$I_{BQ2} = \frac{I_{CQ2}}{\beta} \approx I_{CQ1}$$

$$V_{CEQ2} = V_{CC} - I_{CQ2}(R_C + R_E)$$

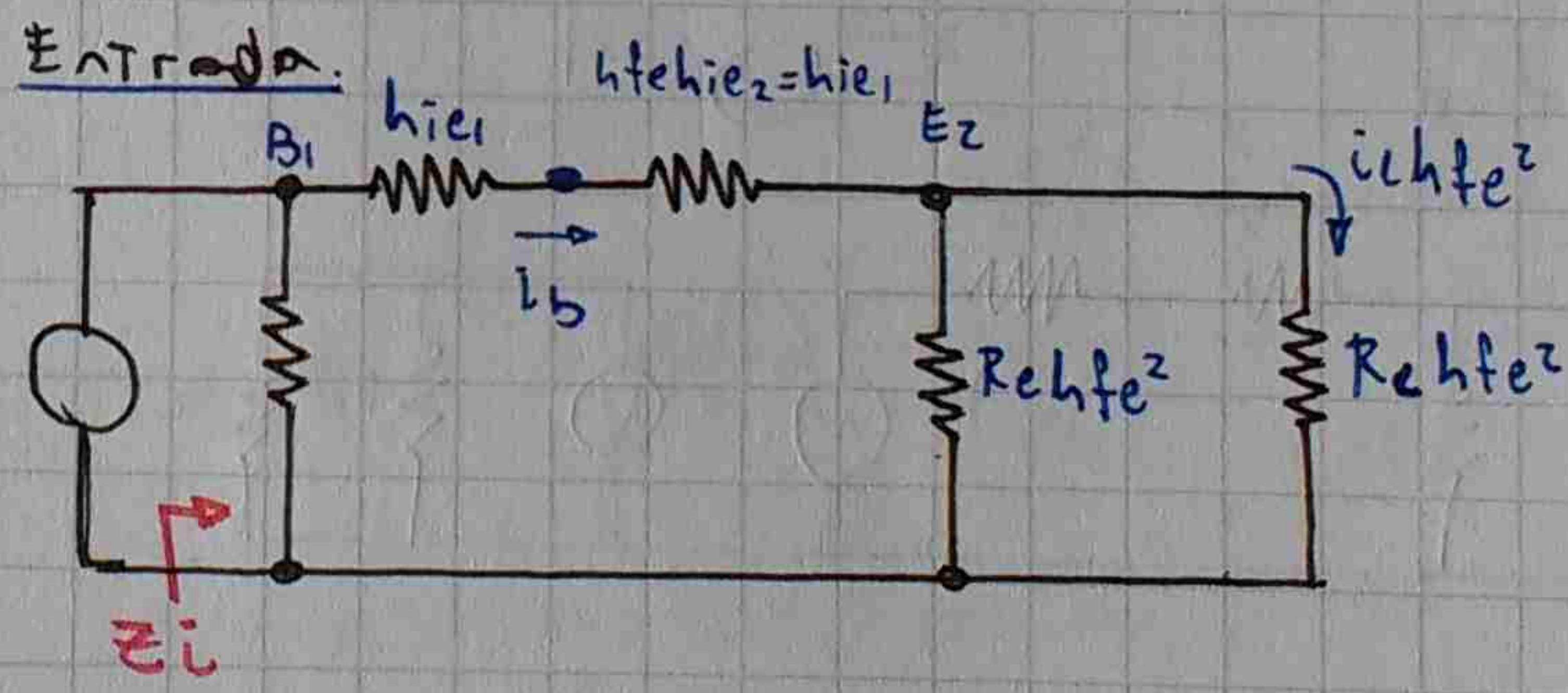
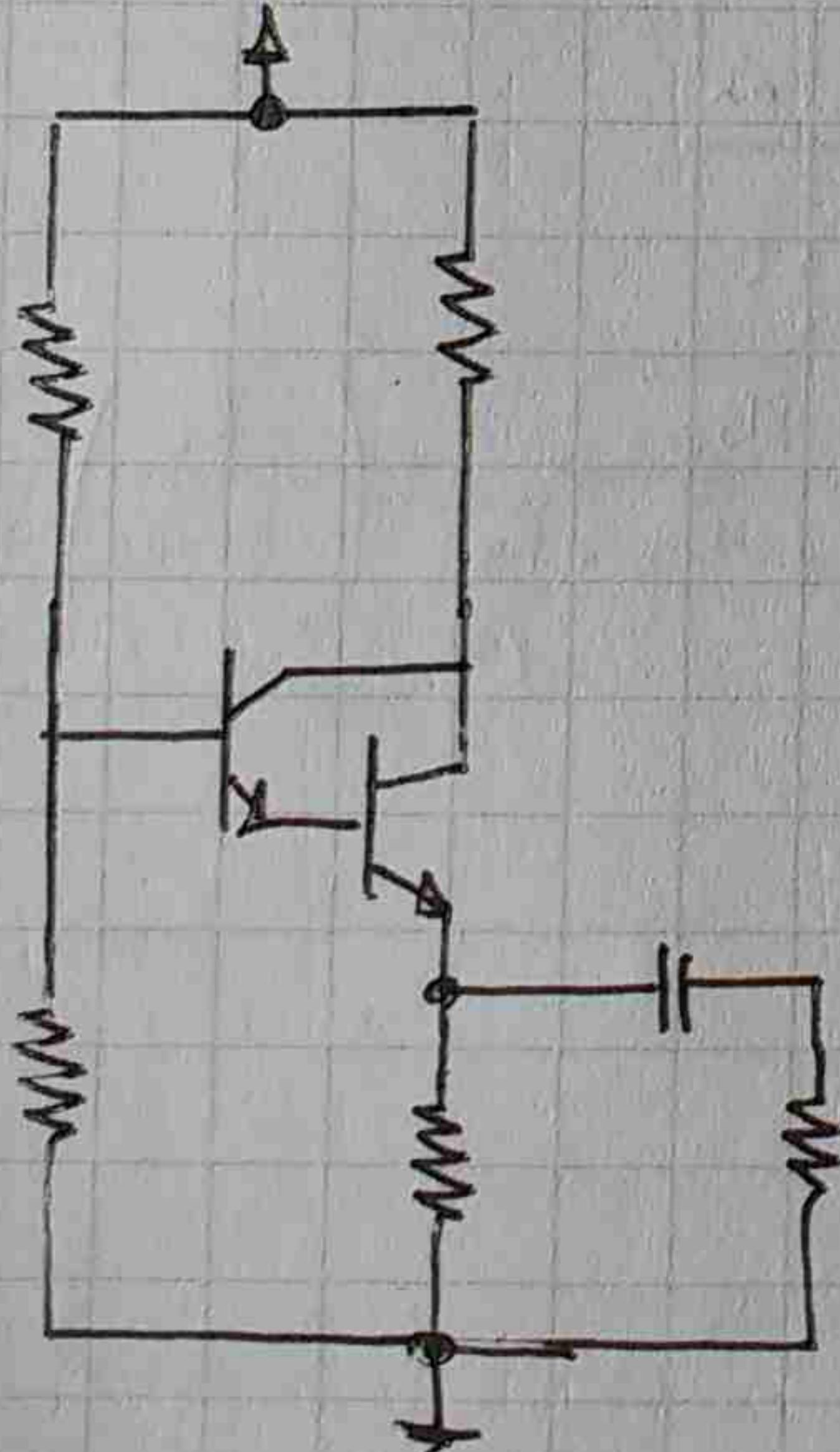
$$V_{CEQ1} = V_{CEQ2} - V_{BE}$$

$$V_{BB} = I_{CQ2} \left(\frac{R_B}{\beta^2} + R_E \right) + 2V_{BE}$$

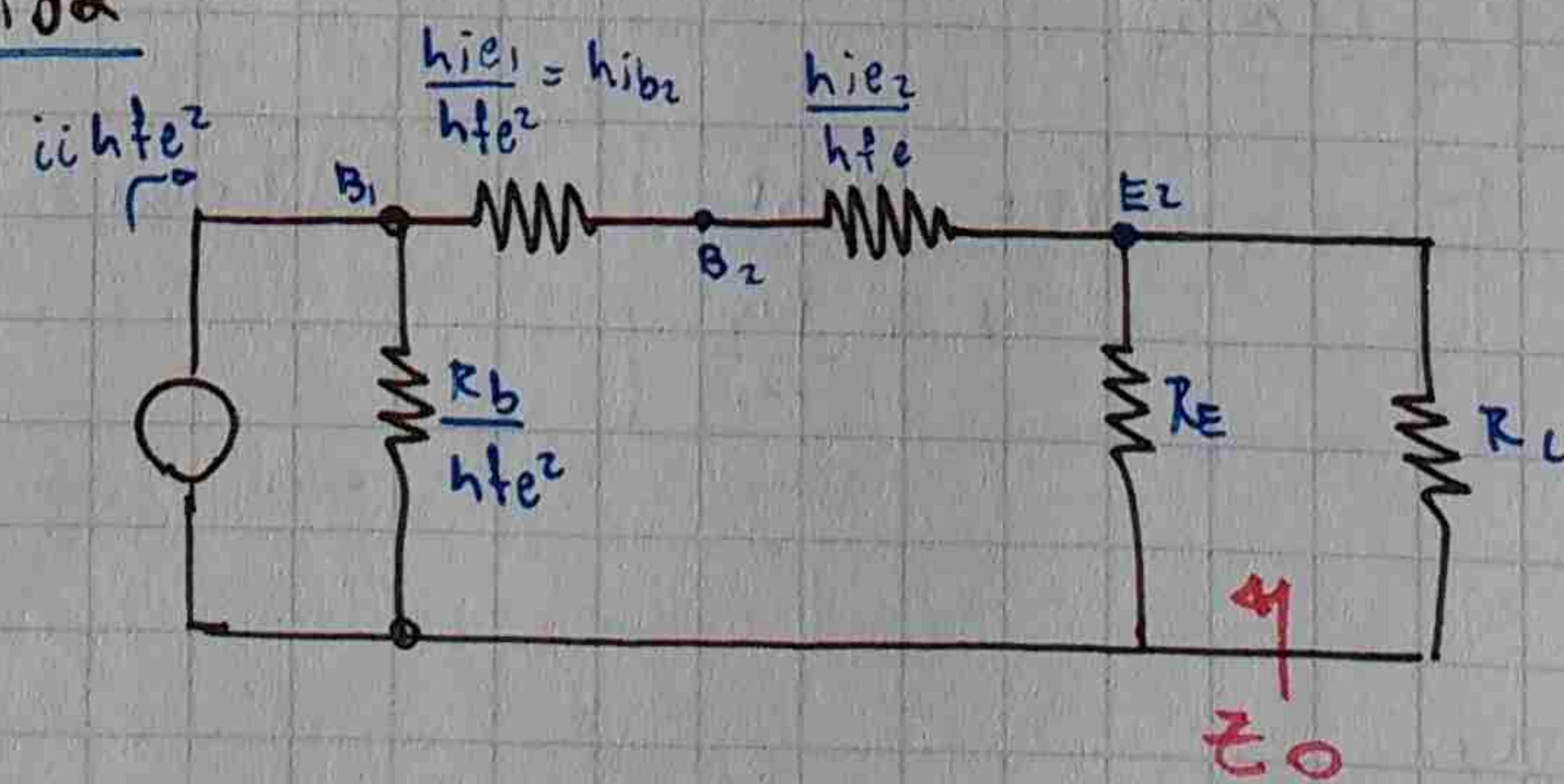


Al Agregar un Transistor (PD) ahora desde la P_1 la impedancia aumenta en un factor de z_{hfe}

Salida Par eíster



Salida

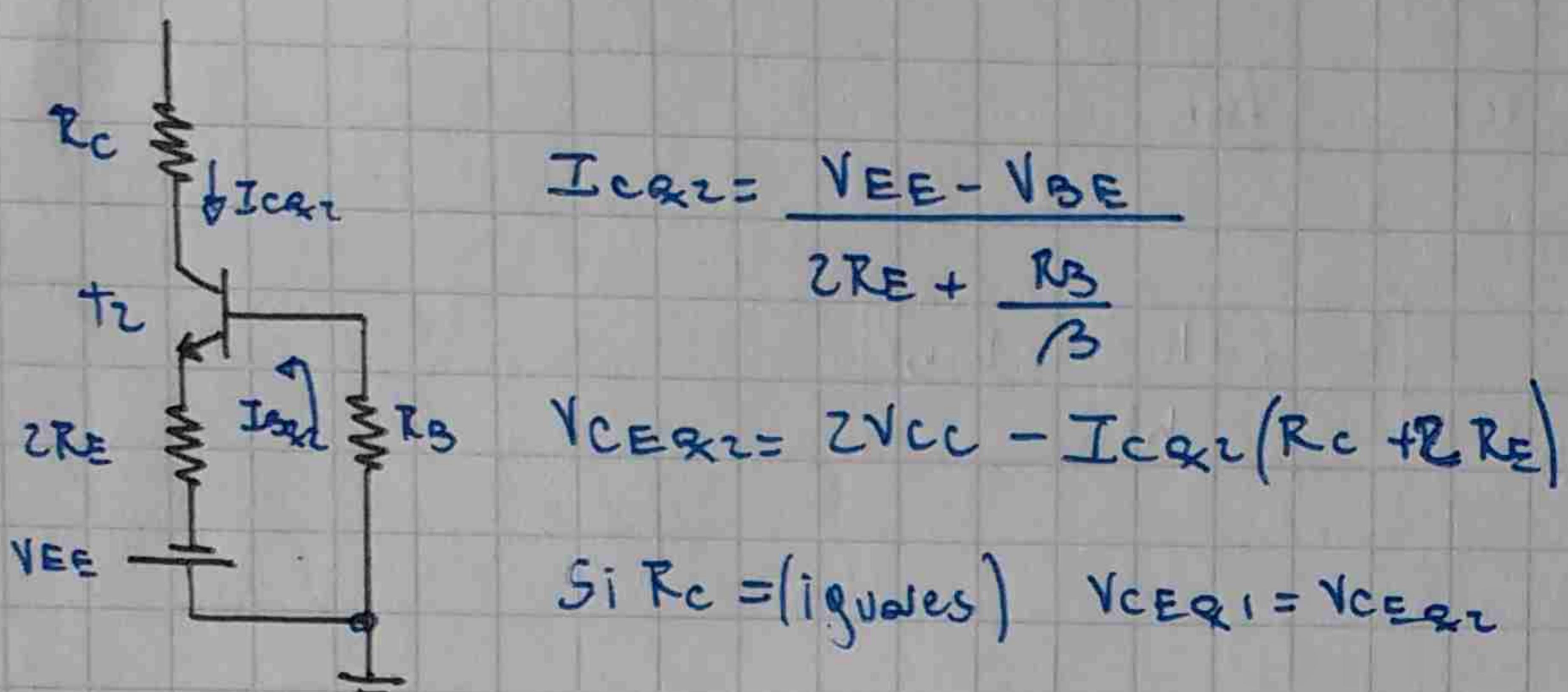
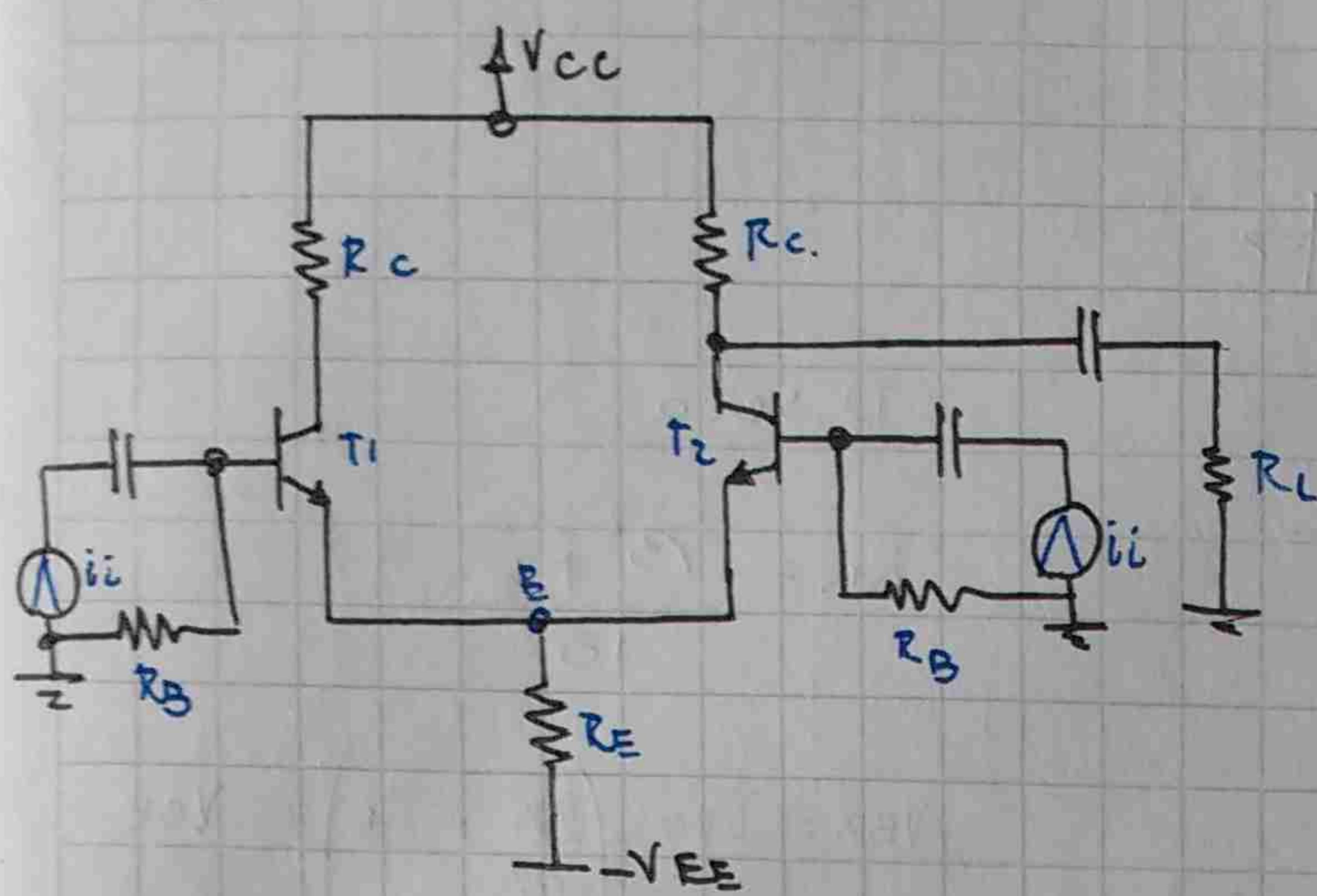


Amplificador Diferencial

$$I_{CQ1} = I_{CQ2}$$

$$I_{RE} = I_{CQ1} + I_{CQ2} = 2I_{CQ1}$$

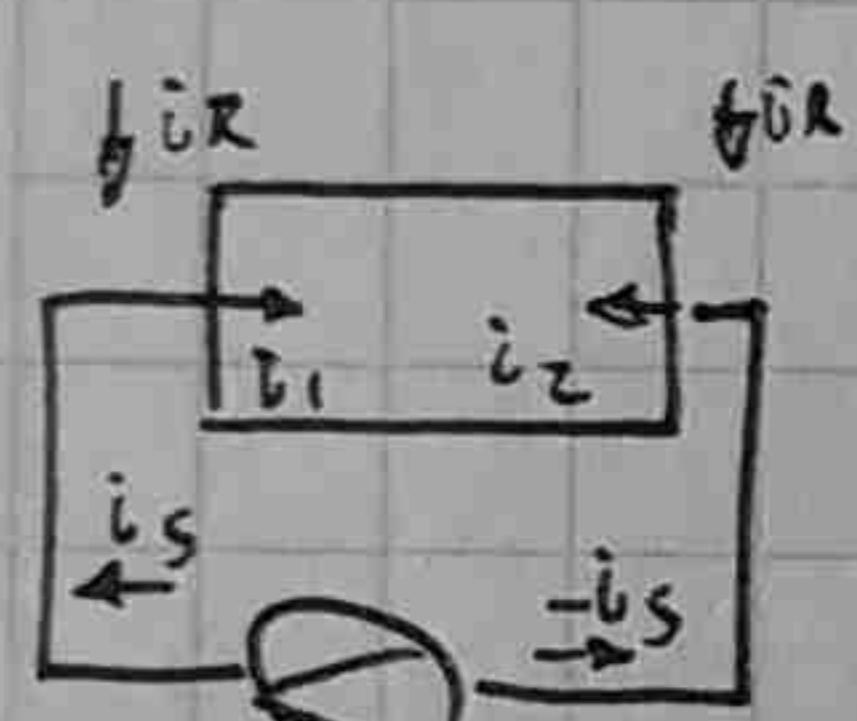
$$V_{RE} = 2I_{CQ2} R_E = I_{CQ2} 2R_E$$



$$\text{Modo Co-um. } i_C = \frac{i_1 + i_2}{2}$$

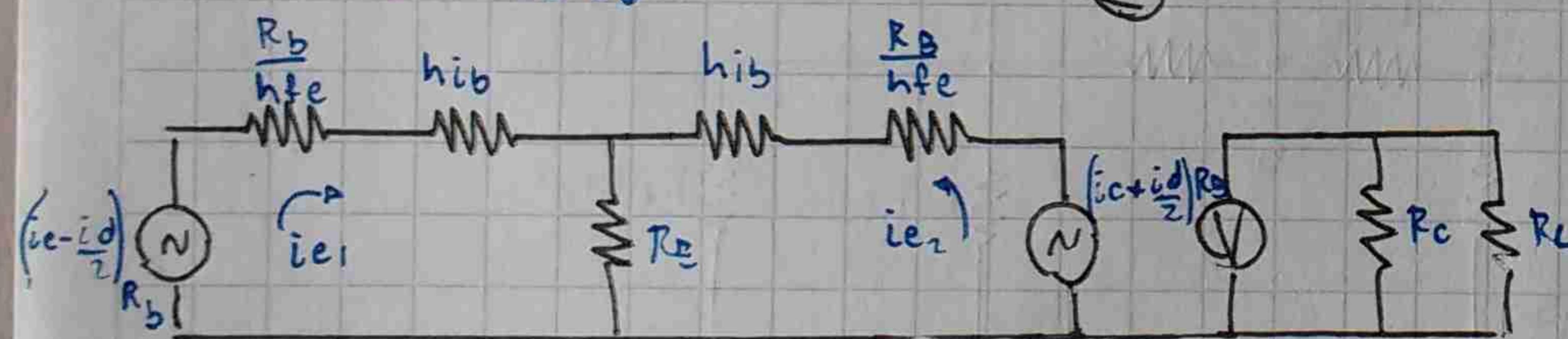
$$\text{Modo diferencial } i_d = i_2 - i_1$$

$$i_L = A_{CIC} i_C + A_{CID}$$



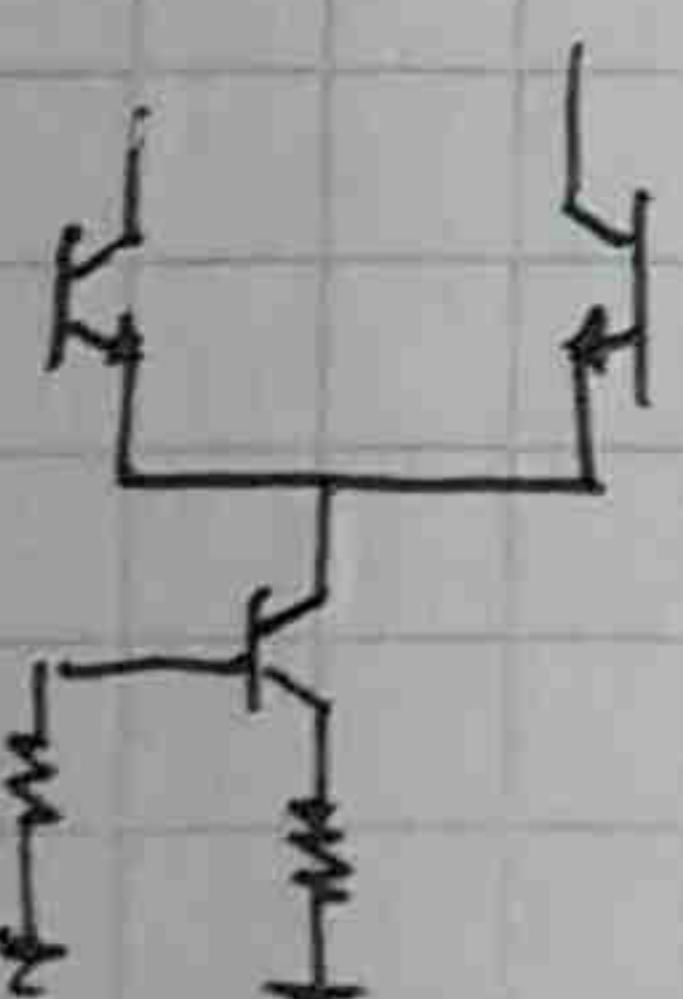
$$\left. \begin{array}{l} i_C = i_T \\ i_d = -2i_S \end{array} \right\} \begin{array}{l} i_1 = i_C - \frac{i_d}{2} \\ i_2 = i_C + \frac{i_d}{2} \end{array}$$

Por Superposición



$$i_L = \left(\frac{-R_C}{R_C + R_L} \right) \frac{R_b}{h_{FE} + h_{IB} + \frac{R_g}{\beta}} i_1 + \left(\frac{-R_C}{R_C + R_L} \right) \frac{R_b}{h_{FE} + \frac{R_g}{\beta}} i_2$$

Agregando un 3º Trans.



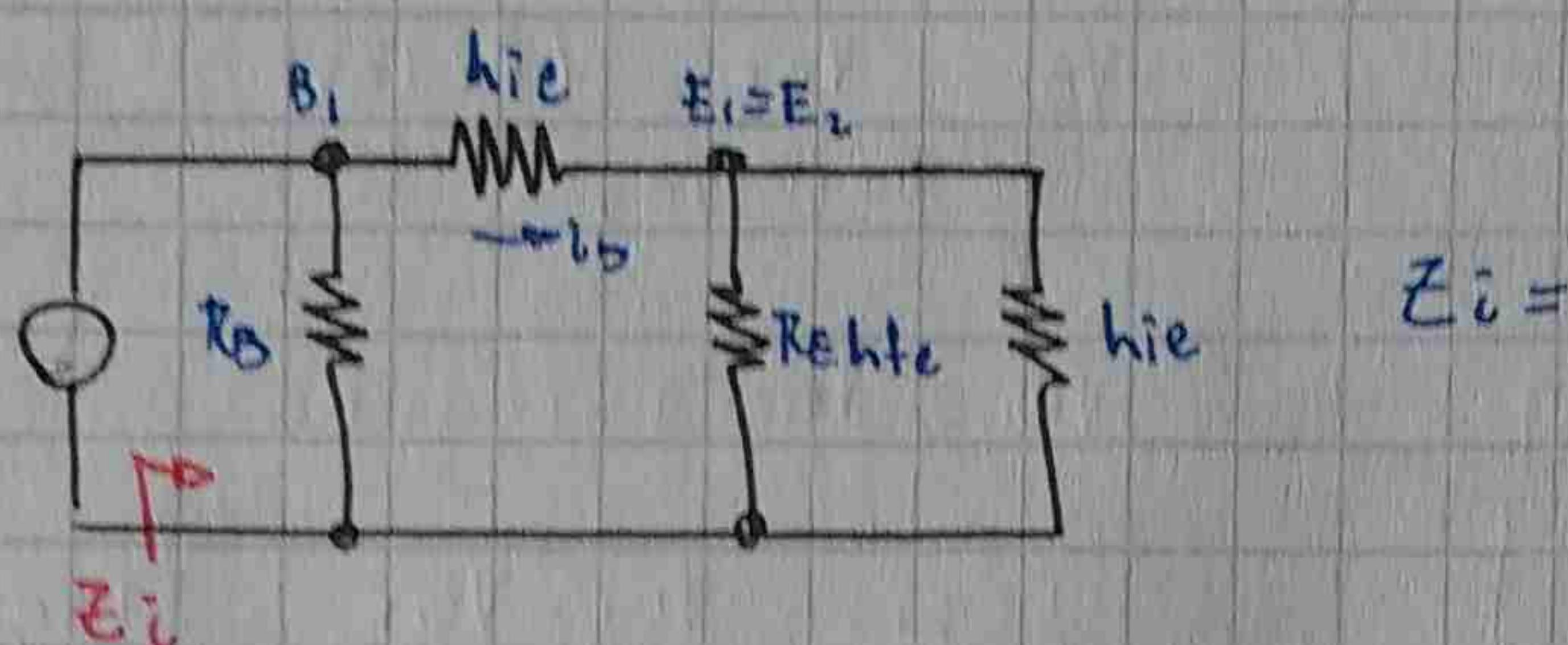
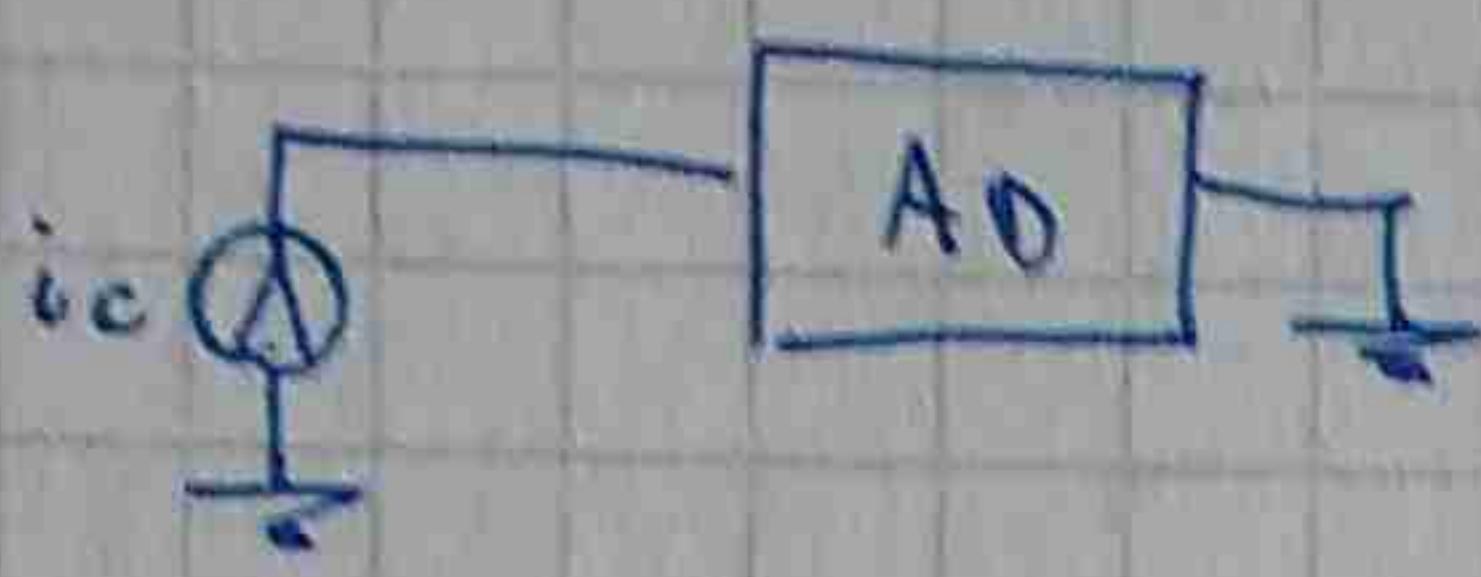
$$I_{CQ3} = \frac{V_{EE} - V_{BE}}{R_E + \frac{R_g}{\beta}}$$

$$I_{CQ1} = I_{CQ2}$$

Salida Si-étrica

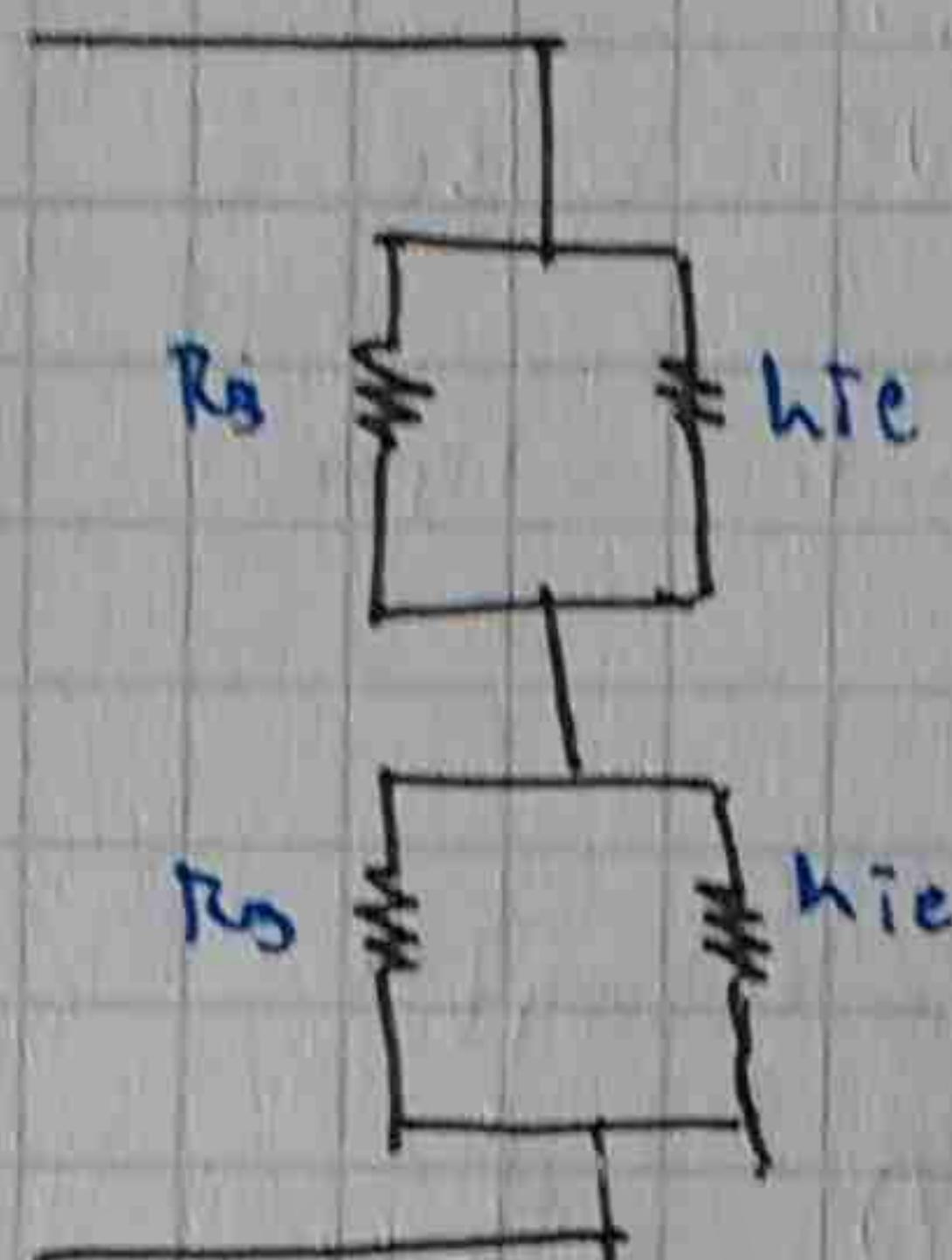
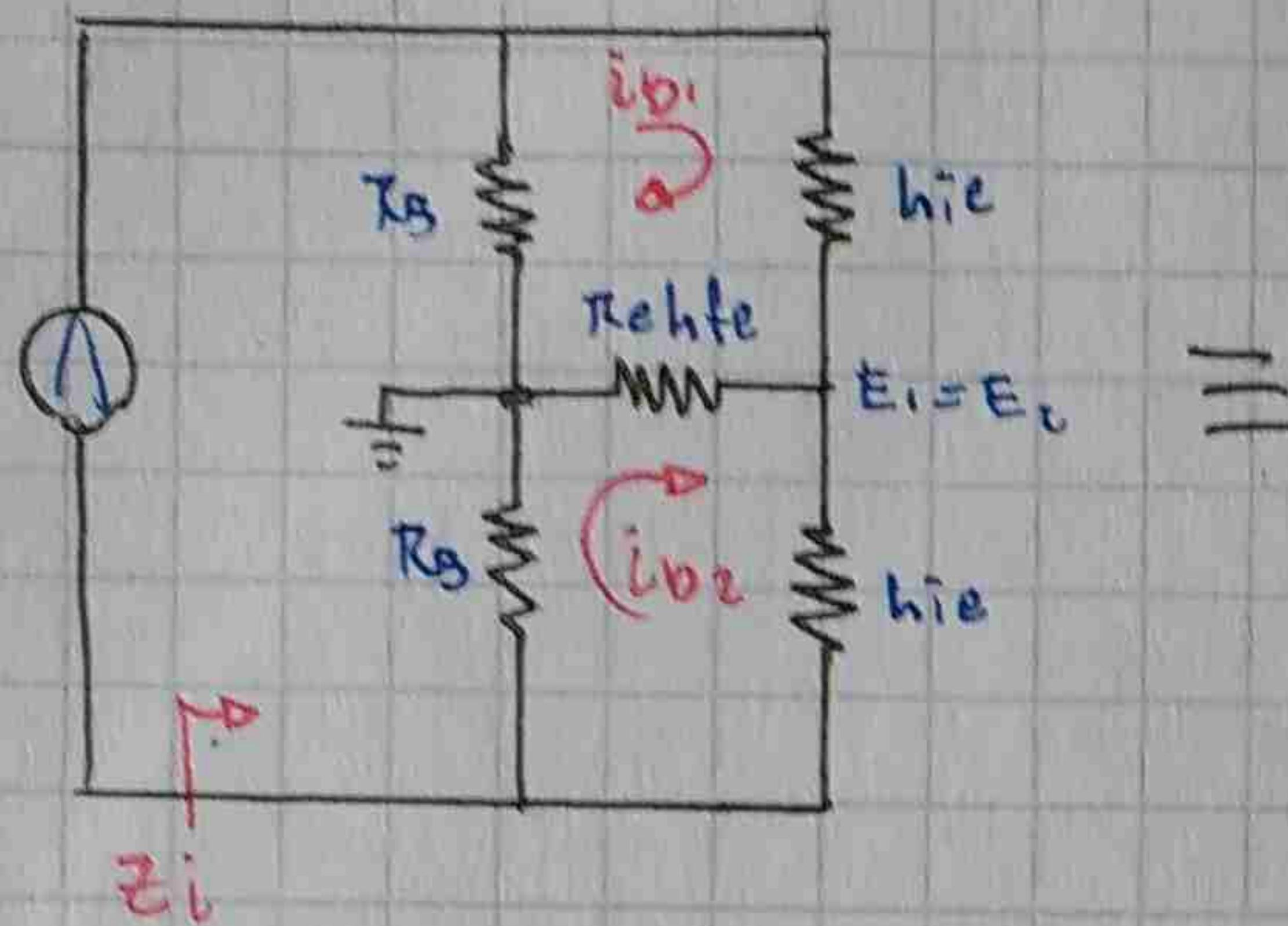
I - impedancia entrada:

Asimétrica.



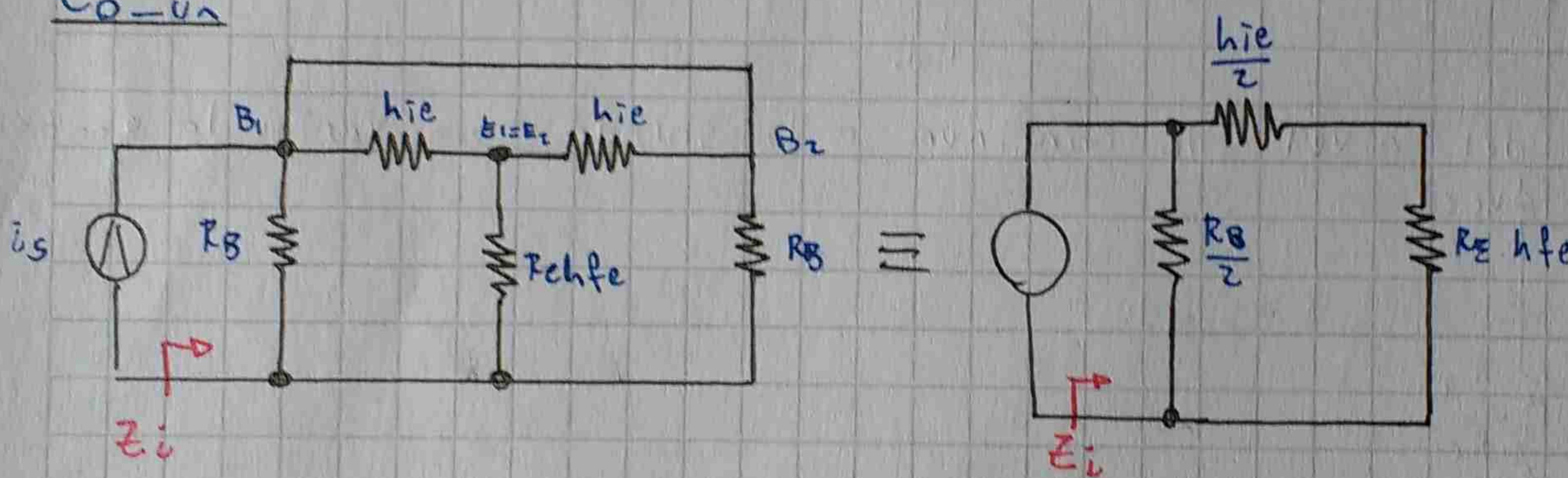
$$Z_i =$$

Simétrica



$$Z_i = 2(h_{ie} \parallel R_B)$$

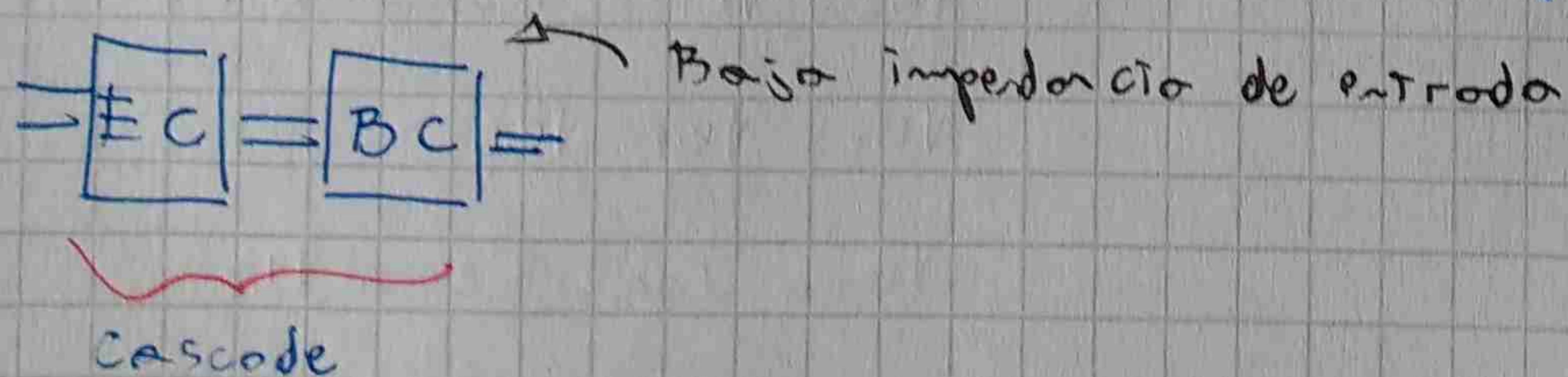
Co-ún

A - amplificador Cascode

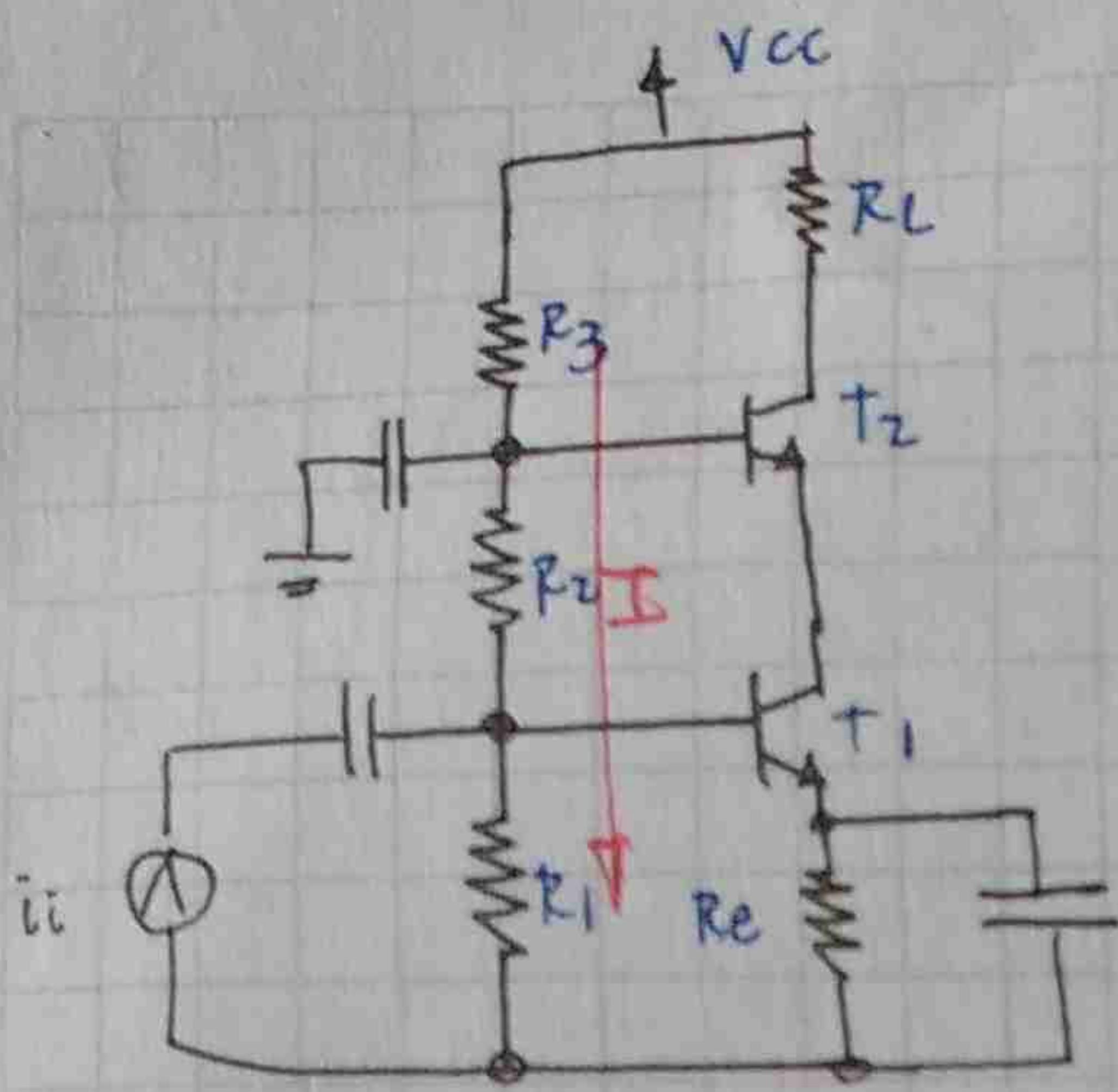
- Para evitar la disminución del ancho de banda debido a la redimensionación por el cap inter-electródico

$$C_M = C_{bc} (1 + g_m R_L)$$

$$C_M = f(R_L) \text{ etapa siguiente}$$



Baja impedancia de entrada



$$I \gg \begin{cases} i_{BQ1} \\ i_{BQ2} \end{cases}$$

$$V_{B2} = \frac{V_{CC}}{R_1 + R_2 + R_3} (R_1 + R_2)$$

$$V_{B1} = \frac{V_{B2}}{R_1 + R_2} \cdot R_1$$

$$V_{B1} = V_{BE} + I_{CQ1} R_E$$

$$I_{CQ1} = \frac{V_{B1} - V_{BE}}{R_E} = I_{CQ2}$$

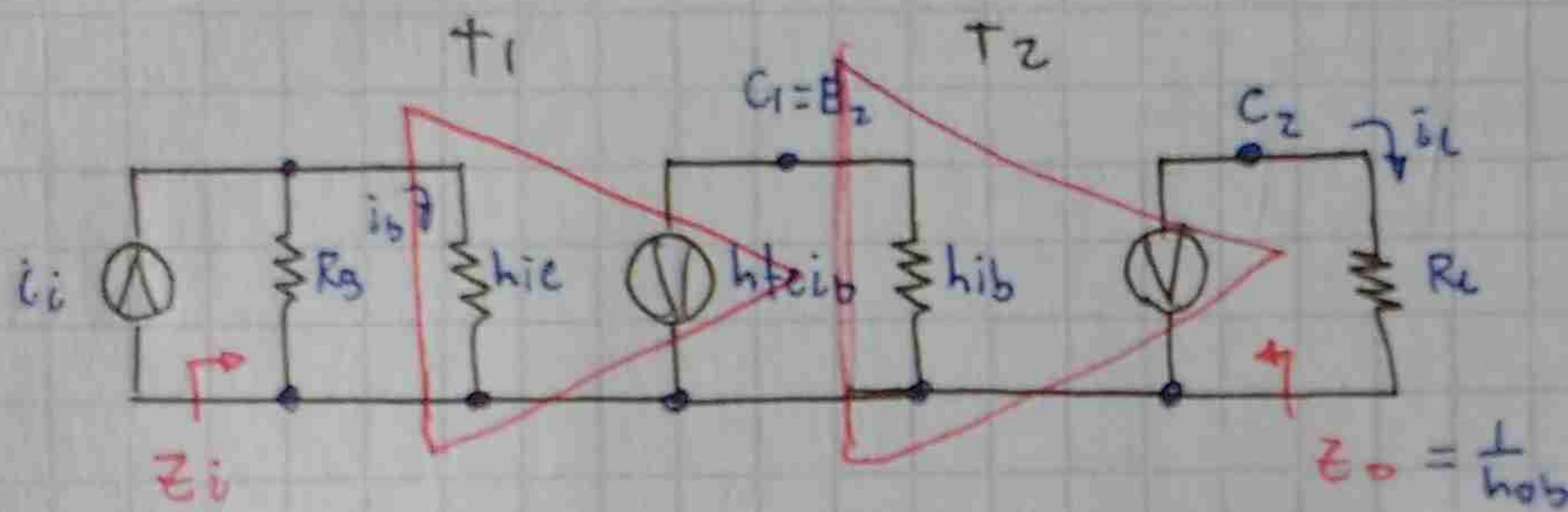
$$I_{BQ2} = \frac{I_{CQ2}}{\beta} = I_{BQ1}$$

$$V_{CEQ1} = V_{B2} - V_{BE} - I_{CQ1} R_E$$

Venga
Desde la base.

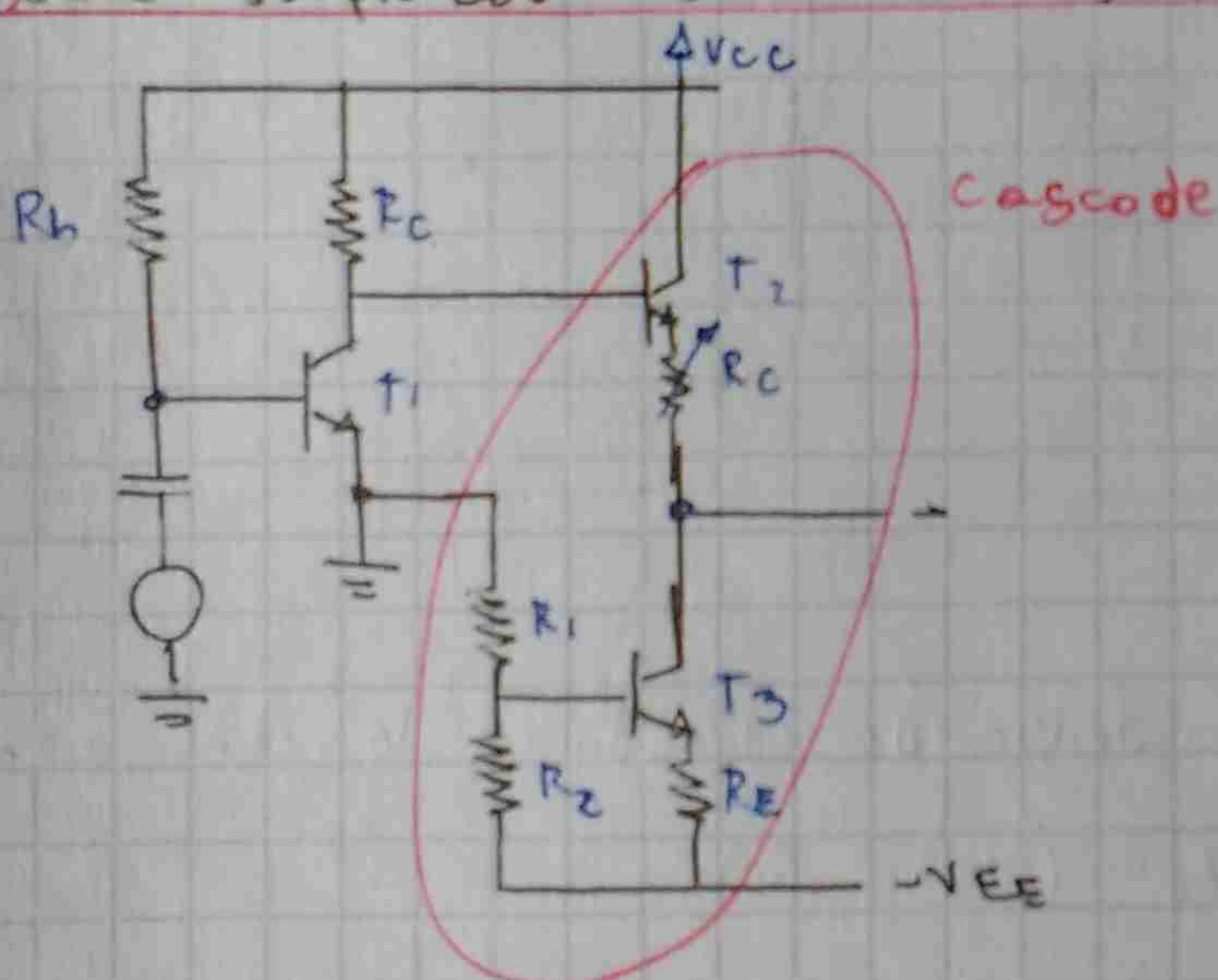
$$V_{CEQ2} = V_{CC} - I_{CQ2} (R_L + R_E)$$

con lo anterior



Cp - o desplazador del nivel de continua a la salida sin variar la ganancia Av

(2)



$$I_{BQ1} = \frac{V_{CC} - V_{BE}}{R_B}$$

$$I_{CQ1} = \beta I_{BQ1}$$

$$I_{CQ1} \gg I_{BQ2}$$

$$V_{B2} = V_{C1} = V_{CC} - I_{CQ1} R_C$$

$$V_{E2} = V_{B2} - V_{BE}$$

$$V_{E2} \Rightarrow I_{CQ3} R'_e = V_L$$

$$R'_e = \frac{V_{E2} - V_L}{I_{CQ3}} \rightarrow \text{offset}$$

$$V_{B3} = \frac{-V_{EE}}{R_1 + R_2} R_1$$

$$V_{E3} = V_{B3} - V_{BE}$$

$$V_{E3} = V_{B3} - V_{BE}$$

$$I_{CQ3} = \frac{V_{RE}}{R_E} = \frac{V_{E3} - (-V_{EE})}{R_E} = I_{CQ2}$$

NOTA